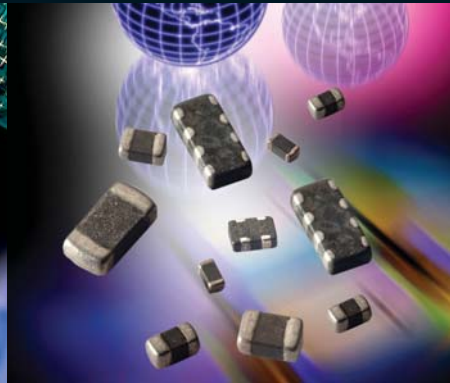
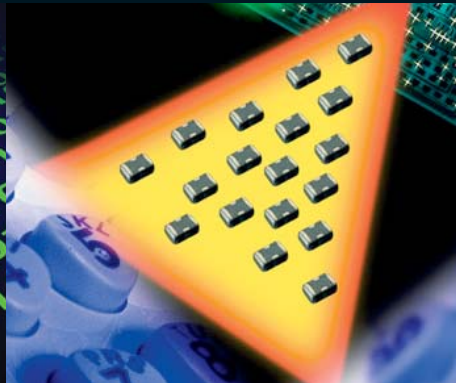


AVX Transient Suppression Products



Version 14.1

AVX
A KYOCERA GROUP COMPANY

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NOTICE: Specifications are subject to change without notice. Contact your nearest AVX Sales Office for the latest specifications. All statements, information and data given herein are believed to be accurate and reliable, but are presented without guarantee, warranty, or responsibility of any kind, expressed or implied. Statements or suggestions concerning possible use of our products are made without representation or warranty that any such use is free of patent infringement and are not recommendations to infringe any patent. The user should not assume that all safety measures are indicated or that other measures may not be required. Specifications are typical and may not apply to all applications.

GENERAL DESCRIPTION

The AVX TransGuard® Transient Voltage Suppressors (TVS) with unique high-energy multilayer construction represents state-of-the-art overvoltage circuit protection. Monolithic multilayer construction provides protection from voltage transients caused by ESD, lightning, NEMP, inductive switching, etc. True surface mount product is provided in EIA industry standard packages. Thru-hole components are supplied as conformally coated axial devices.

TRANSQUARD® DESCRIPTION

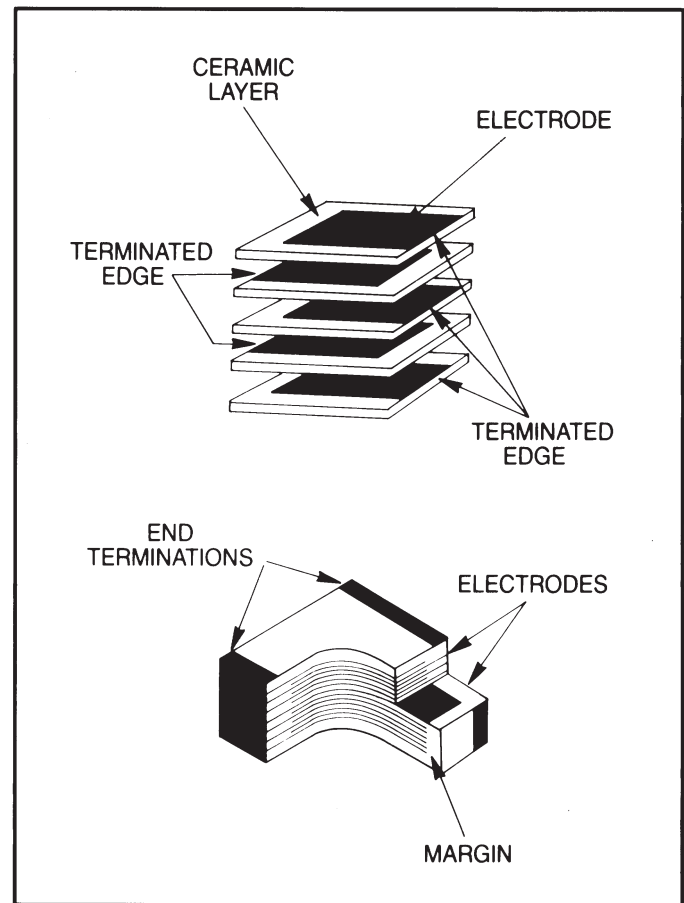
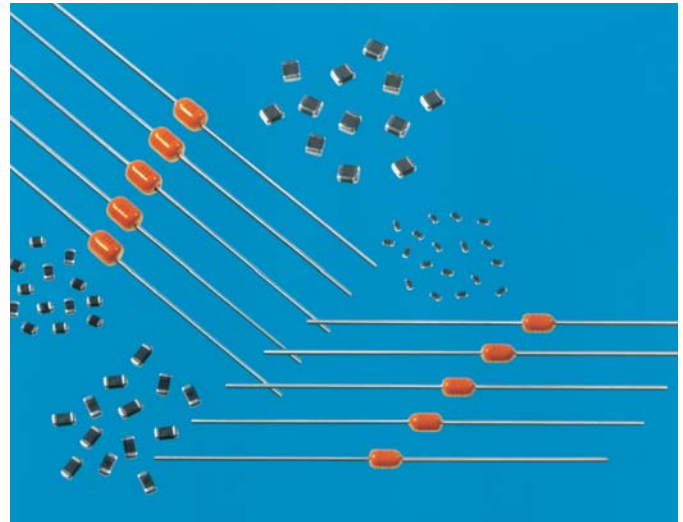
TransGuard® products are zinc oxide (ZnO) based ceramic semiconductor devices with non-linear voltage-current characteristics (bi-directional) similar to back-to-back zener diodes. They have the added advantage of greater current and energy handling capabilities as well as EMI/RFI attenuation. Devices are fabricated by a ceramic sintering process that yields a structure of conductive ZnO grains surrounded by electrically insulating barriers, creating varistor-like behavior.

AVX VG series parts (large case size, high energy) are glass encapsulated. These parts provide the same high reliability as traditional VC series parts. The glass encapsulation provides also enhanced resistance against harsh environment or process such as acids, salts, chlorite flux.

The number of grain-boundary interfaces between conducting electrodes determines "Breakdown Voltage" of the device. High voltage applications such as AC line protection require many grains between electrodes while low voltage requires few grains to establish the appropriate breakdown voltage. Single layer ceramic disc processing proved to be a viable production method for thick cross section devices with many grains, but attempts to address low voltage suppression needs by processing single layer ceramic disc formulations with huge grain sites has had limited success.

AVX, the world leader in the manufacture of multilayer ceramic capacitors, now offers the low voltage transient protection marketplace a true multilayer, monolithic surface mount varistor. Technology leadership in processing thin dielectric materials and patented processes for precise ceramic grain growth have yielded superior energy dissipation in the smallest size. Now a varistor has voltage characteristics determined by design and not just cell sorting whatever falls out of the process.

Multilayer ceramic varistors are manufactured by mixing ceramic powder in an organic binder (slurry) and casting it into thin layers of precision thickness. Metal electrodes are deposited onto the green ceramic layers which are then stacked to form a laminated structure. The metal electrodes are arranged so that their terminations alternate from one end of the varistor to the other. The device becomes a monolithic block during the sintering (firing) cycle providing uniform energy dissipation in a small volume.



PART NUMBER IDENTIFICATION

Surface Mount Devices

Important: For part number identification only, not for construction of part numbers.

The information below only defines the numerical value of part number digits, and cannot be used to construct a desired set of electrical limits. Please refer to the TransGuard® part number data for the correct electrical ratings.

VC 1206 05 D 150 R P

TERMINATION FINISH:

P = Ni/Sn Alloy (Plated)

PACKAGING (Pcs/Reel):

STYLE	"D"	"R"	"T"	"W"
VC0402	N/A	N/A	N/A	10,000
VC0603	1,000	4,000	10,000	N/A
VC0805	1,000	4,000	10,000	N/A
VC1206	1,000	4,000	10,000	N/A
VC1210	1,000	2,000	10,000	N/A

CLAMPING VOLTAGE:

Where:

100 = 12V	500 = 50V
150 = 18V	560 = 60V
200 = 22V	580 = 60V
250 = 27V	620 = 67V
300 = 32V	650 = 67V
390 = 42V	101 = 100V
400 = 42V	121 = 120V

ENERGY:

Where:

A = 0.1J	J = 1.5J	S = 1.9-2.0J
B = 0.2J	K = 0.6J	T = 0.01J
C = 0.3J	L = 0.8J	U = 4.0-5.0J
D = 0.4J	M = 1.0J	V = 0.02J
E = 0.5J	N = 1.1J	W = 6.0J
F = 0.7J	P = 3.0J	X = 0.05J
G = 0.9J	Q = 1.3J	Y = 12.0J
H = 1.2J	R = 1.7J	Z = 25.0J

WORKING VOLTAGE:

Where:

03 = 3.3 VDC	18 = 18.0 VDC
05 = 5.6 VDC	26 = 26.0 VDC
09 = 9.0 VDC	30 = 30.0 VDC
12 = 12.0 VDC	48 = 48.0 VDC
14 = 14.0 VDC	60 = 60.0 VDC
	85 = 85.0 VDC

CASE SIZE DESIGNATOR:

SIZE	LENGTH	WIDTH
0402	1.00±0.10mm (0.040"±0.004")	0.5±0.10mm (0.020"±0.004")
0603	1.60±0.15mm (0.063"±0.006")	0.8±0.15mm (0.032"±0.006")
0805	2.01±0.2mm (0.079"±0.008")	1.25±0.2mm (0.049"±0.008")
1206	3.20±0.2mm (0.126"±0.008")	1.60±0.2mm (0.063"±0.008")
1210	3.20±0.2mm (0.126"±0.008")	2.49±0.2mm (0.098"±0.008")

CASE STYLE:

C = Chip
G = Chip Glass Encapsulated

PRODUCT DESIGNATOR:

V = Varistor

MARKING:

All standard surface mount TransGuard® chips will **not** be marked.

Axial Leaded Devices

Important: For part number identification only, not for construction of part numbers.

The information below only defines the numerical value of part number digits, and cannot be used to construct a desired set of electrical limits. Please refer to the TransGuard® part number data for the correct electrical ratings.

V A 1000 05 D 150 R L

LEAD FINISH:

Copper clad steel, solder coated

PACKAGING (Pcs/Reel):

STYLE	"D"	"R"	"T"
VA1000	1,000	3,000	7,500
VA2000	1,000	2,500	5,000

CLAMPING VOLTAGE:

Where:

100 = 12V	580 = 60V
150 = 18V	650 = 67V
300 = 32V	101 = 100V
400 = 42V	121 = 120V

ENERGY:

Where: A = 0.1J
D = 0.4J
K = 2.0J

WORKING VOLTAGE:

Where:

03 = 3.3 VDC	26 = 26.0 VDC
05 = 5.6 VDC	30 = 30.0 VDC
14 = 14.0 VDC	48 = 48.0 VDC
18 = 18.0 VDC	60 = 60.0 VDC

CASE SIZE DESIGNATOR:

SIZE	LENGTH	DIAMETER
1000	4.32mm (0.170")	2.54mm (0.100")
2000	4.83mm (0.190")	3.56mm (0.140")

CASE STYLE:

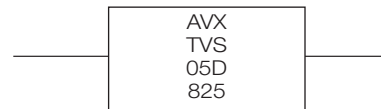
A = Axial

PRODUCT DESIGNATOR:

V = Varistor

MARKING:

All axial TransGuards® are marked with vendor identification, product identification, voltage/energy rating code and date code (see example below):



Where: AVX = Always AVX (Vendor Identification)
TVS = Always TVS (Product Identification - Transient Voltage Suppressor)
05D = Working VDC and Energy Rating (Joules)
Where: 05 = 5.6 VDC, D = 0.4J
725 = Three Digit Date Code
Where: 8 = Last digit of year (2008)
25 = Week of year

Not RoHS Compliant



LEAD-FREE
LEAD-FREE COMPATIBLE
COMPONENT



RoHS
COMPLIANT

For RoHS compliant products,
please select correct termination style.

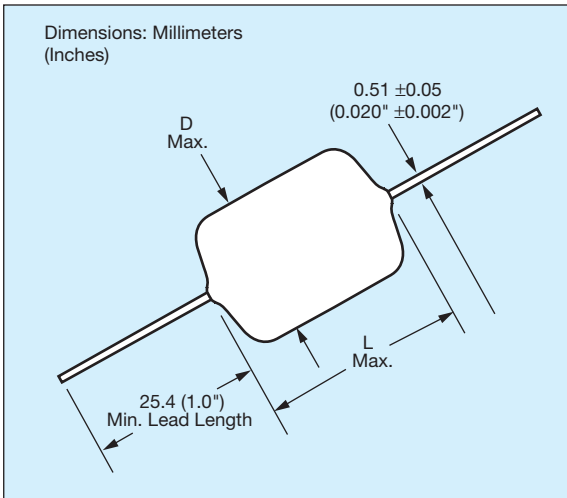
ELECTRICAL CHARACTERISTICS

AVX PN	V _w (DC)	V _w (AC)	V _B	V _C	I _{VC}	I _L	E _T	I _P	Cap	Freq	Case
VC060303A100	3.3	2.3	5.0±20%	12	1	100	0.1	30	1450	K	0603
VC080503A100	3.3	2.3	5.0±20%	12	1	100	0.1	40	1400	K	0805
VC080503C100	3.3	2.3	5.0±20%	12	1	100	0.3	120	5000	K	0805
VC120603A100	3.3	2.3	5.0±20%	12	1	100	0.1	40	1250	K	1206
VC120603D100	3.3	2.3	5.0±20%	12	1	100	0.4	150	4700	K	1206
VA100003A100	3.3	2.3	5.0±20%	12	1	100	0.1	40	1500	K	1000
VA100003D100	3.3	2.3	5.0±20%	12	1	100	0.4	150	4700	K	1000
VC040205X150	5.6	4.0	8.5±20%	18	1	35	0.05	20	175	M	0402
VC060305A150	5.6	4.0	8.5±20%	18	1	35	0.1	30	750	K	0603
VC080505A150	5.6	4.0	8.5±20%	18	1	35	0.1	40	1100	K	0805
VC080505C150	5.6	4.0	8.5±20%	18	1	35	0.3	120	3000	K	0805
VC120605A150	5.6	4.0	8.5±20%	18	1	35	0.1	40	1200	K	1206
VC120605D150	5.6	4.0	8.5±20%	18	1	35	0.4	150	3000	K	1206
VA100005A150	5.6	4.0	8.5±20%	18	1	35	0.1	40	1000	K	1000
VA100005D150	5.6	4.0	8.5±20%	18	1	35	0.4	150	2800	K	1000
VC040209X200	9.0	6.4	12.7±15%	22	1	25	0.05	20	175	M	0402
VC060309A200	9.0	6.4	12.7±15%	22	1	25	0.1	30	550	K	0603
VC080509A200	9.0	6.4	12.7±15%	22	1	25	0.1	40	750	K	0805
VC080512A250	12.0	8.5	16±15%	27	1	25	0.1	40	525	K	0805
VC040214X300	14.0	10.0	18.5±12%	32	1	15	0.05	20	85	K	0402
VC060314A300	14.0	10.0	18.5±12%	32	1	15	0.1	30	350	K	0603
VC080514A300	14.0	10.0	18.5±12%	32	1	15	0.1	40	325	K	0805
VC080514C300	14.0	10.0	18.5±12%	32	1	15	0.3	120	900	K	0805
VC120614A300	14.0	10.0	18.5±12%	32	1	15	0.1	40	600	K	1206
VC120614D300	14.0	10.0	18.5±12%	32	1	15	0.4	150	1050	K	1206
VA100014A300	14.0	10.0	18.5±12%	32	1	15	0.1	40	325	K	1000
VA100014D300	14.0	10.0	18.5±12%	32	1	15	0.4	150	1100	K	1000
VC121016J390	16.0	13.0	25.5±10%	40	2.5	10	1.6	500	3100	K	1210
VG181216P400	16.0	11.0	24.5±10%	42	5	10	2.9	1000	5000	K	1812
VG222016Y400	16.0	11.0	24.5±10%	42	10	10	7.2	1500	13000	K	2220
VC040218X400	18.0	13.0	25.5±10%	42	1	10	0.05	20	65	M	0402
VC060318A400	18.0	13.0	25.5±10%	42	1	10	0.1	30	150	K	0603
VC080518A400	18.0	13.0	25.5±10%	42	1	10	0.1	30	225	K	0805
VC080518C400	18.0	13.0	25.5±10%	42	1	10	0.3	100	550	K	0805
VC120618A400	18.0	13.0	25.5±10%	42	1	10	0.1	30	350	K	1206
VC120618D400	18.0	13.0	25.5±10%	42	1	10	0.4	150	900	K	1206
VC120618E380	18.0	13.0	25.5±10%	38	1	15	0.5	200	930	K	1206
VC121018J390	18.0	13.0	25.5±10%	42	5	10	1.6	500	3100	K	1210
VA100018A400	18.0	13.0	25.5±10%	42	1	10	0.1	40	350	K	1000
VA100018D400	18.0	13.0	25.5±10%	42	1	10	0.4	150	900	K	1000
VG121022R440	22.0	17.0	27±10%	44	2.5	10	1.7	400	1600	K	1210
VC060326A580	26.0	18.0	34.5±10%	60	1	10	0.1	30	155	K	0603
VC080526A580	26.0	18.0	34.5±10%	60	1	10	0.1	30	120	K	0805
VC080526C580	26.0	18.0	34.5±10%	60	1	10	0.3	100	250	K	0805

ELECTRICAL CHARACTERISTICS

AVX PN	V _w (DC)	V _w (AC)	V _B	V _C	I _{vc}	I _L	E _T	I _P	Cap	Freq	Case
VC120626D580	26.0	18.0	34.5±10%	60	1	10	0.4	120	500	K	1206
VC120626F540	26.0	20.0	33.0±10%	54	1	15	0.7	200	600	K	1206
VC121026H560	26.0	18.0	34.5±10%	60	5	10	1.2	300	2150	K	1210
VC181226P540	26.0	20.0	33.0±10%	54	5	15	3.0	800	3000	K	1812
VA100026D580	26.0	18.0	34.5±10%	60	1	10	0.4	120	650	K	1000
VC060330A650	30.0	21.0	41.0±10%	67	1	10	0.1	30	125	K	0603
VC080530A650	30.0	21.0	41.0±10%	67	1	10	0.1	30	90	M	0805
VC080530C650	30.0	21.0	41.0±10%	67	1	10	0.3	80	250	K	0805
VC120630D650	30.0	21.0	41.0±10%	67	1	10	0.4	120	400	K	1206
VC121030G620	30.0	21.0	41.0±10%	67	5	10	0.9	220	1750	K	1210
VC121030H620	30.0	21.0	41.0±10%	67	5	10	1.2	280	1850	K	1210
VC121030S620	30.0	21.0	41.0±10%	67	5	10	1.9	300	1500	K	1210
VA100030D650	30.0	21.0	41.0±10%	67	1	10	0.4	120	550	K	1000
VC080531C650	31.0	25.0	39.0±10%	65	1	10	0.3	80	250	K	0805
VC120631M650	31.0	25.0	39.0±10%	65	1	15	1.0	200	500	K	1206
VC080538C770	38.0	30.0	47.0±10%	77	1	10	0.3	80	200	K	0805
VC120638N770	38.0	30.0	47.0±10%	77	1	15	1.1	200	400	K	1206
VG121038S770	38.0	30.0	47.0±10%	77	2.5	15	2.0	400	1000	K	1210
VG181238U770	38.0	30.0	47.0±10%	77	5	15	4.2	800	1300	K	1812
VG222038Y770	38.0	30.0	47.0±10%	77	10	15	12	2000	4200	K	2220
VC120642L800	42.0	32.0	51.0±10%	80	1	15	0.8	180	600	K	1206
VC120645K900	45.0	35.0	56.0±10%	90	1	15	0.6	200	260	K	1206
VG181245U900	45.0	35.0	56.0±10%	90	5	15	4.0	500	1200	K	1812
VC120648D101	48.0	34.0	62.0±10%	100	1	10	0.4	100	225	K	1206
VC121048G101	48.0	34.0	62.0±10%	100	5	10	0.9	220	450	K	1210
VC121048H101	48.0	34.0	62.0±10%	100	5	10	1.2	250	500	K	1210
VA100048D101	48.0	34.0	62.0±10%	100	1	10	0.4	100	200	K	1000
VC120656F111	56.0	40.0	68.0±10%	110	1	15	0.7	100	180	K	1206
VC181256U111	56.0	40.0	68.0±10%	110	5	15	4.8	500	800	K	1812
VC121060J121	60.0	42.0	76.0±10%	120	5	10	1.5	250	400	K	1210
VA200060K121	60.0	42.0	76.0±10%	120	1	10	2.0	300	400	K	2000
VC120665L131	65.0	50.0	82.0±10%	135	1	15	0.8	100	250	K	1206
VC120665M131	65.0	50.0	82.0±10%	135	1	15	1.0	150	250	K	1206
VG121065P131	65.0	50.0	82±10%	135	2.5	15	2.7	350	600	K	1210
VC121085S151	85.0	60.0	100±10%	150	1	35	2.0	250	275	K	1210

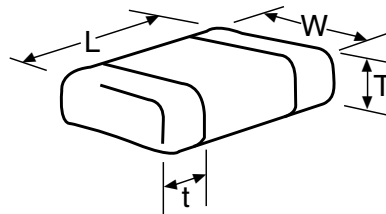
V _w (DC)	DC Working Voltage (V)		Working Voltage (µA)
V _w (AC)	AC Working Voltage (V)	E _T	Transient Energy Rating (J, 10x1000µS)
V _B	Typical Breakdown Voltage (V @ 1mA _{DC})	I _P	Peak Current Rating (A, 8x20µS)
V _B Tol	V _B Tolerance is ± from Typical Value	Cap	Typical Capacitance (pF) @ frequency specified and 0.5 V _{RMS}
V _C	Clamping Voltage (V @ I _{vc})	Freq	Frequency at which capacitance is measured (K = 1kHz, M = 1MHz)
I _{vc}	Test Current for V _C (A, 8x20µS)		
I _L	Maximum Leakage Current at the		



DIMENSIONS: mm (inches)

AVX Style		VA1000	VA2000
(L) Max Length	mm (in.)	4.32 (0.170)	4.83 (0.190)
(D) Max Diameter	mm (in.)	2.54 (0.100)	3.56 (0.140)

Lead Finish: Copper Clad Steel, Solder Coated



DIMENSIONS: mm (inches)

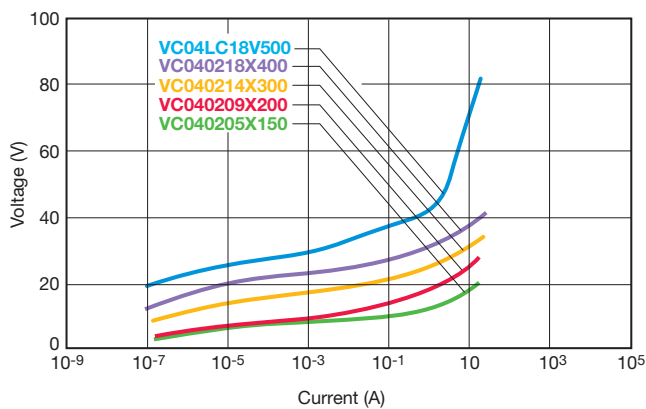
AVX Style		0402	0603	0805	1206	1210	1812	2220
(L) Length	mm (in.)	1.00±0.10 (0.040±0.004)	1.60±0.15 (0.063±0.006)	2.01±0.20 (0.079±0.008)	3.20±0.20 (0.126±0.008)	3.20±0.20 (0.126±0.008)	4.50±0.30 (0.177±0.012)	5.70±0.40 (0.224±0.016)
(W) Width	mm (in.)	0.50±0.10 (0.020±0.004)	0.80±0.15 (0.031±0.006)	1.25±0.20 (0.049±0.008)	1.60±0.20 (0.063±0.008)	2.49±0.20 (0.098±0.008)	3.20±0.30 (0.126±0.012)	5.00±0.40 (0.197±0.016)
(T) Max Thickness	mm (in.)	0.6 (0.024)	0.9 (0.035)	1.02 (0.040)	1.02 (0.040)	1.70 (0.067)	2.00 (0.080)	2.50 (0.098)
(t) Land Length	mm (in.)	0.25±0.15 (0.010±0.006)	0.35±0.15 (0.014±0.006)	0.71 max. (0.028 max.)	0.94 max. (0.037 max.)	1.14 max. (0.045 max.)	1.00 max. (0.039 max.)	1.00 max. (0.039 max.)

AVX Multilayer Ceramic Transient Voltage Suppressors

TYPICAL PERFORMANCE CURVES (0402 CHIP SIZE)

VOLTAGE/CURRENT CHARACTERISTICS

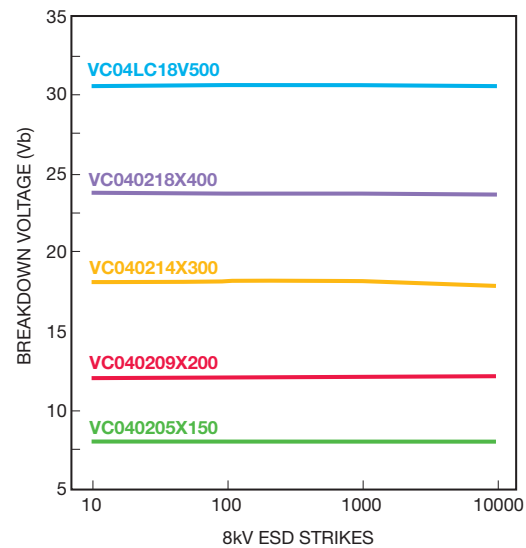
Multilayer construction and improved grain structure result in excellent transient clamping characteristics up to 20 amps peak current, while maintaining very low leakage currents under DC operating conditions. The VI curves below show the voltage/current characteristics for the 5.6V, 9V, 14V, 18V and low capacitance StaticGuard parts with currents ranging from parts of a micro amp to tens of amps.



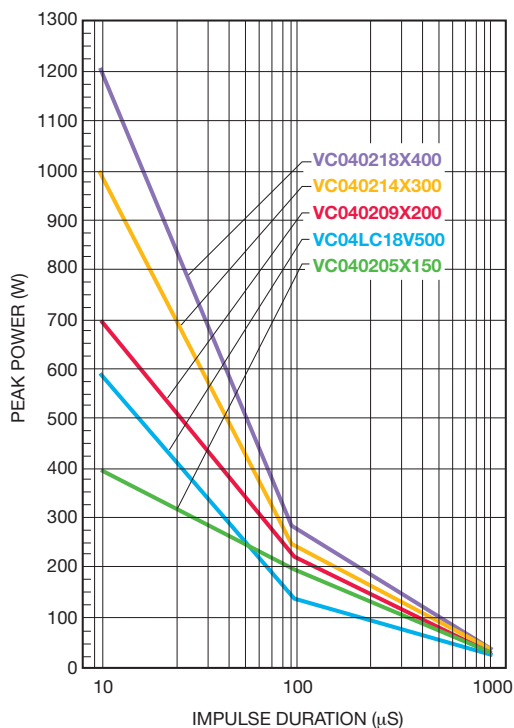
PULSE DEGRADATION

Traditionally varistors have suffered degradation of electrical performance with repeated high current pulses resulting in decreased breakdown voltage and increased leakage current. It has been suggested that irregular intergranular boundaries and bulk material result in restricted current paths and other non-Schottky barrier paralleled conduction paths in the ceramic. Repeated pulsing of TransGuard® transient voltage suppressors with 150Amp peak 8 x 20µS waveforms shows negligible degradation in breakdown voltage and minimal increases in leakage current. This does not mean that TransGuard® suppressors do not suffer degradation, but it occurs at much higher current.

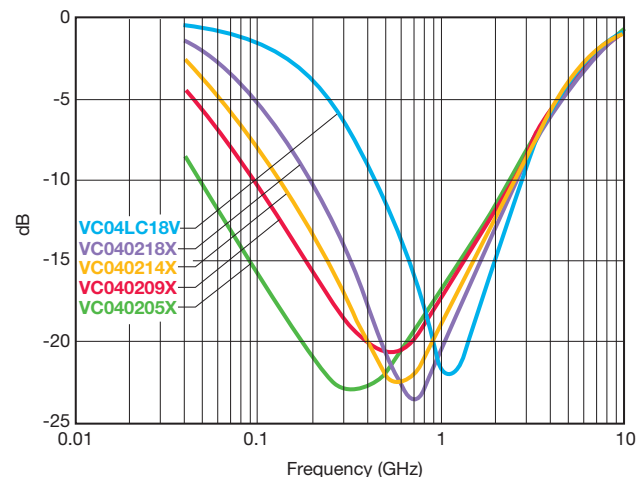
ESD TEST OF 0402 PARTS



PEAK POWER VS PULSE DURATION



INSERTION LOSS CHARACTERISTICS

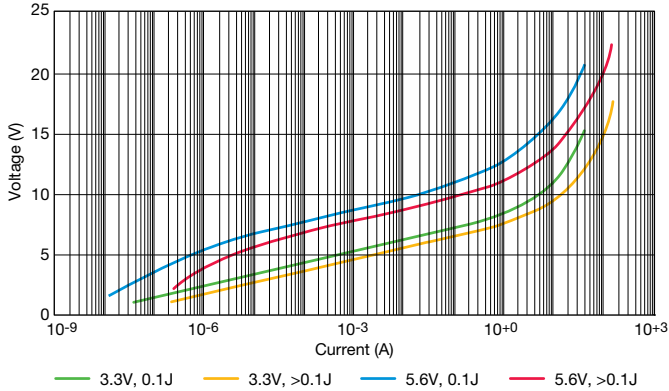


TYPICAL PERFORMANCE CURVES (0603, 0805, 1206 & 1210 CHIP SIZES)

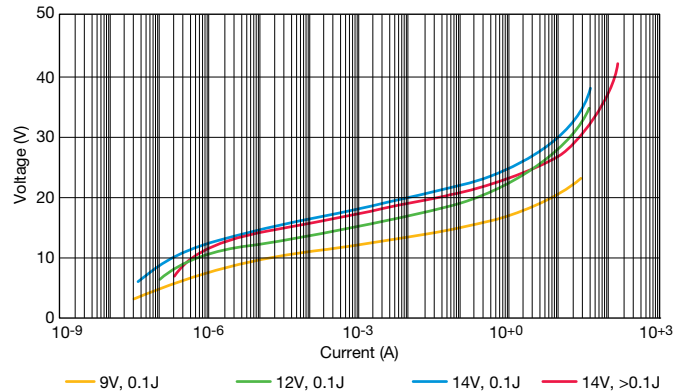
VOLTAGE/CURRENT CHARACTERISTICS

Multilayer construction and improved grain structure result in excellent transient clamping characteristics up to 500 amps peak current, depending on case size and energy rating, while maintaining very low leakage currents under DC operating conditions. The VI curve below shows the voltage/current characteristics for the 3.3V, 5.6V, 12V, 14V, 18V, 26V, 30V, 48V and 60VDC parts with currents ranging from parts of a micro amp to tens of amps.

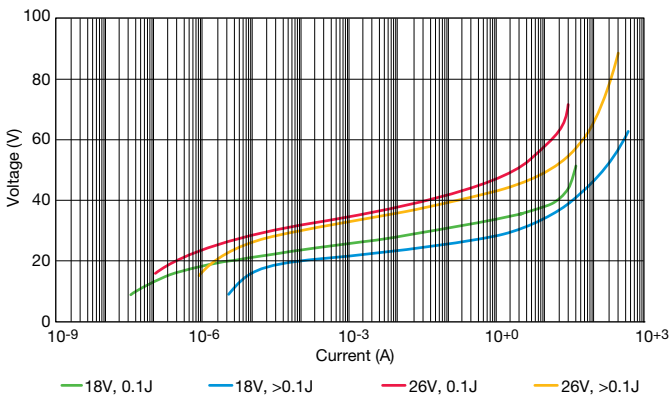
VI Curves - 3.3V and 5.6V Products



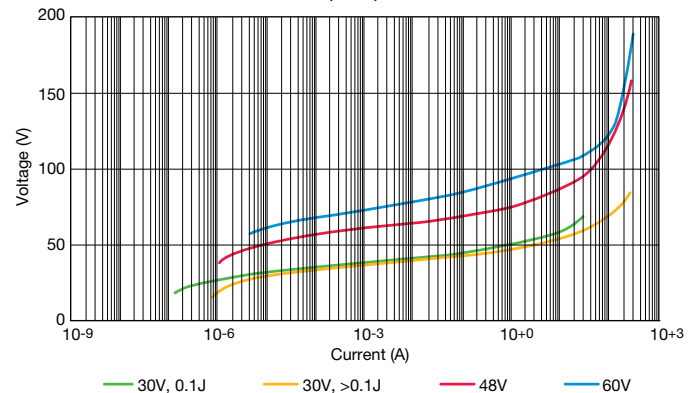
VI Curves - 9V, 12V, and 14V Products



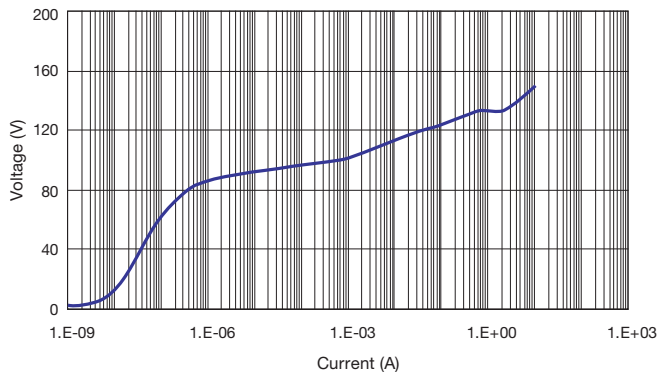
VI Curves - 18V and 26V Products



VI Curves - 30V, 48V, and 60V Products



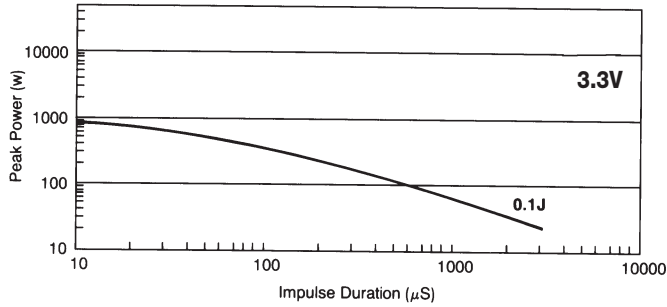
VI Curve - 85V Product



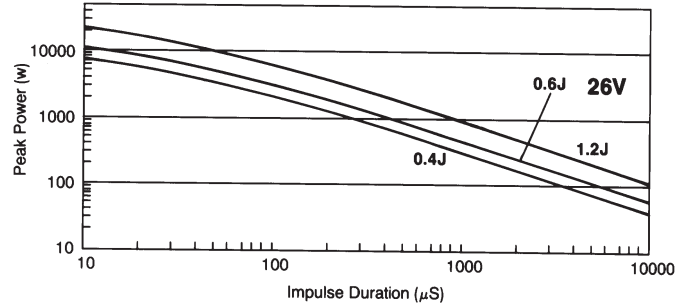
AVX Multilayer Ceramic Transient Voltage Suppressors

TYPICAL PERFORMANCE CURVES (0603, 0805, 1206 & 1210 CHIP SIZES)

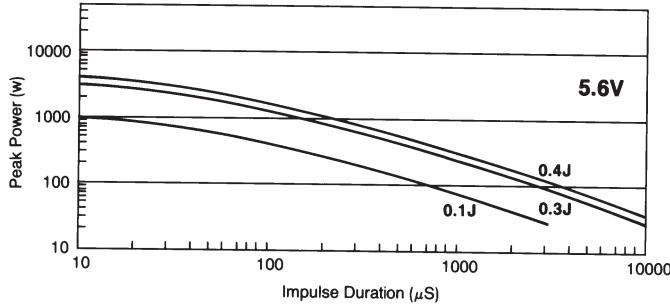
TYPICAL PULSE RATING CURVE
3.3V MULTILAYER TRANSGUARD®



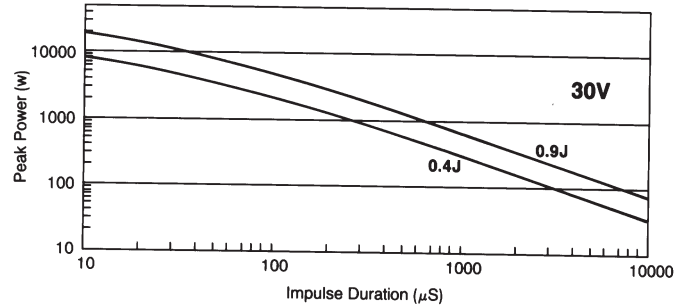
TYPICAL PULSE RATING CURVE
26V MULTILAYER TRANSGUARD®



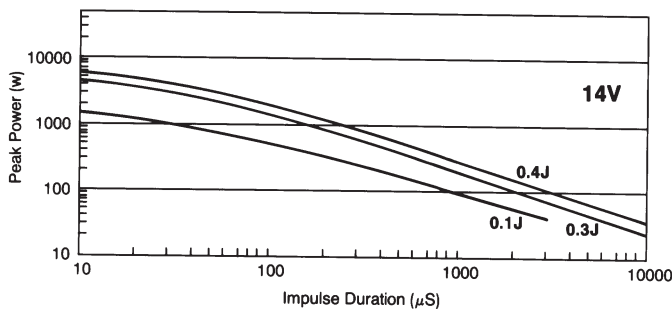
TYPICAL PULSE RATING CURVE
5.6V MULTILAYER TRANSGUARD®



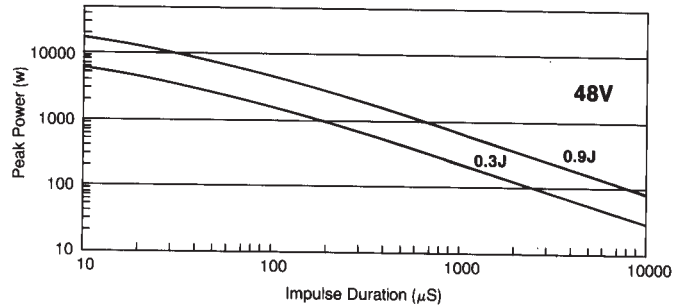
TYPICAL PULSE RATING CURVE
30V MULTILAYER TRANSGUARD®



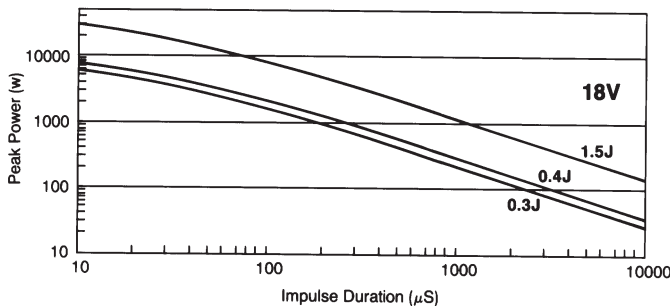
TYPICAL PULSE RATING CURVE
14V MULTILAYER TRANSGUARD®



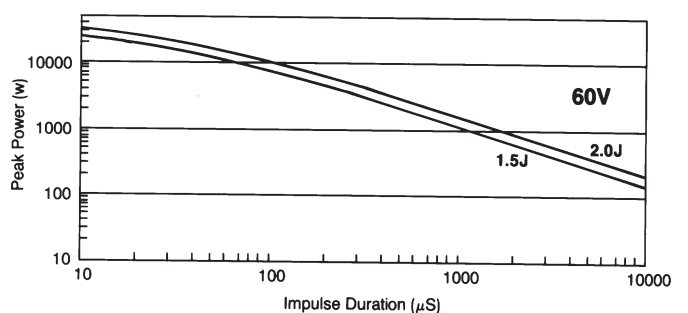
TYPICAL PULSE RATING CURVE
48V MULTILAYER TRANSGUARD®



TYPICAL PULSE RATING CURVE
18V MULTILAYER TRANSGUARD®



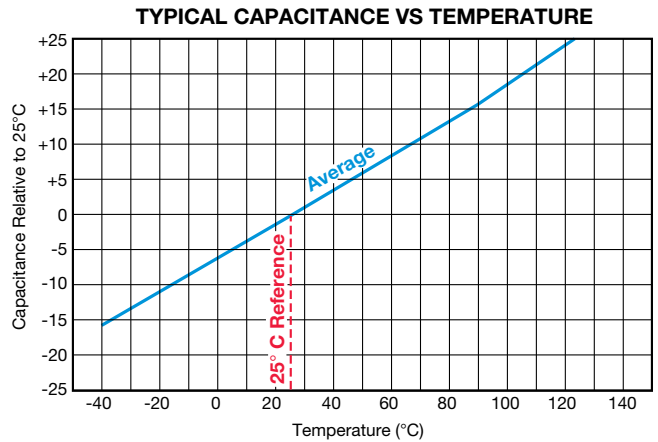
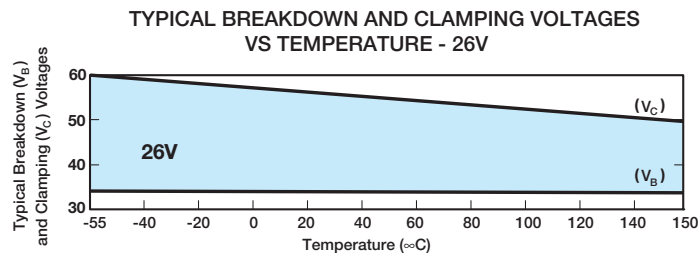
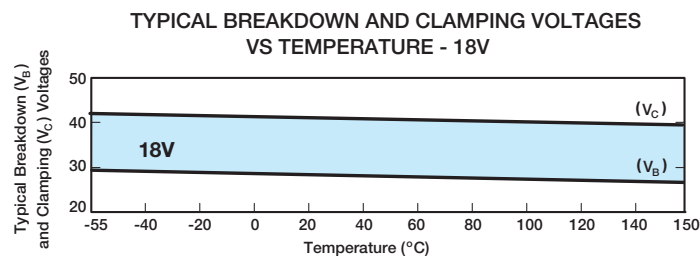
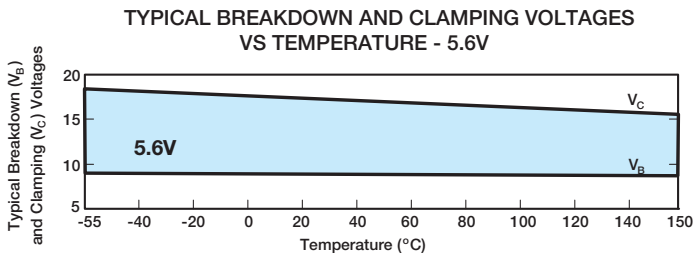
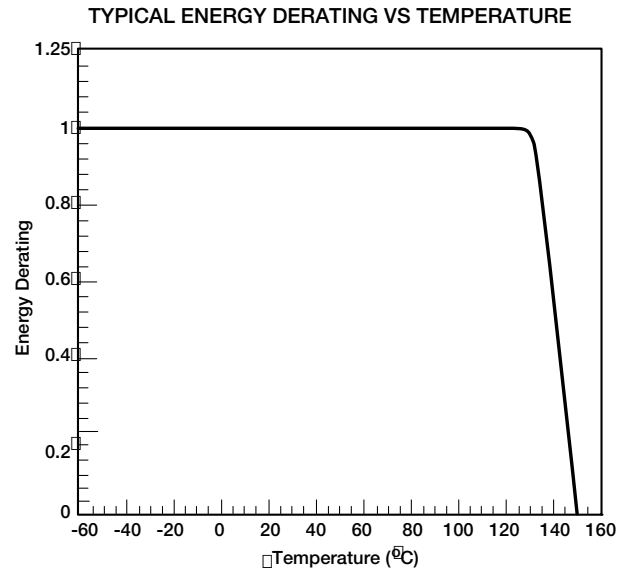
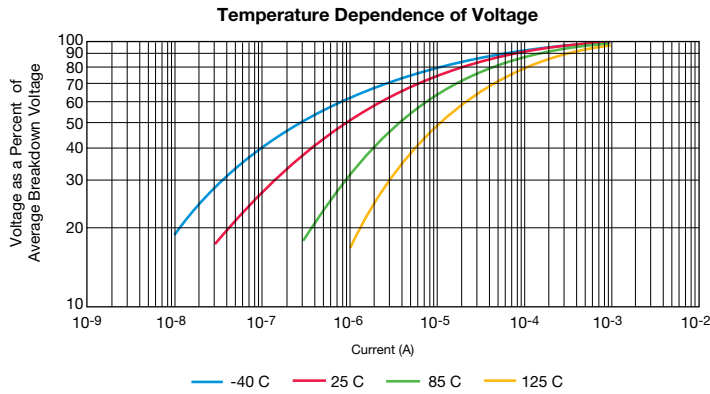
TYPICAL PULSE RATING CURVE
60V MULTILAYER TRANSGUARD®



TYPICAL PERFORMANCE CURVES (0603, 0805, 1206 & 1210 CHIP SIZES)

TEMPERATURE CHARACTERISTICS

TransGuard® suppressors are designed to operate over the full temperature range from -55°C to +125°C. This operating temperature range is for both surface mount and axial leaded products.



TYPICAL PERFORMANCE CURVES (0603, 0805, 1206 & 1210 CHIP SIZES)

PULSE DEGRADATION

Traditionally varistors have suffered degradation of electrical performance with repeated high current pulses resulting in decreased breakdown voltage and increased leakage current. It has been suggested that irregular intergranular boundaries and bulk material result in restricted current paths and other non-Schottky barrier paralleled conduction paths in the ceramic. Repeated pulsing of both 5.6 and 14V TransGuard® transient voltage suppressors with

150 Amp peak $8 \times 20\mu\text{s}$ waveforms shows negligible degradation in breakdown voltage and minimal increases in leakage current. This does not mean that TransGuard® suppressors do not suffer degradation, but it occurs at much higher current. The plots of typical breakdown voltage vs number of 150A pulses are shown below.

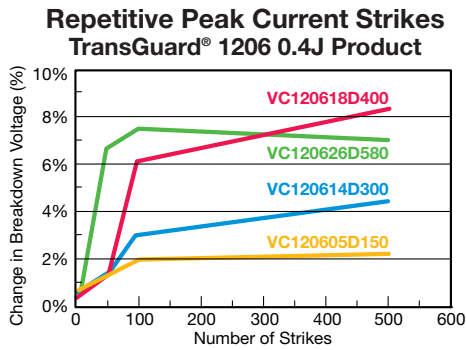


Figure 1

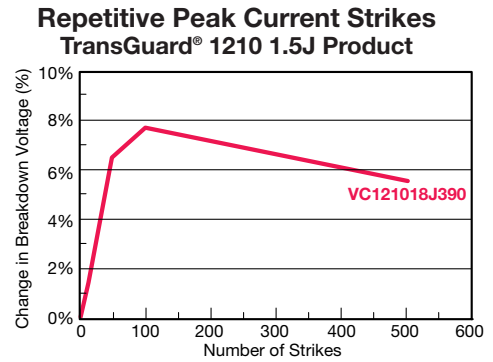


Figure 3

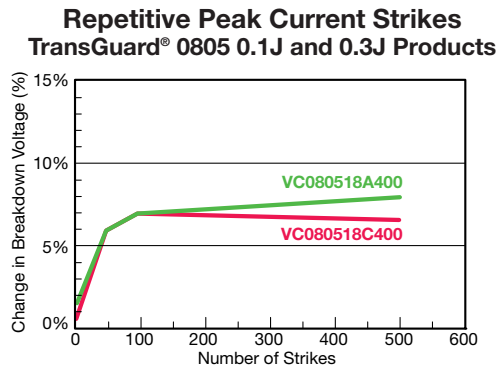


Figure 2

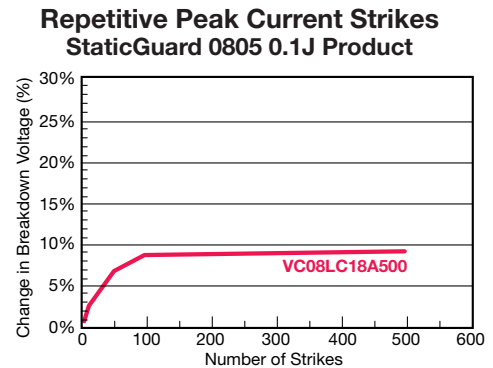
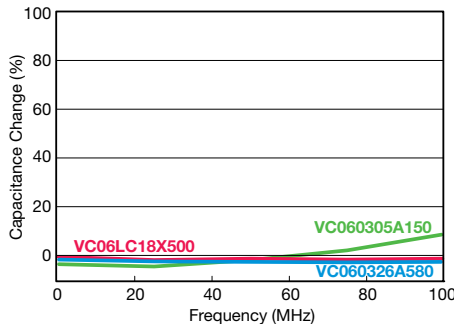


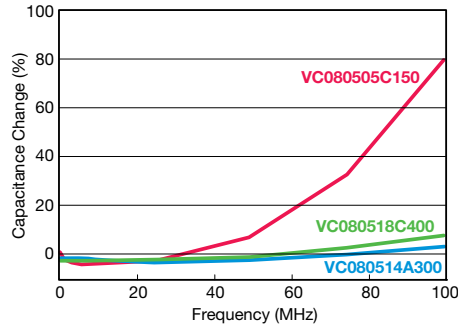
Figure 4

CAPACITANCE/FREQUENCY CHARACTERISTICS

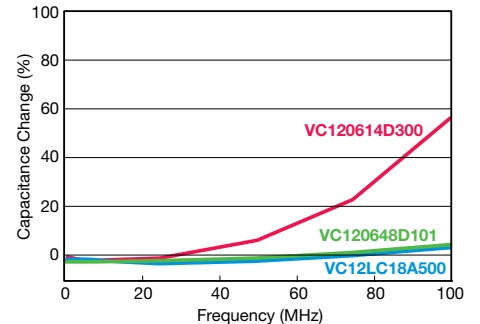
TransGuard® Capacitance vs Frequency 0603



TransGuard® Capacitance vs Frequency 0805



TransGuard® Capacitance vs Frequency 1206



TransGuard® Automotive Series

Multilayer Varistors for Automotive Applications



GENERAL DESCRIPTION

The TransGuard Automotive Series are zinc oxide (ZnO) based ceramic semiconductor devices with non-linear, bi-directional voltage-current characteristics.

They have the advantage of offering bi-directional overvoltage protection as well as EMI/RFI attenuation in a single SMT package. The Automotive Series high current and high energy handling capability make them well suited for protection against automotive related transients.

AVX VG series parts (large case size, high energy) are glass encapsulated. These parts provide the same high reliability as traditional VC series parts. The glass encapsulation provides also enhanced resistance against harsh environment or process such as acids, salts, chlorite flux.

Operating Temperature: -55°C to +125°C

FEATURES

- High Reliability
- High Energy Absorption (Load Dump)
- High Current Handling
- AEC Q200 Qualified
- Bi-Directional protection
- EMI/RFI attenuation
- Multi-strike capability
- Sub 1nS response to ESD strike

APPLICATIONS

- Internal Combustion Engine (ICE) Vehicles
- Hybrid Electric Vehicles (HEV)
- Plug-in Hybrid Electric Vehicles (PHEV)
- Commercial Vehicles
 - CAN, LIN, FLEXRAY based modules
 - Sensors
 - Module load dump protection
 - Motor/inductive load transient suppression

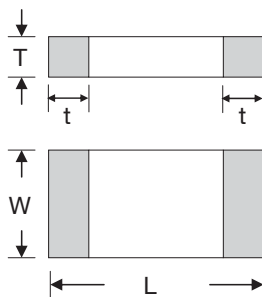


HOW TO ORDER

VC	AS	1206	18	D	400	R	P									
Varistor Chip	Automotive Series	Case Size	Working Voltage	Energy Rating	Clamping Voltage	Package	Termination									
VC = Varistor Chip VG = Varistor Glass Encapsulated Chip		0402 0603 0805 1206 1210 1812 2220	05 = 5.6Vdc 09 = 9Vdc 12 = 12Vdc 14 = 14Vdc 16 = 16Vdc 18 = 18Vdc 26 = 26Vdc 30 = 30Vdc 31 = 31Vdc	34 = 34Vdc 38 = 38Vdc 42 = 42Vdc 45 = 45Vdc 48 = 48Vdc 56 = 56Vdc 60 = 60Vdc 85 = 85Vdc	A = 0.1J B = 0.2J C = 0.3J D = 0.4J E = 0.5J F = 0.7J H = 1.2J J = 1.5J K = 0.6J	L = 0.8J S = 1.9-2.0J X = 0.05J M = 1J N = 1.1J U = 4.0-5.0J P = 2.7-3.0J Y = 7.2-12J	150 = 18V 220 = 22V 250 = 27V 300 = 32V 380 = 38V 390 = 42V 400 = 42V 540 = 54V	580 = 60V 620 = 67V 650 = 67V 770 = 77V 800 = 80V 101 = 100V 111 = 110V 151 = 150V							D = 7" (1000)* R = 7" (4000)* T = 13" (10,000)* W = 13" (10,000)** 0402 only	P = Ni/Sn plated
						D = 7" (1000)* R = 7" (4000)* T = 13" (10,000)* W = 13" (10,000)** 0402 only	P = Ni/Sn plated									

*Not available for 0402
**Only available for 0402

PHYSICAL DIMENSIONS: mm (inches)



Size (EIA)	Length (L)	Width (W)	Max Thickness (T)	Land Length (t)
0402	1.00±0.10 (0.040±0.004)	0.50±0.10 (0.020±0.004)	0.60 (0.024)	0.25±0.15 (0.010±0.006)
0603	1.60±0.15 (0.063±0.006)	0.80±0.15 (0.031±0.006)	0.90 (0.035)	0.35±0.15 (0.014±0.006)
0805	2.01±0.20 (0.079±0.008)	1.25±0.20 (0.049±0.008)	1.02 (0.040)	0.71 max. (0.028 max.)
1206	3.20±0.20 (0.126±0.008)	1.60±0.20 (0.063±0.008)	1.02 (0.040)	0.94 max. (0.037 max.)
1210	3.20±0.20 (0.126±0.008)	2.49±0.20 (0.098±0.008)	1.70 (0.067)	0.14 max. (0.045 max.)
1812	4.50±0.30 (0.177±0.012)	3.20±0.30 (0.126±0.012)	2.00 (0.079)	1.00 max. (0.040 max.)
2220	5.70±0.40 (0.224±0.016)	5.00±0.40 (0.197±0.016)	2.50 (0.098)	1.00 max. (0.040 max.)



TransGuard® Automotive Series

Multilayer Varistors for Automotive Applications



ELECTRICAL CHARACTERISTICS

AVX PN	V _W (DC)	V _W (AC)	V _B	V _C	I _{VC}	I _L	E _T	E _{LD}	I _P	Cap	Freq	V _{Jump}	P _{Diss. Max}
VCAS040205X150 __	5.6	4.0	8.5±20%	18	1	35	0.05	-	20	175	M	-	0.001
VCAS060305A150 __	5.6	4.0	8.5±20%	18	1	35	0.1	-	30	750	K	-	0.001
VCAS080505A150 __	5.6	4.0	8.5±20%	18	1	35	0.1	-	40	1100	K	-	0.001
VCAS080505C150 __	5.6	4.0	8.5±20%	18	1	35	0.3	-	120	3000	K	-	0.005
VCAS120605A150 __	5.6	4.0	8.5±20%	18	1	35	0.1	-	40	1200	K	-	0.002
VCAS120605D150 __	5.6	4.0	8.5±20%	18	1	35	0.4	-	150	3000	K	-	0.008
VCAS040209X200 __	9	6.4	12.7±15%	22	1	25	0.05	-	20	175	M	-	0.001
VCAS060309A200 __	9	6.4	12.7±15%	22	1	25	0.1	-	30	550	K	-	0.002
VCAS080509A200 __	9	6.4	12.7±15%	22	1	25	0.1	-	40	750	K	-	0.002
VCAS080512A250 __	12	8.5	16±15%	27	1	25	0.1	-	40	525	K	-	0.002
VCAS040214X300 __	14	10	18.5±12%	32	1	15	0.05	-	20	85	K	16	0.001
VCAS060314A300 __	14	10	18.5±12%	32	1	15	0.1	-	30	350	K	16	0.002
VCAS080514A300 __	14	10	18.5±12%	32	1	15	0.1	-	40	325	K	16	0.002
VCAS080514C300 __	14	10	18.5±12%	32	1	15	0.3	-	120	900	K	20	0.006
VCAS120614A300 __	14	10	18.5±12%	32	1	15	0.1	-	40	600	K	20	0.002
VCAS120614D300 __	14	10	18.5±12%	32	1	15	0.4	-	150	1050	K	20	0.008
VCAS060316B400 __	16	11	25.5±10%	42	1	10	0.2	0.25	30	150	K	27.5	0.003
VCAS120616K380 __	16	11	25.5±10%	38	1	10	0.6	1.5	200	930	K	27.5	0.010
VCAS121016J390 __	16	11	25.5±10%	42	5	10	1.6	3	500	3100	K	27.5	0.030
VGAS181216P400 __	16	11	24.5±10%	42	5	10	2.9	10	1000	5000	K	27.5	0.070
VGAS222016Y400 __	16	11	24.5±10%	42	10	10	7.2	25	1500	13000	K	25.5	0.100
VCAS040218X400 __	18	13	25.5±10%	42	1	10	0.05	0.05	20	65	M	27.5	0.001
VCAS060318A400 __	18	13	25.5±10%	42	1	10	0.1	0.25	30	150	K	27.5	0.003
VCAS080518A400 __	18	13	25.5±10%	42	1	10	0.1	0.1	30	225	K	27.5	0.002
VCAS080518C400 __	18	13	25.5±10%	42	1	10	0.3	1	120	550	K	27.5	0.007
VCAS120618A400 __	18	13	25.5±10%	42	1	10	0.1	0.5	30	350	K	27.5	0.002
VCAS120618D400 __	18	13	25.5±10%	42	1	10	0.4	1.5	150	900	K	27.5	0.008
VCAS120618E380 __	18	13	25.5±10%	38	1	10	0.5	1.5	200	930	K	27.5	0.010
VCAS121018J390 __	18	13	25.5±10%	42	5	10	1.6	3	500	3100	K	27.5	0.030
VCAS060326A580 __	26	18	34.5±10%	60	1	10	0.1	0.1	30	155	K	27.5	0.002
VCAS080526A580 __	26	18	34.5±10%	60	1	10	0.1	0.15	30	120	K	27.5	0.002
VCAS080526C580 __	26	18	34.5±10%	60	1	10	0.3	0.5	100	250	K	27.5	0.006
VCAS120626D580 __	26	18	34.5±10%	60	1	10	0.4	1	120	500	K	27.5	0.008
VCAS120626F540 __	26	18	33.0±10%	54	1	15	0.7	1.5	200	600	K	27.5	0.008
VCAS121026H560 __	26	18	34.5±10%	60	5	10	1.2	3	300	2150	K	27.5	0.018
VCAS060330A650 __	30	21	41.0±10%	67	1	10	0.1	0.15	30	125	K	29	0.002
VCAS080530A650 __	30	21	41.0±10%	67	1	10	0.1	0.15	30	90	M	29	0.002
VCAS080530C650 __	30	21	41.0±10%	67	1	10	0.3	0.5	80	250	K	29	0.005
VCAS120630D650 __	30	21	41.0±10%	67	1	10	0.4	1	120	400	K	29	0.008
VCAS121030H620 __	30	21	41.0±10%	67	5	10	1.2	3	280	1850	K	29	0.018
VCAS121030S620 __	30	21	41.0±10%	67	5	10	1.9	3	300	1500	K	29	0.038
VCAS080531C650 __	31	25	39.0±10%	65	1	10	0.3	0.5	80	250	K	29	0.005
VCAS120631M650 __	31	25	39.0±10%	65	1	15	1	1.5	200	500	K	29	0.008
VCAS120634N770 __	34	30	47.0±10%	77	1	15	1.1	1.5	200	400	K	48	0.008
VGAS121034S770 __	34	30	47.0±10%	77	2.5	15	2	3.0	400	1000	K	48	0.040
VGAS181234U770 __	34	30	47.0±10%	77	5	15	5	6.1	800	1500	K	48	0.080
VGAS222034Y770 __	34	30	47.0±10%	77	10	15	12	25	2000	6300	K	48	0.240
VCAS080538C770 __	38	30	47.0±10%	77	1	10	0.3	-	80	200	K	48	0.006
VCAS120642L800 __	42	32	51.0±10%	80	1	15	0.8	-	180	600	K	48	0.016
VCAS120642K900 __	42	32	56±10%	90	1	15	0.6	-	200	260	K	48	0.012
VCAS120645K900 __	45	35	56±10%	90	1	25	0.6	-	200	260	K	48	0.012
VCAS120648D101 __	48	34	62.0±10%	100	1	10	0.4	-	100	225	K	48	0.008
VCAS121048H101 __	48	34	62.0±10%	100	1	10	1.2	-	250	500	K	48	0.022
VCAS120656F111 __	56	40	68.0±10%	110	1	15	0.7	-	100	180	K	48	0.014
VCAS120660M131 __	60	50	82.0±10%	135	1	15	1	-	150	250	K	48	0.008
VCAS121060J121 __	60	42	76±10%	120	5	10	1.5	-	250	400	K	48	0.03
VGAS121065P131 __	65	50	82±10%	135	2.5	15	2.7	-	350	600	K	48	0.05
VCAS121085S151 __	85	60	100.0±10%	150	1	35	2	-	250	275	K	48	0.040

V_W(DC) DC Working Voltage [V]
 V_W(AC) AC Working Voltage [V]
 V_B Typical Breakdown Voltage [V @ 1mA_{DC}]
 V_C Clamping Voltage [V @ I_W]
 I_{VC} Test Current for V_C
 I_L Maximum leakage current at the working voltage [μA]

E_T Transient Energy Rating [J, 10x1000μs]
 I_P Peak Current Rating [A, 8x20μs]
 Cap Typical capacitance [pF] @ frequency specified and 0.5V_{RMS}
 V_{Jump} Jump Start (V)
 P Power Dissipation (W)

TransGuard® Automotive Series

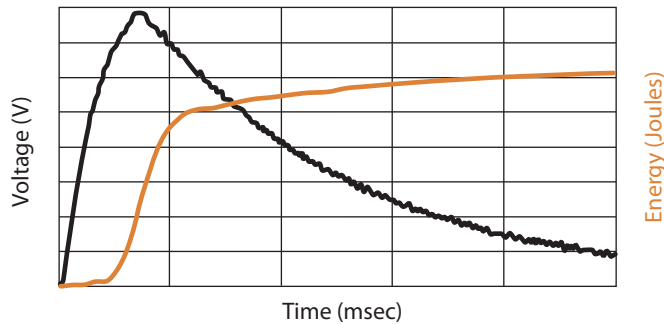
Multilayer Varistors for Automotive Applications



AUTOMOTIVE SERIES – LOAD DUMP TEST

According to ISO DP7637 rev 2 Pulse 5

**Automotive Load Dump Pulse
(According to ISO 7637 Pulse 5)**



When using the test method indicated below, the amount of Energy dissipated by the varistor must not exceed the Load Dump Energy value specified in the product table.

LOAD DUMP LIBRARY

Typical max Vz versus Pulse duration and Ri

12V SYSTEMS

VCAS060316B400	0.5Ω	1Ω	4Ω
100ms	37	38	42
200ms	36	37	41
400ms	35	36	39
VCAS120616K380	0.5Ω	1Ω	4Ω
100ms	42	45	55
200ms	40	43	50
400ms	39	40	45
VCAS121016J390	0.5Ω	1Ω	4Ω
100ms	48	53	74
200ms	46	50	64
400ms	43	46	56
VGAS181216P400	0.5Ω	1Ω	4Ω
100ms	46	52	72
200ms	37	41	59
400ms	32	35	51
VGAS222016Y400	0.5Ω	1Ω	4Ω
100ms	53	60	77
200ms	50	55	73
400ms	47	50	66
VCAS040218X400	0.5Ω	1Ω	4Ω
100ms	38	39	40
200ms	37	37	38
400ms	34	35	36
VCAS060318A400	0.5Ω	1Ω	4Ω
100ms	37	38	42
200ms	36	37	41
400ms	35	36	39
VCAS080518A400	0.5Ω	1Ω	4Ω
100ms	37	39	40
200ms	35	38	39
400ms	33	37	38
VCAS080518C400	0.5Ω	1Ω	4Ω
100ms	40	41	48
200ms	39	40	45
400ms	38	39	42
VCAS120618A400	0.5Ω	1Ω	4Ω
100ms	43	45	55
200ms	41	43	48
400ms	40	41	45
VCAS120618D400	0.5Ω	1Ω	4Ω
100ms	42	45	55
200ms	40	42	50
400ms	39	40	45
VCAS120618E380	0.5Ω	1Ω	4Ω
100ms	42	45	55
200ms	40	43	50
400ms	39	40	45
VCAS121018J390	0.5Ω	1Ω	4Ω
100ms	48	53	74
200ms	46	50	64
400ms	43	46	56

24V SYSTEMS

VCAS060326A580	0.5Ω	1Ω	4Ω
100ms	51	56	58
200ms	50	54	56
400ms	49	51	53
VCAS080526A580	0.5Ω	1Ω	4Ω
100ms	51	53	59
200ms	49	51	57
400ms	48	50	51
VCAS080526C580	0.5Ω	1Ω	4Ω
100ms	51	54	62
200ms	49	51	56
400ms	48	49	51
VCAS120626D580	0.5Ω	1Ω	4Ω
100ms	52	60	68
200ms	50	57	65
400ms	47	54	61
VCAS121026H560	0.5Ω	1Ω	4Ω
100ms	61	74	91
200ms	59	69	82
400ms	55	64	70
VCAS060330A650	0.5Ω	1Ω	4Ω
100ms	57	59	63
200ms	56	58	61
400ms	54	57	58
VCAS080530A650	0.5Ω	1Ω	4Ω
100ms	58	62	66
200ms	56	61	64
400ms	53	57	61
VCAS080530C650	0.5Ω	1Ω	4Ω
100ms	58	61	63
200ms	57	58	62
400ms	55	56	59
VCAS120630D650	0.5Ω	1Ω	4Ω
100ms	61	70	75
200ms	57	66	69
400ms	56	62	64
VCAS121030H620	0.5Ω	1Ω	4Ω
100ms	70	77	98
200ms	64	70	89
400ms	56	65	70
VGAS181234U770	1Ω	4Ω	8Ω
100ms	87	110	125
200ms	82	97	114
400ms	75	85	95
VGAS222034Y770	1Ω	4Ω	8Ω
100ms	100	125	165
200ms	91	115	155
400ms	84	104	120



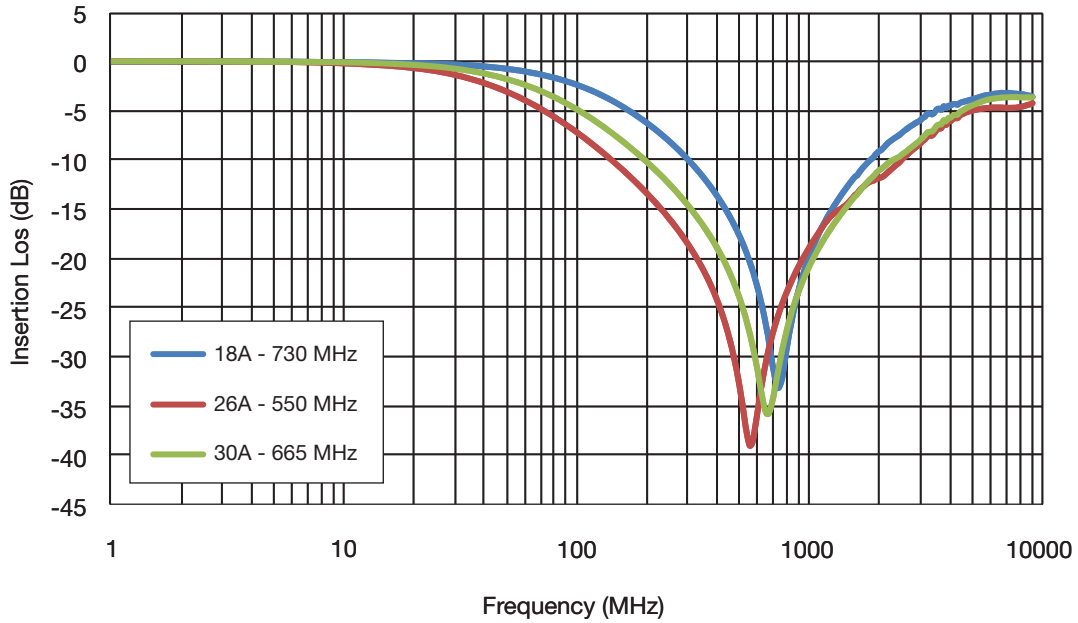
TransGuard® Automotive Series

Multilayer Varistors for Automotive Applications

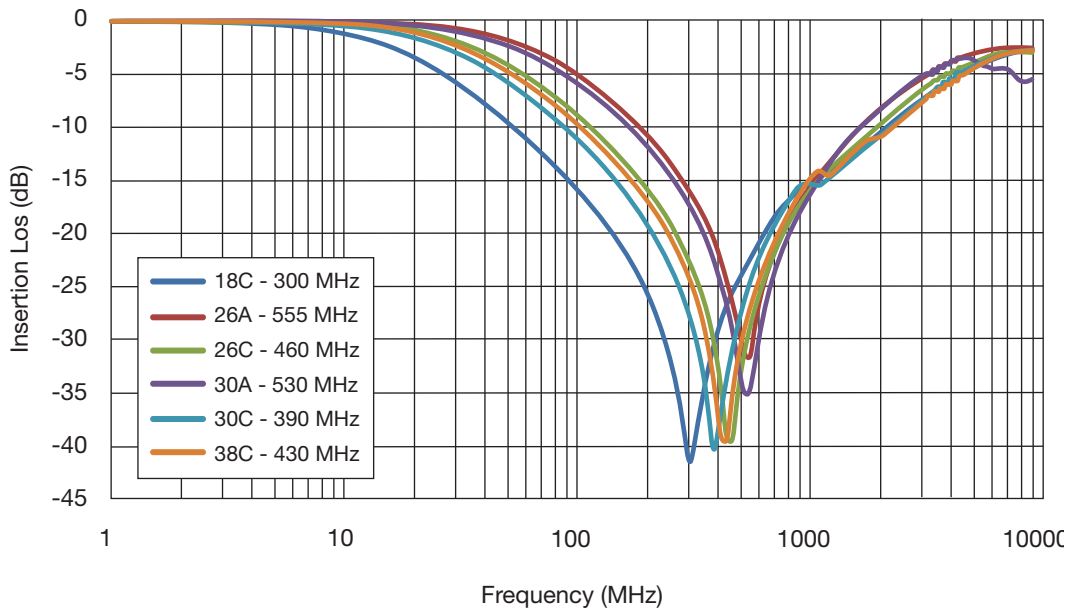


FORWARD TRANSMISSION CHARACTERISTICS (S21)

0603 Case Size



0805 Case Size



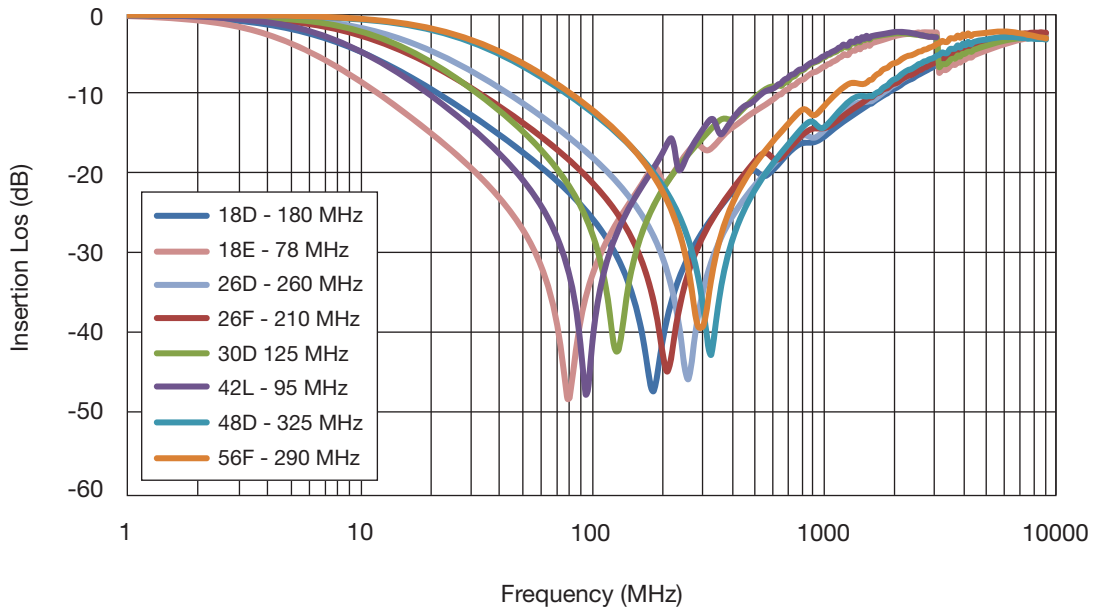
TransGuard® Automotive Series

Multilayer Varistors for Automotive Applications

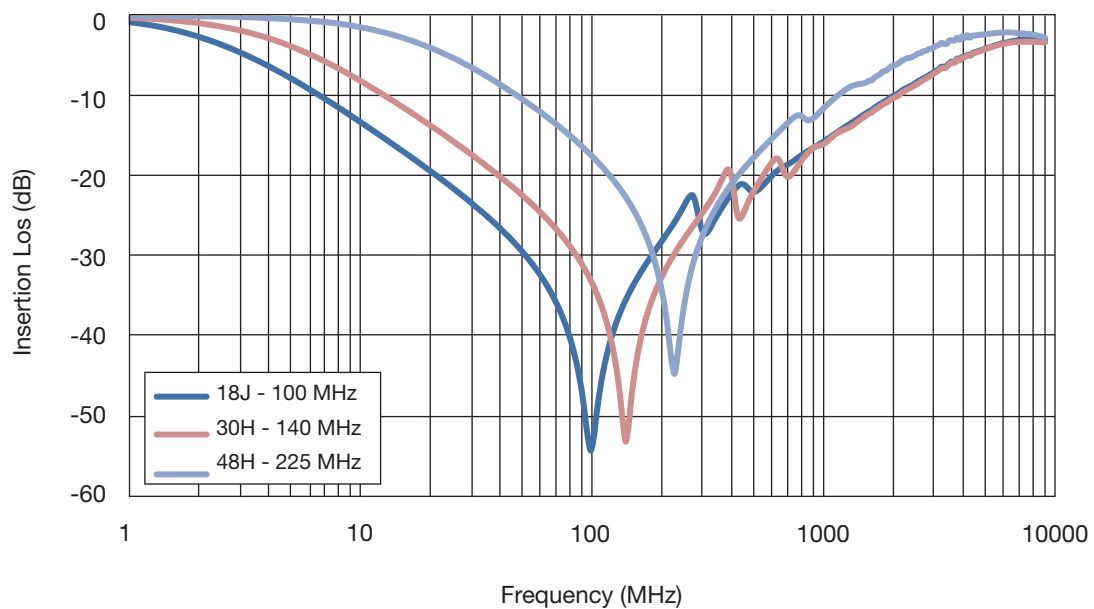


FORWARD TRANSMISSION CHARACTERISTICS (S21)

1206 Case Size



1210 Case Size



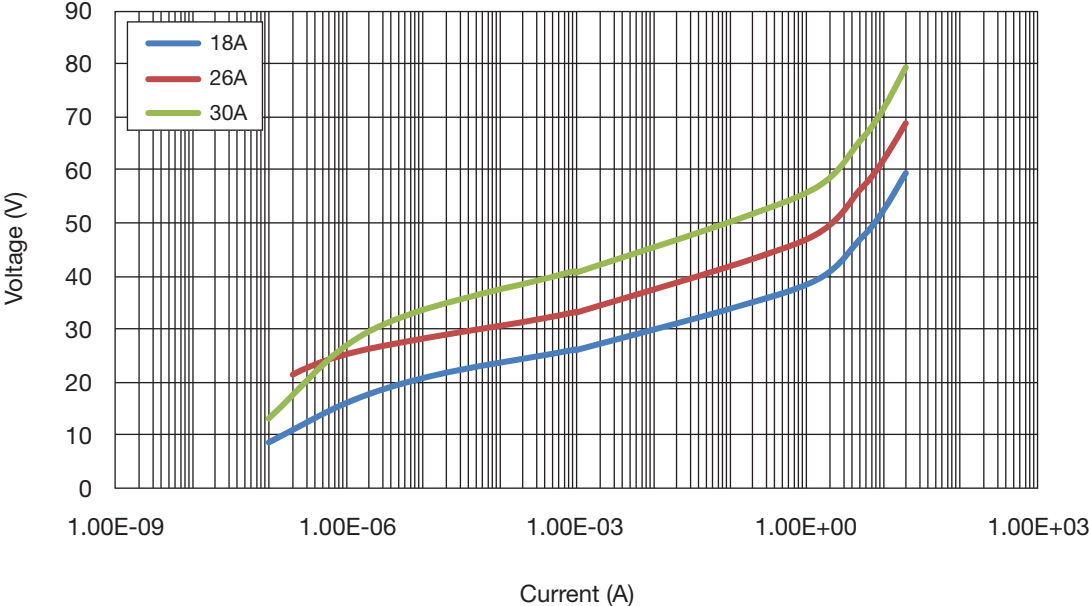
TransGuard® Automotive Series



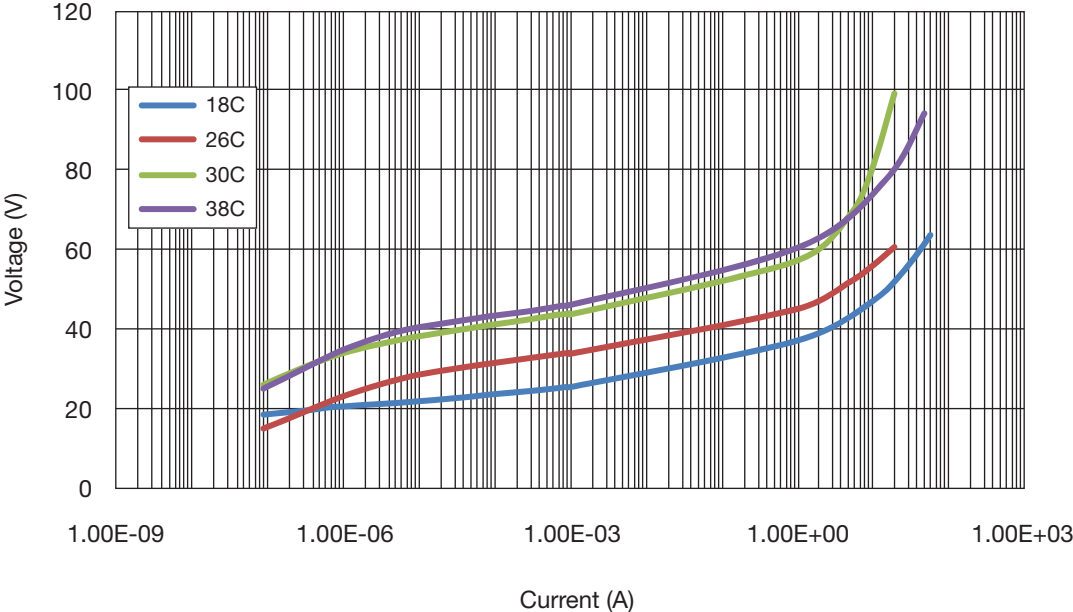
Multilayer Varistors for Automotive Applications

V-I CHARACTERISTICS

0603 Case Size



0805 Case Size



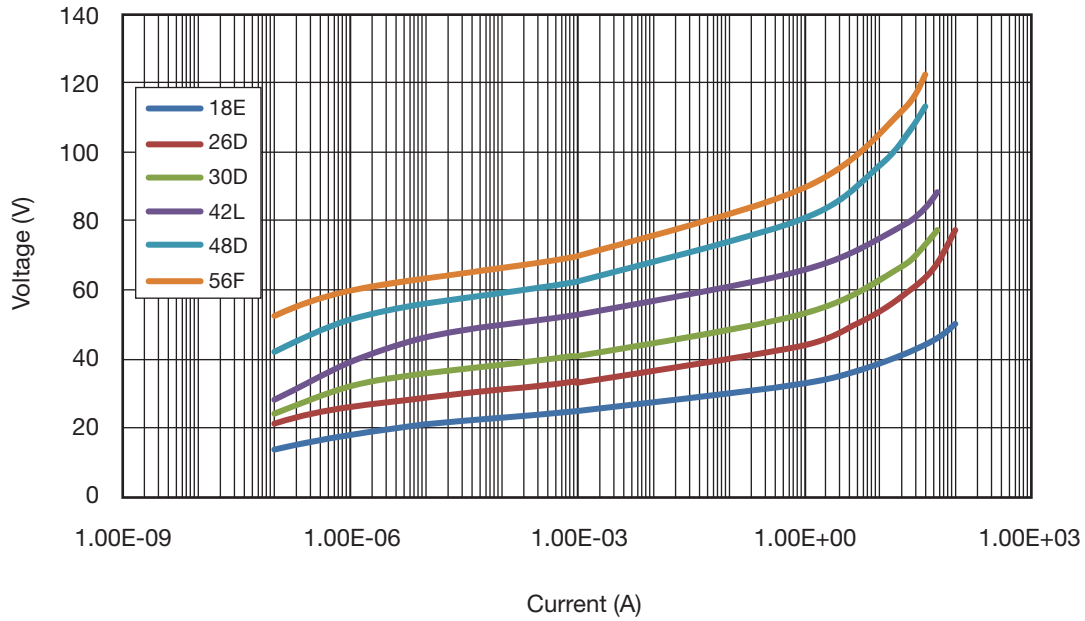
TransGuard[®] Automotive Series

Multilayer Varistors for Automotive Applications

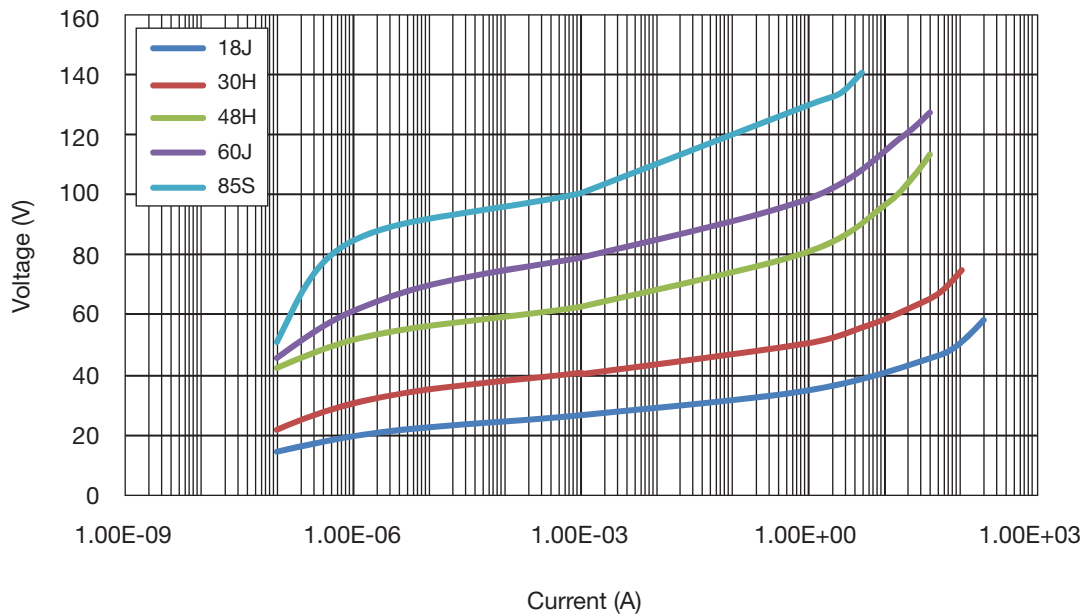


V-I CHARACTERISTICS

1206 Case Size



1210 Case Size



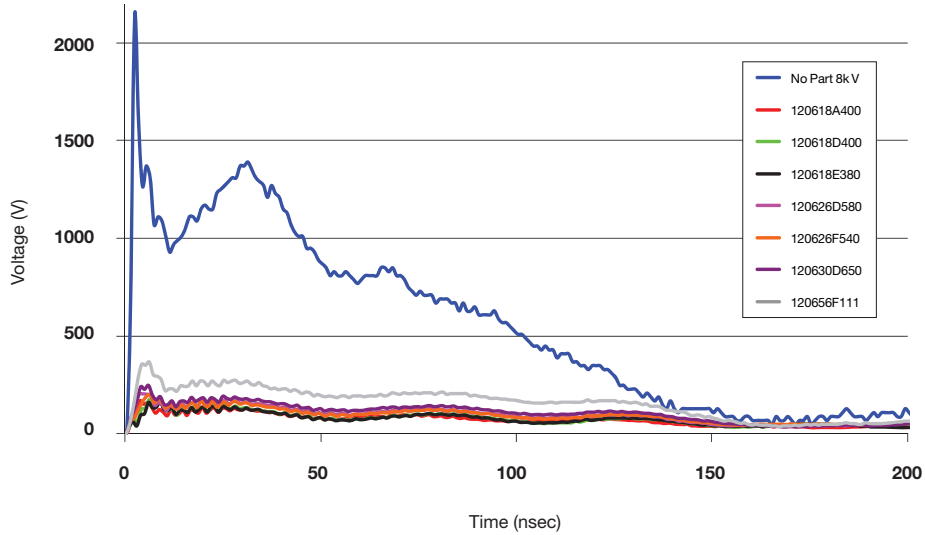
TransGuard® Automotive Series

Multilayer Varistors for Automotive Applications



ESD V-I CHARACTERISTICS

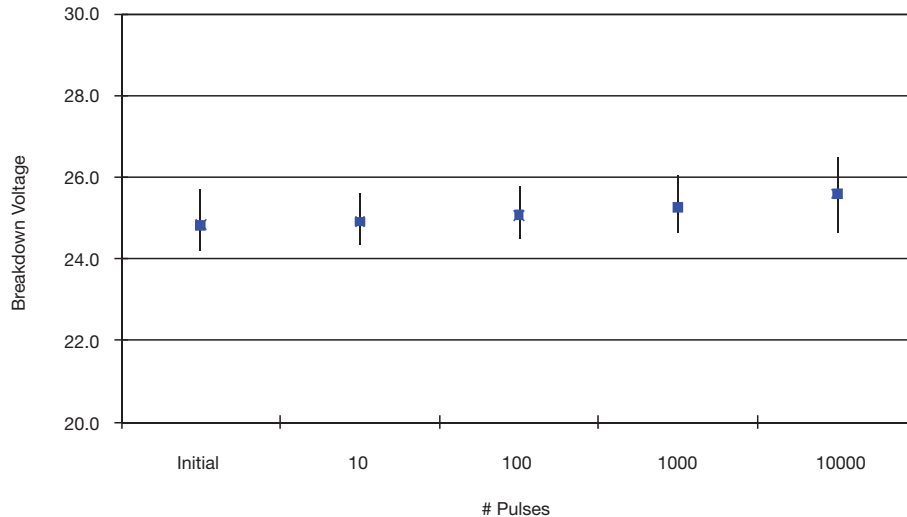
8 kV ESD Vc
(150pF/300ohm IEC Network)



TYPICAL VOLTAGE AT 8 KV PULSE

8kV Pulse	Peak Voltage (V)	30ns Voltage (V)	100ns Voltage (V)
No Part (No Suppression)	2130	1370	517
120618A400	171	123	65
120618D400	177	133	66
120618E380	161	121	63
120626D580	203	155	88
102626F540	201	159	84
120630D650	249	177	106
120656F111	366	262	169

ESD 8 kV IEC 61000-4-2 150pF / 330Ω Resistor
VC060318A400



Automotive Sub pF AG Series

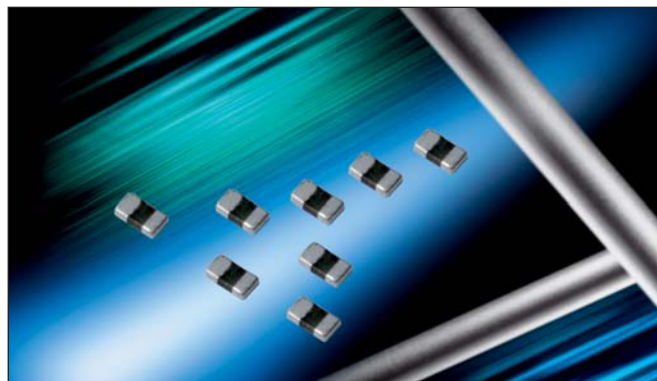


AVX Ultra-low Capacitance Automotive Varistor for ESD Protection for Automotive Circuits Sensitive to Capacitance

GENERAL DESCRIPTION

AVX offers ultra-low capacitance ESD protection in the Sub 1pF range for use in automotive circuits that are sensitive to capacitance. The Automotive Sub pF Varistor (ASPV) is available in 0.8pF capacitance value in a compact 0402 low profile package. ASPV devices provide excellent response time to ESD strikes to protect sensitive circuits from over voltage.

The development of new information processing technologies call for ever increasing digital system speeds. Higher speeds necessitate the use of ultra-low capacitance values in order to minimize signal distortion.



FEATURES

- High Reliability
- Capacitance <1pF
- Bi-Directional protection
- Fastest response time to ESD strikes
- Multi-strike capability
- Low insertion loss
- Low profile 0402 case size
- AEC-Q 200 Qualified

APPLICATIONS

- Antennas, RF circuits
- Optics
- HDMI, Firewire, Thunderbolt
- High speed communication bus
- GPS
- Camera link
- Sensors
- Touch screen interfaces
- Circuits sensitive to capacitance

HOW TO ORDER

VC	AS	H4	AG	16	0R8	M	A	T	W	A
Varistor Chip	Automotive Series	Chip Size Low Profile 0402	Varistor Series AG Series Ultra-low Capacitance	Working Voltage 16 = 16V	Capacitance 0R8 = 0.8pF	Tolerance M = ±20%	N/A	Termination T = Ni Barrier/ 100% Sn	Reel Size W = 7"	Reel Quantity A = 10k

ANTENNAGUARD CATALOG PART NUMBERS/ELECTRICAL VALUES

AVX Part Number	V _w (DC)	V _B	I _L	Cap	Cap Tolerance	3db Freq (MHz)	Case Size
VCASH4AG160R8MA	≤16	125	1	0.8	±20%	5800	LP 0402

- V_w(DC) DC Working Voltage (V)
- V_B Typical Breakdown Voltage (V @ 1mA_{DC})
- I_L Typical leakage current at the working voltage
- Cap Typical capacitance (pF) @ frequency specified and 0.5V_{RMS}
- Freq Frequency at which capacitance is measured (M = 1MHz)

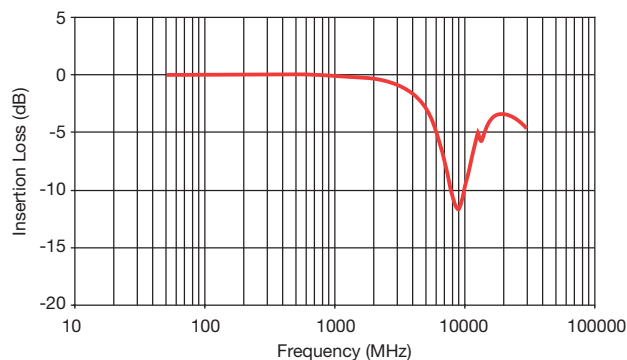


Automotive Sub pF AG Series

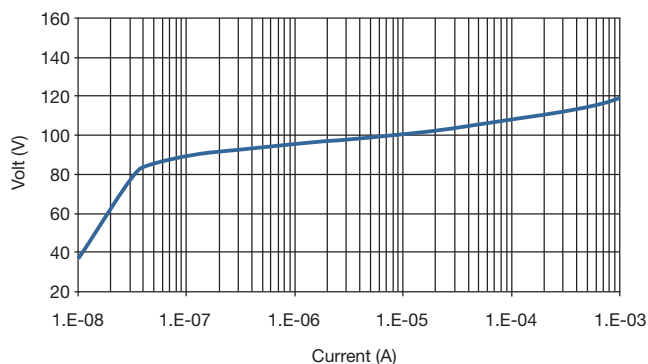


AVX Ultra-low Capacitance Automotive Varistor for ESD Protection for Automotive Circuits Sensitive to Capacitance

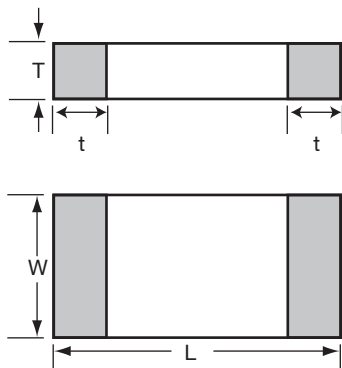
S21 Transmission Characteristics -SPV



V/I Curve - SPV



DIMENSIONS



mm (inches)

Size (EIA)	0402
Length (L)	1.00 ±0.10 (0.040 ± 0.004)
Width (W)	0.50 ±0.10 (0.020 ±0.004)
Max Thickness (T)	0.35 (0.014)
Terminal (t)	0.25±0.15 (0.010±0.006)

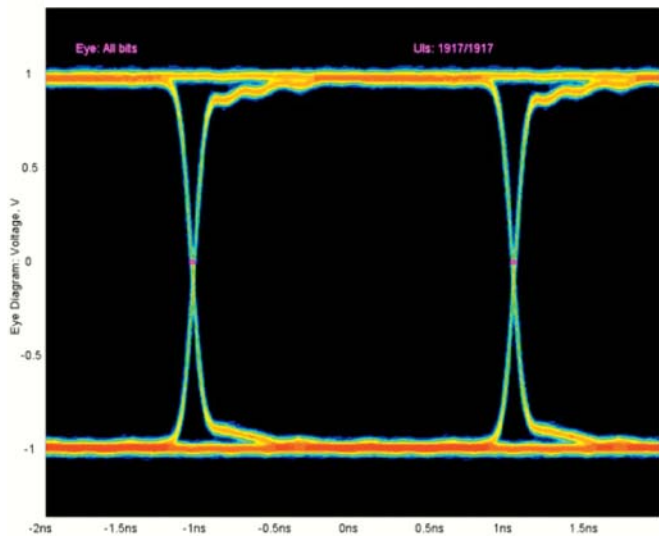
Automotive Sub pF AG Series



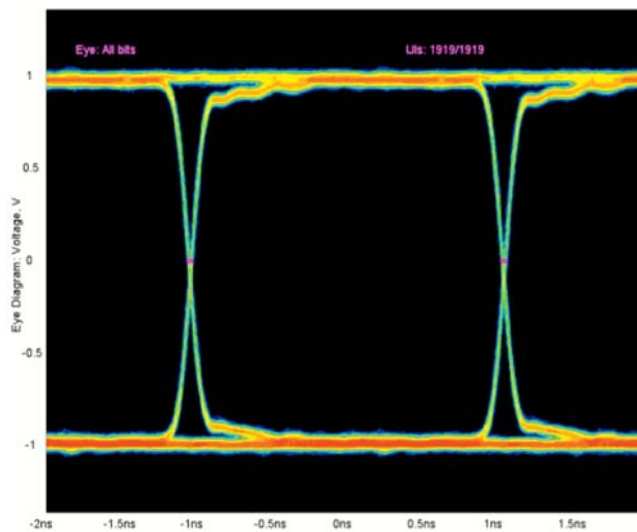
AVX Ultra-low Capacitance Automotive Varistor for ESD Protection for Automotive Circuits Sensitive to Capacitance

EYE DIAGRAM - USB-HS (480MHZ) TEST

No Part

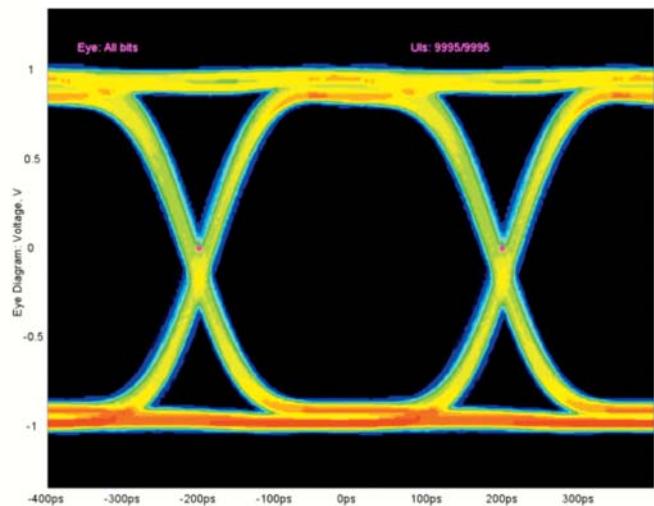


VCASH4AG160R8MATWA

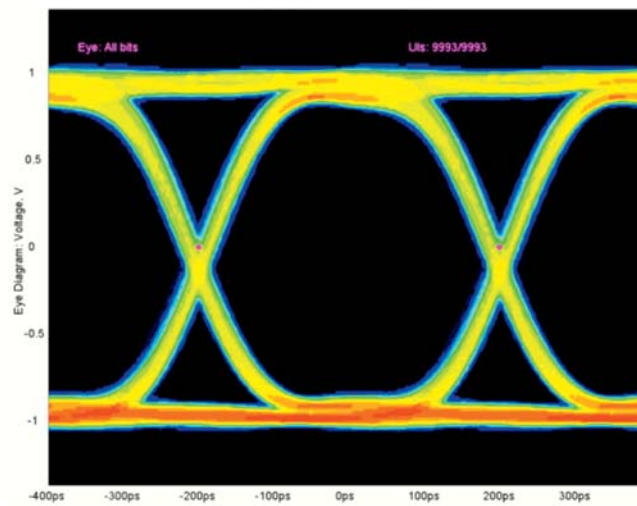


EYE DIAGRAM - PCI-E (2.5GHZ) TEST

No Part



VCASH4AG160R8MATWA



Miniature AC Varistor – MAV

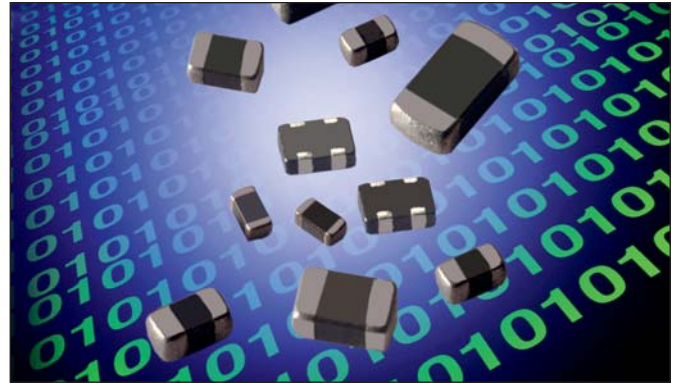


Low Power AC Circuit Protection

GENERAL DESCRIPTION

AVX Miniature AC Varistors are designed for use in low power AC circuit protection. MAV series devices are an ideal solution to transient suppression in LC resonant circuits intended for signal & power transfer. The AVX part provides low loss in the resonant circuit yet is able to clamp large amounts of transients in a bi-directional manner.

The ability to handle large transients makes the MAV series useful in low power AC circuit protection and the AEC Q200 qualification allows for use in automotive applications.



FEATURES

- 110 Pk-Pk @ 125kHz capability
- AEC Q200 qualified
- ESD rated to 25kV (HBM ESD Level 6)
- EMI/RFI attenuation in off state
- Bi-Directional protection

APPLICATIONS

- LC resonant circuits
- AC sampling circuitry
- Transformer secondaries
- GFI modules

HOW TO ORDER

MAV	002	0	W	P	
Series	Size	Capacitance	Packaging	Termination	
	001 = 0603 002 = 0405 004 = 0402	0 = Low	D = 7" reel (1,000 pcs) R = 7" reel (4,000 pcs) T = 13" reel (10,000 pcs) W = 7" Reel (10,000 pcs 0402 and 201 only)	P = Plated Sn over Ni barrier	



ANTENNAGUARD CATALOG PART NUMBERS/ELECTRICAL VALUES

AVX Part Number	V _W (DC)	V _W (AC)	V _B	V _C	I _{VC}	E _T	I _P	I _L	Cap	Elements
MAV0010_P	70	52	120 ±15%	225	1	0.015	2	10	22pF Max	1
MAV0020_P	70	52	120 ±15%	225	1	0.020	3	10	8pF Max	2
MAV0040_P	70	52	120 ± 15%	225	1	0.020	1	10	6pF Max	1

└ Packaging Code

V_W(DC) DC Working Voltage [V]
 V_W(AC) AC Working Voltage [V]
 V_B Breakdown Voltage [V @ 1mA_{DC}]
 V_C Clamping Voltage [V @ I_{VC}]

I_L Maximum leakage current at the working voltage [μA]
 E_T Transient Energy Rating [J, 10x100μS]
 I_P Peak Current Rating [A, 8x10μS]
 Cap Maximum capacitance @ 1MHz and 0.5V_{RMS}

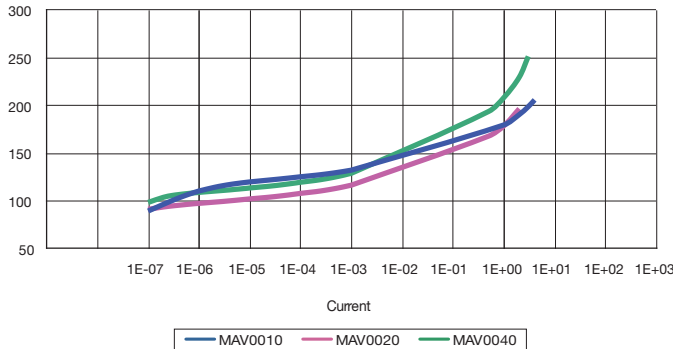
Miniature AC Varistor – MAV



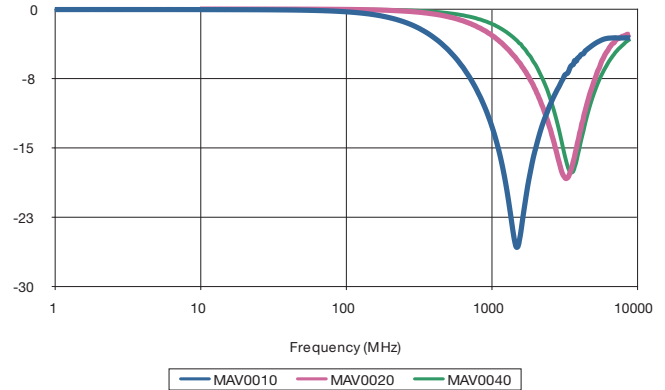
Low Power AC Circuit Protection

TYPICAL PERFORMANCE CURVES

Voltage/Current Characteristics

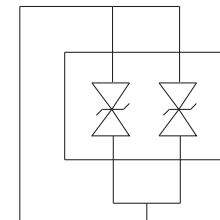
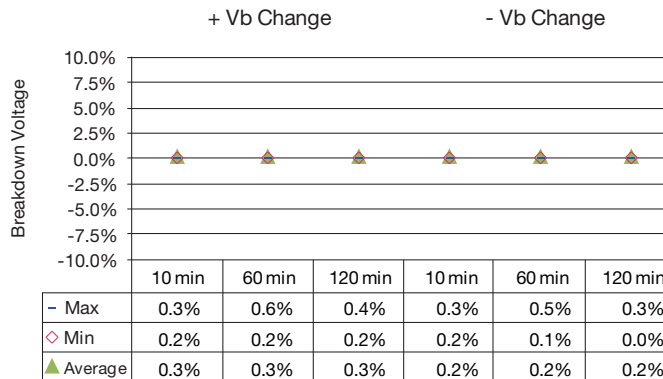


Transmission Characteristics



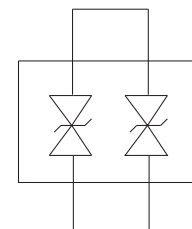
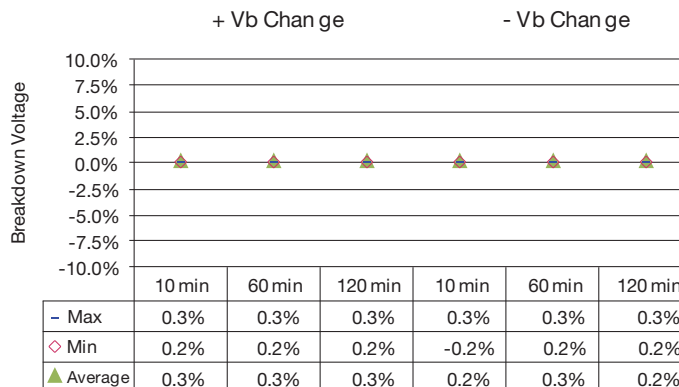
TYPICAL PERFORMANCE CURVES

Impact of AC Voltage on Breakdown Voltage
Parallel 110VPP @ 125 kHz



Apply 110V pp
125KHz Sine wave
(Parallel)

Impact of AC Voltage on Breakdown Voltage
Series 110VPP @ 125 kHz



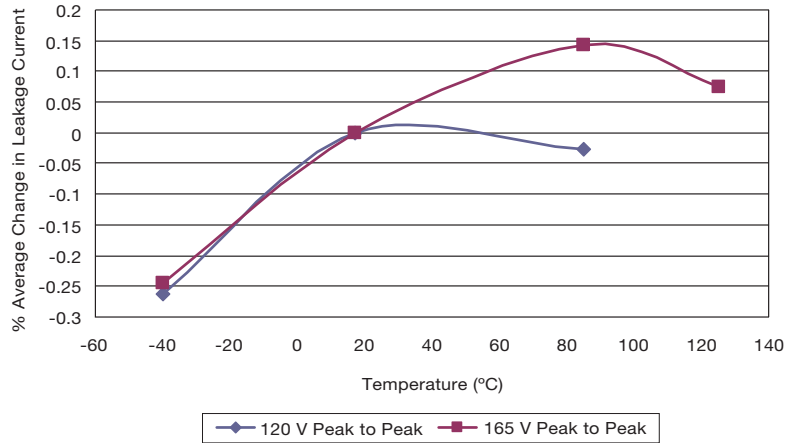
Apply 110V pp
125KHz Sine wave
(Series)

Miniature AC Varistor – MAV

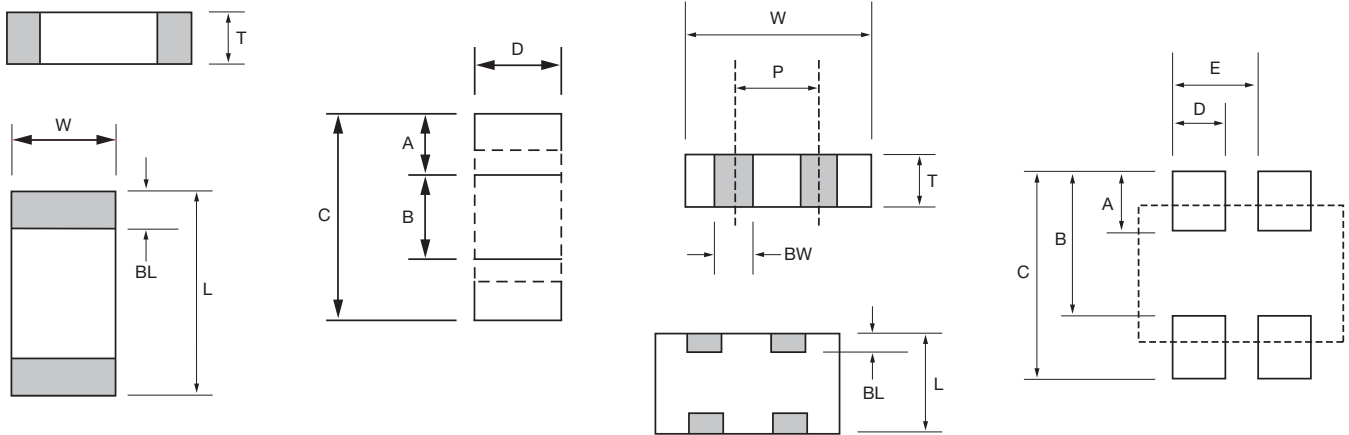


Low Power AC Circuit Protection

IMPACT OF AC VOLTAGE ON LEAKAGE CURRENT



PHYSICAL DIMENSIONS AND RECOMMENDED PAD LAYOUT



L	W	T	BW	BL	P	A	B	C	D	E
MAV0010										
1.60 ± 0.15 (0.063±0.006)	0.80 ± 0.15 (0.032±0.006)	0.90 Max (0.035) Max	N/A	0.35 ± 0.15 (0.014±0.006)	N/A	0.89 (0.035)	0.76 (0.030)	2.54 (0.100)	0.76 (0.030)	N/A
MAV0020										
1.00 ± 0.15 (0.039±0.006)	1.37 ± 0.15 (0.054±0.006)	0.66 Max (0.026) Max	0.36 ± 0.10 (0.014±0.004)	0.20 ± 0.10 (0.008±0.004)	0.64 REF (0.025)REF	0.46 (0.018)	0.74 (0.029)	1.20 (0.047)	0.30 (0.012)	0.64 (0.025)
MAV0040										
1.00±0.10 (0.040±0.004)	0.50±0.10 (0.020±0.004)	0.60 Max (0.024) Max	N/A	0.25±0.15 (0.010±0.006)	N/A	0.61 (0.024)	0.51 (0.020)	1.70 (0.067)	0.51 (0.020)	N/A

Radial Leaded High Temperature Automotive **AVX**

150°C Rated Radial Leaded TransGuard®



GENERAL DESCRIPTION

AVX High Temperature Multi-Layer Varistors are designed for underhood applications. Products have been tested, qualified, and specified to 150°C. The Radial Leaded TransGuard is built for durability in harsh environments. The MLV advantage is EMI/RFI attenuation in the off state. This allows designers to combine the circuit protection and EMI/RFI attenuation function into a single highly reliable device.

GENERAL CHARACTERISTICS

- Operating Temperatures:
-55°C to +150°C
- Working Voltage:
14-48Vdc

FEATURES

- Rated at 150°C
- AEC Q200 qualified
- ESD rated to 25kV (HBM ESD Level 6)
- EMI/RFI attenuation in off state
- Excellent current and energy handling

APPLICATIONS

- Under hood
- Down Hole Drilling
- Any high temperature application

HOW TO ORDER

VR15	AT	18	A	650	R	TR2
AVX Style	Series	Voltage	Energy	Clamping Voltage	Leads	Packaging
VR15 VR20	AT = 150°C Automotive	14 = 14V 18 = 18V 26 = 26V 48 = 48V	A = 0.1J D = 0.4J S = 2.0J	580 = 60V 650 = 67V 101 = 100V 151 = 150V	R = RoHS Compliant	Blank = Bulk TR1 = T&R Standard 1 TR2 = T&R Standard 2

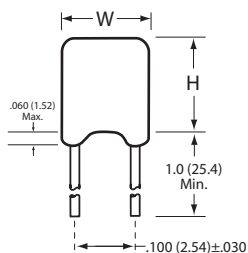


ELECTRICAL CHARACTERISTICS

AVX Part Number	V _{WDC}	V _{WAC}	V _B	V _C	I _{VC}	I _L	ET	ELD	IP	Cap	Freq	V _{JUMP}	P _{DISS}
VR15AT14A580	14.0	10.0	34.5±10%	60	1	10	0.1	0.15	30	120	K	27.5	0.002
VR15AT18A650	18.0	13.0	41.0±10%	67	1	10	0.1	0.15	30	90	M	29	0.002
VR20AT26D101	26.0	18.0	62.0±10%	100	1	10	0.4	1.5	100	225	K	48	0.008
VR20AT48S151	48.0	34.0	100.0±10%	150	1	10	2.0	3.5	250	275	K	48	0.040

V _{W(DC)}	DC Working Voltage [V]	E _t	Transient Energy Rating [J, 10x1000µS]
V _{W(AC)}	AC Working Voltage [V]	E _{LD}	Load Dump Energy (x10) [J]
V _B	Typical Breakdown Voltage [V @ 1mA _{DC}]	I _p	Peak Current Rating [A, 8x20µS]
V _C	Clamping Voltage [V @ I _C]	Cap	Typical capacitance [pF] @ frequency specified and 0.5V _{RMS}
I _{VC}	Test Current for V _C	V _{JUMP}	Jump Start (V)
I _L	Maximum leakage current at the working voltage [µA]	P _{DISS}	Power Dissipation (W)

PHYSICAL DIMENSIONS

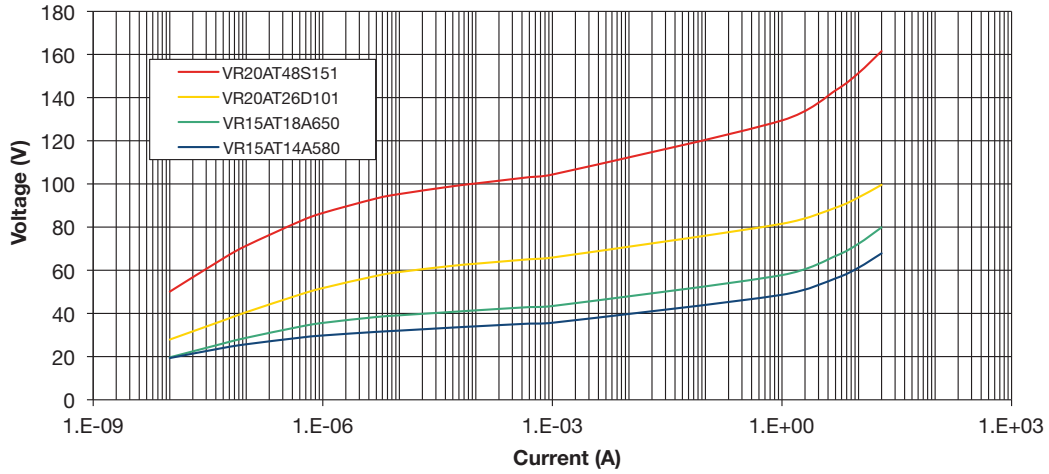


AVX Style	Width (W)	Height (H)	Thickness (T)	Lead Spacing	Lead Diameter
VR15	4.32 Max. (0.170)	3.81 Max. (0.150)	2.54 Max. (0.100)	2.54 (0.100)	0.508 (0.020)
VR20	5.59 Max (0.220)	5.08 Max (0.200)	3.175 Max (0.125)	2.54 (0.100)	0.508 (0.020)

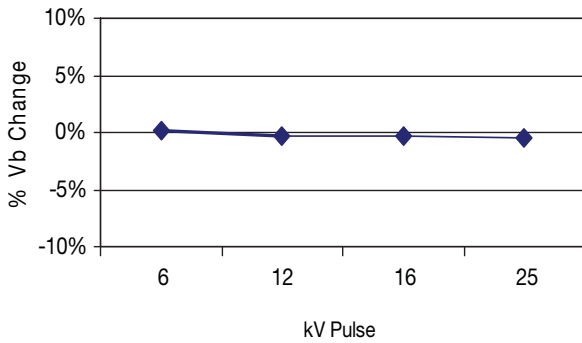


TYPICAL PERFORMANCE CURVES

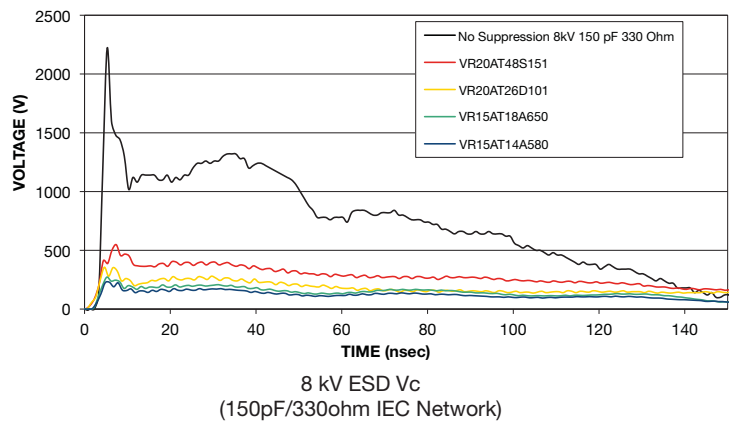
Typical Voltage Current Characteristics



AEC-Q200-002 ESD Characteristics



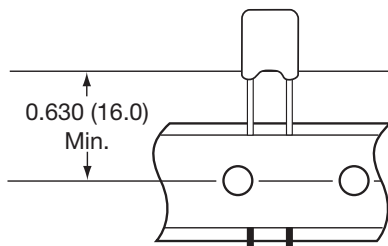
ESD Wave Absorption Characteristics



TAPE & REEL PACKAGING OPTIONS

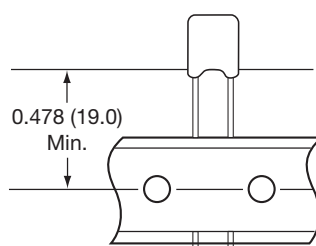
TR1

Tape & Reel Standard 1

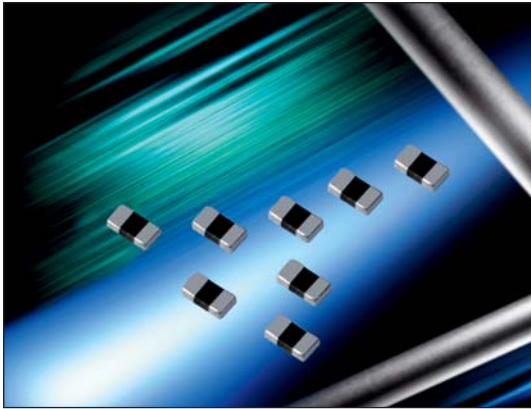


TR2

Tape & Reel Standard 2



Controlled Capacitance Multilayer Varistor



GENERAL DESCRIPTION

The Controlled Capacitance TransGuard is an application specific bi-directional transient voltage suppressor developed for use in mixed signal environments. The Controlled Cap MLV has three purposes: 1) reduce emissions from a high speed ASIC, 2) prevent induced E fields from conducting into the IC, and 3) clamp transient voltages

By controlling capacitance of the MLV, the center frequency and 20db range for filtering purposes can be targeted. A Controlled Cap MLV can greatly improve overall system EMC performance and reduce system size.

Operating Temperature: -55°C to +125°C

HOW TO ORDER

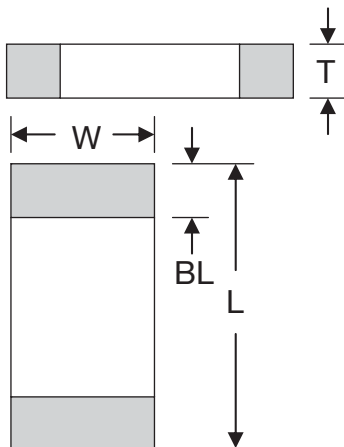
VCAC	0603	22	A	470	N	R	P
Varistor Chip Automotive Capacitance	Chip Size 0603	Working Voltage 22 = 22V 26 = 26V	Energy Rating A = 0.1J C = 0.3J	Capacitance 470 = 47pF 820 = 82pF	Tolerance N = ±30% M = ±20%	Packaging R = 4k pcs	Termination P = Ni Barrier/ 100% Sn (matte)



AVX Part Number	V _w (DC)	V _w (AC)	V _B	V _C	I _L	E _T	I _P	Cap	Cap Tolerance	Case Size
VCAC060322A470NRP	22	17	32.5±25%	50	10	0.1	30	47	30%	0603
VCAC060326C820MRP	26	20	36.0±15%	67	10	0.3	30	82	20%	0603

V_w(DC) DC Working Voltage [V]
V_w(AC) AC Working Voltage [V]
V_B Breakdown Voltage [V @ 1mA_{DC}]
V_C Clamping Voltage [V @ 1A]

I_L Maximum leakage current at the working voltage [µA]
E_T Transient Energy Rating [J, 10x1000µS]
I_P Peak Current Rating [A, 8x20µS]
Cap Capacitance [pF] @ 1KHz specified and 0.5V_{RMS}



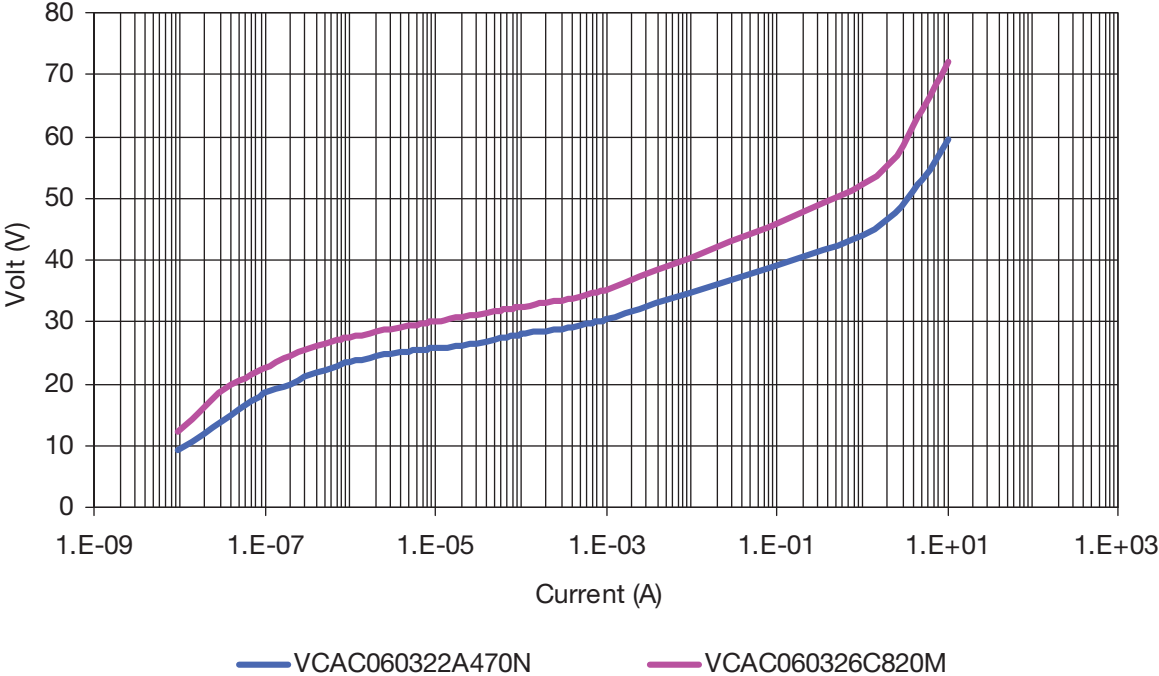
0603 Discrete Dimensions

mm (inches)				
L	W	T	BW	BL
1.60±0.15 (0.063±0.006)	0.80±0.15 (0.031±0.006)	0.90 MAX (0.035 MAX)	N/A	0.35±0.15 (0.014±0.006)

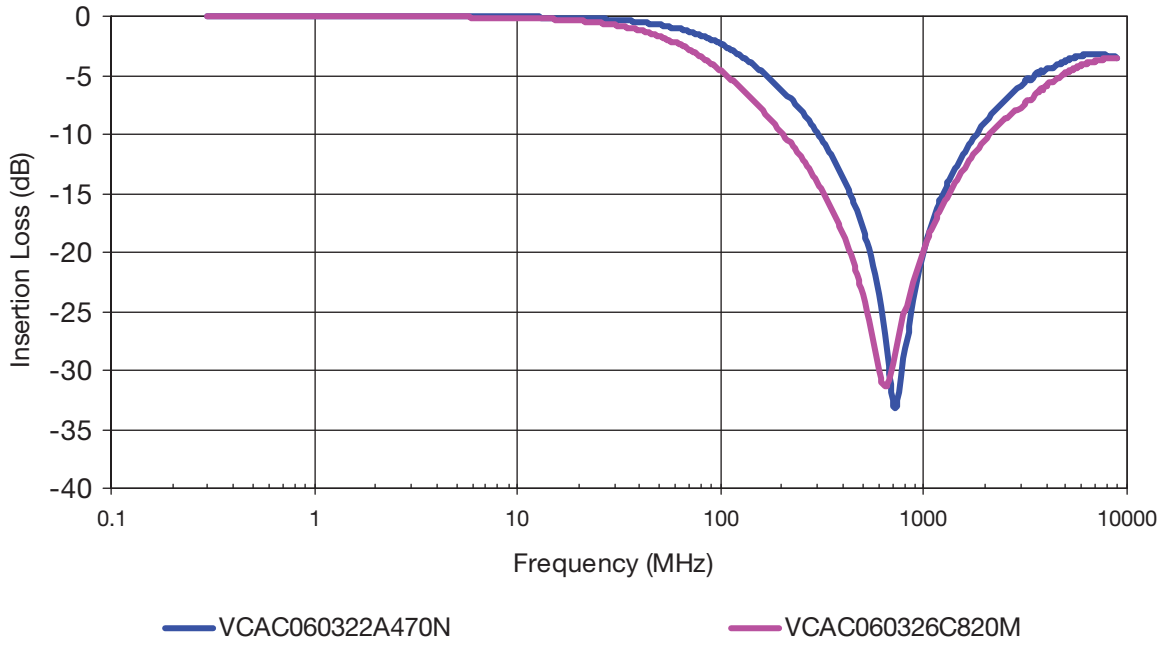
Controlled Capacitance Multilayer Varistor



V-I Curve



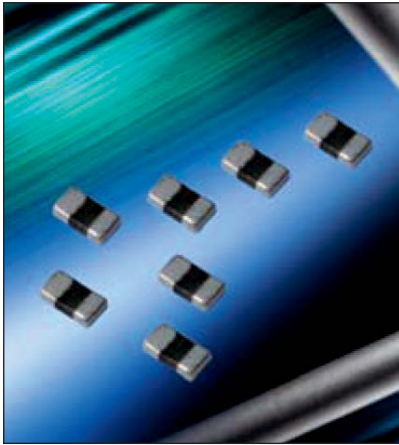
S21



Miniature 0201 MLV

AVX Multilayer Ceramic Transient Voltage Suppressors

ESD Protection for any Circuit with Board Space Constraints



GENERAL DESCRIPTION

AVX 0201 Multi-Layer Varistors are designed for circuits where board space is a premium. 0201 MLV offer bi-directional ESD protection in the smallest package available today. The added advantage is EMI/RFI attenuation. 0201 MLV can replace 2 diodes and the EMC capacitor for a one chip solution.

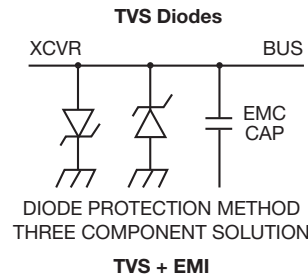
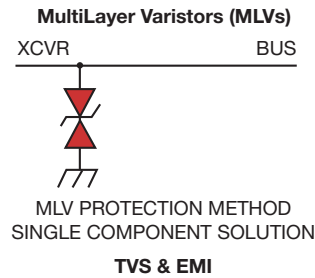
The miniature size and one chip solution team to offer designers the best in ESD protection and EMI filtering in one ultra compact device.

APPLICATIONS

- Cell phone
- PDA
- Camera modules
- Embedded components
- Hearing aid
- Any circuit with space constraints

FEATURES

- Capacitance 15pF to 150pF
- Low V_B Version
- Bi-Directional protection
- Fastest response time to ESD strikes
- Multi-strike capability
- Ultra compact 0201 case size



HOW TO ORDER

VC Varistor Chip	0201 Chip Size 0201	03 Working Voltage 03 = 3.5V	V Energy Rating V = 0.02J	151 Capacitance 151 = 150pF	W Packaging W = 7" 10kpcs	P Termination P = Ni Barrier/ 100% Sn (matte)
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AVX Part Number	V_W (DC)	V_W (AC)	V_B	V_C	I_{VC}	I_L	E_T	I_P	Cap
VC020103V101WP	3.5	2.0	4.76 min 8.84 max	14max	1	50	0.02	10	100pF ±30%
VC020103V121WP	3.5	2.0	4.76 min 8.84 max	14max	1	50	0.02	10	125pF ±30%
VC020103V151WP	3.5	2.0	4.76 min 8.84 max	14max	1	50	0.02	10	150pF ±30%
VC020105T150WP	5.6	4.0	10.0 min 15.6 max	35max	1	50	0.01	2	15pF ±30%
VC020105T330WP	5.6	4.0	10.0 min 15.6 max	35max	1	50	0.01	4	33pF ±30%
VC020105T500WP	5.6	4.0	10.0 min 15.6 max	35max	1	50	0.01	5	50pF ±30%
VC020105T101WP	5.6	4.0	10.0 min 15.6 max	35max	1	50	0.01	5	100pF ±30%
VC020105V101WP	5.6	4.0	6.4 min 9.6 max	17max	1	50	0.02	4	100pF ±30%
VC020107V101WP	7.0	5.6	9.6 min 14.4 max	20max	1	50	0.02	5	100pF ±30%
VC020116T150WP	16	11	21.7 min 29.3 max	45max	1	50	0.01	1	15pF ±30%

V_W (DC) DC Working Voltage [V]

V_W (AC) AC Working Voltage [V]

V_B Breakdown Voltage [V @ 1mA DC]

V_C Clamping Voltage [V @ I_{VC}]

I_{VC} Test Current for VC [A, 8x20µS]

I_L Maximum leakage current at the working voltage [µA]

E_T Transient Energy Rating [J, 10x1000µS]

I_P Peak Current Rating [A, 8x20µS]

Cap Capacitance [pF] @ 1KHz specified and 0.5VRMS



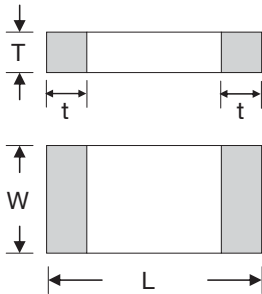
Miniature 0201 MLV

AVX Multilayer Ceramic Transient Voltage Suppressors

ESD Protection for any Circuit with Board Space Constraints

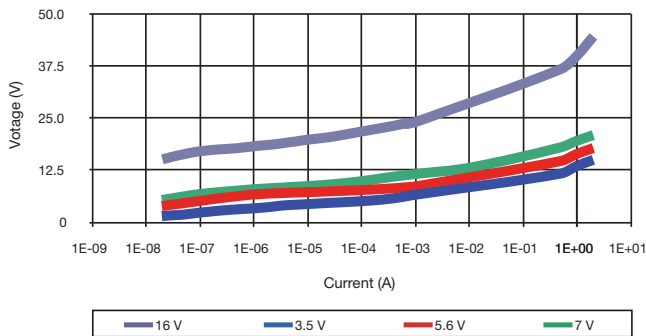


PHYSICAL DIMENSIONS: mm (inches)

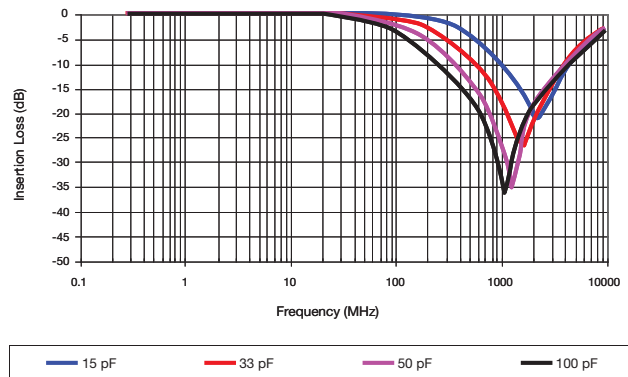


Size (EIA)	Length (L)	Width (W)	Max Thickness (T)	Terminal (t)
0201	0.60±0.03 (0.024±.001)	0.30±0.03 (0.011±0.001)	0.33 max. (0.013 max.)	0.15±0.05 (0.006±0.002)

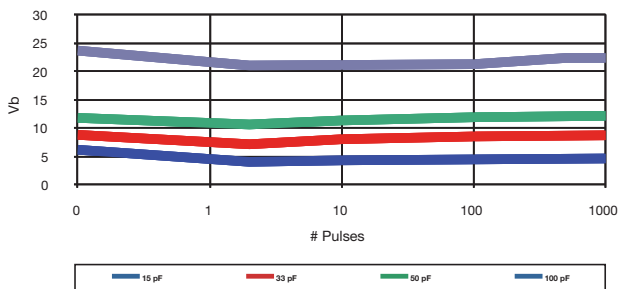
VOLTAGE/CURRENT CHARACTERISTICS



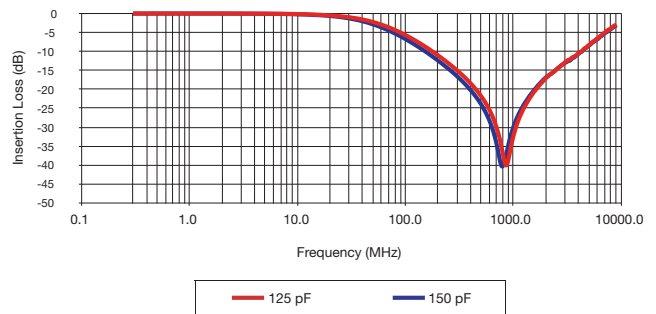
TRANSMISSION CHARACTERISTICS 5.6Vdc



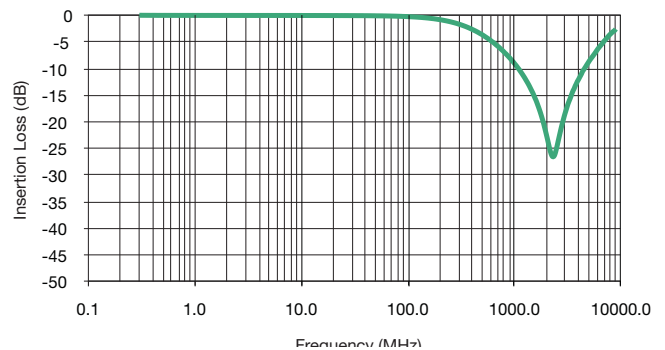
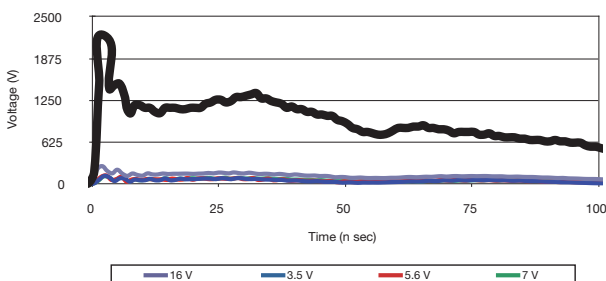
TYPICAL 8 KV ESD PERFORMANCE (150pF / 300ohm IEC Network)



3.5Vdc



8kV CONTACT ESD vs PULSE 1 Mohm Input (150pF / 330ohm Network)



High Temperature Automotive



150°C Rated Varistors



GENERAL DESCRIPTION

AVX High Temperature Multi-Layer Varistors are designed for underhood applications. Products have been tested, qualified, and specified to 150°C. The MLV advantage is EMI/RFI attenuation in the off state. This allows designers the ability to combine the circuit protection and EMI/RFI attenuation function into a single highly reliable device.

FEATURES

- Rated at 150°C
- AEC Q200 qualified
- ESD rating to 25kV contact
- EMI/RFI attenuation in off state
- Excellent current and energy handling

APPLICATIONS

- Under hood
- Down Hole Drilling
- Any high temperature application

CAN SERIES

HOW TO ORDER

CAN	AT	01	R	P	
Type	Series	Case Size	Packaging	Termination	
Controlled Area Network Varistor	Automotive High Temperature	01 = 0603 02 = 0405 2-Element 04 = 0612 4-Element	D = 7" (1000 pcs) R = 7" (4,000 pcs) T = 13" (10,000pcs)	P = Ni Barrier/ 100% Sn (matte)	

AVX Part Number	V _W (DC)	V _W (AC)	V _B	I _L	E _T	I _P	Cap	Case Size	Elements
CANAT01--	≤ 18	≤ 14	120	10	0.015	4	22	0603	1
CANAT02--	≤ 18	≤ 14	70	10	0.015	4	22	0405	2
CANAT04--	≤ 18	≤ 14	100	10	0.015	4	22	0612	4

V _W (DC)	DC Working Voltage [V]	I _L	Maximum leakage current at the working voltage [μA]
V _W (AC)	AC Working Voltage [V]	E _T	Transient Energy Rating [J, 10x1000μS]
V _B	Breakdown Voltage [V @ 1mA _{DC}]	I _P	Peak Current Rating [A, 8x20μS]
V _C	Clamping Voltage [V @ IVC]	Cap	Capacitance [pF] @ 1KHz specified and 0.5VRMS

ANTENNAGUARD SERIES

HOW TO ORDER

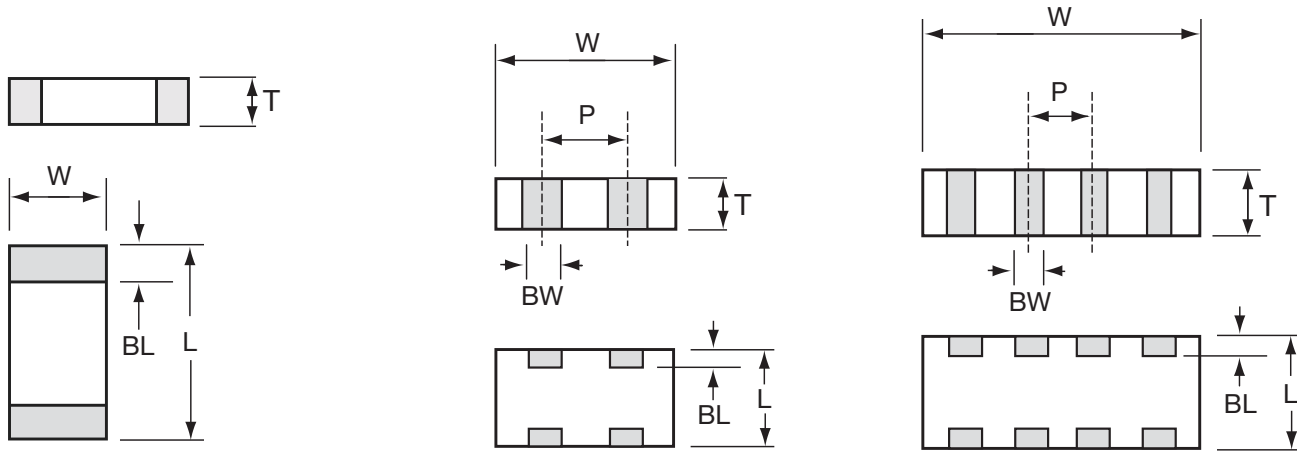
VCAT	06	AG	18	120	Y	A	T	1	A
Type	Case Size	Varistor Series	Working Voltage	Cap	Non-Std. Cap Tolerance	N/A	Termination Finish	Reel Size	Reel Quantity
High Temperature Varistor	04 = 0402 06 = 0603	AntennaGuard	18 = 18Vdc				P = Ni Barrier/ 100% Sn	1 = 7" 3 = 13"	A = 4000 or 10,000

AVX Part Number	V _W (DC)	V _W (AC)	I _L	Cap	Cap Tolerance	Case Size
VCAT06AG18120YAT--	≤ 18	≤ 14	10	12	+4, -2pF	0603

V _W (DC)	DC Working Voltage [V]	I _L	Maximum leakage current at the working voltage [μA]
V _W (AC)	AC Working Voltage [V]	Cap	Capacitance [pF] @ 1KHz specified and 0.5VRMS



PHYSICAL DIMENSIONS



0603 Discrete Dimensions

mm (inches)

L	W	T	BW	BL	P
1.60±0.15 (0.063±0.006)	0.80±0.15 (0.032±0.006)	0.90 MAX (0.035 MAX)	N/A	0.35±0.15 (0.014±0.006)	N/A

0405 2 Elements Array Dimensions

mm (inches)

L	W	T	BW	BL	P
1.00±0.15 (0.039±0.006)	1.37±0.15 (0.054±0.006)	0.66 MAX (0.026 MAX)	0.36±0.10 (0.014±0.004)	0.20±0.10 (0.008±0.004)	0.64 REF (0.025 REF)

0612 4 Elements Array Dimensions

mm (inches)

L	W	T	BW	BL	P
1.60±0.20 (0.063±0.008)	3.20±0.20 (0.126±0.008)	1.22 MAX (0.048 MAX)	0.41±0.10 (0.016±0.004)	0.18 ^{+0.25} _{-0.08} (0.008 ^{+0.010} _{-0.003})	0.76 REF (0.030 REF)

Glass Encapsulated SMD Varistor MLV

(VJ12, 20, 13, 14, 15, 32)

Transient Voltage Suppression, ESD Protection Devices & EMI Devices



GENERAL DESCRIPTION

AVX's Professional Multilayer Varistors include 3 series of glass coated products as listed below:

- Standard M0 Series
- Telecom MT Series
- Automotive MA/PA Series

The glass encapsulation process ensures high insulation resistance values after reflow soldering and excellent SMT compatibility. This protection ensures reliability and acid-resistance against harsh environment like chlorite flux.

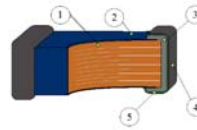
TYPICAL APPLICATIONS

Mainly used to reduce transient over-voltages in a very wide range of electronic products. Some example applications are:

- 1) Telecom, 2) Automotive, 3) Consumer Electronics, and 4) Industrial Applications.

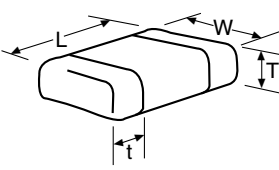
PHYSICAL CHARACTERISTICS

Construction Weight: <0.2g



- 1 Zinc varistor
- 2 Glass lead-free encapsulation
- 3 Silver termination
- 4 Nickel barrier
- 5 Tin 100%

PHYSICAL DIMENSIONS: mm (inches)

	Type	IEC Size	L	W	T	Land Length t
	VJ12	0805	2.01±0.20 (0.079±0.008)	1.25±0.15 (0.049±0.006)	1.3 max. (0.051 max.)	0.15...0.55 (0.006...0.022)
VJ20	1206	3.20±0.20 (0.126±0.008)	1.60±0.20 (0.063±0.008)	1.7 max. (0.067 max.)	0.25...0.75 (0.010...0.030)	
VJ13	1210	3.20±0.30 (0.126±0.012)	2.50±0.25 (0.098±0.010)	1.7 max. (0.067 max.)	0.25...0.75 (0.010...0.030)	
VJ14	1812	4.50±0.30 (0.177±0.012)	3.20±0.30 (0.126±0.012)	2.0 max. (0.079 max.)	0.25...1.00 (0.010...0.039)	
VJ15	2220	5.70±0.40 (0.224±0.016)	5.00±0.40 (0.197±0.016)	2.5 max. (0.098 max.)	0.25...1.00 (0.010...0.039)	
VJ32	3220	8.20±0.40 (0.323±0.016)	5.00±0.40 (0.197±0.016)	2.5 max. (0.098 max.)	0.25...1.00 (0.010...0.039)	

PART NUMBERING

VJ
Varistor Termination
 VJ = Plated Ni/Sn100%
 VU = Plated Ni/SnPb
 VC = Hybrid AgPdPt

14
Chip Size
 12 = 0805
 20 = 1206
 13 = 1210
 14 = 1812
 15 = 2220
 32 = 3220

MT
Series Code
 M0 = Industrial
 MT = Telecom
 MA/PA = Automotive

0950
Operating Voltage
 AC or DC

K
1mA Voltage Tolerance
 K = ±10%

BA
Packaging
 BA = Tape & Reel
 VJ12 = 4000 pcs/reel
 VJ20 = 3000 pcs/reel
 VJ13 = 2000 pcs/reel
 VJ14 = 1250 pcs/reel
 VJ15 = 1250 pcs/reel
 VJ32 = 1000 pcs/reel



Glass Encapsulated SMD Varistor MLV

(VJ12, 20, 13, 14, 15, 32)

Automotive MLV Range – MA and PA Series

AUTOMOTIVE SERIES – VJ12, 20, 13, 14, 15, 32 MA and PA SERIES

FEATURES

- Available in case size 0805, 1206, 1210, 1812, 2220, (3220 under development)
- Nickel and Tin (100%) plated Termination
- Max Energy absorption: 1.5 to 25J (50J under development)
- Well suited to protect against automotive related transients
- Load Dump capabilities: according to ISO standard DP7637-2 12V and 24V pulse 5
- Jump start capability (12V): 24.5 V - 5mn
- Complying to main requirements of AECQ 200
- RoHS Compliant and IMDS Registration

GENERAL CHARACTERISTICS

Storage Temperature: -55°C to +150°C
 Operating Temperature: -55°C to +125°C*
 * 150°C upon request

APPLICATIONS

- Protection of various semiconductor elements from overvoltage.
- Absorption of switching surge and electrostatic surge for relays and motors.
- Protection of electronic equipment for automobiles from induced lightning surge.

PART NUMBERS

Part Number	Case Size EIA	Working Voltage	Breakdown Voltage	Peak current	Maximum leakage current at Vdc	Energy 10*1000µs	Energy Load-Dump (x10)	Jump Start	T max
		Vdc	V(1mA)	Amp. 8*20µs	µA	Joules	Joules	Vmax (5mn min.)	Thickness mm (inches)
*VJ12PA0160---	0805	16	24.5	120	20	0.3	1	24.5	1.3
VJ20MA0160---	1206	16	24.5	200	20	0.6	1.5	24.5	1.7
VJ20PA0160---	1206	16	24.5	300	20	1.1	2	24.5	1.7
VJ13MA0160---	1210	16	24.5	400	20	1.6	3	24.5	1.7
VJ13PA0160---	1210	16	24.5	500	20	2	5	24.5	1.7
VJ14MA0160---	1812	16	24.5	800	20	2.4	6	25.5	2
VJ14PA0160---	1812	16	24.5	1000	20	2.9	10	25.5	2
VJ15MA0160---	2220	16	24.5	1200	20	5.8	12	25.5	2
VJ15PA0160---	2220	16	24.5	1500	20	7.2	25	25.5	2
VJ32PA0160---	3220	16	24.5	2000	20	13.8	50	24.5	2.5
VJ15MA0340---	2220	34	47	1200	20	10	12	47	2.5
VJ15PA0340---	2220	34	47	2000	20	13	25	47	2.5
*VJ32PA0340	3220	34	47	2000	20	19	50	47	2.5

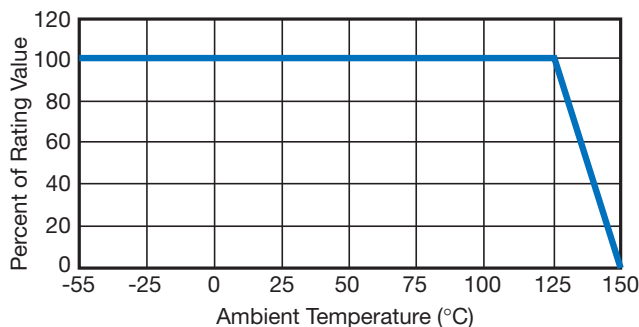
* under development

Hybrid termination AgPdPt upon request

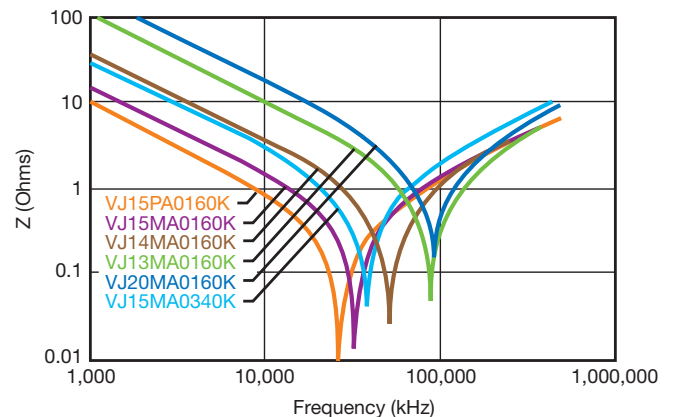


TEMPERATURE CHARACTERISTICS

For Current, Energy and Power



IMPEDANCE CHARACTERISTICS



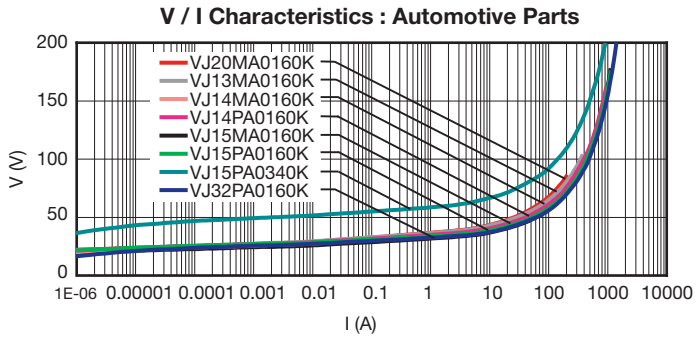
Glass Encapsulated SMD Varistor MLV

(VJ12, 20, 13, 14, 15, 32)

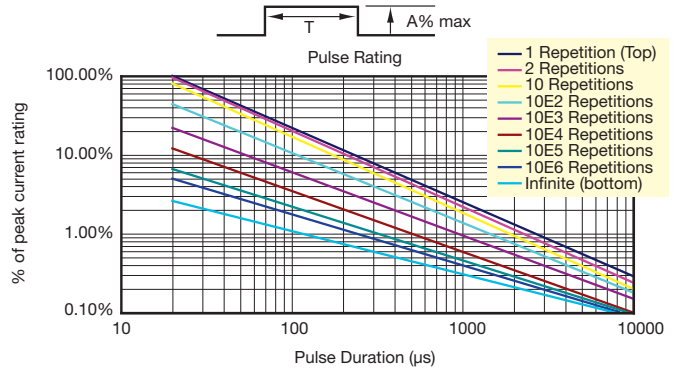
Automotive MLV Range – MA and PA Series

AUTOMOTIVE SERIES – VJ12, 20, 13, 14, 15, 32 MA and PA SERIES

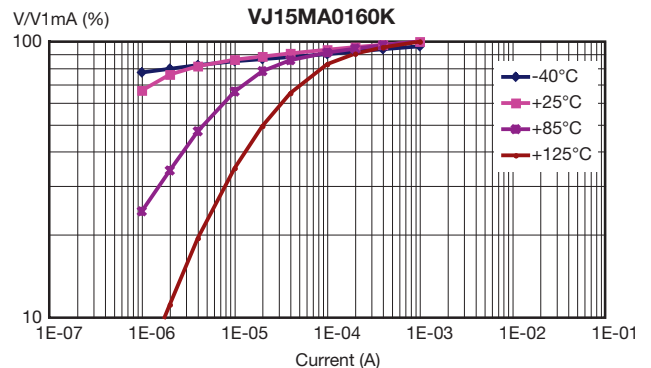
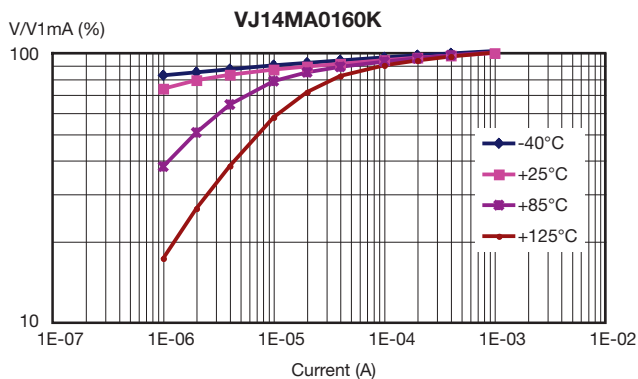
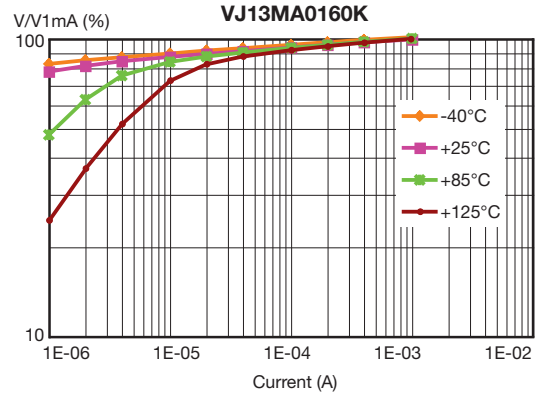
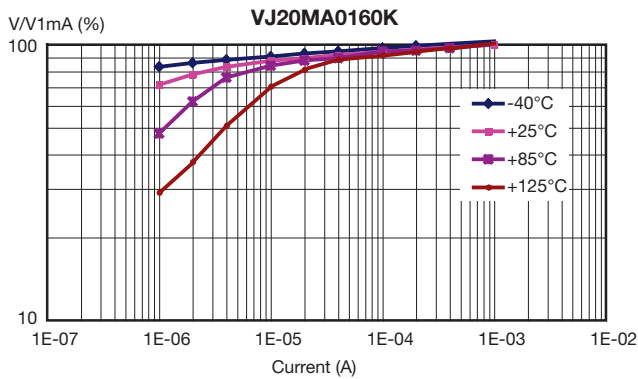
V / I CHARACTERISTICS



PULSE RATING



TEMPERATURE DEPENDENCE OF V/I CHARACTERISTICS

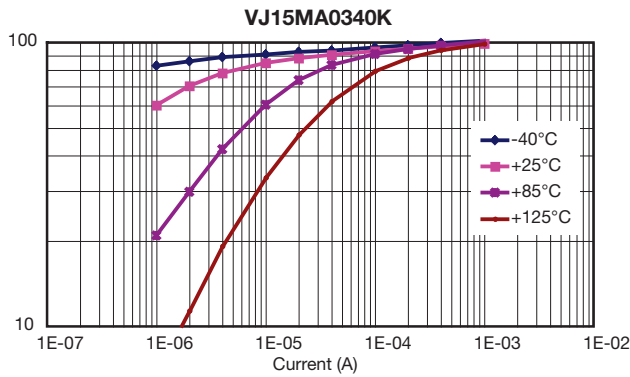
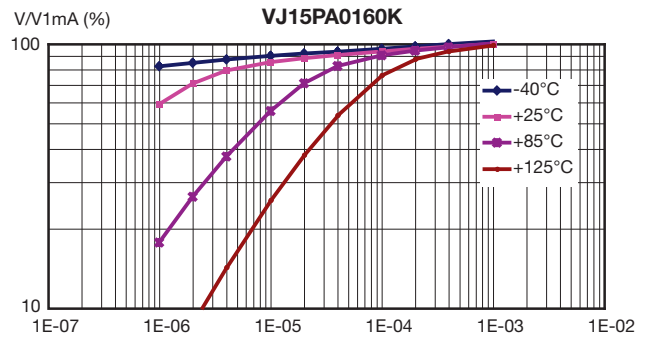
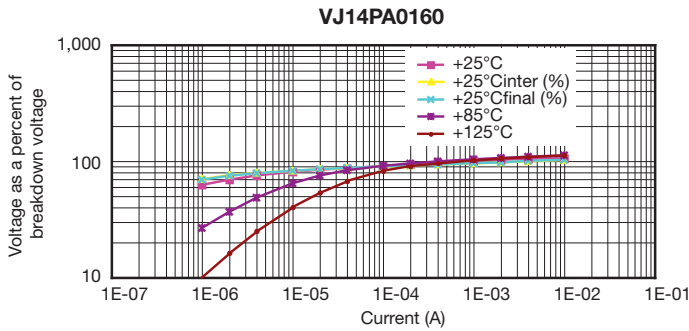


Glass Encapsulated SMD Varistor MLV

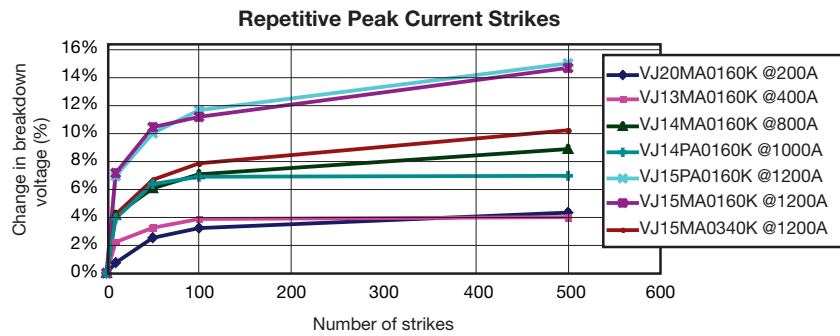
(VJ12, 20, 13, 14, 15, 32)

Automotive MLV Range – MA and PA Series

AUTOMOTIVE SERIES – VJ12, 20, 13, 14, 15, 32 MA and PA SERIES



PULSE DEGRADATION



Glass Encapsulated SMD Varistor MLV

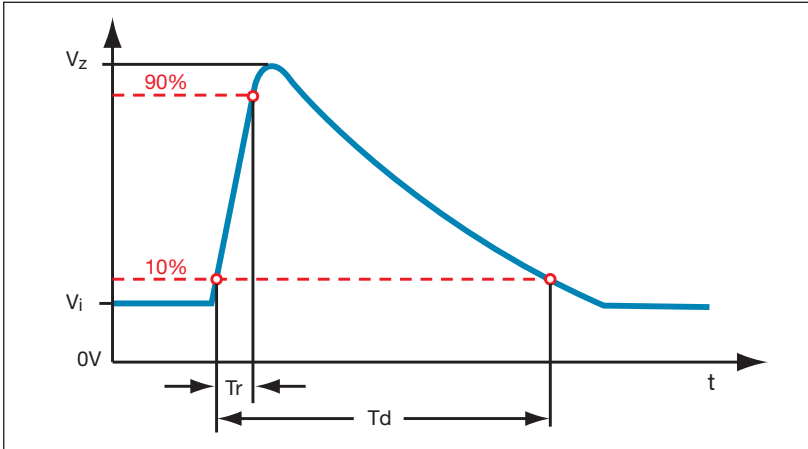
(VJ12, 20, 13, 14, 15, 32)

Automotive MLV Range – MA and PA Series

AUTOMOTIVE SERIES – VJ12, 20, 13, 14, 15, 32 MA and PA SERIES

AUTOMOTIVE LOAD DUMP TEST

(According to ISO DP7637/2 Pulse 5)



When using the test method indicated below, the amount of Energy dissipated by the varistor must not exceed the Load Dump Energy value specified in the product table.

Voltage Pulse applied to the varistor:

12V Network

$V_i = 13.5V$
 $T_d = 100$ to $350ms$
 $R_i = 2$ Ohms (Internal Resistance)
 $V_z = 70$ to $200V$
 Number of Pulses = 10 Pulses
 Other Load Dump Simulations can be achieved

24V Network

$V_i = 27V$
 $T_d = 100$ to $350ms$
 $R_i = 2$ Ohms (Internal Resistance)
 $V_z = 70$ to $200V$
 Number of Pulses = 10 Pulses

Pulse 5: Typical V_z max versus Pulse duration and R_s

VJ20MA0160K	0.5 Ohm	1 Ohm	2 Ohms
50ms	33	34	39
100ms	31	31	34
200ms	27	28	33
400ms	28	30	34
VJ13PA0160K	0.5 Ohm	1 Ohm	2 Ohms
50ms	44	48	57
100ms	36	39	46
200ms	33	33	39
400ms	29	28	34
VJ14PA0160K	0.5 Ohm	1 Ohm	2 Ohms
50ms	60	68	85
100ms	46	52	62
200ms	37	41	50
400ms	32	35	43
VJ15PA0160K	0.5 Ohm	1 Ohm	2 Ohms
50ms	98	116	150
100ms	66	80	104
200ms	50	60	78
400ms	41	47	58
VJ32PA0160K	0.5 Ohm	1 Ohm	2 Ohms
50ms	146	186	200
100ms	105	131	179
200ms	72	88	113
400ms	54	67	96



Glass Encapsulated SMD Varistor MLV

(VJ12, 20, 13, 14, 15)

Industrial MLV Range – M0 Series

INDUSTRIAL MLV RANGE – VJ12, 20, 13, 14, 15 M0 SERIES

FEATURES

- Glass encapsulation device with very low leakage current under DC operating conditions
- Device available in case size 1206, 1210, 1812, 2220 (3220)
- Nickel and Tin (100%) plated Termination (Hybrid AgPdPt termination available upon request)
- Bi-Directional protection. Fast Turn-On Time.
- Excellent transient clamping characteristics up to 1200amps peak current
- Multi strike capability. Provide EMC Capacitance
- RoHS Compliant

GENERAL CHARACTERISTICS

Storage Temperature: -55°C to +150°C
 Operating Temperature: -55°C to +125°C

TYPICAL APPLICATIONS

Many uses to reduce transient over-voltage in the very wide range of electronic products in the Professional, Industrial and Consumer Applications.

Type	Case Size	Vrms	VDC	Breakdown Voltage	Max. Clamping Voltage	Ip (A)	Maximum Leakage Current	Energy 10*1000µs	Max. Peak Current 8*20µs	Cap. Typical (1KHz/0.5V)
		(V)	(V)	(V)	Vp (V)		µA	(J)	(A)	(pF)
VJ20M00140K---	1206	14	18	22±10%	38	1	20	0.5	200	900
VJ13M00140K---	1210	14	18	22±10%	38	2.5	20	1.6	400	1800
VJ14M00140K---	1812	14	18	22±10%	38	5	20	2.3	800	4200
VJ15M00140K---	2220	14	18	22±10%	38	10	20	5.8	1200	9600
VJ20M00170K---	1206	17	22	27±10%	44	1	20	0.6	200	800
VJ13M00170K---	1210	17	22	27±10%	44	2.5	20	1.7	500	2500
VJ14M00170K---	1812	17	22	27±10%	44	5	20	2.7	800	3700
VJ15M00170K---	2220	17	22	27±10%	44	10	20	7.2	1200	8600
VJ20M00200K---	1206	20	26	33±10%	54	1	20	0.7	200	550
VJ13M00200K---	1210	20	26	33±10%	54	2.5	20	1.9	500	1200
VJ14M00200K---	1812	20	26	33±10%	54	5	20	3	800	2800
VJ15M00200K---	2220	20	26	33±10%	54	10	20	7.8	1200	6400
VJ20M00250K---	1206	25	31	39±10%	65	1	20	1	200	500
VJ13M00250K---	1210	25	31	39±10%	65	2.5	20	1.7	500	1100
VJ14M00250K---	1812	25	31	39±10%	65	5	20	3.7	800	2600
VJ15M00250K---	2220	25	31	39±10%	65	10	20	9.6	1200	5800
VJ20M00300K---	1206	30	38	47±10%	77	1	20	1.1	200	400
VJ13M00300K---	1210	30	38	47±10%	77	2.5	20	2	400	1200
VJ14M00300K---	1812	30	38	47±10%	77	5	20	4.2	800	1800
VJ15M00300K---	2220	30	38	47±10%	77	10	20	12	1200	4200
VJ20M00350K---	1206	35	45	56±10%	90	1	20	0.6	200	260
VJ13M00350K---	1210	35	45	56±10%	90	2.5	20	1.5	300	1200
VJ14M00350K---	1812	35	45	56±10%	90	5	20	4	500	2500
VJ15M00350K---	2220	35	45	56±10%	90	10	20	10	1000	4000
VJ20M00400K---	1206	40	56	68±10%	110	1	20	0.7	100	190
VJ13M00400K---	1210	40	56	68±10%	110	2.5	20	2.3	250	380
VJ14M00400K---	1812	40	56	68±10%	110	5	20	4.8	500	800
VJ15M00400K---	2220	40	56	68±10%	110	10	20	9	1000	2000
VJ20M00500K---	1206	50	65	82±10%	135	1	20	0.8	100	130
VJ13M00500K---	1210	50	65	82±10%	135	2.5	20	1.6	250	700
VJ14M00500K---	1812	50	65	82±10%	135	5	20	4.5	400	600
VJ15M00500K---	2220	50	65	82±10%	135	10	20	7	800	1400
VJ20M00600K---	1206	60	85	100±10%	165	1	20	0.9	100	100
VJ13M00600K---	1210	60	85	100±10%	165	2.5	20	1.5	250	600
VJ14M00600K---	1812	60	85	100±10%	165	5	20	4.5	400	500
VJ15M00600K---	2220	60	85	100±10%	165	10	20	6.8	800	1100



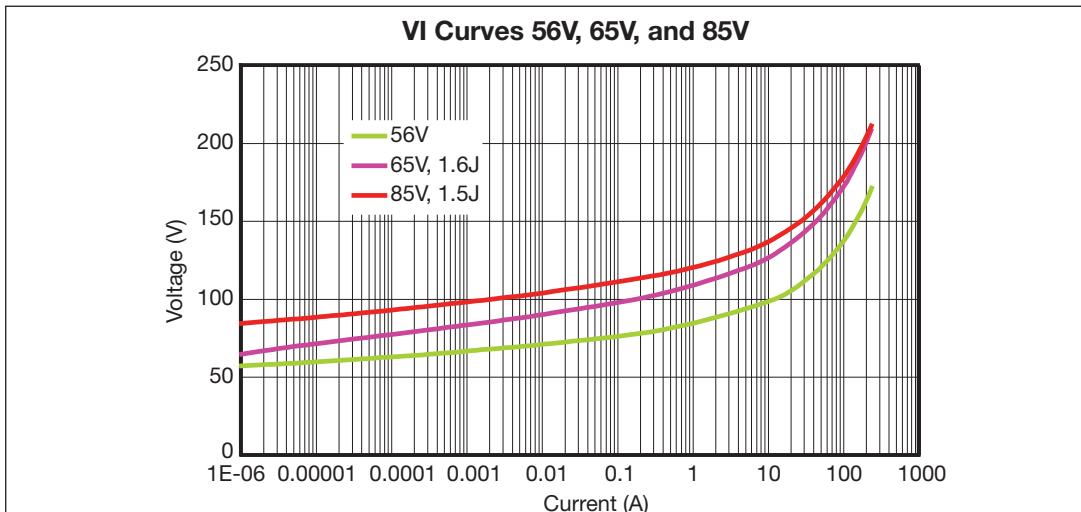
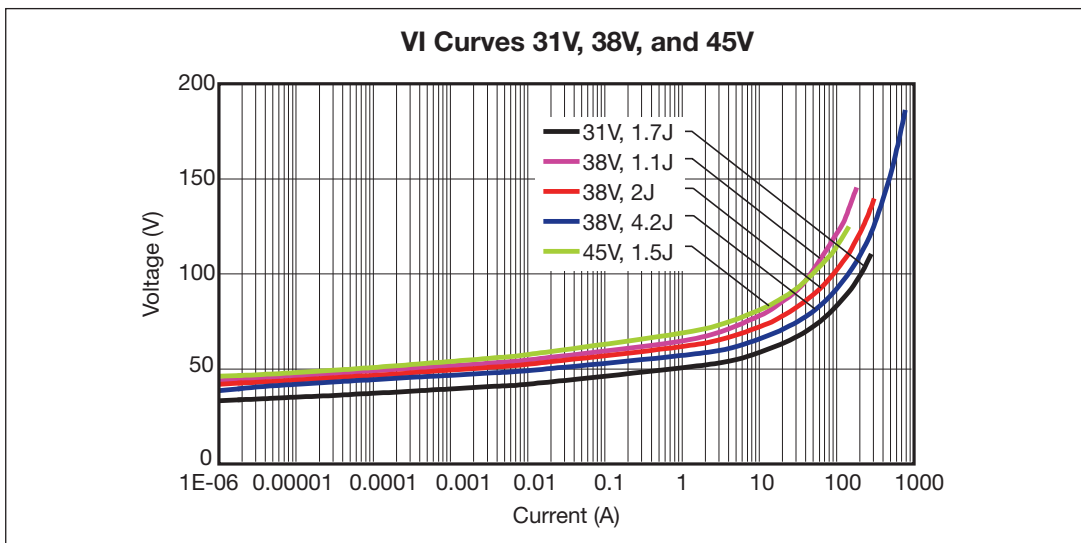
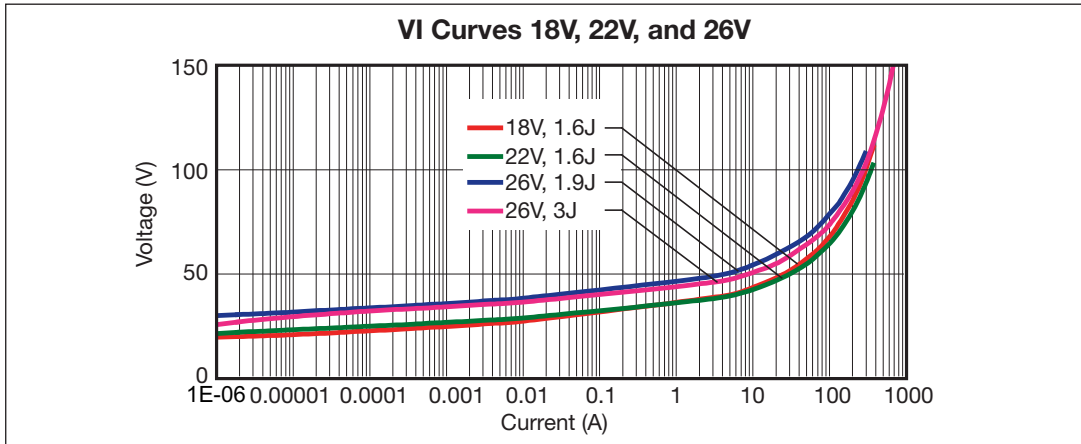
Glass Encapsulated SMD Varistor MLV

(VJ12, 20, 13, 14, 15)

Industrial MLV Range – M0 Series

INDUSTRIAL MLV RANGE – VJ12, 20, 13, 14, 15 M0 SERIES

V/I CHARACTERISTIC



Glass Encapsulated SMD Varistor MLV (VJ14)



Telecom MLV Range – MT Series

TELECOM MLV RANGE - VJ14 MT SERIES

FEATURES

- Effective alternative to leaded MOVs between 60 and 90 Vrsm
- High Energy Ratings up to 6 Joules with 1812 case size
- Nickel barrier or hybrid AgPdPt terminations
- Multiple Strike Capability
- Provide EMC Capacitance
- Specified in accordance to CCITT 10/1000µs Pulse test
- RoHS Compliant and IMDS Registration

TARGET APPLICATIONS

- Phone Lines, ADSL Lines, and other Telecom Circuits
- Consumer Products

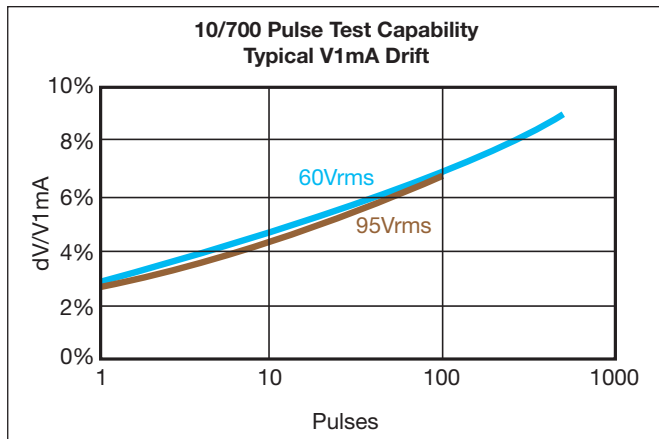
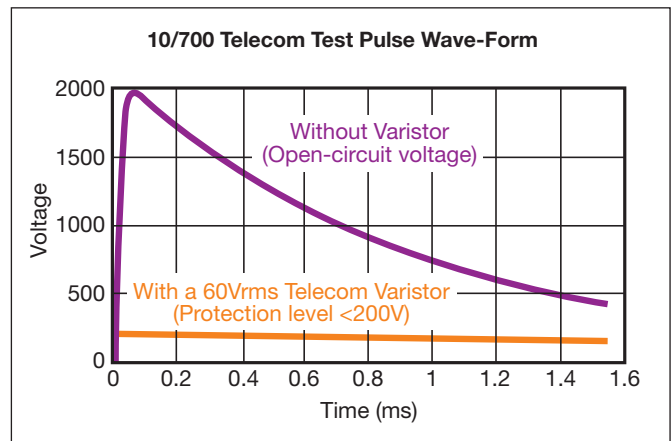
GENERAL CHARACTERISTICS

Storage Temperature: -55°C to +125°C
 Operating Temperature: -55°C to +125°C

CCITT 10x700µs TEST

A pulse of 10 x 700µs duration as specified by CCITT or IEC 61000-4-5 is often used to check the interference immunity of Telecom equipment.

The curves show that the 60Vrms Varistor can reduce the interference of the equipment from 2KV to less than 200V.



Ten pulses with a duration of 10x700µs applied at one minute intervals are specified for telecom equipment.

The curves show the V1mA drift when more than 10 pulses are applied.

PART NUMBERS

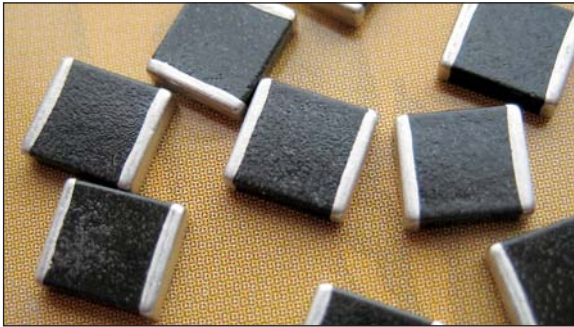
Part Number	Case Size	Operating Voltage		Breakdown Voltage V(1mA)	Max. Clamping Voltage		CCITT 10 Pulses 10*700µs Amp.	I max. 8*20µs Amp.	Energy 10*1000µs Joules	Mean Power Dissipation W	Typical Cap. pF
		Vac	Vdc		V	Amp.					
VJ14MT0600---	1812	60	85	100	400	45	45	400	6	0.015	400
VJ14MT0750---	1812	75	100	120	400	45	45	400	6	0.015	400
VJ14MT0950---	1812	95	125	150	250	45	45	250	5	0.015	250

Hybrid termination AgPdPt (VC Range) upon request



Glass Encapsulated SMD Varistor MLV

(VJ32/VC32)



GENERAL DESCRIPTION

The VJ32/VC32M0 Series offers the designer a surface mount solution with higher voltage ratings and transient energy ratings. This Multilayer Layer Surface Mount Varistor replaces the traditional radial-lead Varistors with reduced size and weight. The glass encapsulation ensures the high performances in voltage up to 300Vrms reliability and acid-resistance against harsh environment like chlorite soldering flux.



FEATURES

- Lead less surface mount chip 3220 Case Size
- Voltage Ratings from 175Vrms to 300 Vrms
- VJ32 with Ni barrier/100% Sn Termination (for lead free soldering applications)
VC32 with hybrid PdPtAg Termination (not suitable for lead free soldering)
- Operating temperature from -55°C to +85°C
- RoHS Compliant

APPLICATIONS

- MOV (Radial) Replacement
- Suppression of transient on line voltage
- Electric Meters
- Industrial Equipment
- Mains PSUs
- Telecommunications
- Consumer Electronics

PART NUMBERS

AVX PN	Case Size	Operating voltage		Breakdown Voltage Voltage at 1mA			Max. Clamping Voltage 8*20µs		Max. Leakage Current	Energy 10*1000µs	Max. Peak Current 8*20µs 1 Pulse	Cap. Typical (1KHz,0.5V)
		Vrms	Vdc	Min.	Average	Max.	V	A				
VJ32M01750K--	3220	175	225	245	270	297	455	10	15	9.5	300	120
VJ32M00231K--	3220	230	300	327	360	396	595	10	15	10	300	80
VJ32M00251K--	3220	250	330	355	390	429	650	10	15	11	300	75
VJ32M02750K--	3220	275	369	391	430	473	710	10	15	13	300	70
VJ32M00301K--	3220	300	385	427	470	517	775	10	15	15	300	65

Glass Encapsulated SMD Varistor MLV

(VJ13, 14, 15, 20)

Surface Mounting Guide

SURFACE MOUNTING GUIDE (VJ13, 14, 15, 20)

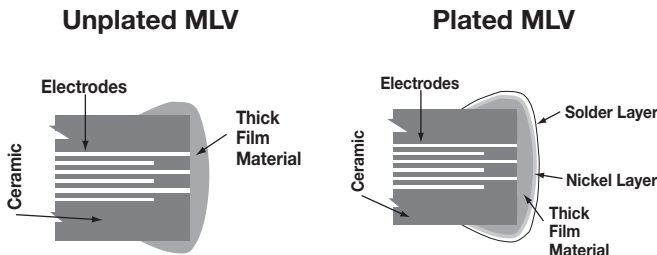
APPLICATIONS NOTES

SOLDERABILITY/LEACHING

Terminations to be well soldered after immersion in a 60/40 tin/lead solder bath at $235 \pm 5^\circ\text{C}$ for 2 ± 1 seconds. Terminations will resist leaching for at least the immersion times and conditions recommendations shown below.

P/N	Termination Type	Solder Tin/Lead	Solder Temp. °C	Immersion Time (sec)
VJ	Plated MLV Nickel and Matte Tin Plating Termination	60/40	260 ± 5	30 ± 1

- The visual standards used for evaluation of solder joints will need to be modified as lead free joints are not as bright as with tin-lead pastes and the fillet may not be as large.
- Lead-free solder pastes do not allow the same self alignment as lead containing systems. Standard mounting pads are acceptable, but machine set up may need to be modified.

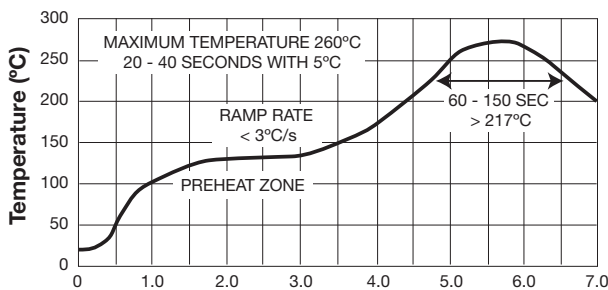


RECOMMENDED SOLDERING PROFILES

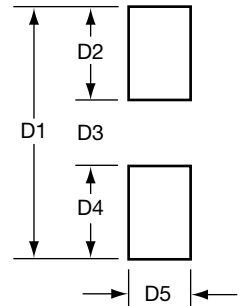
VJ products are compatible with a wide range of soldering conditions consistent with good manufacturing practice for surface mount components. This includes Pb free reflow processes and peak temperatures up to 270°C . Recommended profiles for reflow and wave soldering are show below for reference.

VC products are recommended for lead soldering application or gluing techniques.

VJ Products Lead-Free Reflow Profile



RECOMMENDED SOLDER PAD LAYOUT



REFLOW SOLDERING

Dimensions in mm (inches)

Case Size	D1	D2	D3	D4	D5
1206	4.00 (0.157)	1.00 (0.039)	2.00 (0.079)	1.00 (0.039)	1.06 (0.042)
1210	4.00 (0.157)	1.00 (0.039)	2.00 (0.079)	1.00 (0.039)	2.05 (0.081)
1812	5.60 (0.220)	1.00 (0.039)	3.60 (0.142)	1.00 (0.039)	3.00 (0.118)
2220	6.60 (0.260)	1.00 (0.039)	4.60 (0.181)	1.00 (0.039)	5.00 (0.197)
3220	10.21 (0.402)	2.21 (0.087)	5.79 (0.228)	2.21 (0.087)	5.50 (0.217)

WAVE SOLDERING

Dimensions in mm (inches)

Case Size	D1	D2	D3	D4	D5
1206	5.00 (0.197)	1.50 (0.059)	2.00 (0.079)	1.50 (0.059)	1.06 (0.042)
1210	5.00 (0.197)	1.50 (0.059)	2.00 (0.079)	1.50 (0.059)	2.05 (0.081)
1812	6.60 (0.260)	1.50 (0.059)	3.60 (0.142)	1.50 (0.059)	3.00 (0.118)
2220	7.60 (0.299)	1.50 (0.059)	4.60 (0.181)	1.50 (0.059)	5.00 (0.197)
3220	11.21 (0.441)	1.50 (0.059)	5.79 (0.228)	1.50 (0.059)	5.50 (0.217)





GENERAL DESCRIPTION

The Glass Encapsulated TransGuard® multilayer varistors are zinc oxide (ZnO) based ceramic semiconductor devices with non-linear, bi-directional V-I characteristics.

They have the advantage of offering bi-directional overvoltage protection as well as EMI/RFI attenuation in a single SMT package.

These large case size parts extend TransGuard range into high energy applications. In addition the glass encapsulation provides enhanced resistance against harsh environment or process such as acidic environment, salts or chlorite flux.

GENERAL CHARACTERISTICS

Operating Temperature:
-55°C to 125°C

FEATURES

- Bi-Directional protection
- EMI/RFI attenuation in off-state
- Multi-strike capability
- Sub 1nS response to ESD strike
- High energy / High current
- Glass Encapsulated

APPLICATIONS

- Professional / Industrial / Commercial Applications
- IC Protection, DC motor protection
- Relays, Controllers, Sensors
- Smart Grids
- Alarms and more
- Various Applications where Glass Encapsulation is Needed for Harsh Environment / Acid-Resistance

HOW TO ORDER

V	G	1812	16	P	400	R	P
Varistor	Glass Encapsulate Chip	Chip Size	Working Voltage	Energy Rating	Clamping Voltage	Package	Termination
		1210 1812 2220	16 = 16Vdc 22 = 22Vdc 38 = 38Vdc 65 = 65Vdc	S = 2.0J P = 2.7-3.0J U = 4.0-5.0J Y = 7.2-12J	400 = 42V 440 = 44V 770 = 77V 131 = 135V	D = 7" reel R = 7" reel T = 13" reel	P = Ni/Sn plated

PHYSICAL DIMENSIONS: mm (inches)

Size (EIA)	Length (L)	Width (W)	Max Thickness (T)	Land Length (t)
1210	3.20±0.20 (0.126±0.008)	2.49±0.20 (0.098±0.008)	1.70 (0.067)	0.14 max. (0.045 max.)
1812	4.50±0.30 (0.177±0.012)	3.20±0.30 (0.126±0.012)	2.00 (0.079)	1.00 max. (0.040 max.)
2220	5.70±0.40 (0.224±0.016)	5.00±0.40 (0.197±0.016)	2.50 (0.098)	1.00 max. (0.040 max.)

ELECTRIAL CHARACTERISTICS

AVX PN	V _W (DC)	V _W (AC)	V _B	V _C	I _{VC}	I _L	E _T	I _p	Cap	Freq
VG181216P400	16	11	24.5±10%	42	5	10	2.9	1000	5000	K
VG222016Y400	16	11	24.5±10%	42	10	10	7.2	1500	13000	K
VG121022R440	22	17	27±10%	44	2.5	10	1.7	400	1600	K
VG121038S770	38	30	47.0±10%	77	2.5	15	2	400	1000	K
VG181238U770	38	30	47.0±10%	77	5	15	4.2	800	1300	K
VG222038Y770	38	30	47.0±10%	77	10	15	12	2000	4200	K
VG121065P131	65	50	82.0±10%	135	2.5	15	2.7	350	600	K

V_W(DC) DC Working Voltage [V]
 V_W(AC) AC Working Voltage [V]
 V_B Typical Breakdown Voltage [V @ 1mA_{DC}, 25°C]
 V_C Clamping Voltage [V @ I_{VC}]
 I_{VC} Test Current for V_C [A, 8x20µs]
 I_L Maximum leakage current at the working voltage, 25°C [µA]

E_T Transient Energy Rating [J, 10x1000µs]
 I_p Peak Current Rating [A, 8x20µs]
 Cap Typical capacitance [pF] @ frequency specified and 0.5V_{RMS}, 25°C, M = 1MHz, K = 1kHz



GENERAL DESCRIPTION

The Glass Encapsulated TransGuard® Automotive Series are zinc oxide (ZnO) based ceramic semiconductor devices with non-linear, bi-directional voltage-current characteristics.

They have the advantage of offering bi-directional overvoltage protection as well as EMI/RFI attenuation in a single SMT package. The Automotive Series high current and high energy handling capability make them well suited for protection against automotive related transients.

These large case size parts extend TransGuard range into high energy applications. In addition the glass encapsulation provides enhanced resistance against harsh environment or process such as acidic environment, salts or chlorite flux.

GENERAL CHARACTERISTICS

Operating Temperature:
-55°C to 125°C

FEATURES

- High Reliability
- High Energy Absorption (Load Dump)
- High Current Handling
- Bi-Directional protection
- EMI/RFI attenuation in off-state
- Multi-strike capability
- Sub 1nS response to ESD strike
- AEC Q200 Qualified

APPLICATIONS

- Various Automotive Applications
- Internal Combustion Engine (ICE) Vehicles
- Hybrid Electric Vehicles (HEV)
- Plug-in Hybrid Electric Vehicles (PHEV)
- Commercial Vehicles
- Sensors
- DC Motor
- LIN BUS
- Relays
- ECU
- and more
- Applications where Glass Encapsulation is needed for Harsh Environment/Acid-Resistance

HOW TO ORDER

V	G	AS	1812	16	P	400	R	P
Varistor	Glass Encapsulate Chip	Automotive Series	Chip Size	Working Voltage	Energy Rating	Clamping Voltage	Package	Termination
			1210 1812 2220	16 = 16Vdc 34 = 34Vdc 65 = 65Vdc	S = 2.0J P = 2.9J U = 5.0J Y = 7.2-12J	400 = 42V 770 = 77V 131 = 135V	D = 7" reel R = 7" reel T = 13" reel	P = Ni/Sn plated

PHYSICAL DIMENSIONS: mm (inches)

Size (EIA)	Length (L)	Width (W)	Max Thickness (T)	Land Length (t)
1210	3.20±0.20 (0.126±0.008)	2.49±0.20 (0.098±0.008)	1.70 (0.067)	0.14 max. (0.045 max.)
1812	4.50±0.30 (0.177±0.012)	3.20±0.30 (0.126±0.012)	2.00 (0.079)	1.00 max. (0.040 max.)
2220	5.70±0.40 (0.224±0.016)	5.00±0.40 (0.197±0.016)	2.50 (0.098)	1.00 max. (0.040 max.)

ELECTRIAL CHARACTERISTICS

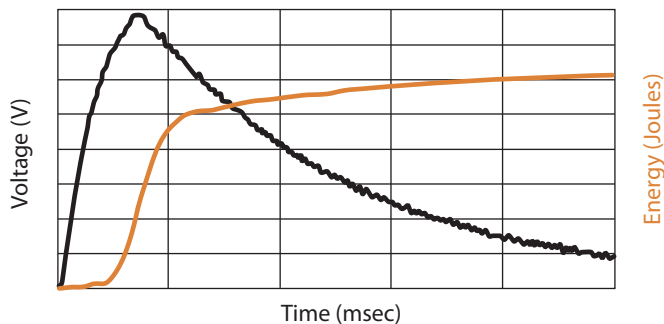
AVX PN	V _W (DC)	V _W (AC)	V _B	V _C	I _{VC}	I _L	E _T	E _{LD}	I _P	Cap	Freq	V _{Jump}	P _{Diss,MAX}
VGAS181216P400	16	11	24.5±10%	42	5	10	2.9	10	1000	5000	K	27.5	0.07
VGAS222016Y400	16	11	24.5±10%	42	10	10	7.2	25	1500	13000	K	25.5	0.1
VGAS121034S770	34	30	47.0±10%	77	2.5	15	2	3	400	1000	K	48	0.04
VGAS181234U770	34	30	47.0±10%	77	5	15	5	6.1	800	1500	K	48	0.08
VGAS222034Y770	34	30	47.0±10%	77	10	15	12	25	2000	6300	K	48	0.24
VGAS121065P131	65	50	82.0±10%	135	2.5	15	2.7	-	350	600	K	48	0.05

V _W (DC)	DC Working Voltage [V]	E _T	Transient Energy Rating [J, 10x1000µS]
V _W (AC)	AC Working Voltage [V]	E _{LD}	Load Dump Energy (x10) [J]
V _B	Typical Breakdown Voltage [V @ 1mA _{DC} , 25°C]	I _P	Peak Current Rating [A, 8x20µS]
V _C	Clamping Voltage [V @ I _{VC}]	Cap	Typical capacitance [pF] @ frequency specified and 0.5V _{RMS} , 25°C, M = 1MHz, K = 1kHz
I _{VC}	Test Current for V _C [A, 8x20µs]	V _{Jump}	Jump Start [V, 5 min]
I _L	Maximum leakage current at the working voltage, 25°C [µA]	P _{DISS}	Power Dissipation [W]

AUTOMOTIVE SERIES – LOAD DUMP TEST

According to ISO DP7637 rev 2 Pulse 5

**Automotive Load Dump Pulse
(According to ISO 7637 Pulse 5)**



When using the test method indicated below, the amount of Energy dissipated by the varistor must not exceed the Load Dump Energy value specified in the product table.

12V SYSTEMS

VGAS181216P400	0.5Ω	1Ω	4Ω
100ms	46	52	72
200ms	37	41	59
400ms	32	35	51
VGAS222016Y400	0.5Ω	1Ω	4Ω
100ms	53	60	77
200ms	50	55	73
400ms	47	50	66

StaticGuard

AVX Multilayer Ceramic Transient Voltage Suppressors ESD Protection for CMOS, Bi Polar and SiGe Based Systems



GENERAL INFORMATION

- Typical ESD failure voltage for CMOS and/or Bi Polar is $\geq 200V$.
- 15kV ESD pulse (air discharge) per IEC 1000-4-2, Level 4, generates < 20 millijoules of energy.
- Low capacitance ($< 200pF$) is required for high-speed data transmission.
- Low leakage current (I_L) is necessary for battery operated equipment.

StaticGuard

AVX Part Number	Working Voltage (DC)	Working Voltage (AC)	Clamping Voltage	Test Current For V_c	Maximum Leakage Current	Transient Energy Rating	Peak Current Rating	Typical Cap	Case Size	Elements
VC04LC18V500_ _	≤ 18.0	≤ 14.0	50	1	10	0.02	15	40	0402	1
VC06LC18X500_ _	≤ 18.0	≤ 14.0	50	1	10	0.05	30	50	0603	1
VC08LC18A500_ _	≤ 18.0	≤ 14.0	50	1	10	0.10	30	80	0805	1
VC12LC18A500_ _	≤ 18.0	≤ 14.0	50	1	10	0.10	30	200	1206	1
VA10LC18A500_ _	≤ 18.0	≤ 14.0	50	1	10	0.10	30	200	Axial	1

Termination/Lead Finish Code
Packaging Code

- V_w (DC) DC Working Voltage (V)
- V_w (AC) AC Working Voltage (V)
- V_c Clamping Voltage (V @ I_{vc})
- I_{vc} Test Current for V_c (A, $8 \times 20\mu S$)
- I_L Maximum Leakage Current at the Working Voltage (μA)
- E_T Transient Energy Rating (J, $10 \times 1000\mu S$)
- I_p Peak Current Rating (A, $8 \times 20\mu S$)
- Cap Typical Capacitance (pF) @ frequency specified and 0.5 V

Not RoHS Compliant

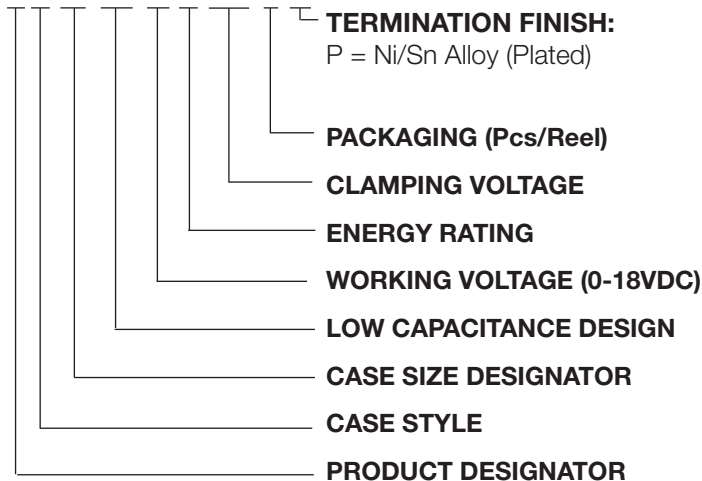


For RoHS compliant products,
please select correct termination style.

PART NUMBER IDENTIFICATION

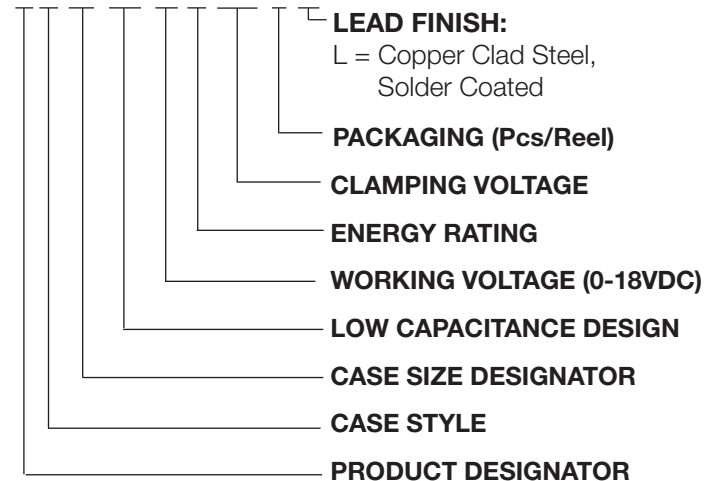
Chips

VC08LC18A500RP



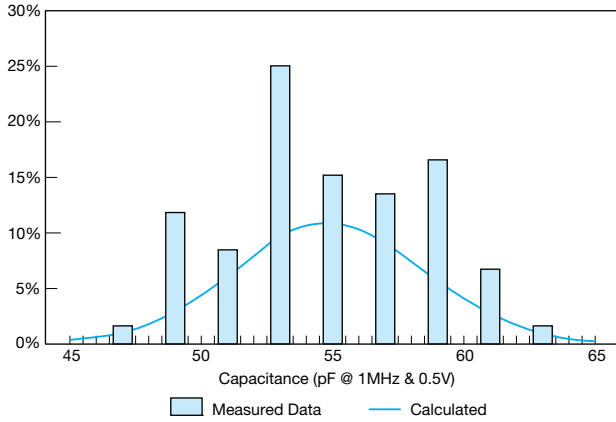
Axials

VA10LC18A500RL

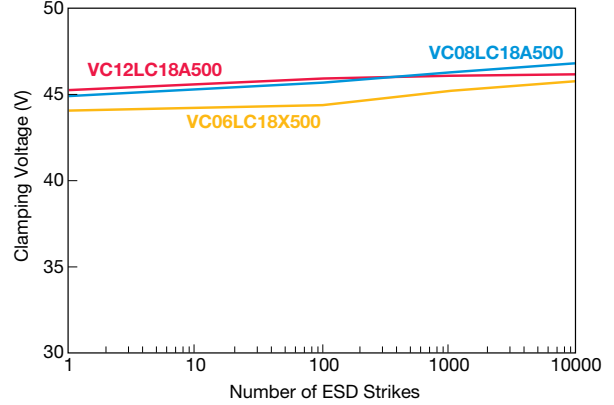


TYPICAL PERFORMANCE DATA

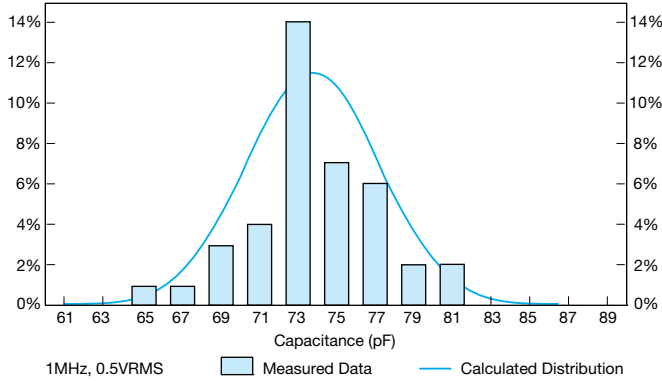
VC06LC18X500 Capacitance Histogram



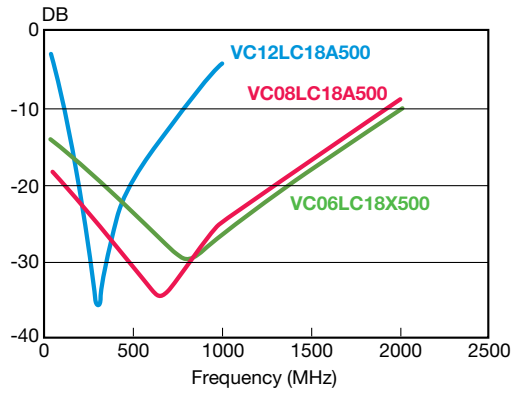
StaticGuard ESD RESPONSE
IEC 1000-4-2 (8 Kv Contact Discharge)



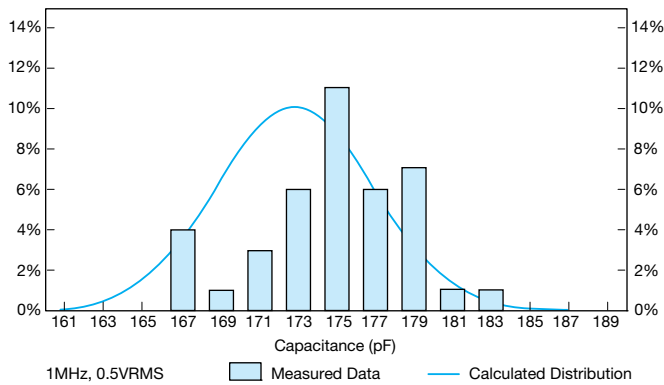
VC08LC18A500 Capacitance Histogram



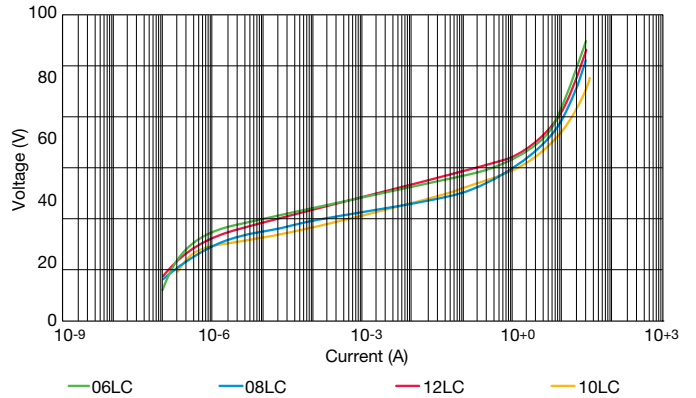
StaticGuard S21



VC12LC18A500 Capacitance Histogram



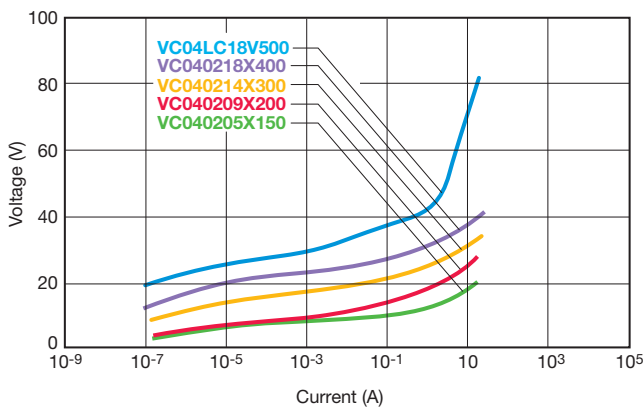
VI Curves - StaticGuard Products



TYPICAL PERFORMANCE CURVES (0402 CHIP SIZE)

VOLTAGE/CURRENT CHARACTERISTICS

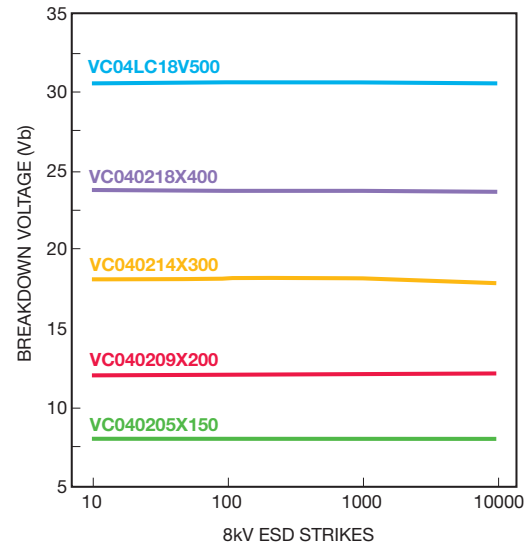
Multilayer construction and improved grain structure result in excellent transient clamping characteristics up to 20 amps peak current, while maintaining very low leakage currents under DC operating conditions. The VI curves below show the voltage/current characteristics for the 5.6V, 9V, 14V, 18V and low capacitance StaticGuard parts with currents ranging from parts of a micro amp to tens of amps.



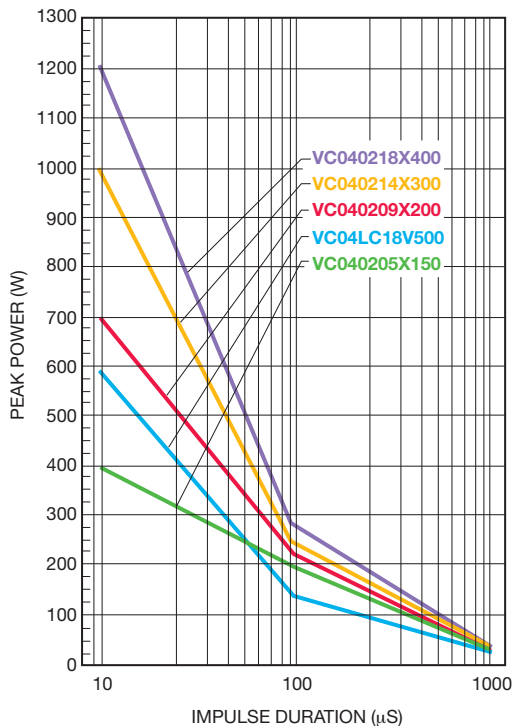
PULSE DEGRADATION

Traditionally varistors have suffered degradation of electrical performance with repeated high current pulses resulting in decreased breakdown voltage and increased leakage current. It has been suggested that irregular intergranular boundaries and bulk material result in restricted current paths and other non-Schottky barrier paralleled conduction paths in the ceramic. Repeated pulsing of TransGuard® transient voltage suppressors with 150Amp peak 8 x 20µS waveforms shows negligible degradation in breakdown voltage and minimal increases in leakage current. This does not mean that TransGuard® suppressors do not suffer degradation, but it occurs at much higher current.

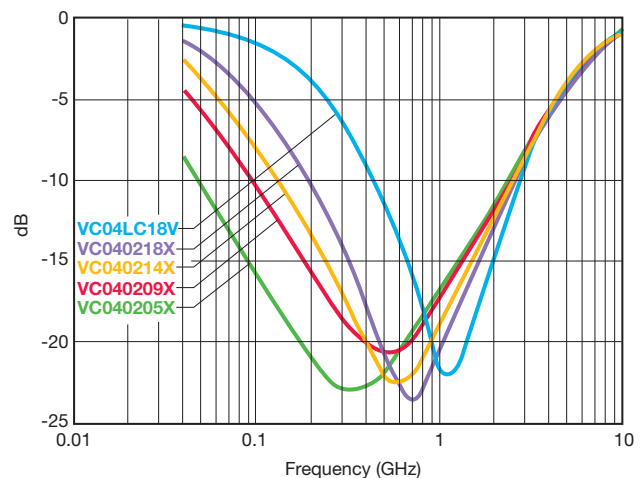
ESD TEST OF 0402 PARTS



PEAK POWER VS PULSE DURATION



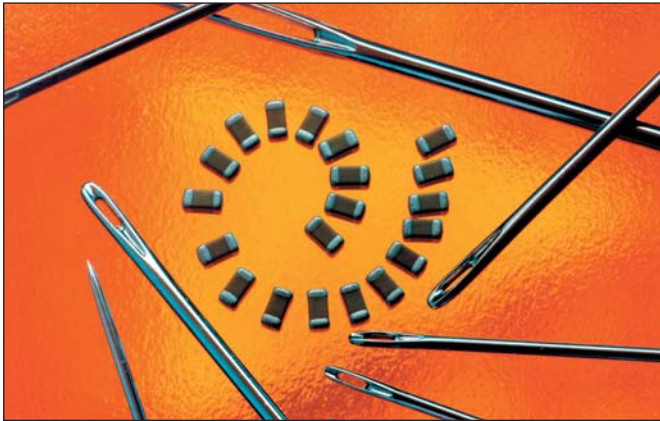
INSERTION LOSS CHARACTERISTICS



StaticGuard Automotive Series



Multilayer Varistors for Automotive Applications



GENERAL DESCRIPTION

The StaticGuard Automotive Series are low capacitance versions of the TransGuard and are designed for general ESD protection of CMOS, Bi-Polar, and SiGe based systems. The low capacitance makes these products suitable for use in high speed data transmission lines.

FEATURES

- AEC Q200 Qualified
- ISO 7637 Pulse 1-3 capability
- Meet 27.5Vdc Jump Start requirements
- Multi-strike capability
- Sub 1nS response to ESD strike

HOW TO ORDER

VC	AS	06	LC	18	X	500	R	P
Varistor Chip	Series AS = Automotive	Case Size 04 = 0402 06 = 0603 08 = 0805	Low Cap Design	Working Voltage 18 = 18.0VDC	Energy Rating A = 0.10 Joules V = 0.02 Joules X = 0.05 Joules	Clamping Voltage 150 = 18V 200 = 22V 300 = 32V 400 = 42V 500 = 50V	Packaging (PCS/REEL) D = 1,000 R = 4,000 T = 10,000 W = 0402 10000	Termination P = Ni/S



ELECTRIAL CHARACTERISTICS

AVX Part Number	Working Voltage (DC)	Working Voltage (AC)	Clamping Voltage	Test Current For V_c	Maximum Leakage Current	Transient Energy Rating	Peak Current Rating	Typical Cap	Case Size	Power Dissipation
VCAS04LC18V500	≤ 18.0	≤ 14.0	50	1	10	0.02	15	40	0402	0.0004
VCAS06LC18X500	≤ 18.0	≤ 14.0	50	1	10	0.05	30	50	0603	0.001
VCAS08LC18A500	≤ 18.0	≤ 14.0	50	1	10	0.10	30	80	0805	0.002

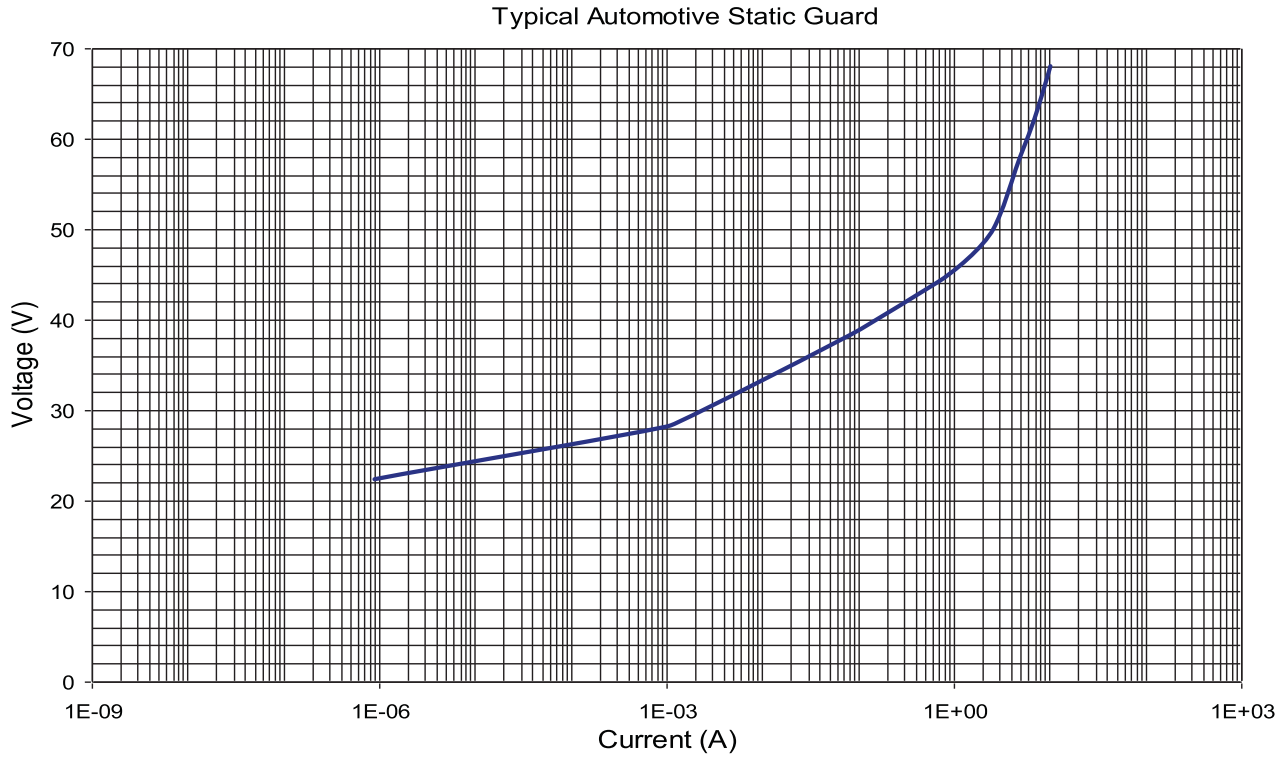
- V_w (DC) DC Working Voltage (V)
- V_w (AC) AC Working Voltage (V)
- V_c Clamping Voltage (V @ I_{vc})
- I_{vc} Test Current for V_c (A, $8 \times 20 \mu S$)
- I_L Maximum Leakage Current at the Working Voltage (μA)
- E_T Transient Energy Rating (J, $10 \times 1000 \mu S$)
- I_p Peak Current Rating (A, $8 \times 20 \mu S$)
- Cap Typical Capacitance (pF) @ frequency specified and $0.5 V_{RMS}$

StaticGuard Automotive Series

Multilayer Varistors for Automotive Applications

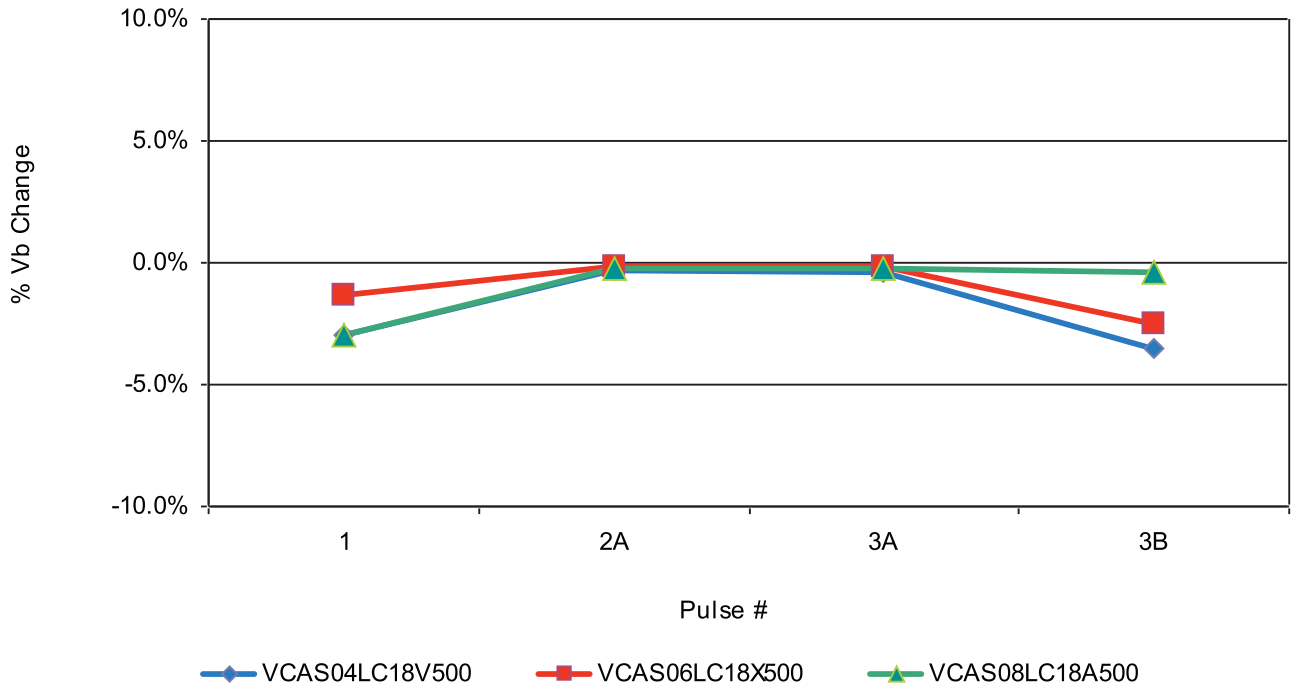


VOLTAGE/CURRENT CHARACTERISTICS



ELECTRICAL TRANSIENT CONDUCTION

ISO 7637 Pulse 1-3



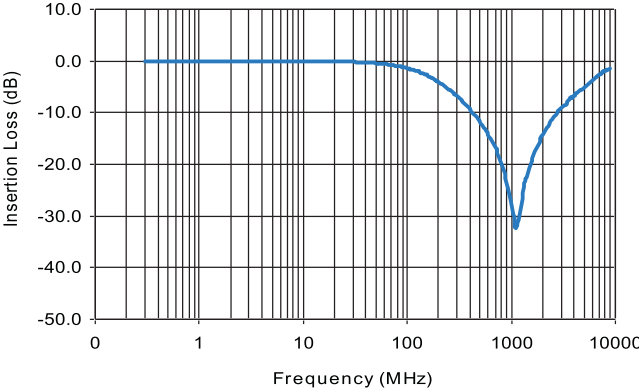
StaticGuard Automotive Series



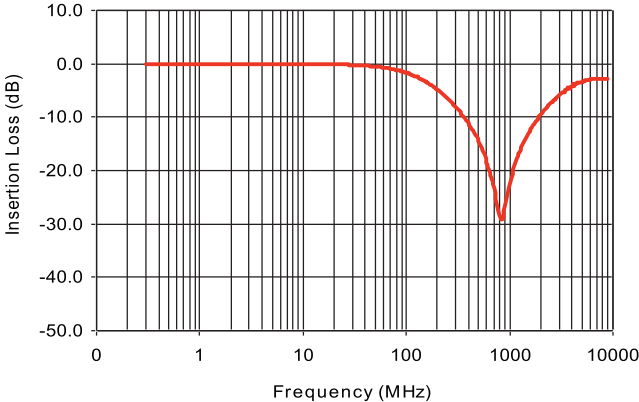
Multilayer Varistors for Automotive Applications

VOLTAGE/CURRENT CHARACTERISTICS

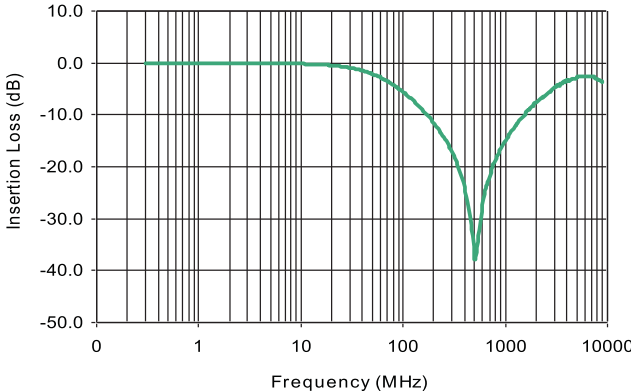
VCAS04LC18V500



VCAS06LC18X500



VCAS08LC18A500



MultiGuard (2 & 4 Elements)

AVX Multilayer Ceramic Transient Voltage Suppression Arrays – ESD Protection for CMOS and Bi Polar Systems



GENERAL DESCRIPTION AND COMMENTS

AVX's Transient Voltage Suppression (TVS) Arrays address six trends in today's electronic circuits: (1) mandatory ESD protection, (2) mandatory EMI control, (3) signal integrity improvement, (4) PCB downsizing, (5) reduced component placement costs, and (6) protection from induced slow speed transient voltages and currents.

AVX's MultiGuard products offer numerous advantages, which include a faster turn-on-time (<1nS), repetitive strike capability, and space savings. In some cases, MultiGuard consumes less than 75% of the PCB real estate required for the equivalent number of discrete chips. This size advantage, coupled with the savings associated with placing only one chip, makes MultiGuard the TVS component of choice for

ESD protection of I/O lines in portable equipment and programming ports in cellular phones. Other applications include differential data line protection, ASIC protection and LCD driver protection for portable computing devices.

Where multiple lines require the ESD protection, the 4-element 0612 chip is an ideal solution. The 2-element 0405 MultiGuard is the smallest TVS array device available in the market today.

Available with standard working voltage of 5.6V up to 18V with low capacitance in the 3 case sizes, AVX MultiGuard arrays offer a very broad range of integrated TVS solutions to the design community.



ELECTRICAL CHARACTERISTICS PER ELEMENT

	AVX Part Number	Working Voltage (DC)	Working Voltage (AC)	Breakdown Voltage	Clamping Voltage	Test Current For V_c	Maximum Leakage Current	Transient Energy Rating	Peak Current Rating	Typical Cap
2 Element 0405 Chip	MG042S05X150 __	5.6	4.0	8.5±20%	18	1	35	0.05	15	300
	MG042L14V400 __	14.0	10.0	18.5±12%	32	1	15	0.02	15	45
	MG042L18V500 __	18.0	14.0	N/A	50	1	10	0.02	15	40
2 Element 0508 Chip	MG052S05A150 __	5.6	4.0	8.5±20%	18	1	35	0.10	30	825
	MG052S09A200 __	9.0	6.4	12.7±15%	22	1	25	0.10	30	550
	MG052S14A300 __	14.0	10.0	19.5±12%	32	1	15	0.10	30	425
	MG052S18A400 __	18.0	14.0	25.5±10%	42	1	10	0.10	30	225
	MG052L18X500 __	≤18.0	≤14.0	N/A	50	1	10	0.10	20	50
4 Element 0612 Chip	MG064S05A150 __	5.6	4.0	8.5±20%	18	1	35	0.10	30	825
	MG064S09A200 __	9.0	6.4	12.7±15%	22	1	25	0.10	30	550
	MG064S14A300 __	14.0	10.0	19.5±12%	32	1	15	0.10	30	425
	MG064S18A400 __	18.0	14.0	25.5±10%	42	1	10	0.05	15	120
	MG064L18X500 __	≤18.0	≤14.0	N/A	50	1	10	0.10	20	75

Termination Finish Code
Packaging Code

V_w (DC) DC Working Voltage (V)
 V_w (AC) AC Working Voltage (V)
 V_B Typical Breakdown Voltage (V @ 1mA_{DC})
 V_B Tol V_B Tolerance is ± from Typical Value

V_c Clamping Voltage (V @ I_{c1})
 I_{c1} Test Current for V_c (A, 8x20μS)
 I_l Maximum Leakage Current at the Working Voltage (μA)
 E_T Transient Energy Rating (J, 10x1000μS)
 I_p Peak Current Rating (A, 8x20μS)
 Cap Typical Capacitance (pF) @ 1MHz and 0.5 V_{RMS}

MultiGuard (2&4 Elements)

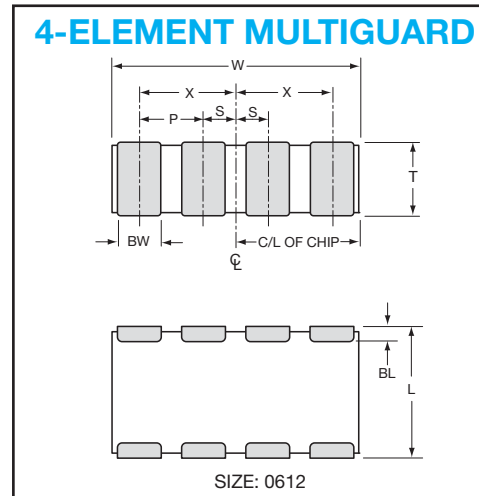
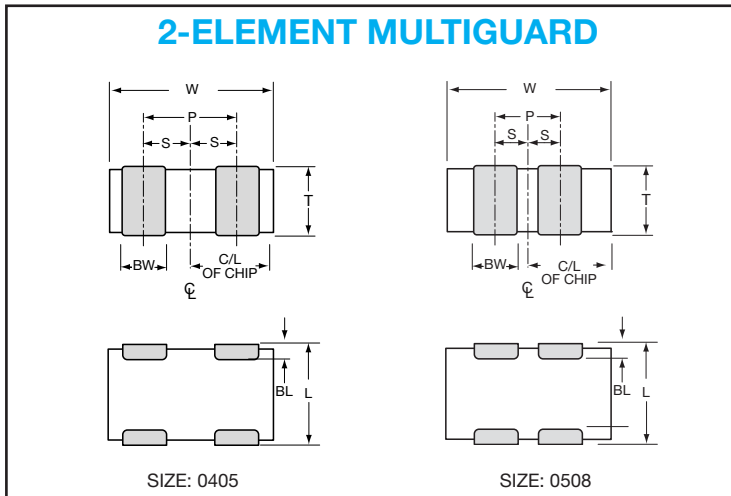


AVX Multilayer Ceramic

Transient Voltage Suppression Arrays

ESD Protection for CMOS and Bi Polar Systems

PHYSICAL DIMENSIONS AND PAD LAYOUT



0405 2 Element Dimensions mm (inches)

L	W	T	BW	BL	P	S
1.00±0.15 (0.039±0.006)	1.37±0.15 (0.054±0.006)	0.66 MAX (0.026 MAX)	0.36±0.10 (0.014±0.004)	0.20±0.10 (0.008±0.004)	064 REF (0.025 REF)	0.32±0.10 (0.013±0.004)

0612 4 Element Dimensions mm (inches)

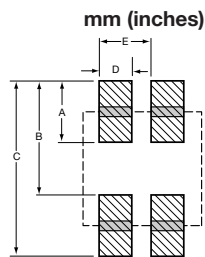
L	W	T	BW	BL	P	X	S
1.60±0.20 (0.063±0.008)	3.20±0.20 (0.126±0.008)	1.22 MAX (0.048 MAX)	0.41±0.10 (0.016±0.004)	0.18 ^{+0.25} _{-0.08} (0.007 ^{+0.08} _{-0.003})	0.76 REF (0.030 REF)	1.14±0.10 (0.045±0.004)	0.38±0.10 (0.015±0.004)

0508 2 Element Dimensions mm (inches)

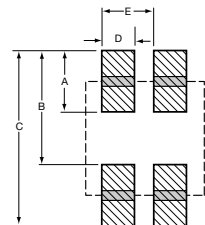
L	W	T	BW	BL	P	S
1.25±0.20 (0.049±0.008)	2.01±0.20 (0.079±0.008)	1.02 MAX (0.040 MAX)	0.41±0.1 (0.016±0.004)	0.18 ^{+0.25} _{-0.08} (0.007 ^{+0.010} _{-0.003})	0.76 REF (0.030 REF)	0.38±0.10 (0.015±0.004)

Pad Layout Dimensions

A	B	C	D	E
0405 2 Element				
0.46 (0.018)	0.74 (0.029)	1.20 (0.047)	0.38 (0.015)	0.64 (0.025)

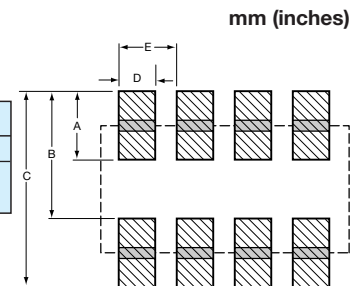


A	B	C	D	E
0508 2 Element				
0.89 (0.035)	1.27 (0.050)	2.16 (0.085)	0.46 (0.018)	0.76 (0.030)



Pad Layout Dimensions

A	B	C	D	E
0612 4 Element				
0.89 (0.035)	1.65 (0.065)	2.54 (0.100)	0.46 (0.018)	0.76 (0.030)



HOW TO ORDER

MG	04	2	L	14	A	300	T	P
MultiGuard	Case Size	Configuration	Style	Working Voltage	Energy Rating	Clamping Voltage	Packaging (PCS/REEL)	Termination Finish
	04 = 0405 05 = 0508 06 = 0612	2 = 2 Elements 4 = 4 Elements	S = Standard Construction L = Low Capacitance	05 = 5.6VDC 09 = 9.0VDC 14 = 14.0VDC 18 = 18.0VDC	A = 0.10 Joules V = 0.02 Joules X = 0.05 Joules	150 = 18V 200 = 22V 300 = 32V 400 = 42V 500 = 50V	D = 1,000 R = 4,000 T = 10,000	P = Ni/Sn Alloy (Plated)



MultiGuard (2 & 4 Elements)

AVX Multilayer Ceramic

Transient Voltage Suppression Arrays

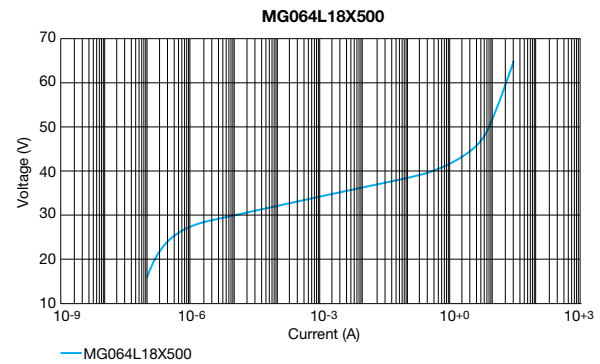
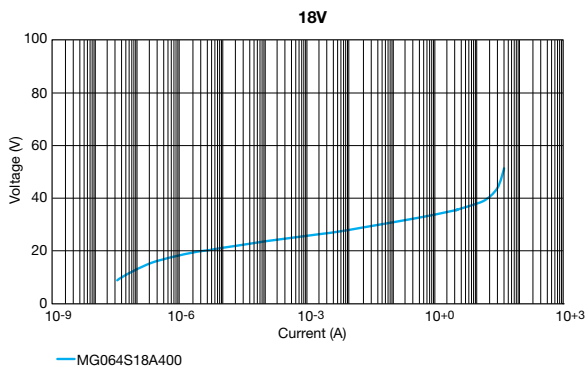
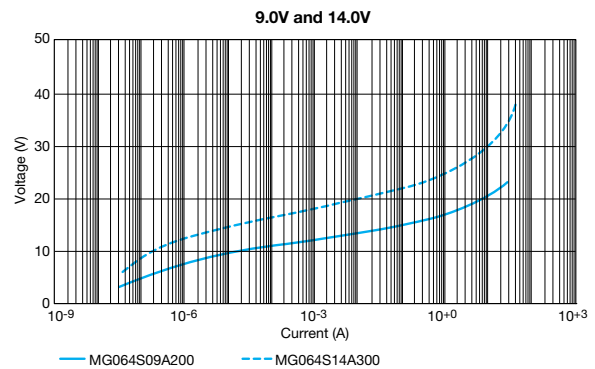
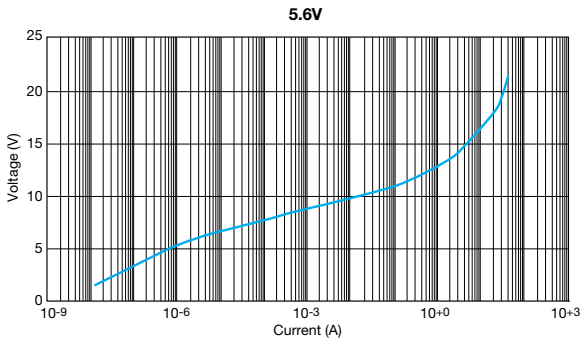
ESD Protection for CMOS and Bi Polar Systems



TYPICAL PERFORMANCE CURVES – VOLTAGE/CURRENT CHARACTERISTICS

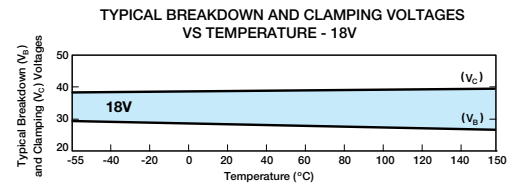
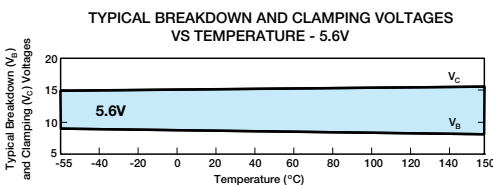
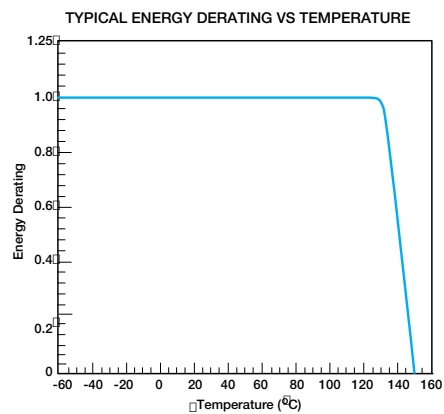
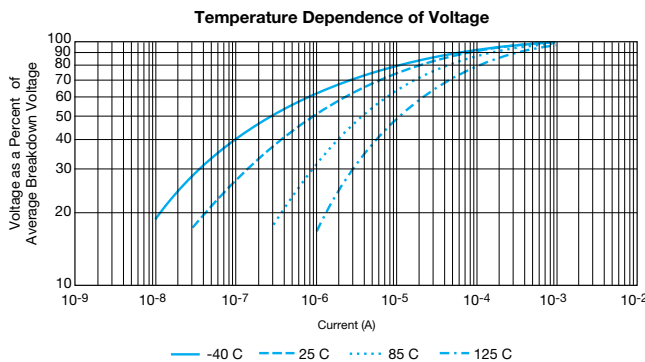
Multilayer construction and improved grain structure result in excellent transient clamping characteristics in excess of 30 amps (20 amps on MG064L18X500) peak current while maintaining very low leakage currents under DC operating

conditions. The VI curves below show the voltage/current characteristics for the 5.6V, 9V, 14V and 18V parts with currents ranging from fractions of a micro amp to tens of amps.



TYPICAL PERFORMANCE CURVES – TEMPERATURE CHARACTERISTICS

MultiGuard suppressors are designed to operate over the full temperature range from -55°C to +125°C.



MultiGuard (2 & 4 Elements)

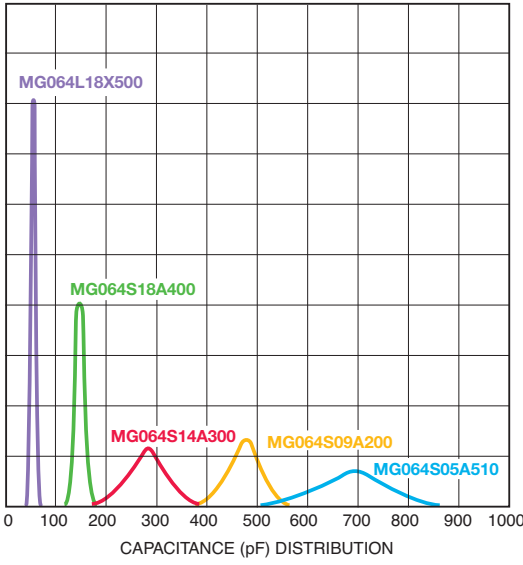
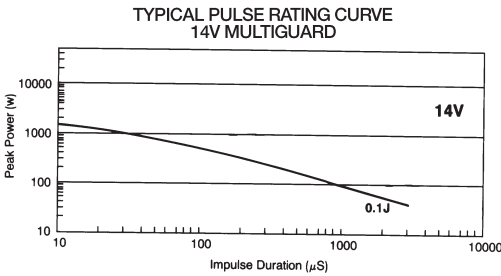
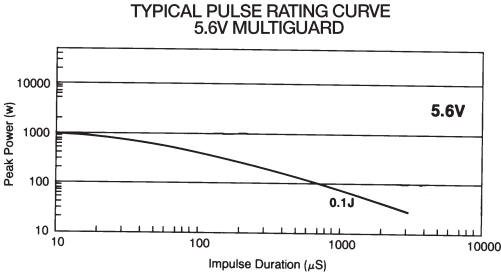
AVX Multilayer Ceramic

Transient Voltage Suppressors Arrays

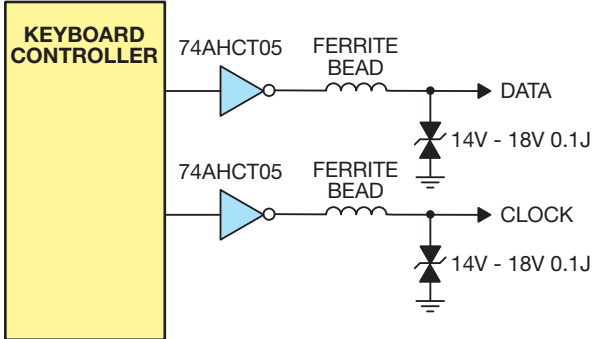
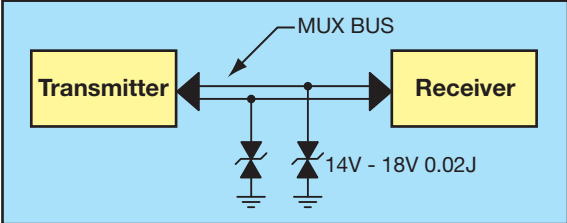
ESD Protection for CMOS and Bi Polar Systems



TRANSIENT VOLTAGE SUPPRESSORS – TYPICAL PERFORMANCE CURVES



APPLICATION



AntennaGuard 0402/0603



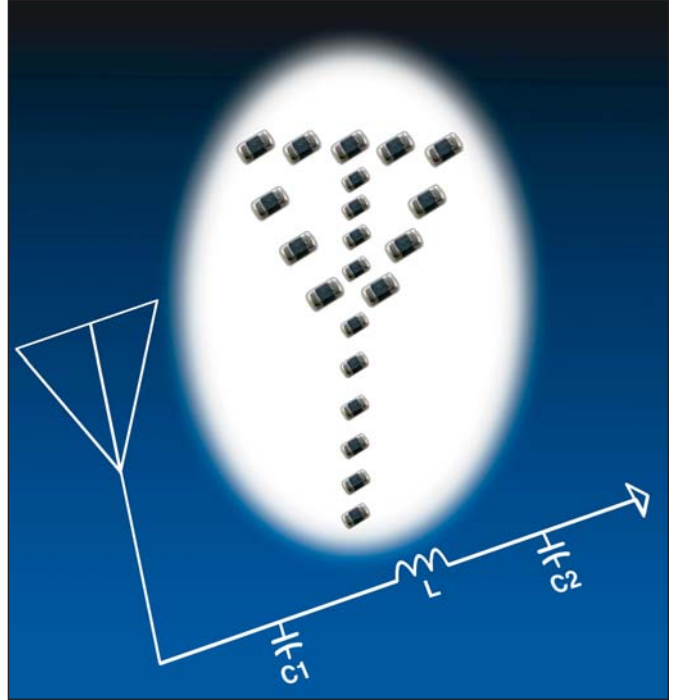
AVX Multilayer Ceramic Transient Voltage Suppressors ESD Protection for Antennas and Low Capacitor Loading Applications

GENERAL DESCRIPTION

RF antenna/RF amplifier protection against ESD events is a growing concern of RF circuit designers today, given the combination of increased signal “gain” demands, coupled with the required downsizing of the transistor package. The ability to achieve both objectives is tied to a reduced thickness of the SiO₂ gate insulator layer within the semiconductor. The corresponding result of such a change increases the Power Amplifier’s (PA’s) vulnerability to ESD strikes — a common event with handheld electronic products with RF transmitting and/or receiving features.

AVX’s 0402/0603 AntennaGuard products are an ultra-low capacitance extension of the proven TransGuard® TVS (transient voltage suppression) line of multilayer varistors. RF designers now have a single chip option over conventional protection methods (passive filters with diode clamps), which not only gives superior performance over traditional schemes, but also provides the added benefits of reduced PCB real estate and lower installation costs.

AVX’s AntennaGuard products are available in capacitance ratings of ≤3pF (0402 & 0603 chips) and ≤12pF (0603 chip). These low capacitance values have low insertion loss, as well as give other TransGuard® advantages such as small size, sub-nanosecond response time, low leakage currents and unsurpassed reliability (FIT Rate of 0.2) compared to diodes.



FEATURES

- Smallest TVS Component
- Standard EIA Chip Sizes
- Chip Placement Compatible
- Fastest Response Time to ESD Strikes
- Two Cap Values (≤3 and ≤12pF)

APPLICATION

- ESD Protection for RF Amplifiers
- Laser Drivers

HOW TO ORDER

VC	04	AG	18	3R0	Y	A	T	x	x
Varistor Chip	Chip Size 04 = 0402 06 = 0603	Varistor Series AntennaGuard	Working Voltage (DC)	Capacitance 3pF = 3R0 12pF = 120	Non-Std. Cap Tolerance (Maximum)	Not Applicable	Termination T = Ni/Sn Alloy (Plated)	Reel Size 1 = 7" 3 = 13" W = 7" (0402 only)	Reel Quantity A = 4,000 or 10,000 (i.e., 1A = 4,000 3A = 10,000) WA = 10,000



AntennaGuard 0402/0603



AVX Multilayer Ceramic Transient Voltage Suppressors ESD Protection for Antennas and Low Capacitor Loading Applications

ANTENNAGUARD CATALOG PART NUMBERS/ELECTRICAL VALUES

AVX Part Number	V _w (DC)	V _w (AC)	I _L	Cap	Case Size	Elements
VC04AG183R0YAT__	≤18	≤14	0.1	3	0402	1
VC06AG183R0YAT__	≤18	≤14	0.1	3	0603	1
VC06AG18120YAT__	≤18	≤14	0.1	12	0603	1

Termination Finish Code
Packaging Code

V_w (DC) DC Working Voltage (V)

V_w (AC) AC Working Voltage (V)

I_L Maximum Leakage Current at the Working Voltage (μA)

Cap Maximum Capacitance (pF) @ 1 MHz and 0.5 V_{rms}; VC06AG18120YAT capacitance tolerance: +4, -2pF

PHYSICAL DIMENSIONS

mm (inches)

	0402	0603
Length	1.0 (0.039) ±0.1 (0.004)	1.6 (0.063) ±0.15 (0.006)
Width	0.5 (0.020) ±0.1 (0.004)	0.8 (0.031) ±0.15 (0.006)
Thickness	0.6 Max. (0.024)	0.9 Max. (0.035)
Termination Band Width	0.25 (0.010) ±0.15 (0.006)	0.35 (0.014) ±0.15 (0.006)

AVX Multilayer Ceramic Transient Voltage Suppressors ESD Protection for Antennas and Low Capacitor Loading Applications

Antenna Varistors

AVX offers a series of 0402 and 0603 chip varistors, designated the AntennaGuard series, for RF antenna/RF amplifier protection. These devices offer ultra-low capacitance (<3pF in 0402 chips, and ≤3pF & ≤12pF in 0603 packages), as well as low insertion loss. Antenna varistors can replace output capacitors and provide ESD suppression in cell phones, pagers and wireless LANs.

It is very common to employ some form of a FET in many types of efficient/minature RF amplifiers. Typically, these RF transistors have nearly ideal input gate impedance and outstanding noise figures. However, FETs are very susceptible to ESD damage due to the very thin layer of SiO₂ uses as the gate insulator. The ultra-thin SiO₂ layer is required to improve the gain of the transistor. In other words, the upside of the performance enhancement becomes the downside of the transistors survival when subjected to an ESD event.

ESD damage to the RF Field Effect Transistors (FETs) is a

growing concern among RF designers due to the following trends: (1) RF amplifiers continue to shrink in size, and (2) FET gains figures continue to increase. Both trends relate to decreasing gate oxide thickness, which in turn, is directly proportional to increased ESD sensitivity. As miniaturization trends accelerate, the traditional methods to protect against ESD damage (i.e., PC board layout, passive filters, and diode clamps) are becoming less and less effective.

AVX's AntennaGuard varistor can be used to protect the FET and offer superior performance to the previously mentioned protection methods given above. The standard EIA 0603 chip size, and particularly the 0402 chip, offer designers an ESD protection solution consistent with today's downsizing trend in portable electronic products. Savings in component volume up to 86%, and PC board footprint savings up to 83% are realistic expectations. These percentages are based upon the following table and Figures 1A and 1B.

mm (inches)

Suppression Device	Pad Dimensions				
	D1	D2	D3	D4	D5
AVX 0402 TransGuard®	1.70 (0.067)	0.61 (0.024)	0.51 (0.020)	0.61 (0.024)	0.51 (0.020)
AVX 0603 TransGuard®	2.54 (0.100)	0.89 (0.035)	0.76 (0.030)	0.89 (0.035)	0.76 (0.030)
Competitor's SOT23 Diode	See Below				

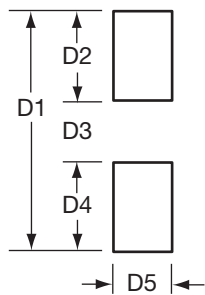


Figure 1A. 0402/0603
IR Solder Pad Layout

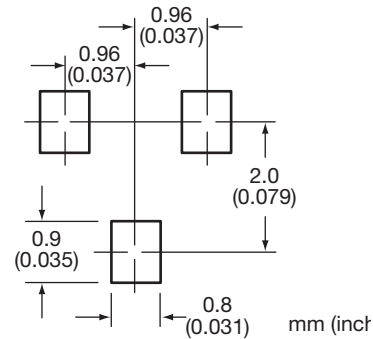


Figure 1B. SOT23- Solder Pad Layout

AntennaGuard 0402/0603



AVX Multilayer Ceramic Transient Voltage Suppressors ESD Protection for Antennas and Low Capacitor Loading Applications

Antenna varistors offer excellent ESD repetitive strike capability compared to a SOT23 diode when subjected to IEC 61000-4-2 8kV contact discharge. A performance summary is shown in Figure 2.

ESD TEST OF ANTENNAGUARD RATINGS

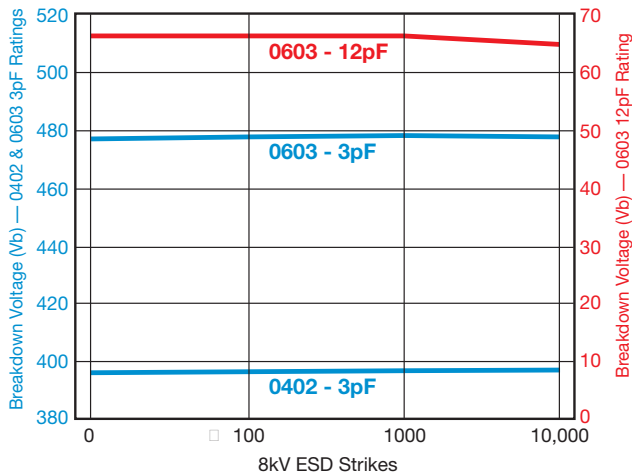


Figure 2. Repetitive 8kV ESD Strike

Antenna varistors also turn on and divert ESD overvoltages at a much faster rate than SOT23 devices (typically 300pS vs 1500pS - 5000pS). See Figure 3.

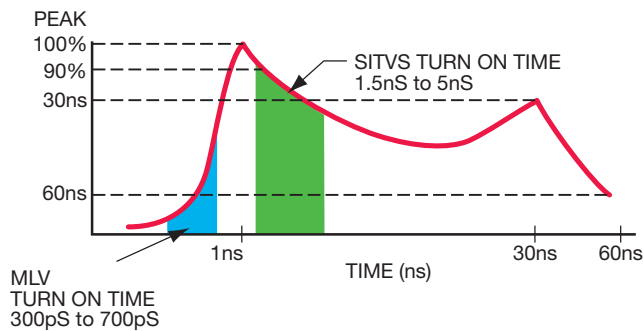


Figure 3. Turn On Time

The equivalent circuit model for a typical antenna varistor is shown in Figure 4.

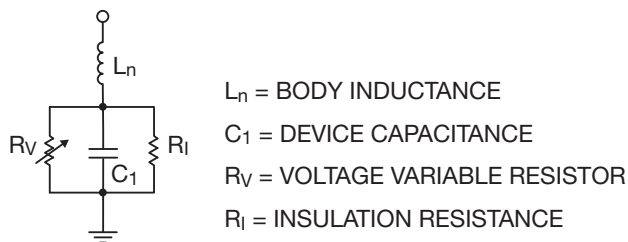


Figure 4. Antenna Varistor

The varistor shown exhibits a capacitance of $\leq 3\text{pF}$ which can be used to replace the parallel capacitance typically found prior to the antenna output of an RF amplifier. In the off state, the varistor acts as a capacitor and helps to filter RF output. The varistor is not affected by RF output power or voltage and has little insertion loss. See Figure 3.

ANTENNA VARISTOR S21

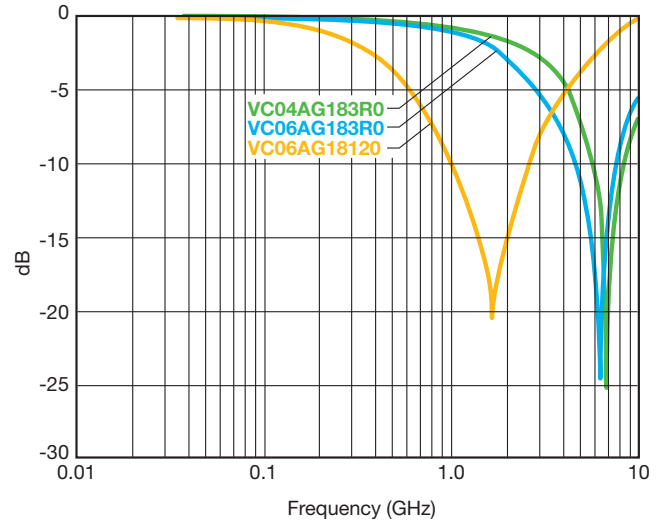


Figure 5. Antenna vs Frequency

Typical implementations of the antenna varistors are shown for use in cell phone, pager and wireless LAN applications in Figures 6A, 6B and 6C.

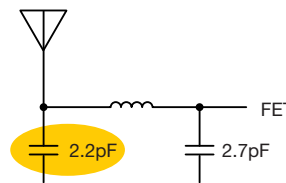


Figure 6A. Cell Phone

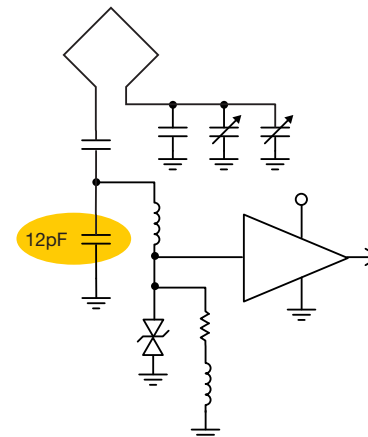


Figure 6B. Pager

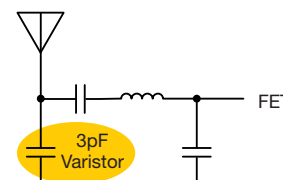


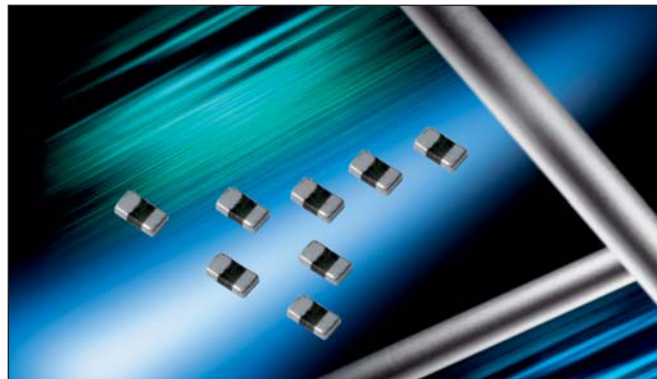
Figure 6C.

AVX Multilayer Ceramic Transient Voltage Suppressors ESD Protection for any Circuit Sensitive to Capacitance

GENERAL DESCRIPTION

AVX offers ultra-low capacitance ESD protection in the Sub 1pF range for use in circuits that are sensitive to capacitance. The Sub pF Varistor (SPV) is available in 0.8pF and 0.4pF capacitance values in a compact 0402 low profile package. SPV devices provide excellent response time to ESD strikes to protect sensitive circuits from over voltage conditions.

The development of new information processing technologies call for ever increasing digital system speeds. Higher speeds necessitate the use of ultra-low capacitance values in order to minimize signal distortion.



FEATURES

- High Reliability
- Capacitance <1pF
- Bi-Directional protection
- Fastest response time to ESD strikes
- Multi-strike capability
- Low insertion loss
- Low profile 0402 case size

APPLICATIONS

- Antennas
- Optics
- HDMI
- RF circuits
- FlexRay
- Portable devices
- Analog sensors
- Any circuit sensitive to capacitance

HOW TO ORDER

VC	H4	AG	10	OR8	M	A	T	W	A
Varistor Chip	Chip Size	Varistor Series	Working Voltage	Capacitance	Tolerance	N/A	Termination	Reel Size	Reel Quantity
	Thin 0402	AntennaGuard	10 = 10V 15 = 15V	OR8 = 0.8pF OR4 = 0.47pF	M = ±20%		T = Ni/Sn Alloy	W = 7"	A = 10k

ANTENNAGUARD CATALOG PART NUMBERS/ELECTRICAL VALUES

AVX Part Number	V _w (DC)	V _B	I _L	Cap	Cap Tolerance	3db Freq (MHz)	Case Size
VCH4AG100R8MA	≤10	125	<10 nA	0.8	±20%	5800	LP 0402
VCH4AG150R8MA	≤15	125	<10 nA	0.96 pF Max	Max	5800	LP 0402
VCH4AG150R4MA	≤15	135	<100 nA	0.47 pF Max	±20%	6700	LP 0402

V_w(DC) DC Working Voltage (V)

V_B Typical Breakdown Voltage (V @ 1mA_{DC})

I_L Typical leakage current at the working voltage

Cap Typical capacitance (pF) @ frequency specified and 0.5V_{RMS}

Freq Frequency at which capacitance is measured (M = 1MHz)

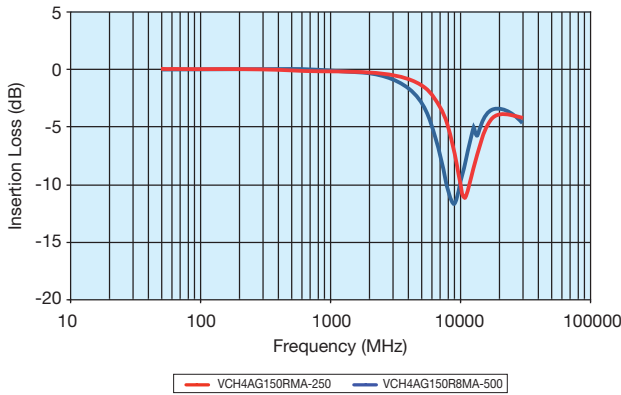


AntennaGuard/SPV

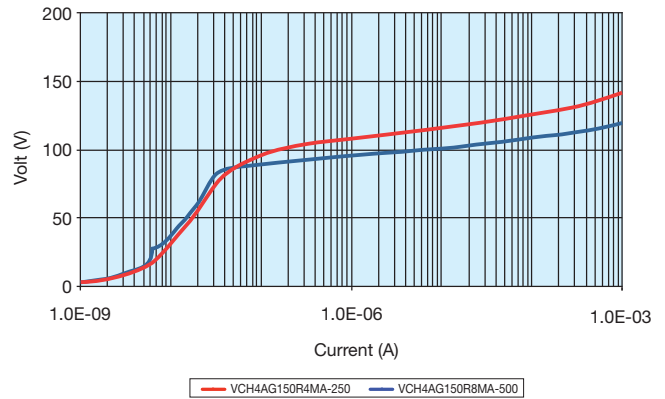


AVX Multilayer Ceramic Transient Voltage Suppressors ESD Protection for any Circuit Sensitive to Capacitance

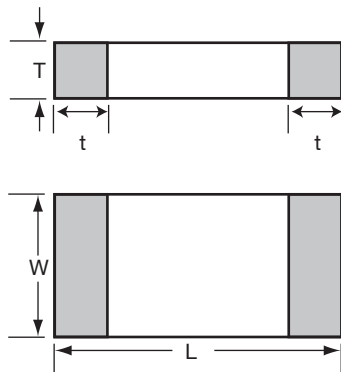
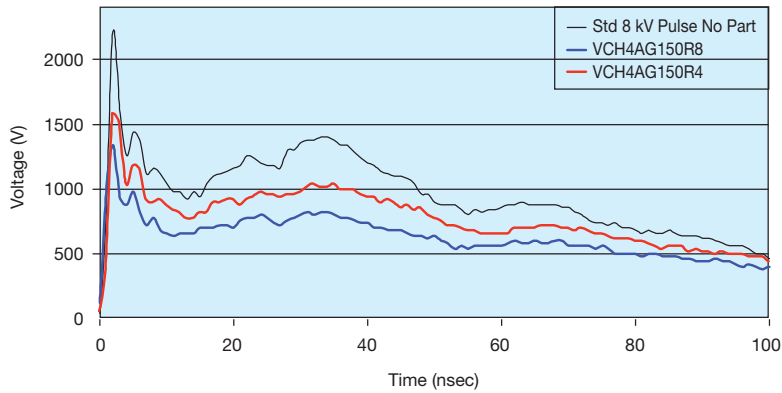
S21 Transmission Characteristics -SPV



V/I Curve - SPV



ESD Wave Absorption Characteristics



mm (inches)

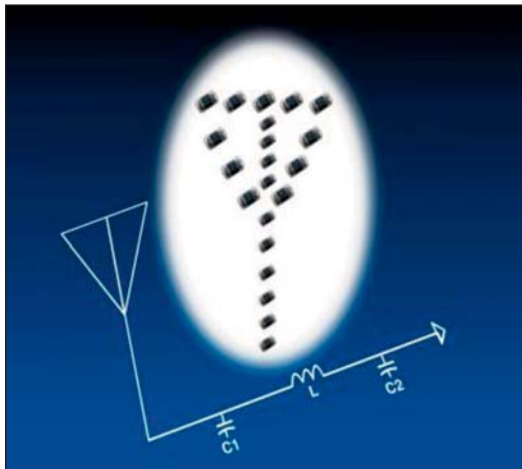
Size (EIA)	0402
Length (L)	1.00 ±0.10 (0.040 ± 0.004)
Width (W)	0.50 ±0.10 (0.020 ±0.004)
Max Thickness (T)	0.35 (0.014)
Terminal (t)	0.25±0.15 (0.010±0.006)



AntennaGuard Automotive Series



Multilayer Varistors for Automotive Applications



GENERAL DESCRIPTION

AVX 0402/0603 Automotive AntennaGuard products are an ultra low capacitance extension to the Automotive TransGuard® Series and are intended for use in RF and other capacitance sensitive circuits.

These low capacitance values have low insertion loss, low leakage current and unsurpassed reliability compared to diode options. These advantages combined with size advantages and bi-directional protection make the AntennaGuard the right choice for automotive applications including RF circuits, sensors, high-speed signal transmission lines, etc...

FEATURES

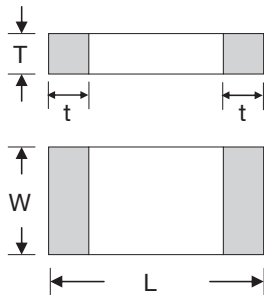
- AEC Q200 Qualified
- 25kV ESD rating
- Meet 27.5Vdc Jump Start requirements
- Multi-strike capability
- Sub 1nS response to ESD strike



HOW TO ORDER

VC Varistor Chip	AS Series AS = Automotive	06 Case Size 04 = 0402 06 = 0603 08 = 0805	AG Type	18 Working Voltage 18 = 18.0VDC	3R0 Capactance 3R0 = 3pF 120 = 12pF	Y Non-Std Cap Tol Y = Max	A Not Applicable	T Termination T = Ni/Sn Plated 1 = pd/Ag/Pt	R Reel T = Ni/Sn Plated 1 = pd/Ag/Pt	P Reel A = 4K or 10K
----------------------------	--	---	-------------------	--	---	--	----------------------------	---	--	-----------------------------------

PHYSICAL DIMENSIONS: mm (inches)



Size (EIA)	Length (L)	Width (W)	Max Thickness (T)	Land Length (t)
0402	1.00±0.10 (0.040±0.004)	0.50±0.10 (0.020±0.004)	0.60 (0.024)	0.25±0.15 (0.010±0.006)
0603	1.60±0.15 (0.063±0.006)	0.80±0.15 (0.031±0.006)	0.90 (0.035)	0.35±0.15 (0.014±0.006)

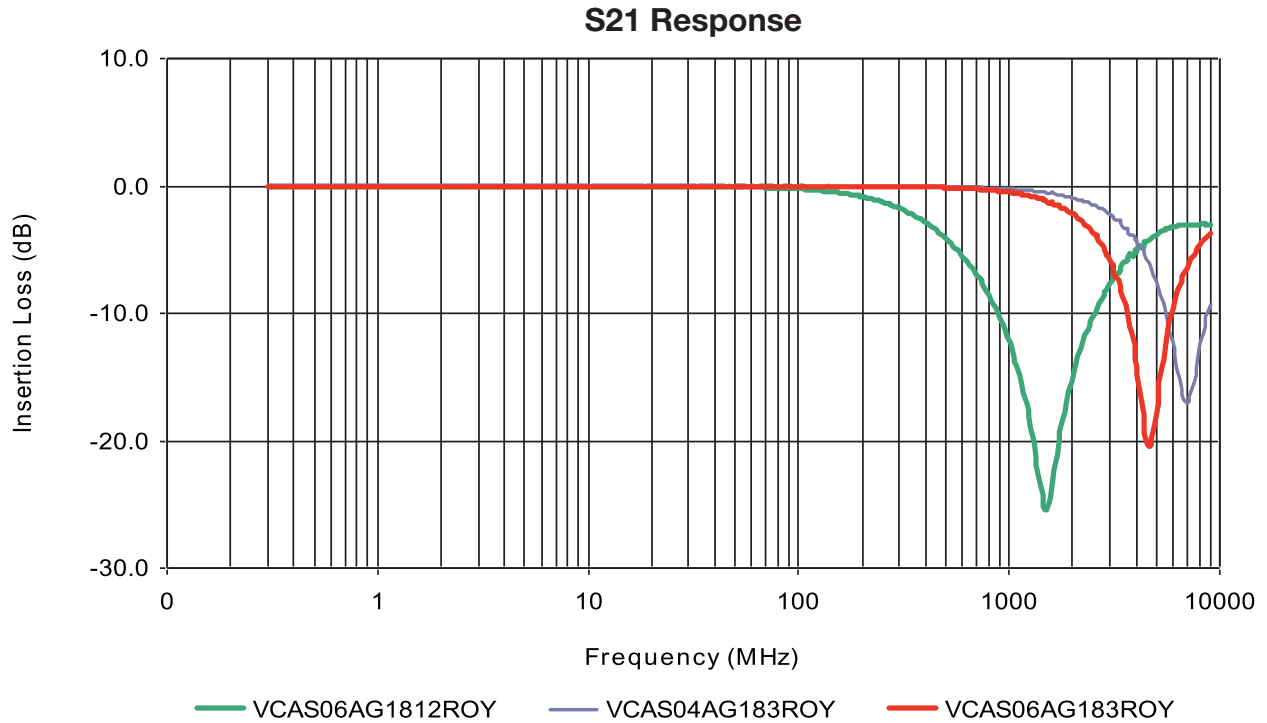
ELECTRIAL CHARACTERISTICS

AVX Part Number	Working Voltage (DC)	Working Voltage (AC)	Maximum Leakage Current	Cap	Case Size	Elements	Jump Start
VCAS04AG183R0Y	≤18.0	≤14.0	0.1	3 max	0402	1	27.5
VCAS06AG183R0Y	≤18.0	≤14.0	0.1	3 max	0603	1	27.5
VCAS06AG18120Y	≤18.0	≤14.0	0.1	12 ^{±2}	0603	1	27.5

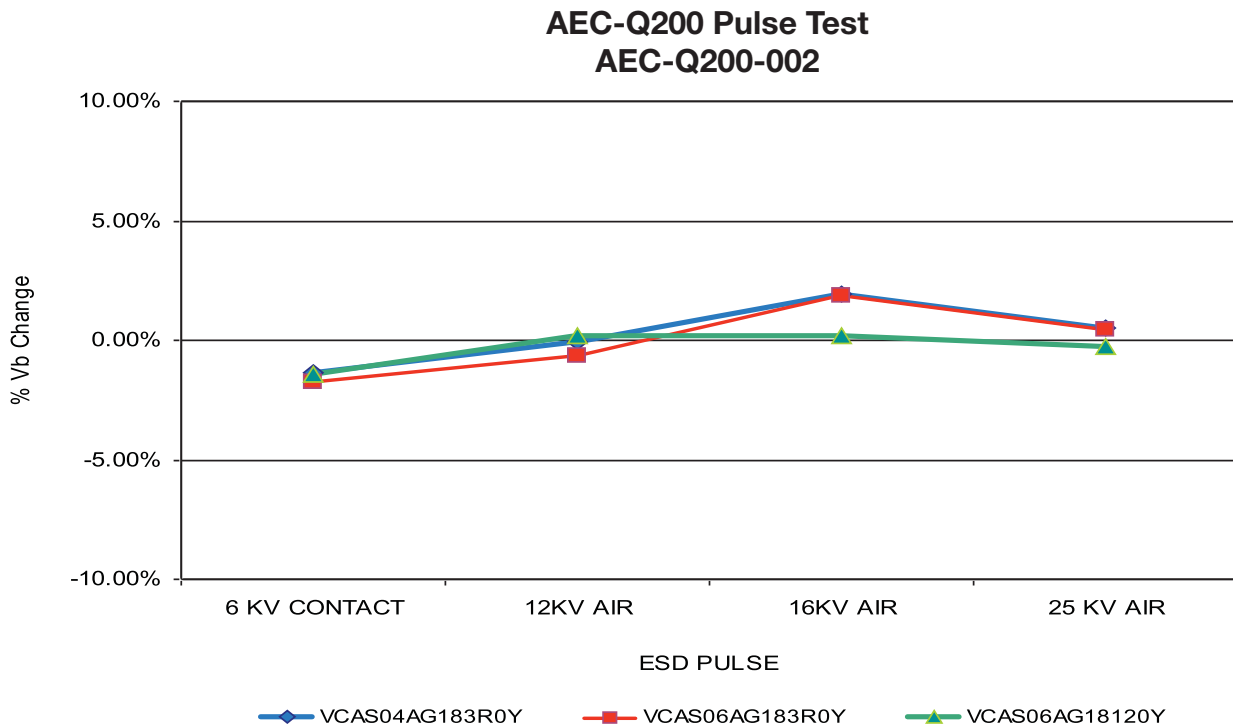
- V_w (DC) DC Working Voltage (V)
- V_w (AC) AC Working Voltage (V)
- I_L Maximum Leakage Current at the Working Voltage (μ A)
- Cap Capacitance (pF) @ frequency specified and $0.5 V_{RMS}$
- Jump Start Maximum Jump start voltage at 5 minutes



S21 TRANSMISSION CHARACTERISTICS



ESD CHARACTERISTICS

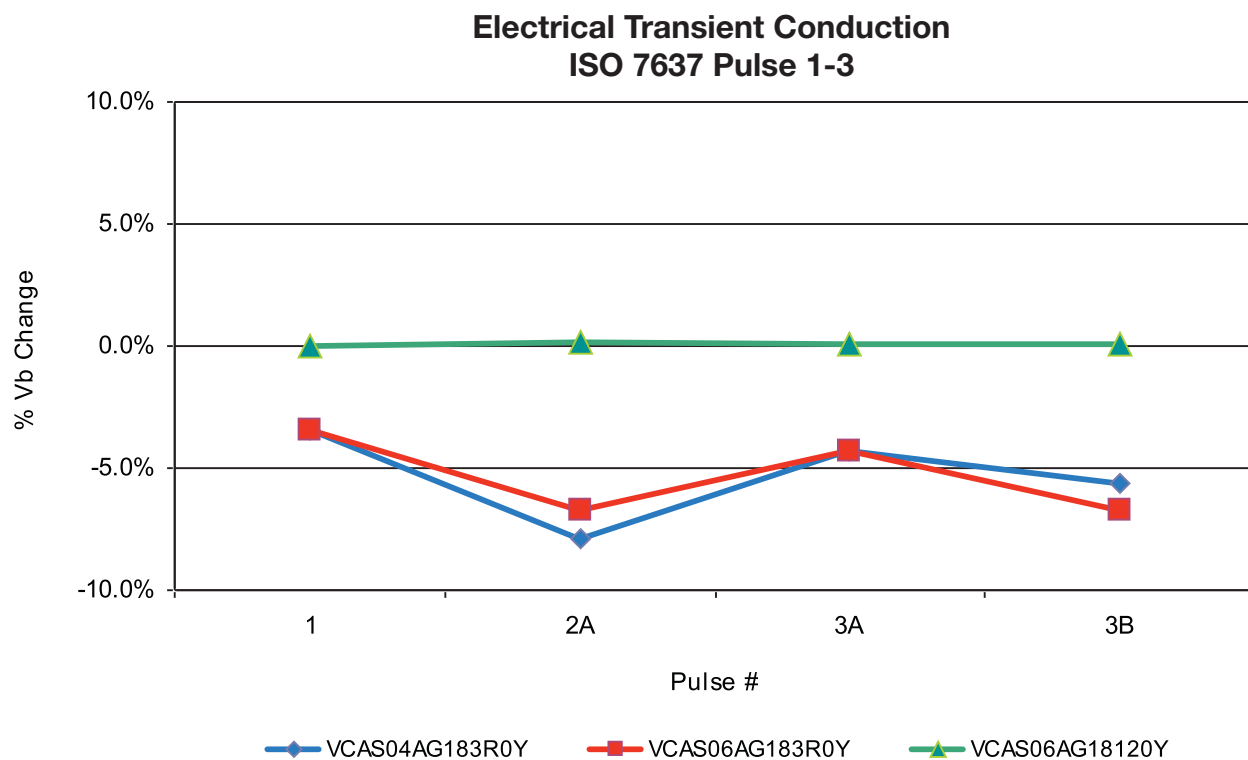


AntennaGuard Automotive Series



Multilayer Varistors for Automotive Applications

ELECTRICAL TRANSIENT CONDUCTION



USB Series Varistor

Multilayer Varistors for Universal Serial BUS Protection

GENERAL DESCRIPTION

USB Series varistors are designed to protect the high speed data lines against ESD transients. They have very low capacitance and fast turn on times that make this series ideal for data and transmission lines with high data rates. The unique design enables these devices to meet the rigorous testing criteria of the **IEC 61000-4-2** standards. New and improved manufacturing process has created these USB series to be one of the best plated varistors in the market today.

FEATURES

- Zinc Oxide (ZnO) based ceramic semiconductor devices with non-linear voltage-current characteristics
- Bi-directional device, similar to back-to-back Zener diodes plus an EMC capacitor in parallel
- Entire structure made up of conductive ZnO grains surrounded by electrically insulating barriers, creating varistor-like behavior
- Electrical advantages over Zener diodes are repetitive strike capability, high in rush current capability, fast turn-on-time and EMI attenuation
- Protects against ESD to meet **IEC 61000-4-2** 15kV (air) and 8kV (contact)
- Low capacitance for high speed data lines
- Available in discrete and array packages (2 and 4 element)
- Low Clamping Voltage
- Low Operating Voltage
- Response time is < 1ns

MECHANICAL CHARACTERISTICS

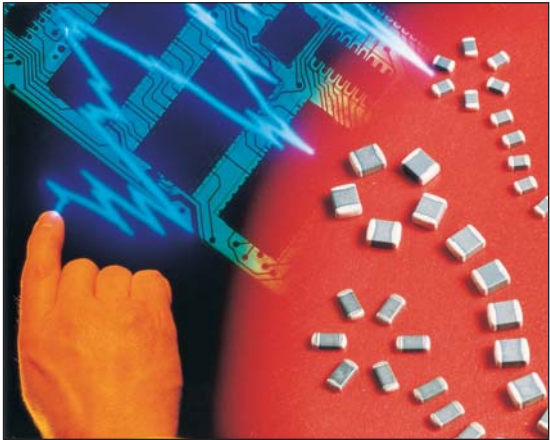
- Available in EIA 0603 (Single), 0405 (Dual) and 0612 (Quad) cases
- Plated Tin over Nickel Barrier
- Packaged in Tape & Reel

PART NUMBERING

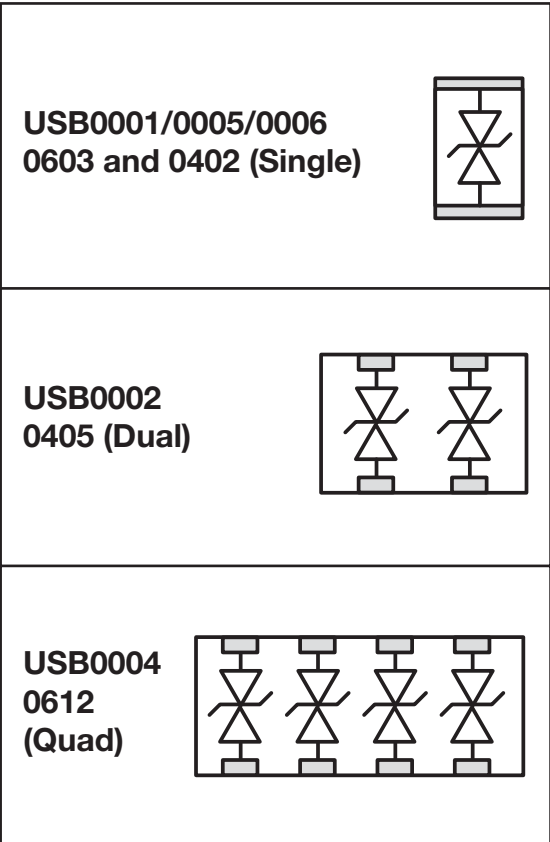
USB	0001	D	P
Style	Case Size	Packaging Code (Reel Size)	Termination
	0001 = 0603 (Single)	D = 7" (1,000 pcs.)	P = Ni/Sn Alloy (Plated)
	0002 = 0405 (2-Element)	R = 7" (4,000 pcs.)	
	0004 = 0612 (4-Element)	T = 13" (10,000 pcs.)	
	0005 = 0402 (Single)	W = 7" (10,000 pcs. 0402 only)	
	0006 = 0402 (Single)		

TYPICAL APPLICATIONS

- USB BUS Lines/Firewire Data BUS Lines
- I/O BUS Lines
- 10/100/1000 Ethernet Transmission Lines
- Video Card Data Lines
- Handheld Devices
- Laptop Computers
- LCD Monitors



PINOUT CONFIGURATION



USB Series Varistor



Multilayer Varistors for Universal Serial BUS Protection

RATINGS

Air Discharge ESD	15kV
Contact Discharge ESD	8kV
Operating Temperature	-55°C to +125°C
Soldering Temperature	230°C

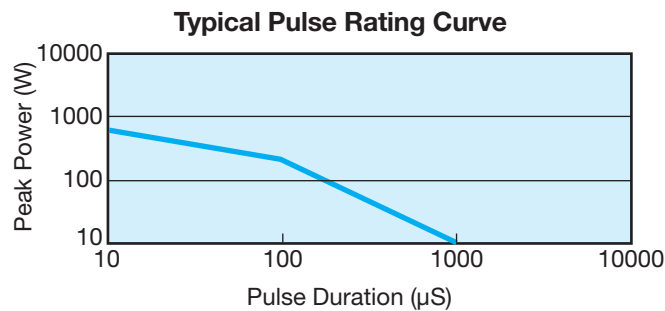
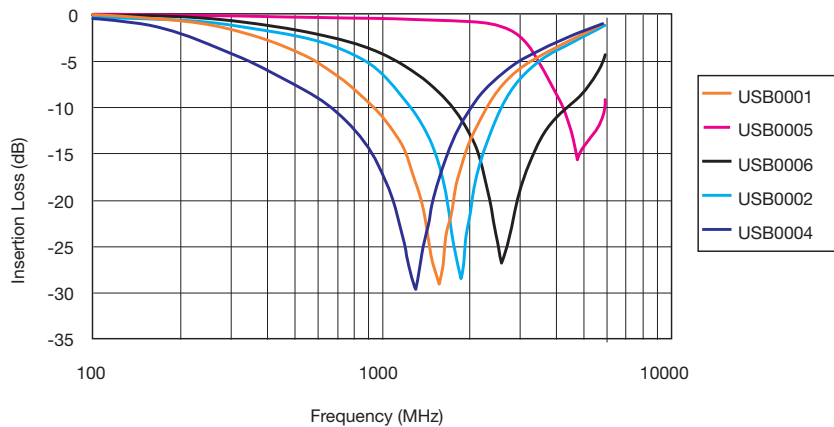
PERFORMANCE CHARACTERISTICS

AVX Part No.	V _W (DC)	V _W (AC)	V _B	I _L	E _T	I _p	Cap.	Case Size	Elements
USB0001__	≤18	≤14	120	2	0.015	4	10	0603	1
USB0002__	≤18	≤14	70	2	0.015	4	10	0405	2
USB0004__	≤18	≤14	100	2	0.015	4	10	0612	4
USB0005__	≤18	≤14	300	2	0.015	4	3	0402	1
USB0006__	≤18	≤14	65	2	0.015	4	6	0402	1

Termination Finish Code
Packaging Code

- V_W(DC) DC Working Voltage (V)
- V_W(AC) AC Working Voltage (V)
- V_B Typical Breakdown Voltage (V @ 1mA_{DC})
- I_L Maximum Leakage Current at the Working Voltage (μA)
- E_T Transient Energy Rating (J, 10x1000μS)
- I_p Peak Current Rating (A, 8x20μS)
- Cap Typical Capacitance (pF) @ 1 MHz and 0.5Vrms

USB TYPICAL S21 CHARACTERISTICS



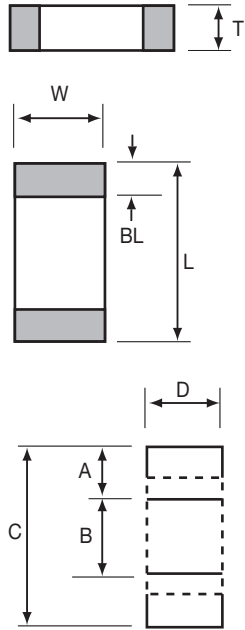
USB Series Varistor



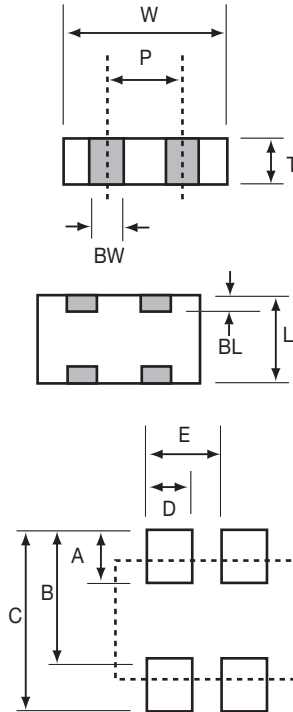
Multilayer Varistors for Universal Serial BUS Protection

PHYSICAL DIMENSIONS AND PAD LAYOUT

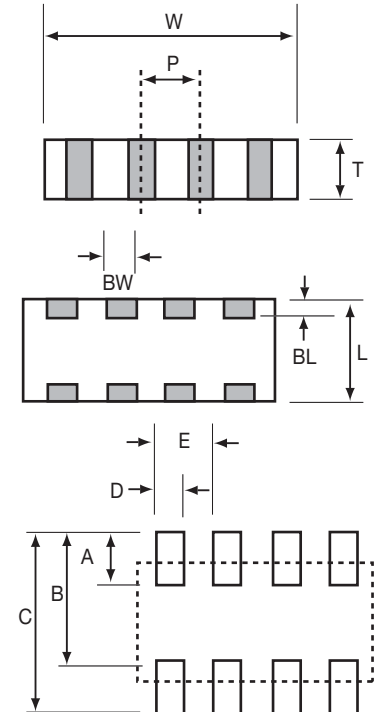
USB0001/5/6 (Single)



USB0002 (Dual)



USB0004 (Quad)



mm (inches)

L	W	T	BW	BL	P
USB0001					
1.60±0.15 (0.063±0.006)	0.80±0.15 (0.032±0.006)	0.90 Max (0.035 Max.)	N/A	0.35±0.15 (0.014±0.006)	N/A
USB0002					
1.00±0.15 (0.039±0.006)	1.37±0.15 (0.054±0.006)	0.66 Max (0.026 Max.)	0.36±0.10 (0.014±0.004)	0.20±0.10 (0.008±0.004)	0.64 REF (0.025 REF)
USB0004					
1.60±0.20 (0.063±0.008)	3.20±0.20 (0.126±0.008)	1.22 Max (0.048 Max.)	0.41±0.10 (0.016±0.004)	0.18 ^{+0.25/-0.08} (0.007 ^{+0.01/-0.003})	0.76 REF (0.030 REF)
USB0005 / USB0006					
1.0±0.10 (0.040±0.004)	0.50±0.10 (0.020±0.004)	0.60 Max (0.024 Max.)	N/A	0.25±0.15 (0.010±0.006)	N/A

mm (inches)

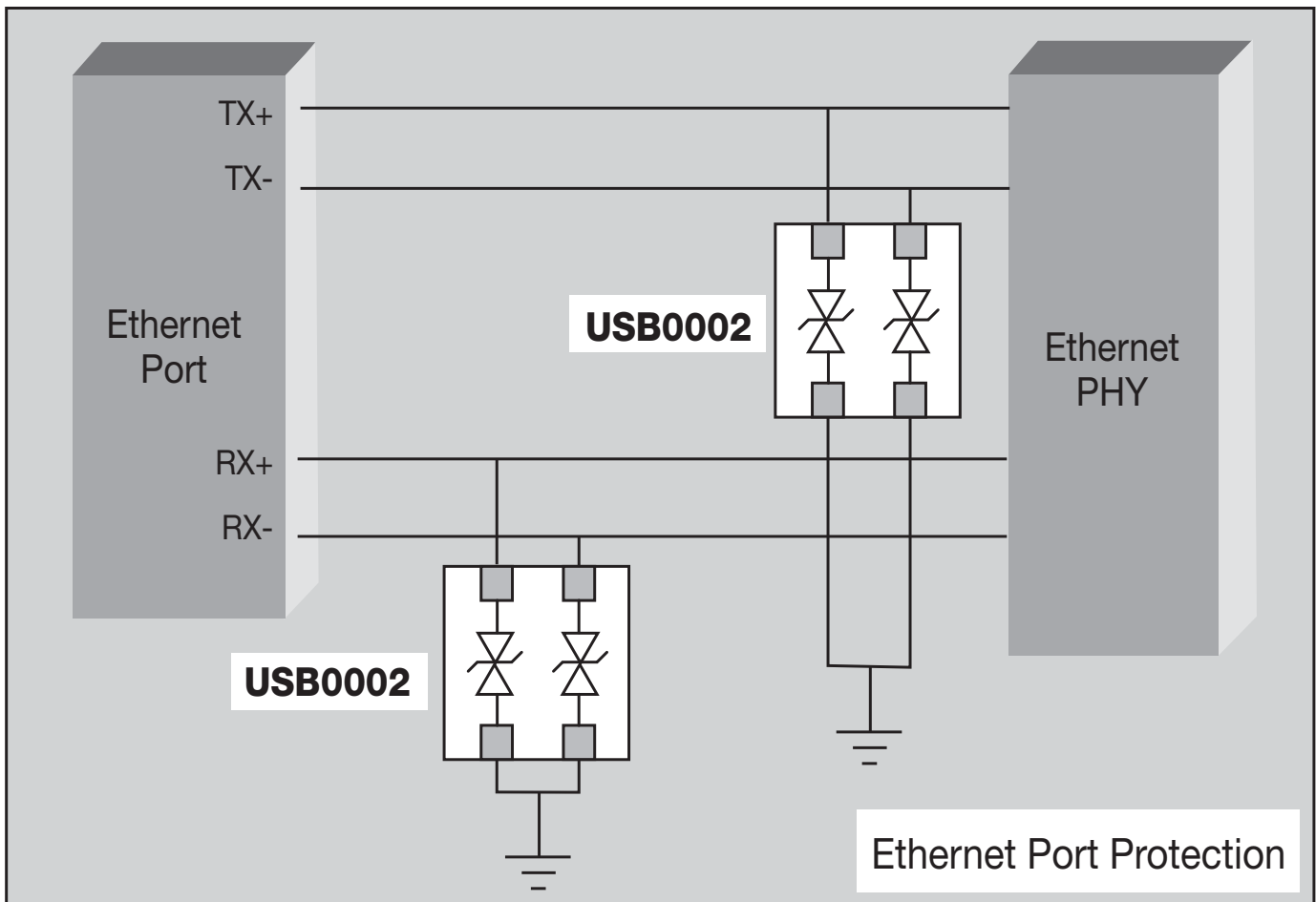
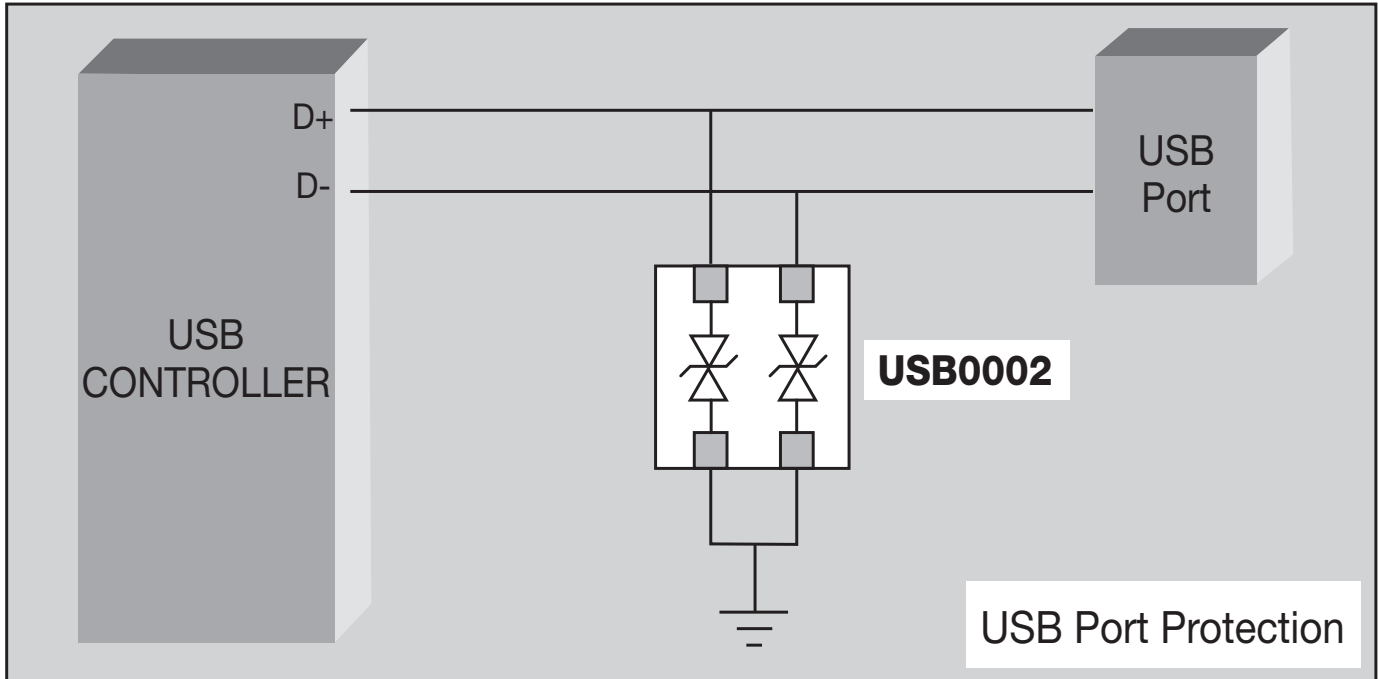
A	B	C	D	E
USB0001				
0.89 (0.035)	0.76 (0.030)	2.54 (0.100)	0.76 (0.030)	N/A
USB0002				
0.46 (0.018)	0.74 (0.029)	1.20 (0.047)	0.30 (0.012)	0.64 (0.025)
USB0004				
0.89 (0.035)	1.65 (0.065)	2.54 (0.100)	0.46 (0.018)	0.76 (0.030)
USB0005 / USB0006				
0.61 (0.024)	0.51 (0.020)	1.70 (0.067)	0.51 (0.020)	N/A

USB Series Varistor



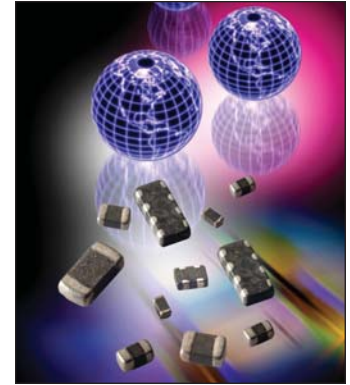
Multilayer Varistors for Universal Serial BUS Protection

APPLICATIONS



GENERAL DESCRIPTION

The CAN BUS and FlexRay varistor is a zinc oxide (ZnO) based ceramic semiconductor device with non-linear voltage-current characteristics (bi-directional) similar to back-to-back Zener diodes and an EMC capacitor in parallel (see equivalent circuit model). They have the added advantage of greater current and energy handling capabilities as well as EMI/RFI attenuation. Devices are fabricated by a ceramic sintering process that yields a structure of conductive ZnO grains surrounded by electrically insulating barriers, creating varistor like behavior.



HOW TO ORDER

CAN	0001	D	P	
Style	Case Size	Packaging Code (Reel Size)	Termination	
CAN = CAN BUS FLX = FlexRay	0001 = 0603 Discrete 0002 = 0405 2-Element 0004 = 0612 4-Element 0005 = 0402 Discrete	D = 7" reel (1,000 pcs.) R = 7" reel (4,000 pcs.) T = 13" reel (10,000 pcs.) W = 7" reel (10,000 pcs.) 0402 and 0201 only	P = Ni/Sn Alloy (Plated)	

PERFORM

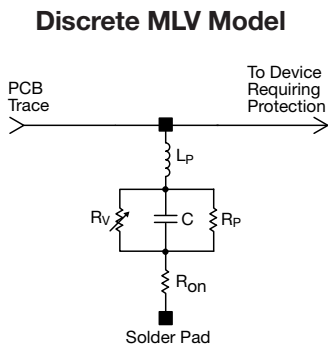
AVX PN	V _W (DC)	V _W (AC)	V _B	V _C	I _{VC}	I _L	E _T	I _P	Cap	Freq	V _{Jump}	P _{Diss Max}	Case	Elements
CAN0001 __	≤ 18	≤ 14	120	225	1	2	0.015	4	22 Max	M	27.5	0.003	0603	1
CAN0002 __	≤ 18	≤ 14	70	145	1	2	0.015	4	22 Max	M	27.5	0.003	0405	2
CAN0004 __	≤ 18	≤ 14	100	180	1	2	0.015	4	22 Max	M	27.5	0.003	0612	4
CAN0005 __	≤ 18	≤ 14	33	55	1	2	0.05	10	37 Max	M	27.5	0.01	0402	1
FLX0005 __	≤ 18	≤ 14	26	45	1	5	0.02	4	17 Max	M	27.5	0.004	0402	1

Termination Finish Code
Packaging Code

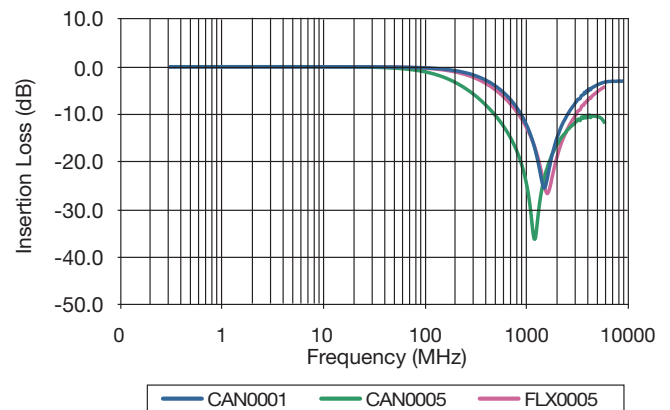
V_W(DC) DC Working Voltage (V)
 V_W(AC) AC Working Voltage (V)
 V_B Typical Breakdown Voltage (V @ 1mA_{DC})
 V_C Clamping Voltage (V @ I_{VC})
 I_{VC} Test Current for V_C (A, 8x20μS)

I_L Maximum Leakage Current at the Working Voltage (μA)
 E_T Transient Energy Rating (J, 10x1000μS)
 I_P Peak Current Rating (A, 8x20μS)
 Cap Maximum Capacitance (pF) @ 1 MHz and 0.5Vrms
 Temp Range -55°C to +125°C

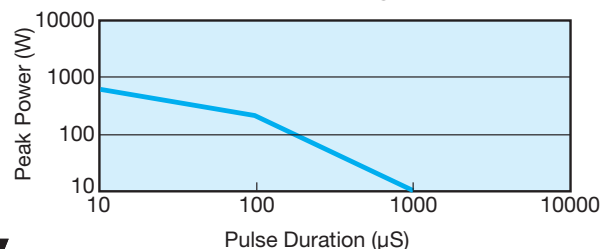
EQUIVALENT CIRCUIT MODEL



Where: R_v = Voltage Variable resistance (per VI curve)
 R_p ≥ 10¹² Ω
 C = defined by voltage rating and energy level
 R_{on} = turn on resistance
 L_p = parallel body inductance



Typical Pulse Rating Curve



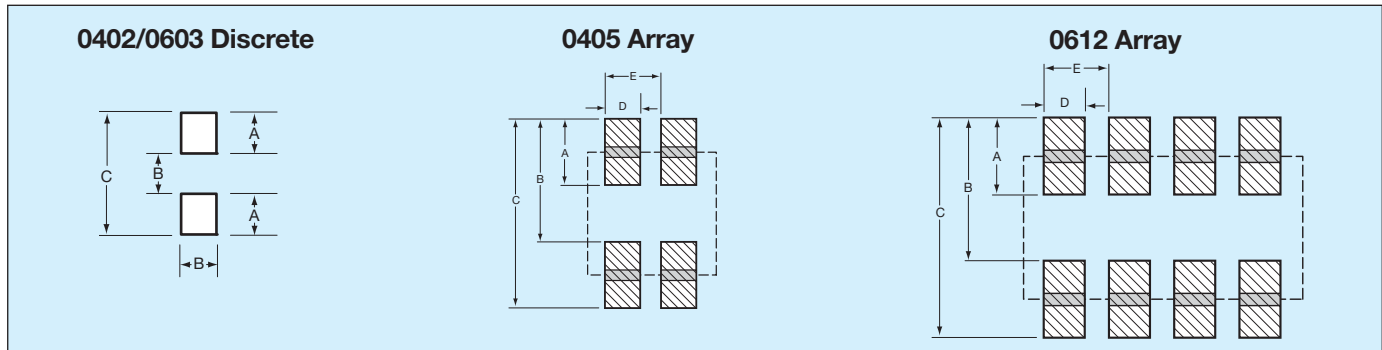
PHYSICAL DIMENSIONS

mm (inches)

	0402 Discrete	0603 Discrete	0405 Array	0612 Array
Length	1.00 ±0.10 (0.040 ±0.004)	1.60 ±0.15 (0.063 ±0.006)	1.00 ±0.15 (0.039 ±0.006)	1.60 ±0.20 (0.063 ±0.008)
Width	0.50 ±0.10 (0.020 ±0.004)	0.80 ±0.15 (0.032 ±0.006)	1.37 ±0.15 (0.054 ±0.006)	3.20 ±0.20 (0.126 ±0.008)
Thickness	0.60 Max. (0.024 Max.)	0.90 Max. (0.035 Max.)	0.66 Max. (0.026 Max.)	1.22 Max. (0.048 Max.)
Term Band Width	0.25 ±0.15 (0.010 ±0.006)	0.35 ±0.15 (0.014 ±0.006)	0.36 ±0.10 (0.014 ±0.004)	0.41 ±0.10 (0.016 ±0.010)

SOLDER PAD DIMENSIONS

mm (inches)

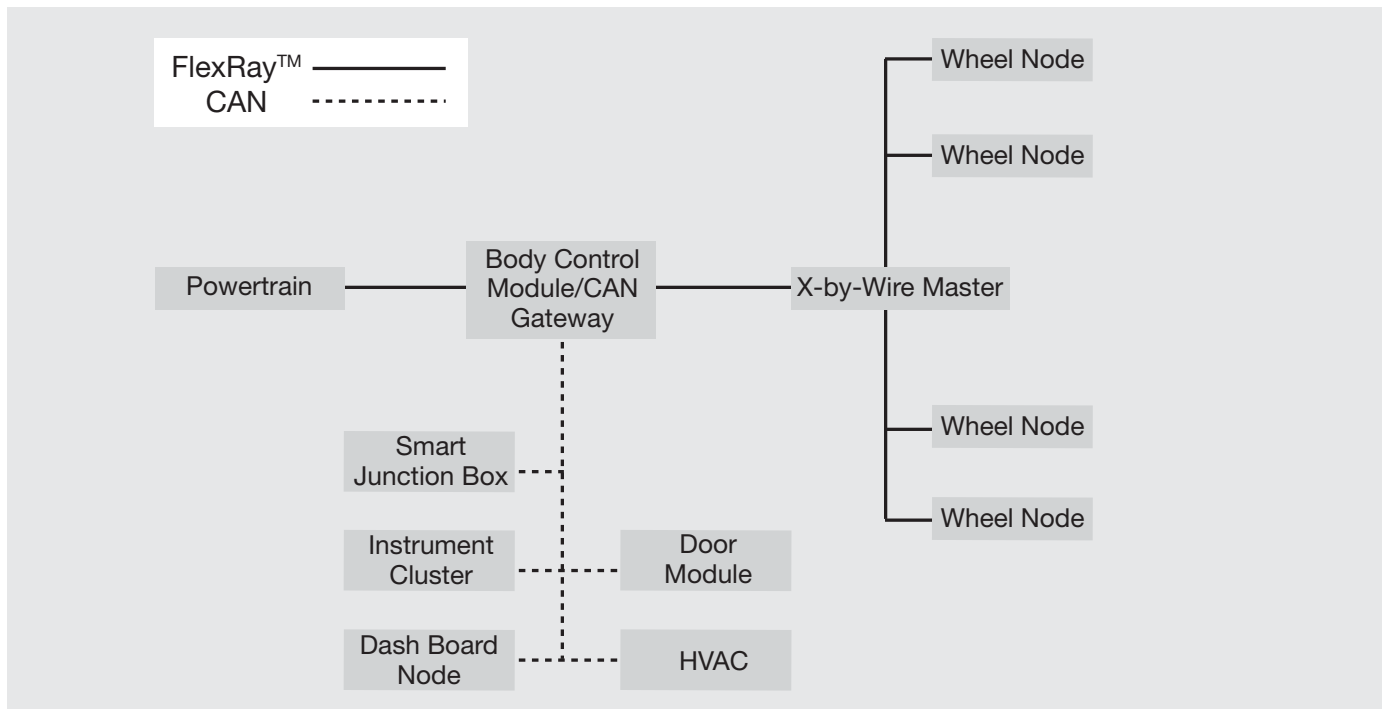
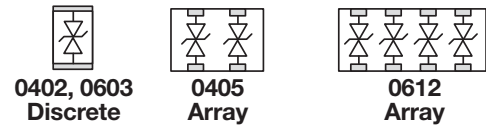


APPLICATION

AVX CAN BUS and FlexRay varistors offer significant advantages in general areas of a typical CAN or FlexRay network as shown on the right. Some of the advantages over diodes include:

- space savings
- higher ESD capability @ 25kV contact
- higher in rush current (4A) 8 x 20µS
- FIT rate ≤0.1 failures (per billion hours)

	A	B	C	D	E
0402 Discrete	0.61 (0.024)	0.51 (0.020)	1.70 (0.067)	-	-
0603 Discrete	0.89 (0.035)	0.76 (0.030)	2.54 (0.100)	-	-
0405 Array	0.46 (0.018)	0.74 (0.029)	0.12 (0.0047)	0.38 (0.015)	0.64 (0.025)
0612 Array	0.89 (0.035)	1.65 (0.065)	2.54 (0.100)	0.46 (0.018)	0.76 (0.030)



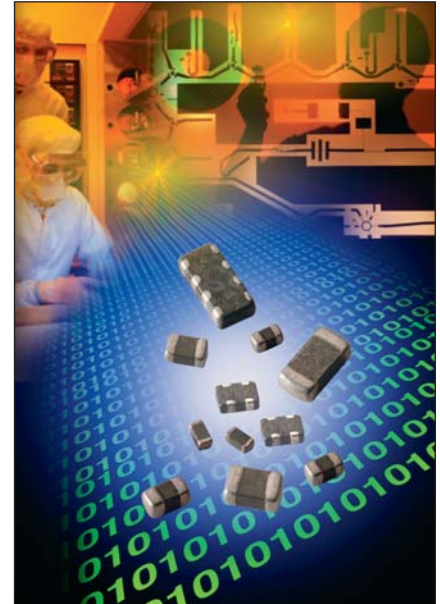
ESD Protection for Low Leakage Requirements

GENERAL DESCRIPTION

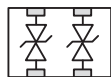
Faster semiconductor clock speeds and an increasing reliance on batteries as power sources have resulted in the need for varistors that exhibit very low leakage current. The UltraGuard (UG) Series of AVX Transient Voltage Suppressors address this problem.

The UG Series is the ideal transient protection solution for high clock speed integrated circuit application, battery-operated device, backlit display, medical/instrument application, low voltage power conversion circuits and power supervisory chip sets. In addition, UltraGuard's low leakage characteristics are also suitable for optic circuits like LDD, SerDes, and laser diodes.

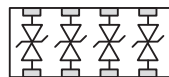
The UG Series is offered as discrete chips (0402, 0603, and 0805), 2-element packages (0405 and 0508), and 4-element packages (0612).



Discrete Chips
0402, 0603,
and 0805



2-Element Arrays
(0405 and 0508)



4-Element Arrays
(0612)

HOW TO ORDER

VC
VC=Surface
Mount Chip

UG
Series
UG = Low
Leakage
Series

04
Case Size
04 = 0402
06 = 0603
08 = 0805

0180
**Maximum
Working
Voltage**
0030 = 3.0V_{DC}
0050 = 5.0V_{DC}
0075 = 7.5V_{DC}
0100 = 10.0V_{DC}
0150 = 15.0V_{DC}
0180 = 18.0V_{DC}

L
Capacitance
L = Low
H = High

1
**No. of
Elements**

W
**Packaging
(pieces per
reel)**
D = 1,000
(7" reel)
R = 4,000
(7" reel)
T = 10,000
(13" reel)
W = 10,000
(7" reel,
0402 only)

P
**Termination
Finish**
P = Ni/Sn Alloy
(Plated)

HOW TO ORDER

MG
MG=Array

UG
Series
UG = Low
Leakage
Series

06
Case Size
04 = 0405
05 = 0508
06 = 0612

0150
**Maximum
Working
Voltage**
0030 = 3.0V_{DC}
0050 = 5.0V_{DC}
0075 = 7.5V_{DC}
0100 = 10.0V_{DC}
0150 = 15.0V_{DC}

L
Capacitance
L = Low
H = High

4
**No. of
Elements**
2 = 2 Elements
4 = 4 Elements

D
**Packaging
(pieces per
reel)**
D = 1,000
(7" reel)
R = 4,000
(7" reel)
T = 10,000
(13" reel)

P
**Termination
Finish**
P = Ni/Sn Alloy
(Plated)



ESD Protection for Low Leakage Requirements

AVX Part Number	V _w	V _w	V _B (Min)	V _C	I _{VC}	I _L	E _T	I _P	Cap	Freq	Case	Elements
MGUG040030L2 __	3.0	2.3	6.8	18	1	1	0.05	15	300	M	0405	2
MGUG050030L2 __	3.0	2.3	17.2	32	1	1	0.1	30	425	M	0508	2
MGUG060030L4 __	3.0	2.3	17.2	32	1	1	0.1	30	425	M	0612	4
VCUG040030L1 __	3.0	2.3	6.8	18	1	1	0.05	20	175	M	0402	1
VCUG060030L1 __	3.0	2.3	6.8	18	1	1	0.1	30	750	K	0603	1
VCUG080030H1 __	3.0	2.3	6.8	18	1	1	0.3	120	3000	K	0805	1
VCUG080030L1 __	3.0	2.3	6.8	18	1	1	0.1	40	1100	K	0805	1
VCUG120030H1 __	3.0	2.3	6.8	18	1	1	0.4	150	3000	K	1206	1
VCUG120030L1 __	3.0	2.3	6.8	18	1	1	0.1	40	1200	K	1206	1
MGUG040050L2 __	5.0	3.5	20	50	1	1	0.02	15	40	M	0405	2
MGUG050050L2 __	5.0	3.5	17.2	32	1	1	0.1	30	425	M	0508	2
MGUG060050L4 __	5.0	3.5	17.2	32	1	1	0.1	30	425	M	0612	4
VCUG040050L1 __	5.0	3.5	10.8	22	1	1	0.05	20	175	M	0402	1
VCUG060050L1 __	5.0	3.5	10.8	22	1	1	0.1	30	550	K	0603	1
VCUG080050L1 __	5.0	3.5	10.8	22	1	1	0.1	40	750	K	0805	1
VCUG120050H1 __	5.0	3.5	16.3	32	1	1	0.4	150	1050	K	1206	1
VCUG120050L1 __	5.0	3.5	16.3	32	1	1	0.1	40	600	K	1206	1
MGUG040075L2 __	7.5	5.3	20	50	1	1	0.02	15	40	M	0405	2
MGUG050075L2 __	7.5	5.3	17.2	32	1	1	0.1	30	425	M	0508	2
MGUG060075L4 __	7.5	5.3	17.2	32	1	1	0.1	30	425	M	0612	4
VCUG040075L1 __	7.5	5.3	16.3	32	1	1	0.05	20	85	M	0402	1
VCUG060075L1 __	7.5	5.3	16.3	32	1	1	0.1	30	350	K	0603	1
VCUG080075H1 __	7.5	5.3	16.3	32	1	1	0.3	120	900	K	0805	1
VCUG080075L1 __	7.5	5.3	16.3	32	1	1	0.1	40	325	K	0805	1
VCUG120075H1 __	7.5	5.3	16.3	32	1	1	0.4	150	1050	K	1206	1
VCUG120075L1 __	7.5	5.3	16.3	32	1	1	0.1	40	600	K	1206	1
MGUG040100L2 __	10	7.1	20	50	1	1	0.02	15	40	M	0405	2
MGUG050100L2 __	10	7.1	23	42	1	1	0.1	30	225	M	0508	2
MGUG060100L4 __	10	7.1	23	42	1	1	0.1	15	120	M	0612	4
VCUG040100L1 __	10	7.1	23	42	1	1	0.05	20	65	M	0402	1
VCUG060100L1 __	10	7.1	23	42	1	1	0.1	30	150	K	0603	1
VCUG080100H1 __	10	7.1	23	42	1	1	0.3	100	550	K	0805	1
VCUG080100L1 __	10	7.1	23	42	1	1	0.1	30	225	K	0805	1
VCUG120100H1 __	10	7.1	23	42	1	1	0.4	150	900	K	1206	1
VCUG120100L1 __	10	7.1	23	42	1	1	0.1	30	350	K	1206	1
MGUG040150L2 __	15	11	20	50	1	1	0.02	15	50	M	0405	2
MGUG050150L2 __	15	11	20	50	1	1	0.1	20	50	M	0508	2
MGUG060150L4 __	15	11	20	50	1	1	0.05	20	75	M	0612	4
VCUG040150L1 __	15	11	25	50	1	1	0.02	15	40	M	0402	1
VCUG060150L1 __	15	11	31.1	60	1	1	0.1	30	155	K	0603	1
VCUG080150H1 __	15	11	31.1	60	1	1	0.3	100	250	K	0805	1
VCUG080150L1 __	15	11	31.1	60	1	1	0.1	30	120	K	0805	1
VCUG120150H1 __	15	11	31.1	60	1	1	0.4	120	500	K	1206	1
VCUG040180L1 __	18	14	28	55	1	1	0.05	10	30	M	0402	1
VCUG080320L1 __	32	22	42.3	77	1	1	0.1	40	50	M	0805	1

└ Termination Finish Code
└ Packaging Code

- V_{CIR} (DC) DC Circuit Voltage (V)
- V_{CIR} (AC) AC Circuit Voltage (V)
- Cap Req Standard or Low
- I_L Maximum Leakage Current at the Circuit Voltage (μA)
- Cap Typical Capacitance (pF) @ frequency specified and 0.5 Vrms
- Freq Frequency at which capacitance is measured (K = 1kHz, M = 1MHz)

ESD Protection for Low Leakage Requirements

PHYSICAL DIMENSIONS

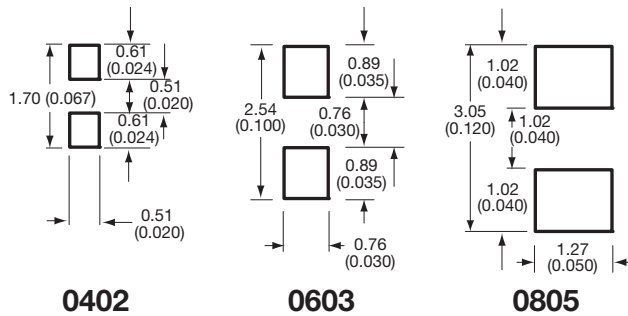
mm (inches)

	0402 Discrete	0603 Discrete	0805 Discrete
Length	1.00 ±0.10 (0.040 ±0.004)	1.60 ±0.15 (0.063 ±0.006)	2.01 ±0.20 (0.079 ±0.008)
Width	0.50 ±0.10 (0.020 ±0.004)	0.80 ±0.15 (0.032 ±0.006)	1.25 ±0.20 (0.049 ±0.008)
Thickness	0.60 Max. (0.024 Max.)	0.90 Max. (0.035 Max.)	1.02 Max. (0.040 Max.)
Term Band Width	0.25 ±0.15 (0.010 ±0.006)	0.35 ±0.15 (0.014 ±0.006)	0.71 Max. (0.028 Max.)

	0405 Array	0508 Array	0612 Array
Length	1.00 ±0.15 (0.039 ±0.006)	1.25 ±0.20 (0.049 ±0.008)	1.60 ±0.20 (0.063 ±0.008)
Width	1.37 ±0.15 (0.054 ±0.006)	2.01 ±0.20 (0.079 ±0.008)	3.20 ±0.20 (0.126 ±0.008)
Thickness	0.66 Max. (0.026 Max.)	1.02 Max. (0.040 Max.)	1.22 Max. (0.048 Max.)
Term Band Width	0.36 ±0.10 (0.014 ±0.004)	0.41 ±0.10 (0.016 ±0.004)	0.41 ±0.10 (0.016 ±0.004)

SOLDER PAD DIMENSIONS

mm (inches)

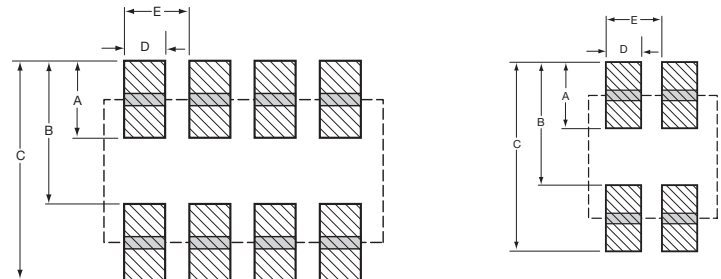


0612 4-Element Array

A	B	C	D	E
0.89 (0.035)	1.65 (0.065)	2.54 (0.100)	0.46 (0.018)	0.76 (0.030)

2-Element Arrays

	A	B	C	D	E
0405	0.46 (0.018)	0.74 (0.029)	1.20 (0.047)	0.38 (0.015)	0.64 (0.025)
0508	0.89 (0.035)	1.27 (0.050)	2.16 (0.085)	0.46 (0.018)	0.76 (0.030)



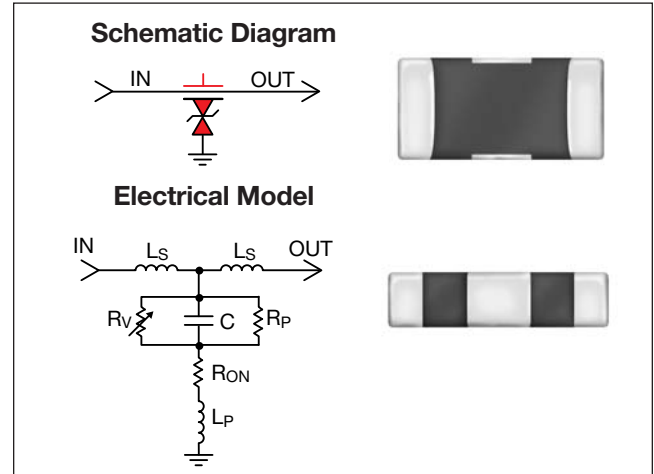
TransFeed

AVX Multilayer Ceramic Transient Voltage Suppressors TVS Protection and EMI Attenuation in a Single Chip

GENERAL DESCRIPTION

AVX has combined the best electrical characteristics of its TransGuard® Transient Voltage Suppressors (TVS) and its Feedthru Capacitors into a single chip for state-of-the-art overvoltage circuit protection and EMI reduction over a broad range of frequencies. This unique combination of multilayer ceramic construction in a feedthru configuration gives the circuit designer a single 0805 chip that responds to transient events faster than any TVS device on the market today, and provides significant EMI attenuation when in the off-state.

The reduction in parallel inductance, typical of the feedthru chip construction when compared to the construction of standard TVS or ceramic capacitor chips, gives the TransFeed product two very important electrical advantages: (1) faster “turn-on” time. Calculated response times of <200 pSec are not unusual with this device, and measured response times range from 200 – 250 pSec. The TransFeed “turn-on” characteristic is less than half that of an equivalent TransGuard® part — and TransGuards® clamp transient voltages faster than any other bipolar TVS solution such as diodes; (2) the second electrical advantage of lower parallel inductance, coupled with optimal series inductance, is the enhanced attenuation characteristics of the TransFeed product. Not only is there significantly greater attenuation at a higher self-resonance frequency, but the roll-off characteristic becomes much flatter, resulting in EMI filtering over a much broader frequency spectrum. Typical applications include filtering/protection on Microcontroller I/O Lines, Interface I/O Lines, Power Line Conditioning and Power Regulation.



TYPICAL APPLICATIONS

- Fingerprint ID Circuit
- Magnetic Field Circuit
- LCD Dashboard Driver

Where designers are concerned with both transient voltage protection and EMI attenuation, either due to the electrical performance of their circuits or due to required compliance to specific EMC regulations, the TransFeed product is an ideal choice.



HOW TO ORDER

V	2	F	1	05	A	150	Y	2	E	D	P
Varistor		Feedthru Capacitor		Voltage		Varistor Clamping Voltage		DC Resistance		Packaging Code	
	Chip Size		No. of Elements	05 = 5.6VDC 09 = 9.0VDC 14 = 14.0VDC 18 = 18.0VDC		150 = 18V 200 = 22V 300 = 32V 400 = 42V 500 = 50V		1 = 0.150 Ohms 2 = 0.200 Ohms 3 = 0.250 Ohms		Pcs./Reel	
	2 = 0805 3 = 0612				Energy Rating		Capacitance Tolerance		Feedthru Current		Termination Finish
					X = 0.05J A = 0.1J C = 0.3J		Y = +100/-50%		D = 500 mA E = 750 mA F = 1.0 Amp		P = Ni/Sn Alloy (Plated)

TransFeed

AVX Multilayer Ceramic Transient Voltage Suppressors TVS Protection and EMI Attenuation in a Single Chip



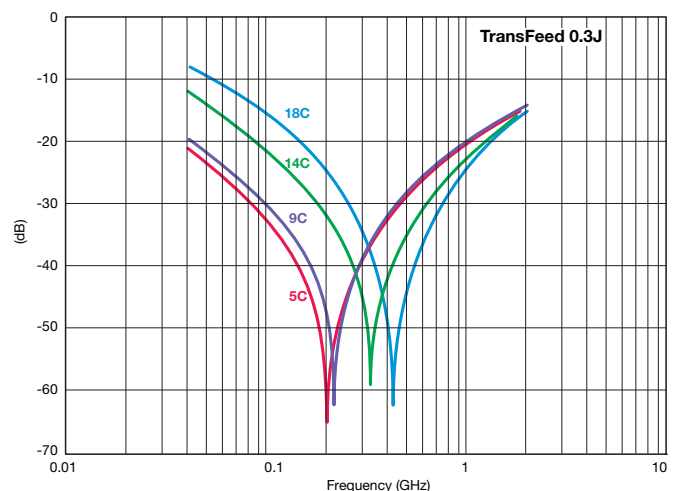
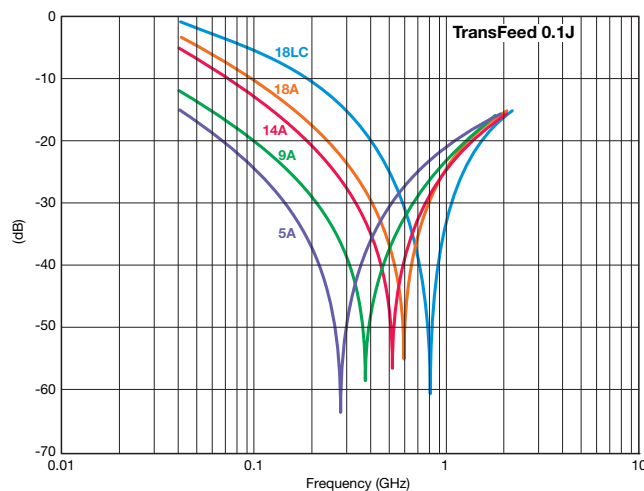
TRANSFEED ELECTRICAL SPECIFICATIONS

AVX Part Number	Working Voltage (DC)	Working Voltage (AC)	Breakdown Voltage	Clamping Voltage	Maximum Leakage Current	Transient Energy Rating	Peak Current Rating	Typical Cap	DC Resistance	Maximum Feedthru Current
V2F105A150Y2E__	5.6	4.0	8.5±20%	18	35	0.10	30	800	0.200	0.75
V2F105C150Y1F__	5.6	4.0	8.5±20%	18	35	0.30	120	2500	0.150	1.00
V2F109A200Y2E__	9.0	6.4	12.7±15%	22	25	0.10	30	575	0.200	0.75
V2F109C200Y1F__	9.0	6.4	12.7±15%	22	25	0.30	120	1800	0.150	1.00
V2F114A300Y2E__	14.0	10.0	18.5±12%	32	15	0.10	30	300	0.200	0.75
V2F114C300Y1F__	14.0	10.0	18.5±12%	32	15	0.30	120	900	0.150	1.00
V2F118A400Y2E__	18.0	13.0	25.5±10%	42	10	0.10	30	200	0.200	0.75
V2F118C400Y1F__	18.0	13.0	25.5±10%	42	10	0.30	120	500	0.150	1.00
V2F118X500Y3D__	18.0	13.0	25.5±10%	50	10	0.05	20	75	0.250	0.50
V3F418A400Y3G__	18.0	13.0	25.5±10%	42	10	0.10	20	150	0.200	0.30
V3F418X500Y3G__	18.0	13.0	25.5±10%	50	10	0.05	15	65	0.250	0.20

Termination Finish Code
Packaging Code

- V_w (DC) DC Working Voltage (V)
- V_w (AC) AC Working Voltage (V)
- V_B Typical Breakdown Voltage (V @ $1mA_{DC}$)
- V_B Tol V_B Tolerance is \pm from Typical Value
- V_C Clamping Voltage (V @ 1A $8 \times 20\mu S$)
- I_L Maximum Leakage Current at the Working Voltage (μA)
- E_T Transient Energy Rating (J, $10 \times 1000\mu S$)
- I_P Peak Current Rating (A, $8 \times 20\mu S$)
- Cap Typical Capacitance (pF) @ 1MHz and 0.5 V
- DCR DC Resistance (Ohms)
- I_{FT} Maximum Feedthru Current (A)

dB Attenuation vs Frequency



TransFeed

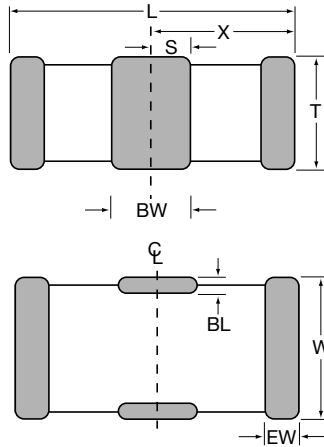
AVX Multilayer Ceramic Transient Voltage Suppressors TVS Protection and EMI Attenuation in a Single Chip



DIMENSIONS

mm (inches)

	L	W	T	BW	BL	EW	X	S
0805	2.01 ± 0.20 (0.079 ± 0.008)	1.25 ± 0.20 (0.049 ± 0.008)	1.143 Max. (0.045 Max.)	0.46 ± 0.10 (0.018 ± 0.004)	0.18 + 0.25 - 0.08 (0.007 + 0.010 - 0.003)	0.25 ± 0.13 (0.010 ± 0.005)	1.02 ± 0.10 (0.040 ± 0.004)	0.23 ± 0.05 (0.009 ± 0.002)

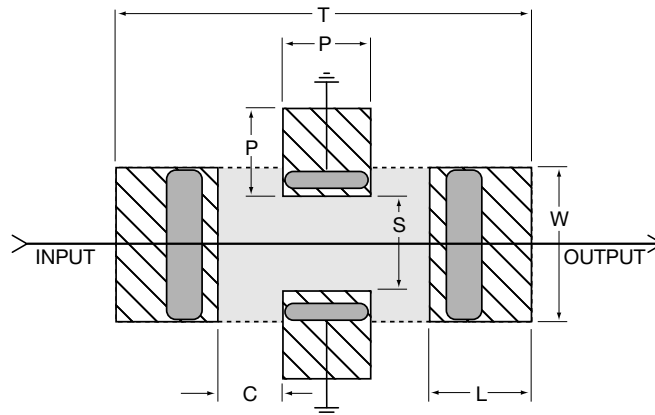


RECOMMENDED SOLDER PAD LAYOUT (Typical Dimensions)

mm (inches)

	T	P	S	W	L	C
0805	3.45 (0.136)	0.51 (0.020)	0.76 (0.030)	1.27 (0.050)	1.02 (0.040)	0.46 (0.018)

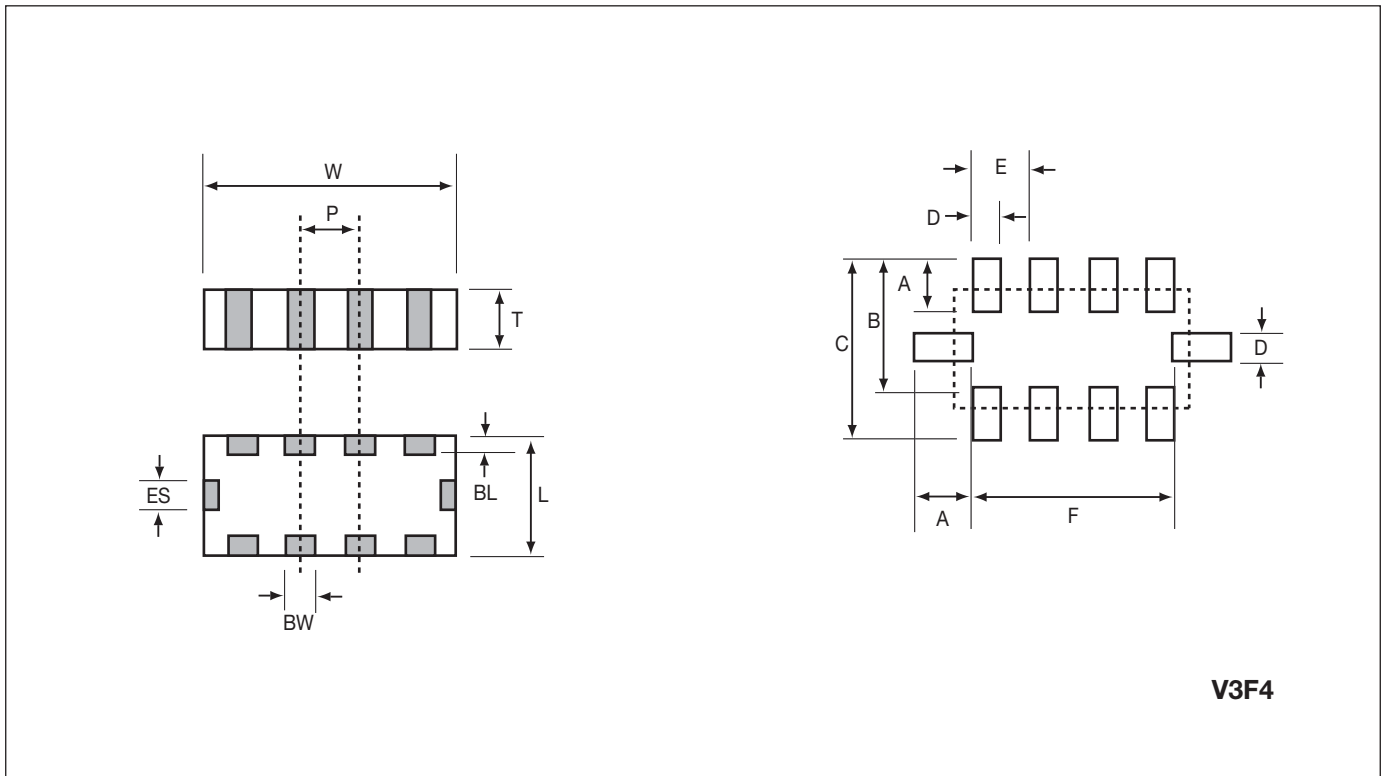
4 Pad Layout



TransFeed Array - V3F4 Series



TVS Protection and EMI Attenuation in a 4-Element Array



V3F4

DIMENSIONS

mm (inches)

L	W	T	BW	BL	ES	P
1.60 ± 0.20 (0.063 ± 0.008)	3.25 ± 0.15 (0.128 ± 0.006)	1.22 Max. (0.048 Max.)	0.41 ± 0.10 (0.016 ± 0.004)	0.18 +0.25 -0.08 (0.007 +0.010 -0.003)	0.41 ± 0.10 (0.016 ± 0.004)	0.76 REF (0.030 REF)

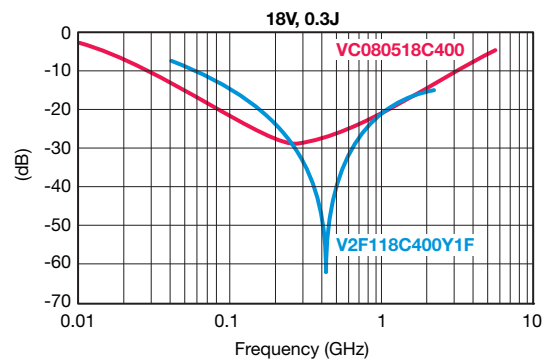
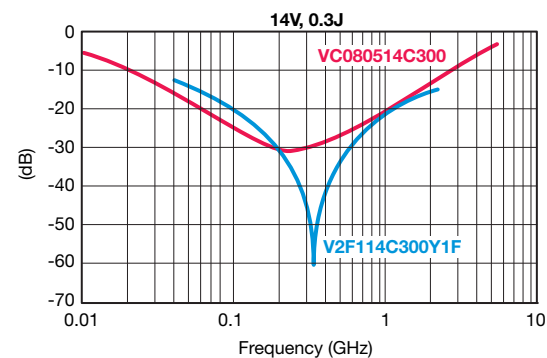
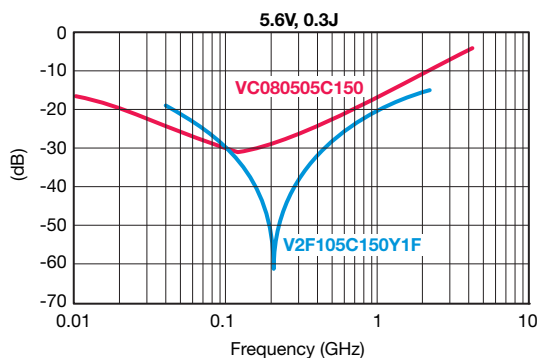
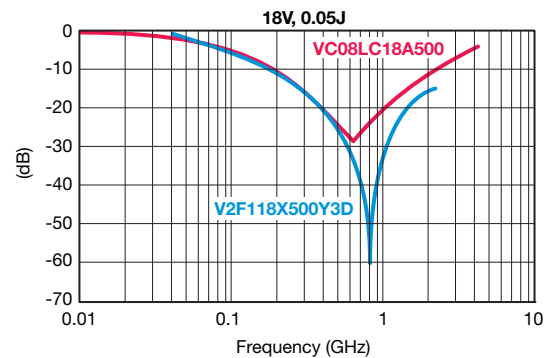
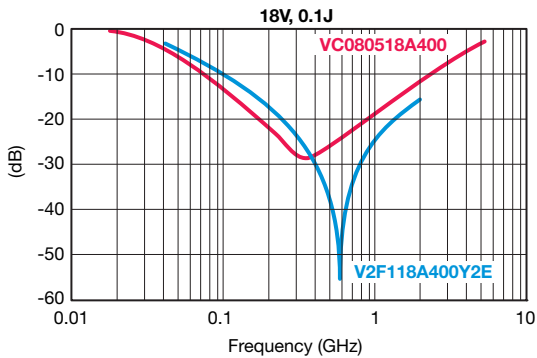
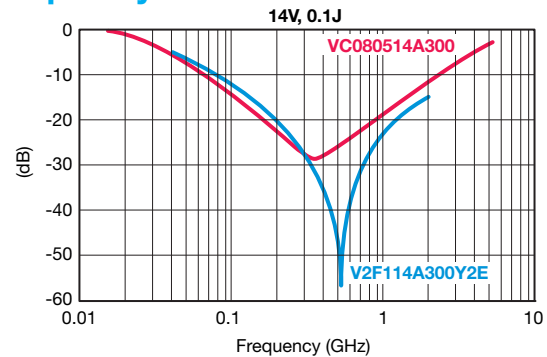
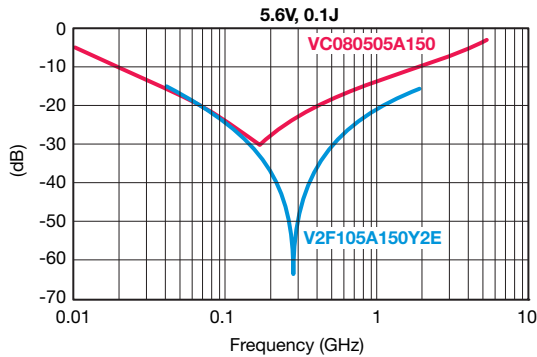
mm (inches)

A	B	C	D	E	F
0.60 (0.024)	1.60 (0.064)	2.20 (0.088)	0.35 (0.014)	0.76 (0.030)	2.60 (0.104)

PERFORMANCE CHARACTERISTICS

INSERTION LOSS COMPARISON (TransFeed vs TransGuard®)

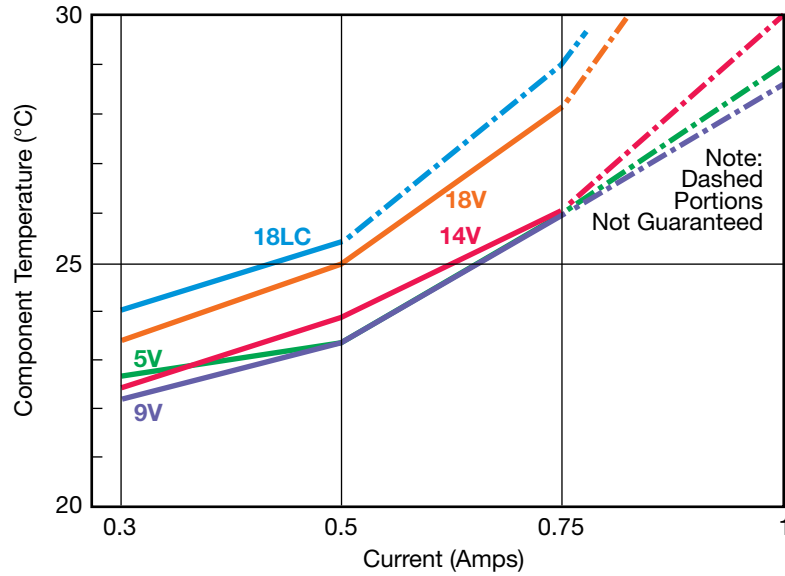
0805 – dB vs Frequency



PERFORMANCE CHARACTERISTICS

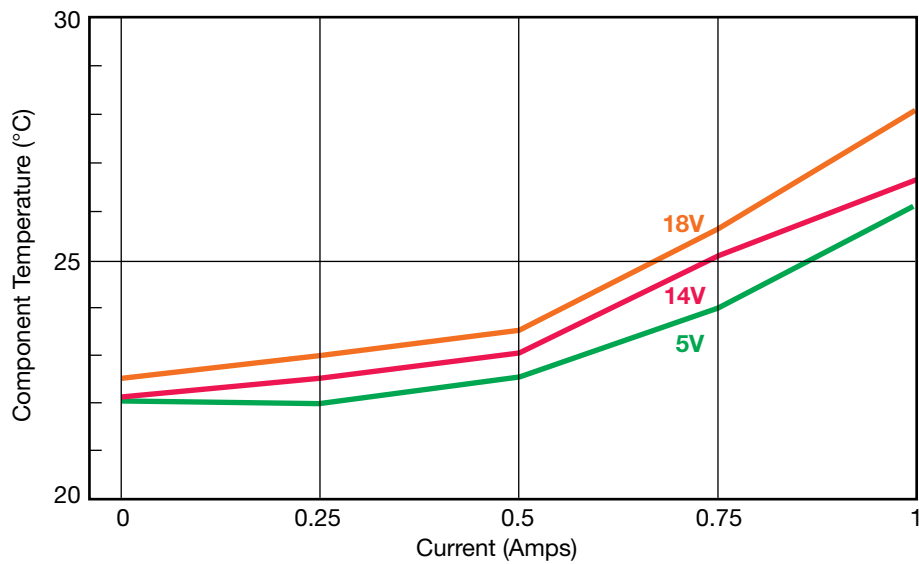
CURRENT vs TEMPERATURE

0805 – 0.1 Joule



CURRENT vs TEMPERATURE

0805 – 0.3 Joule



PERFORMANCE CHARACTERISTICS

FEEDTHRU VARISTORS

AVX Multilayer Feedthru Varistors (MLVF) are an ideal choice for system designers with transient strike and broadband EMI/RFI concerns.

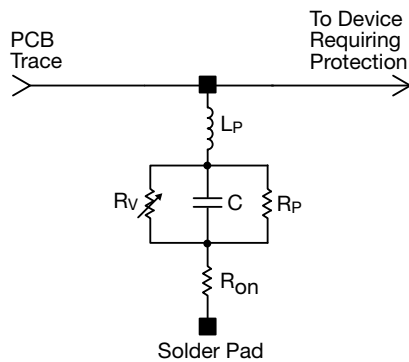
Feedthru Varistors utilize a ZnO varistor material and the electrode pattern of a feedthru capacitor. This combination allows the package advantage of the feedthru and material advantages of the ZnO dielectric to be optimized.

ZnO MLV Feedthrus exhibit electrical and physical advantages over standard ZnO MLVs. Among them are:

1. Faster Turn on Time
2. Broadband EMI attenuation
3. Small size (relative to discrete MLV and EMI filter schemes)

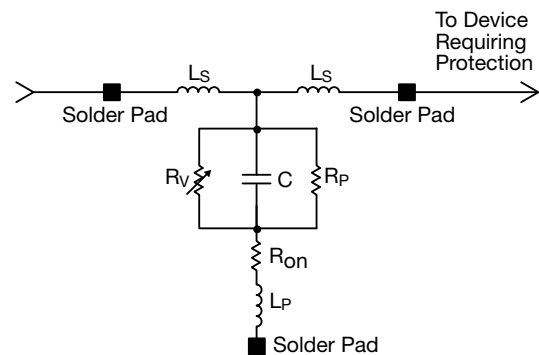
The electrical model for a ZnO MLV and a ZnO Feedthru MLV are shown below. The key difference in the model for the Feedthru is a transformation in parallel to series inductance. The added series inductance helps lower the injected transient peak current (by $2\pi fL$) resulting in an additional benefit of a lower clamping voltage. The lowered parallel inductance decreases the turn on time for the varistor to <250ps.

Discrete MLV Model



Where: R_v = Voltage Variable resistance (per VI curve)
 $R_p \geq 10^{12} \Omega$
 C = defined by voltage rating and energy level
 R_{on} = turn on resistance
 L_p = parallel body inductance

Discrete MLVF Model



Where: R_v = Voltage Variable resistance (per VI curve)
 R_p = Body IR
 C = defined by voltage rating and energy level
 R_{on} = turn on resistance
 L_p = minimized parallel body inductance
 L_s = series body inductance

TransFeed

AVX Multilayer Ceramic Transient Voltage Suppressors TVS Protection and EMI Attenuation in a Single Chip



PERFORMANCE CHARACTERISTICS

APPLICATIONS

- EMI Suppression
- Broadband I/O Filtering
- Vcc Line Conditioning

FEATURES

- Small Size
- Low ESR
- Ultra-fast Response Time
- Broad S21 Characteristics

MARKET SEGMENTS

- Computers
- Automotive
- Power Supplies
- Multimedia Add-On Cards
- Bar Code Scanners
- Remote Terminals
- Medical Instrumentation
- Test Equipment
- Transceivers
- Cellular Phones / Pagers

TYPICAL CIRCUITS REQUIRING TRANSIENT VOLTAGE PROTECTION AND EMI FILTERING

The following applications and schematic diagrams show where TransFeed TVS/ EMI filtering devices might be used:

- System Board Level Interfaces: (Fig. 1)
Digital to RF
Analog to Digital
Digital to Analog
- Voltage Regulation (Fig. 2)
- Power Conversion Circuits (Fig. 3)
- GaAs FET Protection (Fig. 4)

Fig. 1 – System Interface

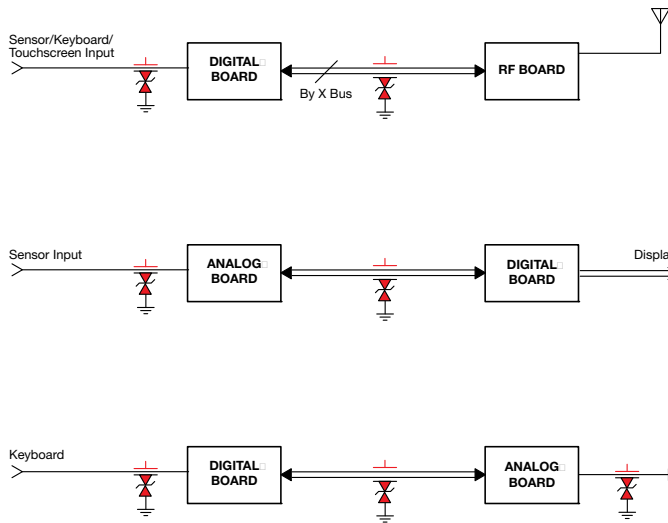


Fig. 2 – Voltage Regulators

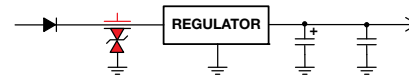


Fig. 3 – Power Conversion Circuits/Power Switching Circuits

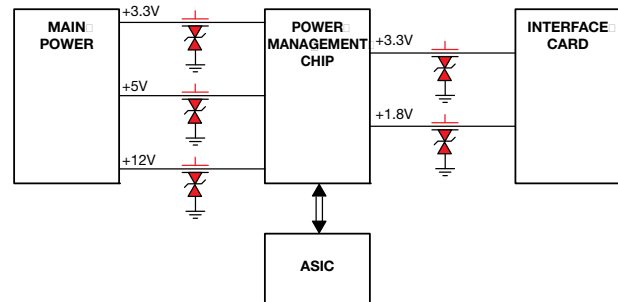
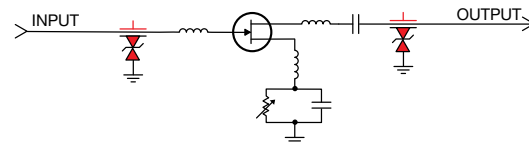


Fig. 4 – GaAs FET Protection



SPECIFICATION COMPARISON

MLVF 0805	PARAMETER	MLV 0805
5ph	L_s typical	N/A
<600nh	L_p typical	<1.5nh
<0.025 Ω	R_{on} typical	<0.1 Ω
100pf to 2.5nf	C typical	100pf to 5.5nf
see VI curves	R_v typical	see VI curves
>0.25 x 10 ¹² Ω	R_p typical	>1 x 10 ¹² Ω
<250ps	Typical turn on time Typical frequency response	<500ps

A comparison table showing typical element parameters and resulting performance features for MLV and MLVF is shown above.

TransFeed Automotive Series

AVX Multilayer Ceramic Transient Voltage Suppressors TVS Protection and EMI Attenuation in a Single Chip

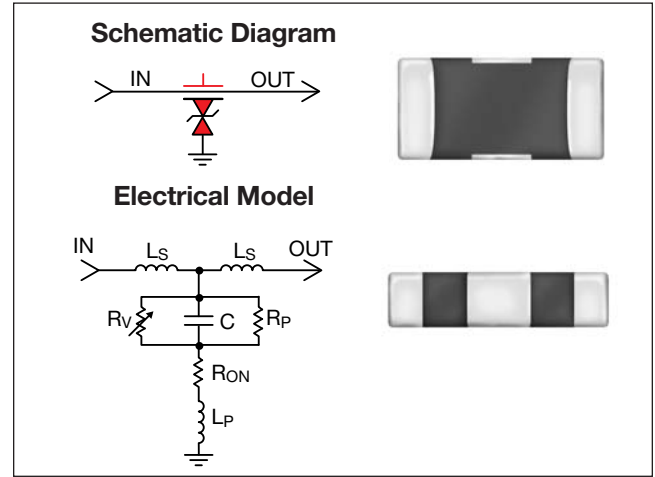


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AVX has combined the best electrical characteristics of its TransGuard® Transient Voltage Suppressors (TVS) and its Feedthru Capacitors into a single chip for state-of-the-art overvoltage circuit protection and EMI reduction over a broad range of frequencies. This unique combination of multilayer ceramic construction in a feedthru configuration gives the circuit designer a single 0805 chip that responds to transient events faster than any TVS device on the market today, and provides significant EMI attenuation when in the off-state.

Automotive TransFeeds are designed for automotive applications and are AEC-Q 200 qualified.

The reduction in parallel inductance, typical of the feedthru chip construction when compared to the construction of standard TVS or ceramic capacitor chips, gives the TransFeed product two very important electrical advantages: (1) faster “turn-on” time. Calculated response times of <200 pSec are not unusual with this device, and measured response times range from 200 – 250 pSec. The TransFeed “turn-on” characteristic is less than half that of an equivalent TransGuard® part — and TransGuards® clamp transient voltages faster than any other bipolar TVS solution such as diodes; (2) the second electrical advantage of lower parallel inductance, coupled with optimal series



inductance, is the enhanced attenuation characteristics of the TransFeed product. Not only is there significantly greater attenuation at a higher self-resonance frequency, but the roll-off characteristic becomes much flatter, resulting in EMI filtering over a much broader frequency spectrum. Typical applications include filtering/protection on Microcontroller I/O Lines, Interface I/O Lines, Power Line Conditioning and Power Regulation.

TYPICAL APPLICATIONS

- Drive by Wire
- Dimming Mirror Circuit
- Filtering/protection on Microcontroller I/O lines
- Filtering/protection on Interface I/O lines
- Power Line Conditioning
- Power Regulation
- LCD Dashboard driver

Where designers are concerned with both transient voltage protection and EMI attenuation, either due to the electrical performance of their circuits or due to required compliance to specific EMC regulations, the TransFeed product is an ideal choice.

GENERAL CHARACTERISTICS

- Operating Temperature: -55°C to +125°C
- Working Voltage: 5.6Vdc - 18 Vdc
- Case Size: 0805, 0612 4xArray
- Energy Rating: 0.05 - 0.3J
- Current: 15 - 120A
- Max Feedthru Current: 0.2 - 1A

FEATURES

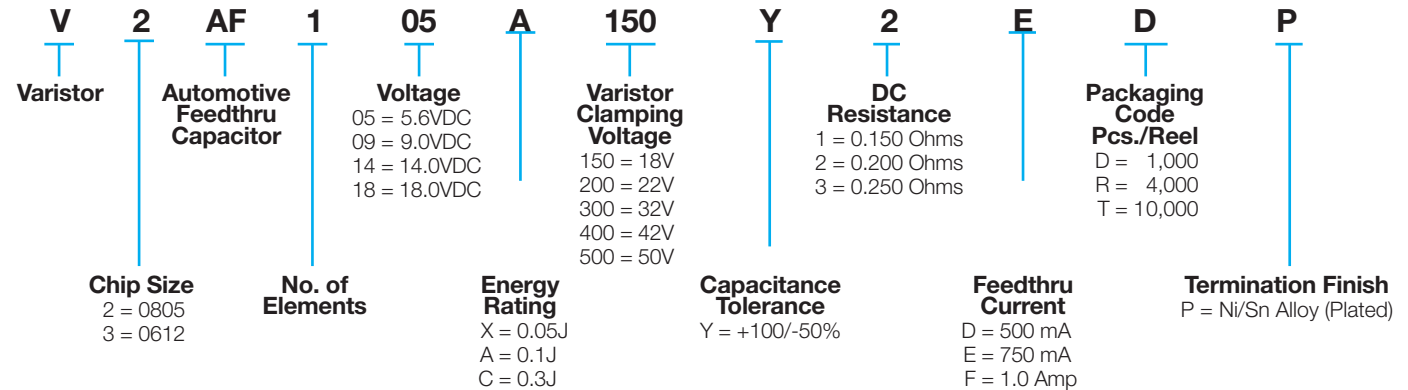
- Bi-directional TVS
- Narrow band, high attenuation filter
- EMI Filtering over broader frequency range
- Fastest Response Time to ESD Strikes
- AEC-Q 200 Qualified

TransFeed Automotive Series

AVX Multilayer Ceramic Transient Voltage Suppressors TVS Protection and EMI Attenuation in a Single Chip



HOW TO ORDER



TRANSFEED ELECTRICAL SPECIFICATIONS

AVX Part Number	Working Voltage (DC)	Working Voltage (AC)	Breakdown Voltage	Clamping Voltage	Maximum Leakage Current	Transient Energy Rating	Peak Current Rating	Typical Cap	DC Resistance	Maximum Feedthru Current	Jump Start Voltage
V2AF105A150Y2E __	5.6	4.0	8.5±20%	18	35	0.10	30	800	0.200	0.75	-
V2AF105C150Y1F __	5.6	4.0	8.5±20%	18	35	0.30	120	2500	0.150	1.00	-
V2AF109A200Y2E __	9.0	6.4	12.7±15%	22	25	0.10	30	575	0.200	0.75	-
V2AF109C200Y1F __	9.0	6.4	12.7±15%	22	25	0.30	120	1800	0.150	1.00	-
V2AF114A300Y2E __	14.0	10.0	18.5±12%	32	15	0.10	30	300	0.200	0.75	27.5
V2AF114C300Y1F __	14.0	10.0	18.5±12%	32	15	0.30	120	900	0.150	1.00	27.5
V2AF118A400Y2E __	18.0	13.0	25.5±10%	42	10	0.10	30	200	0.200	0.75	27.5
V2AF118C400Y1F __	18.0	13.0	25.5±10%	42	10	0.30	120	500	0.150	1.00	27.5
V2AF118X500Y3D __	18.0	13.0	25.5±10%	50	10	0.05	20	75	0.250	0.50	27.5
V3AF418A400Y3G __	18.0	13.0	25.5±10%	42	10	0.10	20	150	0.200	0.30	27.5
V3AF418X500Y3G __	18.0	13.0	25.5±10%	50	10	0.05	15	65	0.250	0.20	27.5

Termination Finish Code
Packaging Code

- | | | | |
|------------|---|------------|---|
| V_w (DC) | DC Working Voltage (V) | E_T | Transient Energy Rating (J, 10x1000µS) |
| V_w (AC) | AC Working Voltage (V) | I_p | Peak Current Rating (A, 8x20µS) |
| V_B | Typical Breakdown Voltage (V @ 1mA _{DC}) | Cap | Typical Capacitance (pF) @ 1MHz and 0.5 V |
| V_B Tol | V_B Tolerance is ± from Typical Value | DCR | DC Resistance (Ohms) |
| V_C | Clamping Voltage (V @ 1A 8x20µS) | I_{FT} | Maximum Feedthru Current (A) |
| I_L | Maximum Leakage Current at the Working Voltage (µA) | V_{JUMP} | Jump Start Voltage (V, 5 min) |



TransFeed Automotive Series

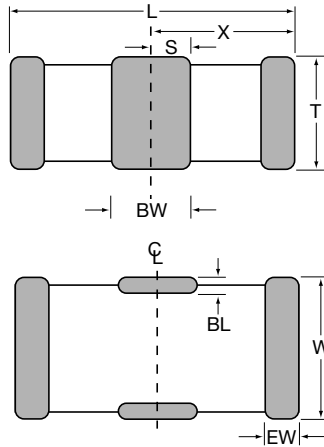
AVX Multilayer Ceramic Transient Voltage Suppressors

TVS Protection and EMI Attenuation in a Single Chip



DIMENSIONS

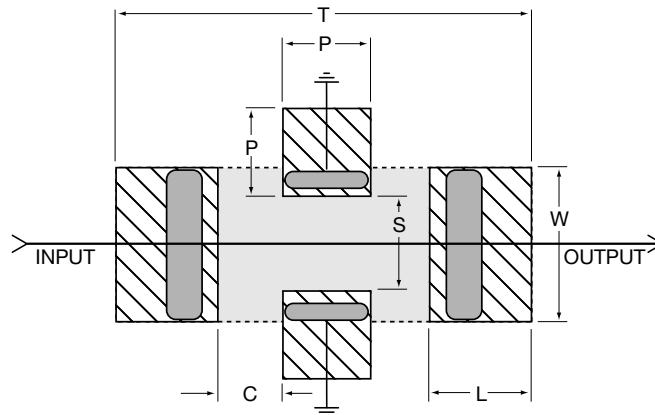
	mm (inches)							
	L	W	T	BW	BL	EW	X	S
0805	2.01 ± 0.20 (0.079 ± 0.008)	1.25 ± 0.20 (0.049 ± 0.008)	1.143 Max. (0.045 Max.)	0.46 ± 0.10 (0.018 ± 0.004)	0.18 + 0.25 - 0.08 (0.007 + 0.010 - 0.003)	0.25 ± 0.13 (0.010 ± 0.005)	1.02 ± 0.10 (0.040 ± 0.004)	0.23 ± 0.05 (0.009 ± 0.002)

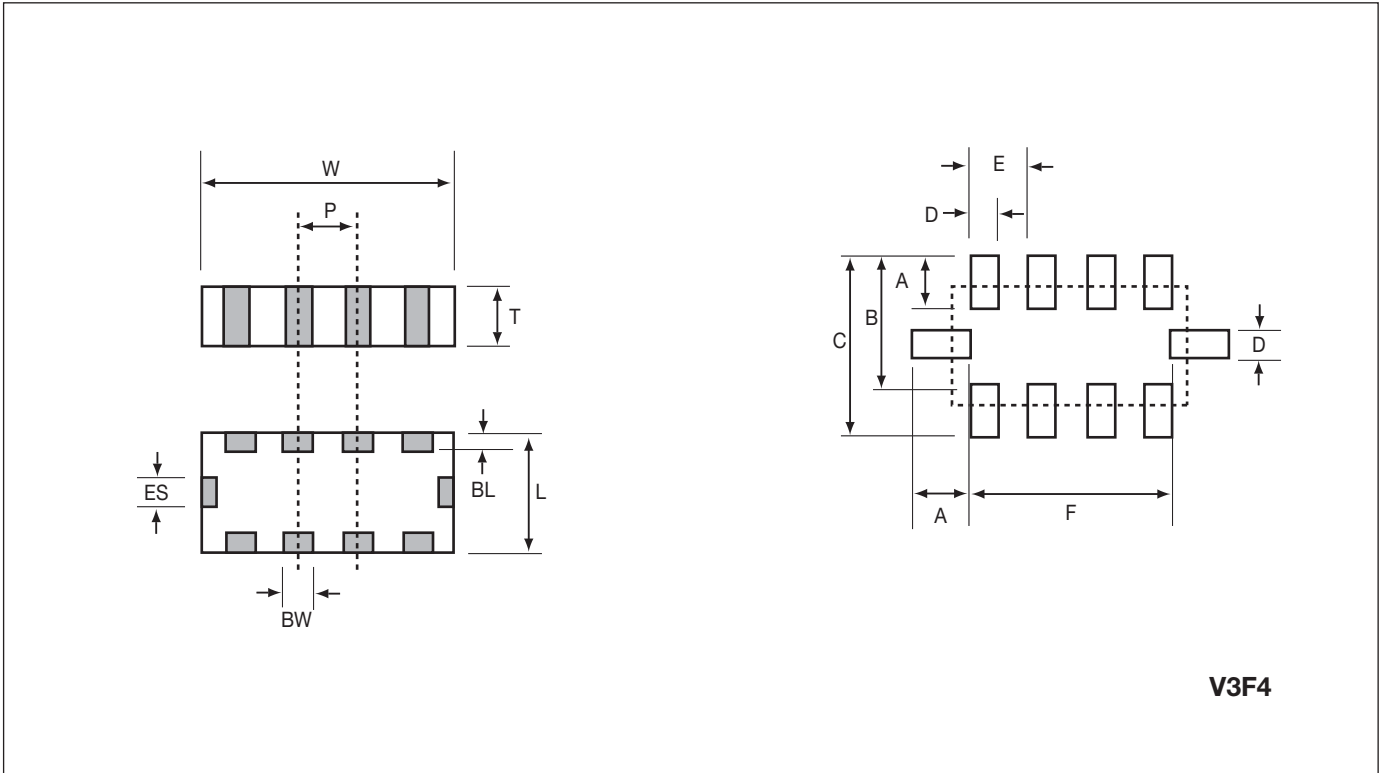


RECOMMENDED SOLDER PAD LAYOUT (Typical Dimensions)

	mm (inches)					
	T	P	S	W	L	C
0805	3.45 (0.136)	0.51 (0.020)	0.76 (0.030)	1.27 (0.050)	1.02 (0.040)	0.46 (0.018)

4 Pad Layout





V3F4

DIMENSIONS

mm (inches)

L	W	T	BW	BL	ES	P
1.60 ± 0.20 (0.063 ± 0.008)	3.25 ± 0.15 (0.128 ± 0.006)	1.22 Max. (0.048 Max.)	0.41 ± 0.10 (0.016 ± 0.004)	0.18 +0.25 -0.08 (0.007 +0.010 -0.003)	0.41 ± 0.10 (0.016 ± 0.004)	0.76 REF (0.030 REF)

mm (inches)

A	B	C	D	E	F
0.60 (0.024)	1.60 (0.064)	2.20 (0.088)	0.35 (0.014)	0.76 (0.030)	2.60 (0.104)

TransFeed Automotive Series

AVX Multilayer Ceramic Transient Voltage Suppressors TVS Protection and EMI Attenuation in a Single Chip



PERFORMANCE CHARACTERISTICS

FEEDTHRU VARISTORS

AVX Multilayer Feedthru Varistors (MLVF) are an ideal choice for system designers with transient strike and broadband EMI/RFI concerns.

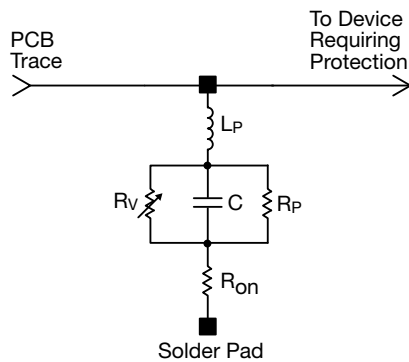
Feedthru Varistors utilize a ZnO varistor material and the electrode pattern of a feedthru capacitor. This combination allows the package advantage of the feedthru and material advantages of the ZnO dielectric to be optimized.

ZnO MLV Feedthrus exhibit electrical and physical advantages over standard ZnO MLVs. Among them are:

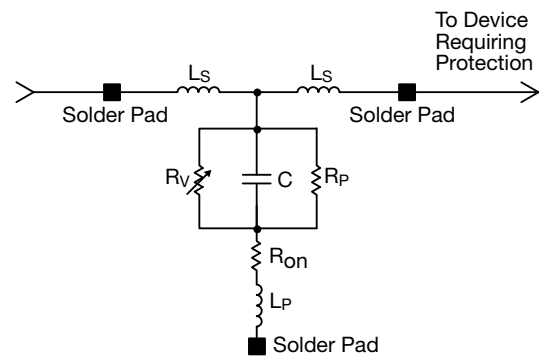
1. Faster Turn on Time
2. Broadband EMI attenuation
3. Small size (relative to discrete MLV and EMI filter schemes)

The electrical model for a ZnO MLV and a ZnO Feedthru MLV are shown below. The key difference in the model for the Feedthru is a transformation in parallel to series inductance. The added series inductance helps lower the injected transient peak current (by $2\pi fL$) resulting in an additional benefit of a lower clamping voltage. The lowered parallel inductance decreases the turn on time for the varistor to <250ps.

Discrete MLV Model



Discrete MLVF Model



Where: R_V = Voltage Variable resistance (per VI curve)
 $R_P \geq 10^{12} \Omega$
 C = defined by voltage rating and energy level
 R_{ON} = turn on resistance
 L_P = parallel body inductance

Where: R_V = Voltage Variable resistance (per VI curve)
 R_P = Body IR
 C = defined by voltage rating and energy level
 R_{ON} = turn on resistance
 L_P = minimized parallel body inductance
 L_S = series body inductance

TransFeed Automotive Series

AVX Multilayer Ceramic Transient Voltage Suppressors TVS Protection and EMI Attenuation in a Single Chip



PERFORMANCE CHARACTERISTICS

APPLICATIONS

- EMI Suppression
- Broadband I/O Filtering
- Vcc Line Conditioning

FEATURES

- Small Size
- Low ESR
- Ultra-fast Response Time
- Broad S21 Characteristics

MARKET SEGMENTS

- Computers
- Automotive
- Power Supplies
- Multimedia Add-On Cards
- Bar Code Scanners
- Remote Terminals
- Medical Instrumentation
- Test Equipment
- Transceivers
- Cellular Phones / Pagers

TYPICAL CIRCUITS REQUIRING TRANSIENT VOLTAGE PROTECTION AND EMI FILTERING

The following applications and schematic diagrams show where TransFeed TVS/ EMI filtering devices might be used:

- System Board Level Interfaces: (Fig. 1)
Digital to RF
Analog to Digital
Digital to Analog
- Voltage Regulation (Fig. 2)
- Power Conversion Circuits (Fig. 3)
- GaAs FET Protection (Fig. 4)

Fig. 1 – System Interface

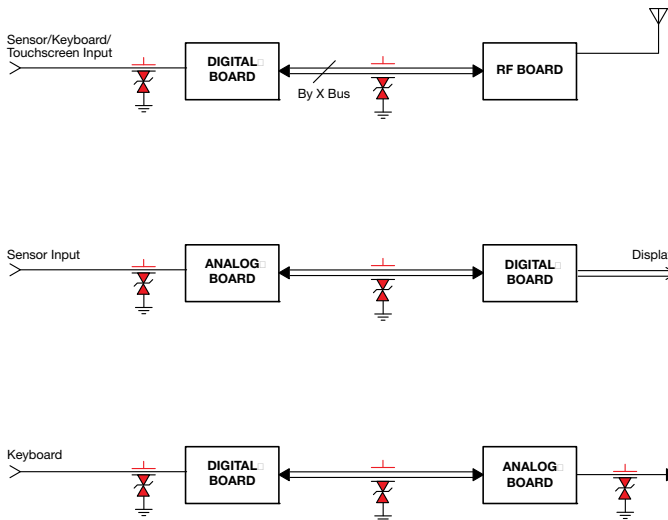


Fig. 2 – Voltage Regulators

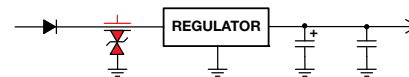


Fig. 3 – Power Conversion Circuits/Power Switching Circuits

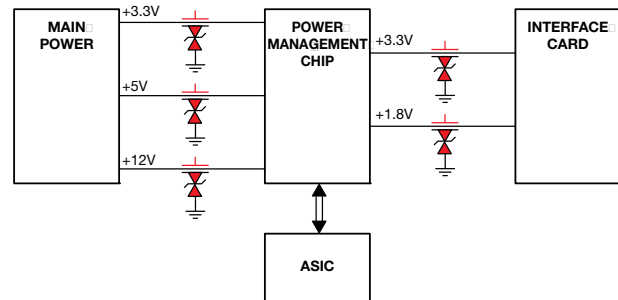


Fig. 4 – GaAs FET Protection

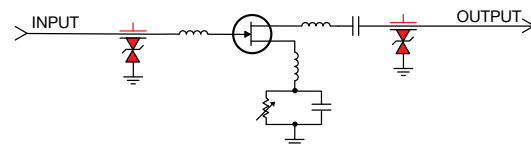
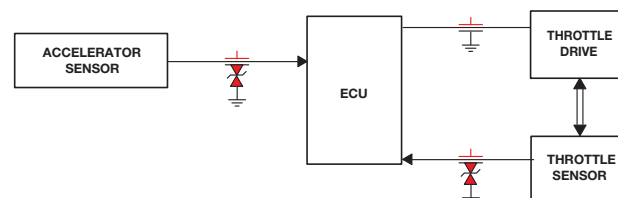


Fig. 5 – Automotive TransFeed - Throttle by Wire



SPECIFICATION COMPARISON

MLVF 0805	PARAMETER	MLV 0805
5ph	L_s typical	N/A
<600nh	L_p typical	<1.5nh
<0.025 Ω	R_{on} typical	<0.1 Ω
100pf to 2.5nf	C typical	100pf to 5.5nf
see VI curves	R_v typical	see VI curves
>0.25 x 10 ¹² Ω	R_p typical	>1 x 10 ¹² Ω
<250ps	Typical turn on time Typical frequency response	<500ps

A comparison table showing typical element parameters and resulting performance features for MLV and MLVF is shown above.

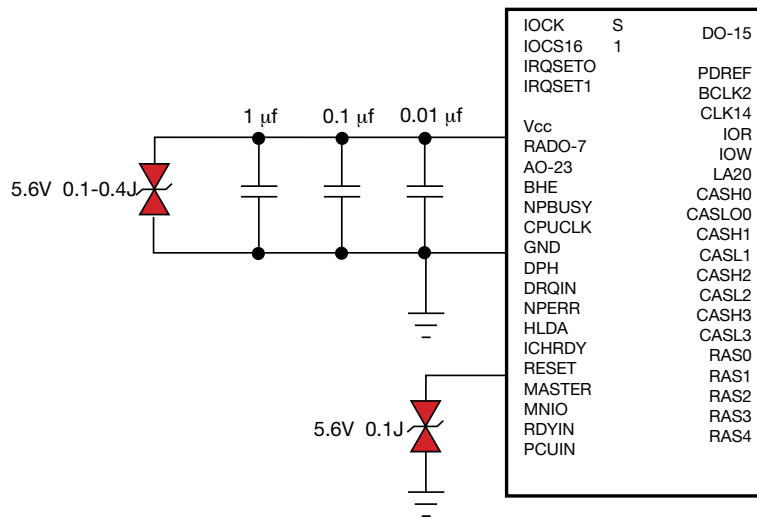
AVXTransGuard[®]

TYPICAL CIRCUITS REQUIRING PROTECTION

The following applications and schematic diagrams show where TransGuards[®] might be used to suppress various transient voltages:

- ASIC Reset & Vcc Protection
- Micro Controllers, Relays, DC Motors
- I/O Port Protection
- Keyboard Protection
- Modem Protection
- Sensor Protection
- Preamplifier Protection
- Audio Circuit Protection
- LCD Protection
- Optics Protection

ASIC RESET & V_{CC} PROTECTION

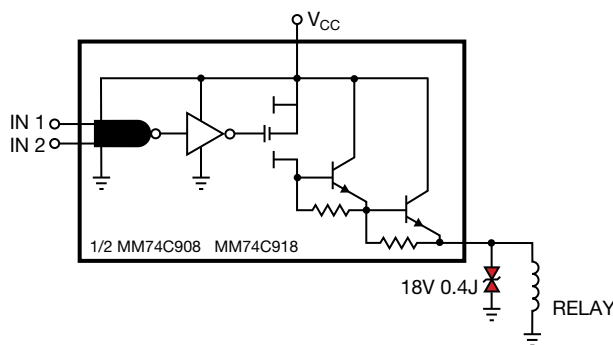


MICRO CONTROLLERS RELAYS, DC MOTORS

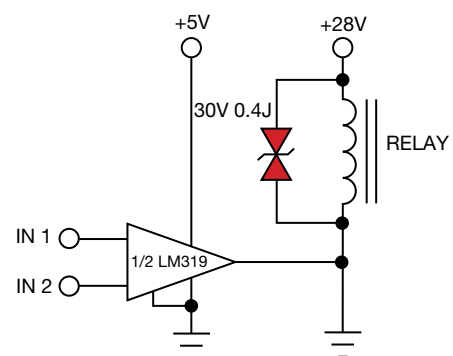
TRANSGUARD® CHARACTERISTICS

WORKING VOLTAGE ≥ RELAY OR MOTOR VOLTAGE
 ENERGY RATING TYPICALLY > 0.3J
 CAPACITANCE IS OF NO CONCERN

CMOS RELAY DRIVER



LM319 RELAY DRIVER

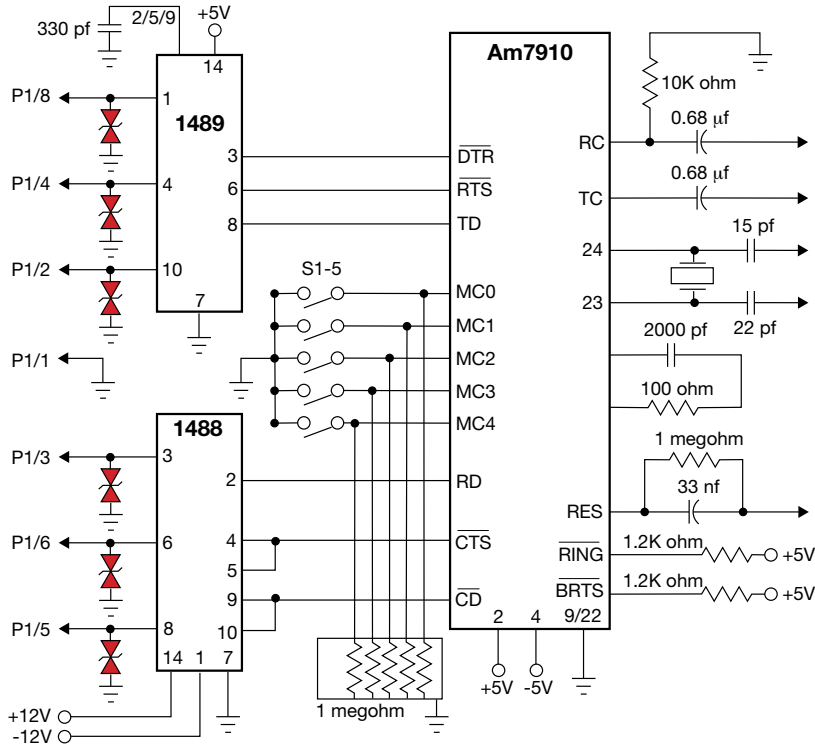


= TransGuard®

MODEM PROTECTION

TRANSQUARD® CHARACTERISTICS

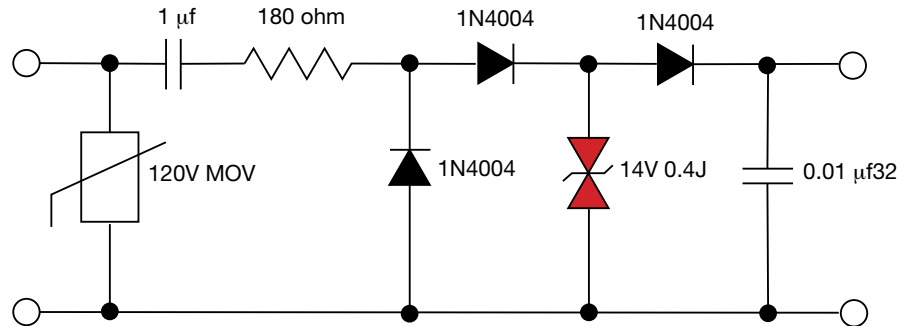
WORKING VOLTAGE <26V
ENERGY RATING ≥ 0.1J



SENSOR PROTECTION

TRANSQUARD® CHARACTERISTICS

WORKING VOLTAGE TYPICALLY >14V
ENERGY RATING > 0.4J
CAPACITANCE IS NO CONCERN



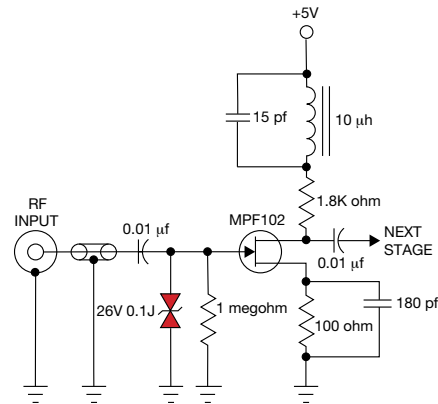
= TransGuard®

ANTENNA AND PREAMPLIFIER PROTECTION

TRANSGUARD® CHARACTERISTICS

WORKING VOLTAGE TYPICALLY 18V - 26V
ENERGY RATING 0.05J - 0.9J
CAPACITANCE OF CONCERN ON MANY DESIGNS

PREAMPLIFIER PROTECTION

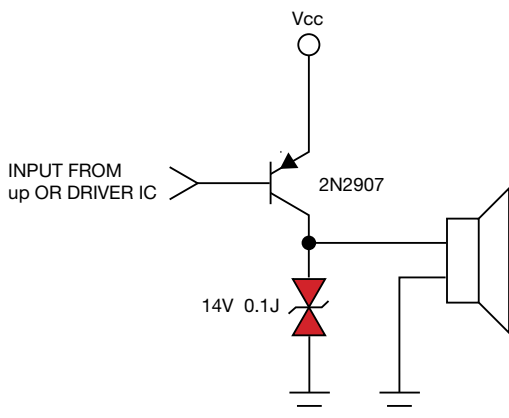


AUDIO CIRCUIT PROTECTION

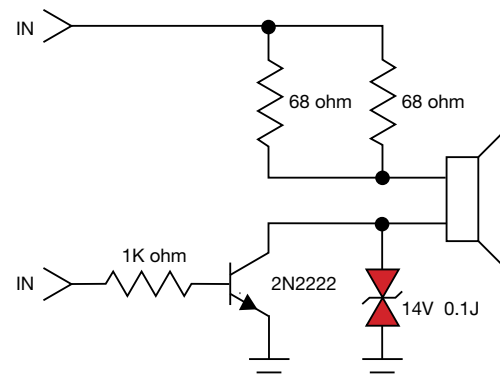
TRANSGUARD® CHARACTERISTICS

WORKING VOLTAGE TYPICALLY 14V - 18V
ENERGY RATING 0.1J

PAGER AUDIO PROTECTION



NOTEBOOK, WORK STATION AUDIO PROTECTION

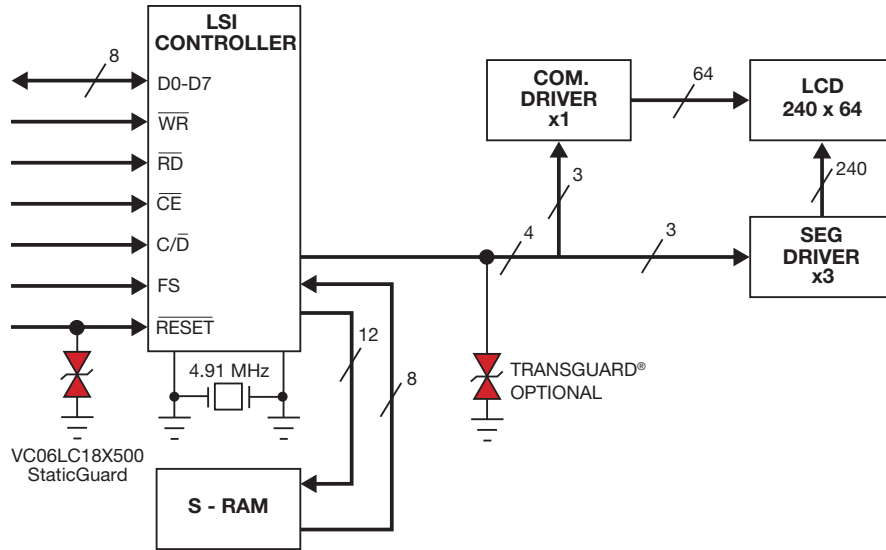


= TransGuard®

LCD PROTECTION

TRANSGUARD® CHARACTERISTICS

WORKING VOLTAGE < 5.6V
ENERGY RATING < 0.1J

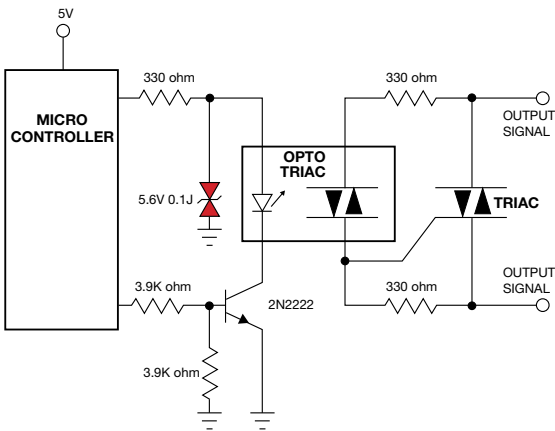


OPTICS PROTECTION

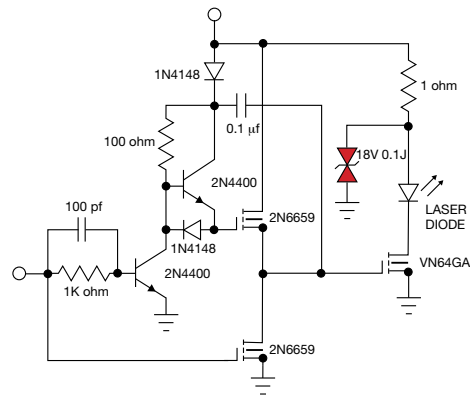
TRANSGUARD® CHARACTERISTICS

WORKING VOLTAGE ≤ 18V
ENERGY RATING 0.1J
CAPACITANCE SHOULD BE MINIMIZED

OPTO ISOLATER PROTECTION



LASER DIODE PROTECTION



= TransGuard®

AVXTransGuard[®]

APPLICATION NOTES

- AVX Multilayer Varistors – Assembly Guidelines
- IEC 61000-4 Requirements
- Turn On Time Characteristics of AVX Multilayer Varistors
- The Impact of ESD on Insulated Portable Equipment
- AVX TransGuard[®] Motor and Relay Application Study
- AVX Multilayer Varistors in Automobile MUX Bus Applications

TRANSGUARD® SURFACE MOUNT DEVICES

The move toward SMT assembly of Transient Voltage Suppressors (TVS) will continue accelerating due to improved long-term reliability, more efficient transient voltage attenuation and size/functionality/cost issues.

TransGuards® are uniquely suited for wide-scale usage in SMT applications. TransGuards® exhibit many advantages when used in SMT assemblies. Among them are:

- Available in standard EIA chip sizes 0402/0603/0805/1206/1210.
- Placed with standard equipment (8mm tape and reel).
- Processed with fewer guidelines than either ceramic chip or resistor chip devices.
- Exhibit the highest energy/volume ratio of any EIA size TVS.

This general guideline is aimed at familiarizing users with the characteristics of soldering multilayer SMT ZnO TransGuards®. TransGuards® can be processed on wave or infrared reflow assembly lines. For optimum performance, EIA standard solder pads (land areas) shown in Figure 1 are recommended regardless of the specific attachment method.

Dimensions: mm (inches)

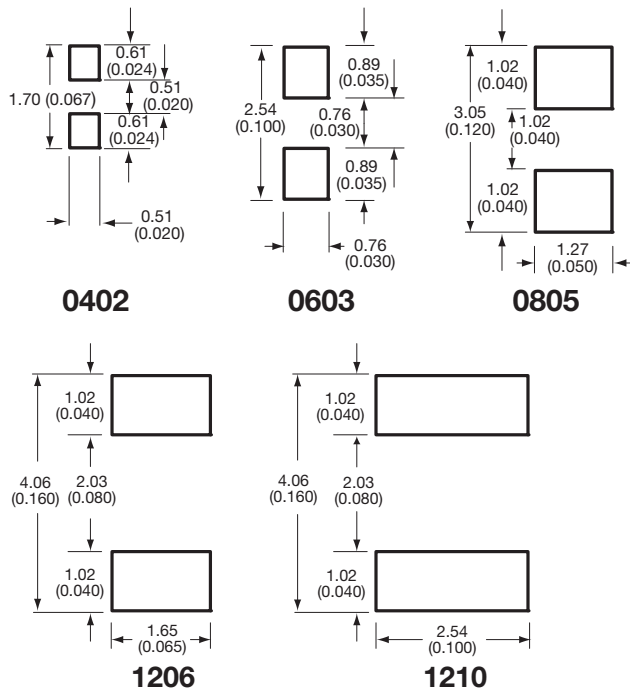


Figure 1: TransGuard® Solder Pad Dimensions

STORAGE

Good solderability of plated components is maintained for at least twelve months, provided the components are stored in their “as received” packaging at less than 30°C and 85% RH.

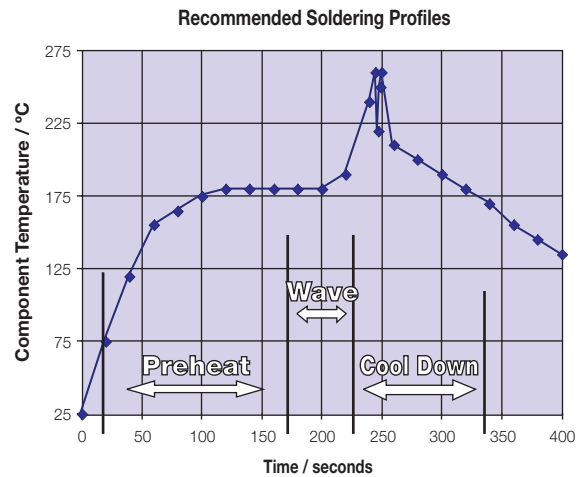
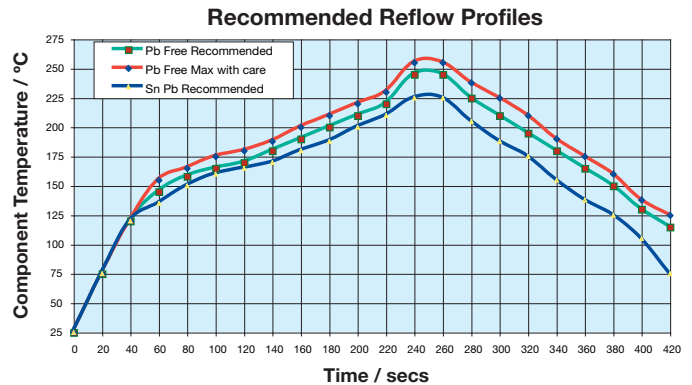
SOLDERABILITY

Plated terminations will be well soldered after immersion in a 60/40 tin/lead solder bath at 235°C ±5°C for 5 ±1 seconds.

LEACHING

Plated terminations will resist leaching for at least 30 seconds when immersed in 60/40 tin/lead solder at 260°C ±5°C.

RECOMMENDED SOLDERING PROFILES



GENERAL

Surface mount multilayer varistors (MLVs) are designed for soldering to printed circuit boards or other substrates. The construction of the components is such that they will withstand the time/temperature profiles used in both wave and reflow soldering methods.

HANDLING

MLVs should be handled with care to avoid damage or contamination from perspiration and skin oils. The use of tweezers or vacuum pickups is strongly recommended for individual components. Bulk handling should ensure that abrasion and mechanical shock are minimized. Taped and reeled components provide the ideal medium for direct presentation to the placement machine.

PREHEAT

It is important to avoid the possibility of thermal shock during soldering and carefully controlled preheat is therefore required. The rate of preheat should not exceed 4°C/second and a target figure 2°C/second is recommended.

SOLDERING

Mildly activated rosin fluxes are preferred. The minimum amount of solder to give a good joint should be used. Excessive solder can lead to damage from the stresses caused by the difference in coefficients of expansion between solder, chip and substrate. AVX terminations are suitable for all wave and reflow soldering systems. If hand soldering cannot be avoided, the preferred technique is the utilization of hot air soldering tools.

COOLING

Natural cooling in air is preferred, as this minimizes stresses within the soldered joint. When forced air cooling is used, cooling rate should not exceed 4°C/second.

CLEANING

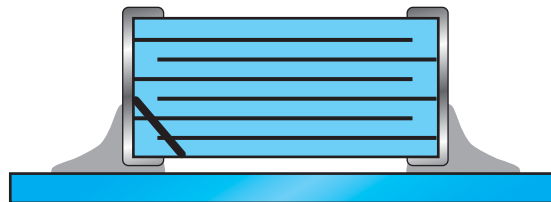
Flux residues may be hygroscopic or acidic and must be removed. AVX MLVs are acceptable for use with all of the solvents described in the specifications MIL-STD-202 and EIA-RS-198. Alcohol-based solvents are acceptable and properly controlled water cleaning systems are also acceptable. Many other solvents have been proven successful, and most solvents that are acceptable to other components on circuit assemblies are equally acceptable for use with MLVs.

POST SOLDER HANDLING

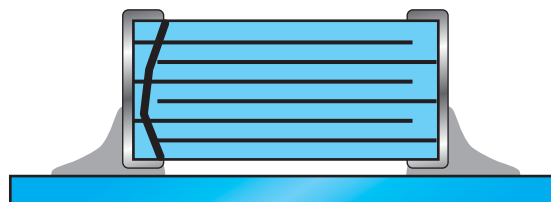
Once the components are soldered to the board, any bending or flexure of the PCB applies stresses to the soldered joints of the components. For leaded devices, the stresses are absorbed by the compliancy of the metal leads and generally don't result in problems unless the stress is large enough to fracture the soldered connection.

Surface mount devices are more susceptible to such stress because they don't have compliant leads and are brittle in nature. The most frequent failure mode is high leakage current (or low breakdown voltage). Also, a significant loss of capacitance due to severing of contact between sets of internal electrodes may be observed.

Cracks caused by mechanical flexure are very easily identified and generally take one of the following two general forms:



Type A:
Angled crack between bottom of device to top of solder joint.



Type B:
Fracture from top of device to bottom of device.

Mechanical cracks are often hidden underneath the termination and are difficult to see externally. However, if one end termination falls off during the removal process from PCB, this is one indication that the cause of failure was excessive mechanical stress due to board flexure.

COMMON CRACKS OF MECHANICAL CRACKING

The most common source for mechanical stress is board depanelization equipment, such as manual breakapart, v-cutters and shear presses. Improperly aligned or dull cutters may cause torquing of the PCB resulting in flex stresses being transmitted to components near the board edge. Another common source of flexural stress is contact during parametric testing when test points are probed. If the PCB is allowed to flex during the test cycle, nearby components may be broken.

A third common source is board-to-board connections at the vertical connectors where cables or other PCBs are connected to the PCB. If the board is not supported during the plug/unplug cycle, it may flex and cause damage to nearby components.

Special care should also be taken when handling large (>6" on a side) PCBs since they more easily flex or warp than smaller boards.

AVX Multilayer Varistors – Application Notes

REWORKING ASSEMBLIES

Thermal shock is common in MLVs that are manually attached or reworked with a soldering iron. AVX strongly recommends that any reworking of MLVs be done with hot air reflow rather than soldering irons.

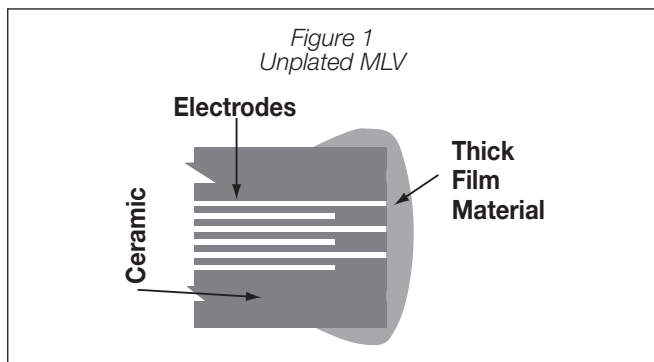
Direct contact by the soldering iron tip often causes thermal cracks that may fail at a later date. If rework by soldering iron is absolutely necessary, it is recommended that the wattage of the iron be less than 30 watts and the tip temperature be <300°C. Rework should be performed by applying the solder iron tip to the pad and not directly contacting any part of the component.

VARISTOR SOLDERABILITY

Historically, the solderability of Multilayer Varistors (MLVs) has been a problem for the electronics manufacturer. He was faced with a device that either did not wet as well as other electronic components, or had its termination material leached away during the assembly process. However, by utilizing proprietary procedures, AVX Corporation provides the market with a MLV that has solderability comparable to that of other electronic components, and resists leaching during assembly.

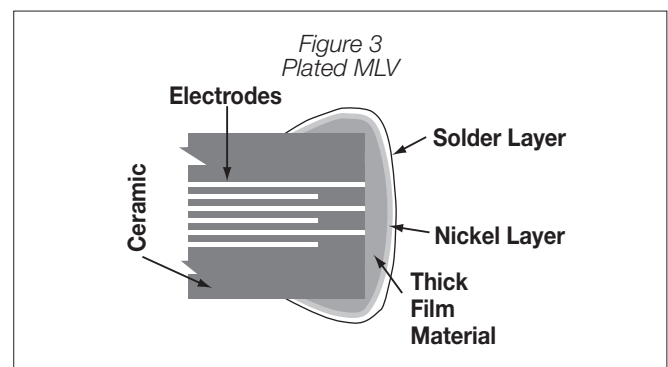
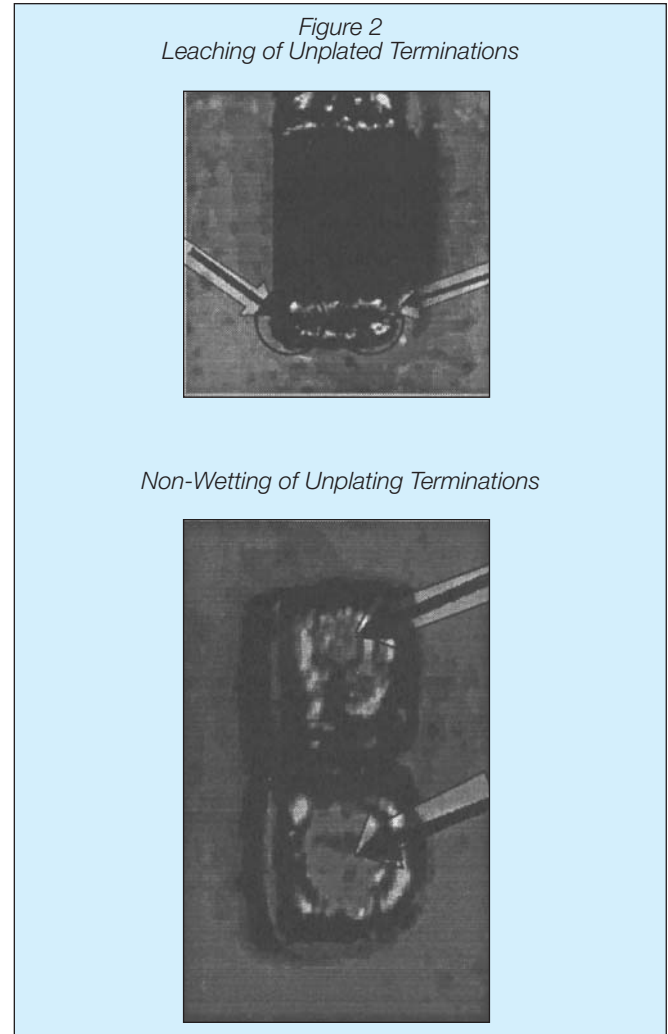
BACKGROUND

The basic construction of an unplated MLV is presented in Figure 1. The external termination is a metal that connects



the internal electrodes to the circuitry of the assembly using the MLV. The external electrode must accomplish two goals. First, it must be sufficiently solderable to allow the solder used in assembly to wet the end of the chip and make a reliable connection to the traces on the circuit board. Second, it must be robust enough to withstand the assembly process. This is particularly important if wave soldering is used. Unfortunately these two goals are competing. In order to achieve good solderability, an alloy high in silver content is chosen. However, this alloy is prone to leaching during assembly, so an additional metal is added to improve the leach resistance. While this improves the leach resistance, this addition makes the termination less solderable. The results are either terminations that leach away, or do not solder well (see the photographs in Figure 2).

Clearly, a plated termination system (as seen in Figure 3) is desired. This system, which is typical of other electronic components such as capacitors and resistors, produces a much better assembled product.



In the plated termination, the base termination layer is still used (it provides contact from the electrodes to the circuitry). On top of the base termination is a layer of nickel. This is the surface to which the solder bonds during assembly. It must be thick enough to stay intact during IR reflow or wave

AVX Multilayer Varistors – Application Notes

soldering so that the thick film material does not leach away. It must also be thick enough to prevent the inter-metallic layer between the thick film termination and the nickel layer from affecting the solderability.

In order to protect the nickel (i.e., maintain its solderability), a layer of solder is plated on top of the nickel. The solder preserves the solderability of the nickel layer. It must be thick and dense to keep oxygen and water from reaching the nickel layer.

THE CHALLENGE

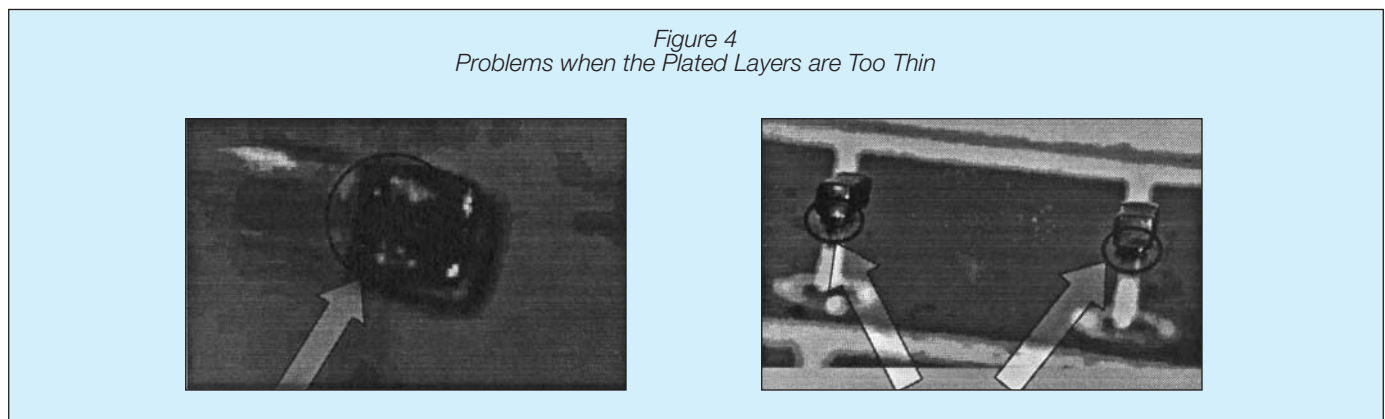
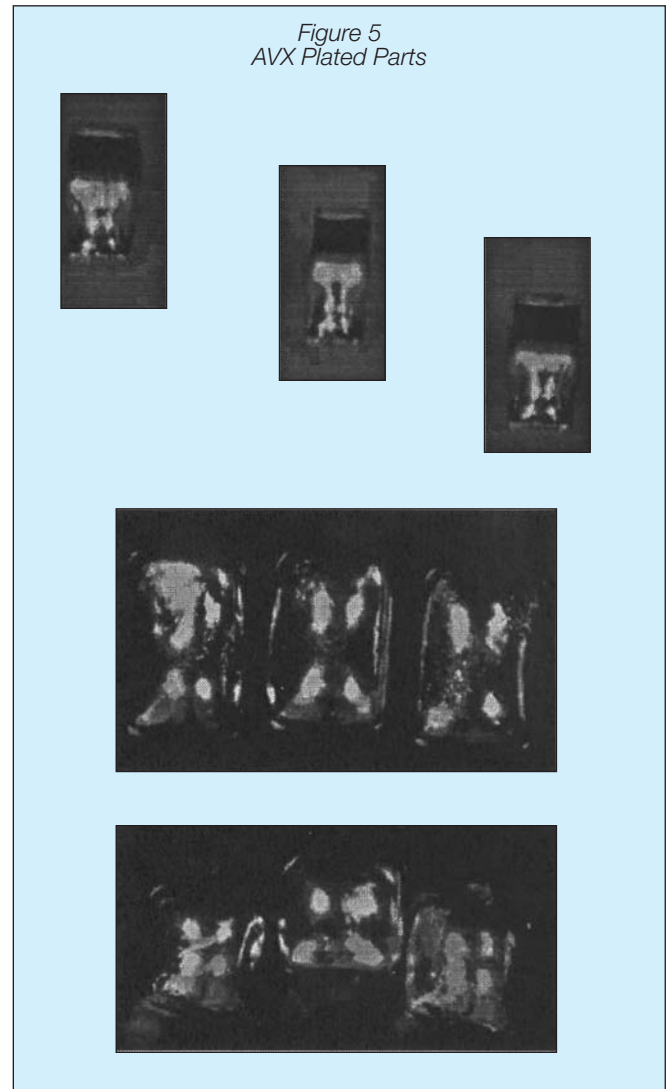
Zinc oxide varistors are semi-conductive in nature – that is what allows them to “turn on” and divert a damaging transient away from sensitive electronic circuitry and safely to ground. This semi-conduction poses a major problem for the manufacturer that wants to plate the terminations – the ceramic plates also! This condition, overplating, must be controlled, as it is cosmetically undesirable and could result in an unwanted path of conduction across the chip.

Early efforts in plating MLVs revolved around limiting the time that the chip was in the plating bath. This helped prevent overplating, but also produced chips with marginal solderability. The photographs in Figure 4 depict the problems that occur when the plated layers are not thick enough.

THE SOLUTION

AVX has developed a proprietary process that passivates the ceramic surface of the MLV. This allows us to plate the parts for a longer time without getting the overplate. This results in significantly thicker layers of nickel and alloy plated onto the base termination. These thicker layers translate into bond strengths that are typically twice those of our competitors and solder fillets and parts that pass all measured of solderability (as seen in Figure 5).

AVX: The solution for MLV assembly problems.



WHAT IS IEC 61000-4?

The International Electrotechnical Commission (IEC) has written a series of specifications, IEC 61000-4, which mandate the performance of all electronic devices in a variety of transient and incident RF conditions. This specification requirement resulted as part of Europe's move toward a single market structure and a desire to formalize and harmonize current member countries' requirements. As of January 1, 1996, all electronic and electrical items sold to Europe must meet IEC 61000-4 series specifications.

WHY IS IEC 61000-4 REQUIRED BY EUROPE?

The various regulatory agencies within Europe feel that the IEC 61000-4 series of specifications is necessary to insure acceptable performance of electronic equipment in a world filled with increasingly more Electromagnetic Interference - EMI. Furthermore, as electronic systems become more portable, and the transient susceptibility of semiconductors increases, government regulations are essential to maintain a minimum level of performance in all equipment. Europe is so serious about the problem that they require that equipment be certified via testing to meet IEC 61000-4 series specifications after 1/1/96 to avoid fines and prosecution.

HOW DO COMPANIES SELLING ELECTRONIC SYSTEMS MEET IEC 61000-4 PARTS 2-5 SPECIFICATIONS?

Companies and design engineers must now use protective circuits or devices to meet these requirements. First, a description of IEC 61000-4/2-6 is in order:

IEC 61000-4-2 ESD TESTING REQUIREMENTS

All equipment destined for Europe must be able to withstand 10 strikes of ESD waveforms with $T_r < 1\text{ns}$ in contact discharge mode (preferred) at pre-selected points accessible during normal usage or maintenance. Testing shall be performed at one or more of four (4) severity levels, depending upon equipment category.

Level	Contact Discharge ¹ Mode Test Voltage kV	Air Discharge Mode Test Voltage kV
1	2	2
2	4	4
3	6	8
4	8	15

61000-4-2 Test Conditions

¹Preferred mode of testing due to repeatability.

WAVEFORM PARAMETERS

Level	Test Voltage Level kV	First Peak of Discharge Current Amps $\pm 10\%$	TR nS	30 nS Current Amps $\pm 30\%$	60 nS Current Amps $\pm 30\%$
1	2	7.5	0.7 -1	4	2
2	4	15	0.7 -1	8	4
3	6	22.5	0.7 -1	12	6
4	8	30	0.7 -1	16	8

Upon completion of the test, the system must not experience upset (data or processing errors) or permanent damage. The waveforms are to be injected at or along the DUT's body which is accessible in normal set-up and operation.

IEC 61000-4-3 ELECTROMAGNETIC COMPATIBILITY IMPACT TESTING (EMC)

This test is concerned with the susceptibility of equipment when subjected to radio frequencies of 27 MHz to 500 MHz. The system must be able to withstand three (3) incident radiation levels:

- Level 1** 1V/m field strength
- Level 2** 3V/m field strength
- Level 3** 10V/m field strength
- Level X** User defined > 10V/m field strength

The system must not experience upset (data or processing errors) or permanent errors.

IEC 61000-4-4 ELECTRICAL FAST TRANSIENT (EFT) TESTING

The EFT test is modeled to simulate interference from inductive loads, relay contacts and switching sources. It consists of coupling EFT signals on I/O parts, keyboard cables, communication lines and power source lines. The system, depending upon appropriate severity level, must be able to withstand repetition rates of 2.5 kHz to 5 kHz for ≥ 1 minute as follows:

	Open Circuit Output Voltage/10%	
	On Power Supply	On I/O, Signal, Data, Control lines
Level 1	0.5kV	0.25kV
Level 2	1kV	0.5kV
Level 3	2kV	1kV
Level 4	4kV	2kV

TransGuard[®]

AVX Multilayer Ceramic Transient Voltage Suppressors

Application Notes: IEC 61000-4 Requirements



IEC 61000-4-5 UNIDIRECTIONAL POWER LINE SURGE TEST

The details of this specification for high energy disturbances are being addressed in several drafts under discussion within the EC at this time.

IEC 61000-4-6 CONDUCTED RF TEST FROM 9kHz TO 80MHz

The details of this specification for conducted broad band RF signals are being addressed in a first edition draft within the EC at this time.

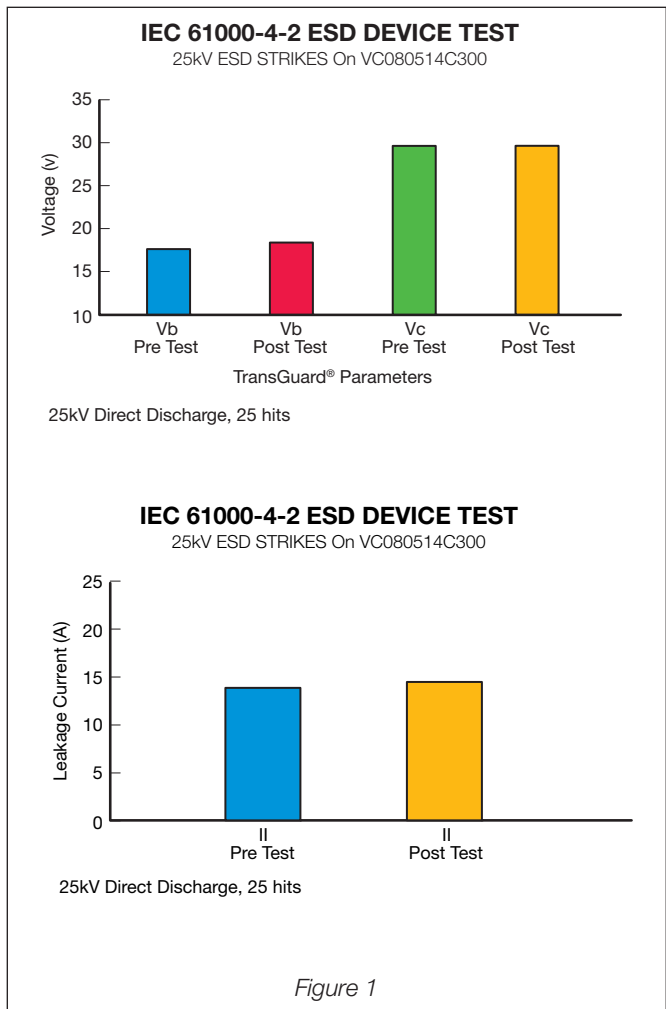
Designers have the option of using AVX TransGuards[®] to meet IEC 61000-4-2, 3 and 4.

In the case of IEC 61000-4-2 TransGuards[®] can be used to suppress the incoming Transient just like a Zener diode would. TransGuards[®], however, exhibit bipolar characteristics, a faster turn-on-time (<1nS), a better repetitive strike capability and superior thermal stability to the Zener suppression device. Furthermore, TransGuards[®] are typically smaller and lighter when placed on SMT circuit boards. See Figure 1 for data illustrating IEC 61000-4-2 repetitive strike capability.

The TransGuards[®] effective capacitance allows the device to be used to meet IEC 61000-4-3 and 61000-4-4. The device's parallel capacitance can be used as effectively as a capacitor to block low level incident and conducted RF energy. If in the case of some levels of IEC 61000-4-3 and IEC 61000-4-4 when the intensity of pulse is greater than the device's breakdown capability it will then turn on and suppress via MOV means rather than capacitance (as in the small signal case). Effectiveness hinges upon the proper placement of the device within the PCB (which is usually easily accomplished since TransGuards[®] are so small).

SUMMARY

AVX TransGuards[®] are exceptionally suited to meet the defined portions of the IEC 61000-4 document. Experimentation is critical to proper choice and selection of devices to suppress 61000-4-3/4. Samples are available from your local sales representative.



AVX Multilayer Ceramic Transient Voltage Suppressors Application Notes: Turn on Time Characteristics of AVX Multilayer Varistors

INTRODUCTION

Due to the growing importance of ESD immunity testing, as required by the EMC Directive, proper selection of voltage suppressor devices is critical. The proper selection is a function of the performance of the device under transient conditions. An ideal transient voltage suppressor would reach its “clamping voltage” in zero time. Under the conditions imposed by the 1991 version of IEC 61000-4-2, the actual turn-on-time must be less than one nanosecond to properly respond to the fast leading edge of the waveform defined in the standard.

It has been found during testing of transient suppressors that the response time is very closely dictated by the packaging of the device. Inductance that is present in the connection between the silicon die and the leads of the device creates an impedance in series with the suppressor device; this impedance increases the overall device response time, reducing the effectiveness of the suppressor device.

The purpose of this paper is to present the Turn on Time characteristics of Multilayer Varistors (MLVs) and to compare the MLV Turn on Time to that of various silicon transient voltage suppressors (SiTVs).

The Turn on Time of a transient voltage suppressor (TVS) is of growing importance since IEC 61000-4-2 now specifies ESD waveform with a rise time < 1 ns. Therefore, TVS’s must have a turn on time < 1 ns to effectively suppress ESD. In many, if not all, ESD suppression applications, TVS turn on time can be of more importance than absolute clamping voltage (V_c) of the TVS (assuming that the TVS clamping voltage is less than the damage voltage of the circuit or IC).

To measure the turn on time of today’s TVS’s, a broad cross section of MLVs and SiTVs were chosen. Only surface mount devices were chosen in order to best represent today’s TVS current usage/trends and to keep the test matrix to a reasonable level of simplicity. The following devices were tested:

SMT MLV	SiTVS
	MA141WA
0603	BAV 99
0805	SOT 23 type
1206	SMB - 500W gull-wing SM device
1210	SMC - 1500W gull-wing SM device

TEST PROCEDURE

The TVS device under test (DUT) was placed on a PCB test fixture using SN60/40 solder. The test fixture (see Figure 1) was designed to provide an input region for an 8kV contact ESD discharge waveform (per IEC 61000-4-2 level 4 requirements). In addition, the fixture was designed to provide low impedance connections to the DUTs.

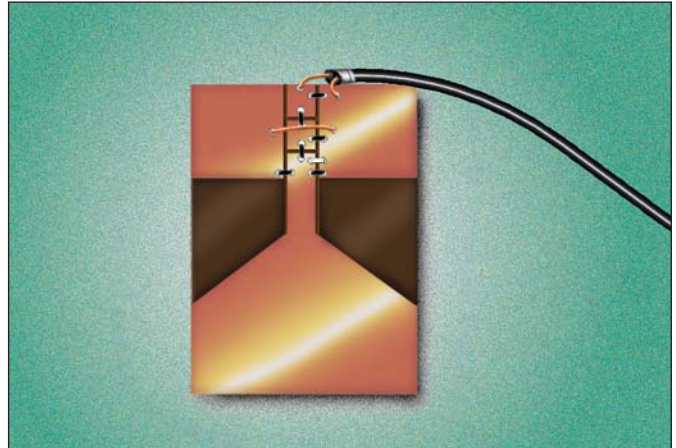


Figure 1. DUT Test Fixture

The ESD pulse was injected to the PCB from a Keytek mini-zap ESD simulator. Additionally, the fixture was to channel the ESD event to a storage oscilloscope to monitor the suppressor’s response. Six resistors were used on the PCB to provide waveshaping and an attenuated voltage to the storage scope (see Figure 2):

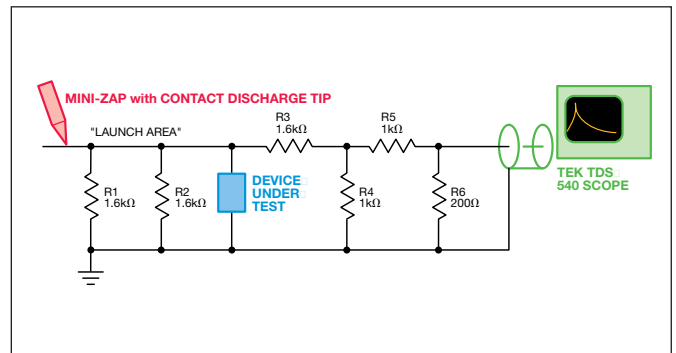


Figure 2. Schematic of Test Set Up

The functions of the resistors are as follows: The resistor values were adjusted in “open circuit” conditions to obtain best open circuit response.

R1, R2 (1.6K) - provide wave shaping during the ESD discharge event

R3 (1.6K), R4 (1K), R5 (1K) - Form a 60 dB Attenuator (1000:1 ratio) for input of Tektronix TDS 540 1 giga sample/second storage oscilloscope

R6 (200 Ω) - provides matching to the 50 ohm coax feeding the TDS 540 oscilloscope.

The open circuit response of the ESD test fixture with a 9kV ESD pulse is shown in Figure 3.

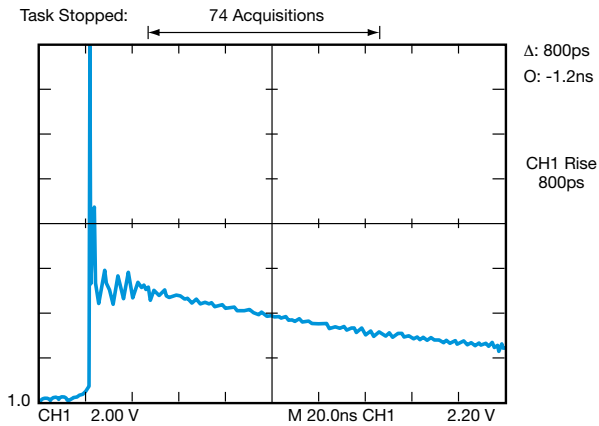


Figure 3. Open Circuit Response of Test Fixture to an Injected ESD Waveform

The graph shows the voltage attenuated by a factor of 1000, with a 800ps risetime for the ESD waveform (this agrees with typical data given by Keytek for equipment performance). It should be noted that only the positive polarity was tested. Prior testing showed turn on time was not dependent upon waveform polarity (assuming that DUTs are bidirectional).

TEST RESULTS

MLV TURN ON TIME TRANSGUARDS®

The turn on time test results for AVX TransGuards® showed that all case sizes were capable of a sub-nanosecond turn on response. This corresponds favorably with the calculated turn on time of less than 1 ns. Specific performance data follows:

AVX TransGuard®	
CASE SIZE	TURN ON SPEED
0603	< 0.7 ns
0805	< 0.9 ns
1206	< 0.9 ns
1210	< 0.8 ns

TVS TURN ON TIME

Test results for SiTVs varied widely depending upon the physical size and silicon die mounting configuration of the device. The results agree with several SiTVs manufacturers papers indicating that the absolute response from the silicon die could be < 1 ns. However, when the die is placed in a package, the turn on time delay increases dramatically. The reason for this is the series inductance of the SiTVs packaging decreases the effective response time of the device. Reports of 1-5 ns are frequently referred to in SiTVs manufacturers publications. Further, the turn on times for SiTVs vary dramatically from manufacturer to manufacturer and also vary within a particular manufacturers lot. The data provided in the following table generally agreed with these findings:

SiTVS	
CASE SIZE	TURN ON SPEED
MA141WA	0.8ns
BAV 99	0.9ns to 1.2ns
SOT 23 Type	0.8ns
SMB	1.5ns to 2.2ns
SMC	1.5ns to 3ns

SUMMARY

This test confirms calculations that show that AVX TransGuards® have a true sub-nanosecond turn on time. Although the silicon die of a SiTVs has a sub-nanosecond response, the packaged SiTVs typically has a response time much slower than a TransGuard®. If the two devices were directly compared on a single graph (see Figure 4), it could be shown that the TransGuard® diverts significantly more power than even the fastest SiTVs devices. Additionally, TransGuards® have a multiple strike capability, high peak inrush current, high thermal stability and an EMI/RFI suppression capability which diodes do not have.

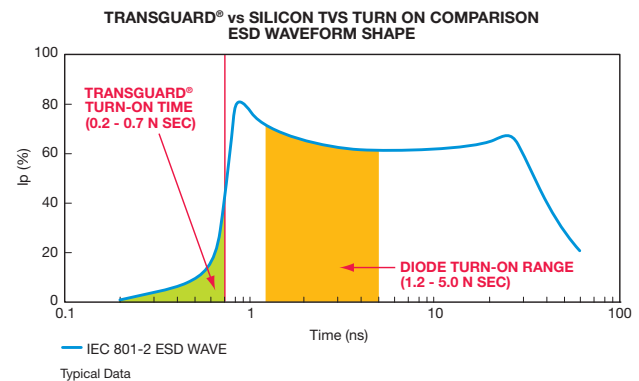


Figure 4.

The purpose of this discussion is to recap the impact ESD has on portable, battery powered equipment. It will be shown that ESD can cause failures in “floating ground systems” in a variety of ways. Specifically, ESD induced failures can be caused by one or more of its complex components:

- Predischarge** - Corona Generated RF
- Predischarge** - E Field
- Discharge** - Collapsing E Field
- Discharge** - Collapsing H Field
- Discharge** - Current Injection...Voltage...Additional Fields

With this in mind it will be shown that the only way to insure equipment survivability to ESD is to use a Transient Voltage Suppressor (in addition to proper circuit layout, decoupling, and shielding).

In order to get a better understanding of what happens in an ESD event the charge developed by a human body should be defined. The ESD schematic equivalent of the human body model is shown in Figure 1. Typically, the charge developed on a person can be represented by a 150pF capacitor in series with a resistance of 330 ohms. The energy of an ESD waveform generated from this model is $Q = 1/2 CV^2$ where Q = total energy in Joules, C = capacitance of the human body model in farads and V = charging voltage in volts.

Voltages can be as high as 25 kV, however typical voltages seen are in the 8 to 15 kV regions.

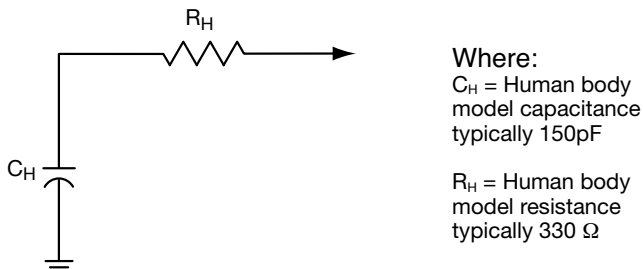


Figure 1. Human Body Model

PREDISCHARGE E FIELD FAILURES

Now that we have a definition of the basic ESD human body model we can discuss the predischarge E field failure mode.

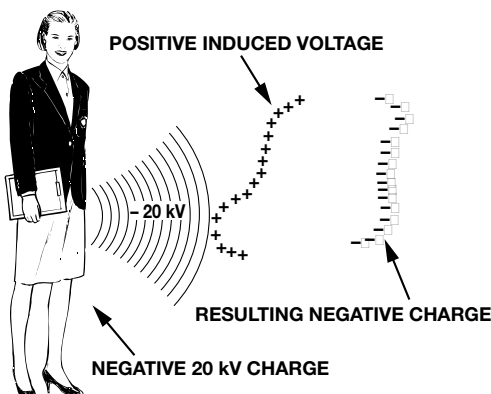


Figure 2. Pre-Discharge Scenario

In the predischarge scenario (Figure 2) a human charged to -20 kV may approach a battery powered “system” on a table. As the person reaches toward the system electrostatics dictate that the system will have an equal and opposite charge on the system’s surface nearest to the person. Since the system we are approaching is isolated from ground, the charge is only redistributed among the device. (If the system were grounded a current would be generated by the loss of electrons to ground. The system would then become positive relative to ground). The rate of approach of the human body model affects the charging current to a small extent. However, most importantly, it is the electrostatic field and the unequal voltages which developed across the equipment that cause the destruction of components within the system. In general, unprotected IC’s (particularly CMOS) are susceptible to damage due to induced E field voltages. This problem is further complicated by the device type and complexity and the fact that the breakdown voltage of a generic IC will vary greatly from manufacturer to manufacturer (Figure 3). This brief discussion should be adequately convincing that electrostatically induced E field can impact system reliability. IC protection can be achieved by placing a transient suppressor on the most susceptible pins of the sensitive IC’s (e.g., Vcc and I/O pins, etc.).

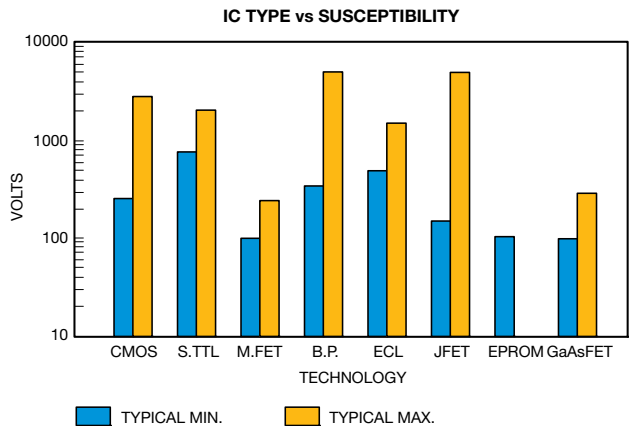


Figure 3. IC Type E Field Susceptibility

CONTACT DISCHARGE FAILURES

As the charged person gets closer to the system, the situation is more complex. First a much more detailed human body model is needed to represent the complex transmission line which will transport energy to the system (see Figure 4). In this discussion we will only consider the case of a single contact discharge. In the real world, however, multiple discharges will likely occur (possibly caused by a person’s hand reacting to an ESD spark and then touching the system again, etc.).

In contact discharge, when a charged person approaches the system, E fields are induced. As the person gets closer to the system, the field intensity becomes greater, eventually reaching a point large enough to draw an arc between the

person and the system. In contrast to the noncontrast E field example, the speed of approach is of great importance in the contact discharge model. A fast approach causes a more intensive discharge and faster current rise times and peaks.

The model shown on Figure 4 can be broken up into 4 sections for the sake of simplification. The first section is the human body model input voltage. This section is identical to the simplified human body model shown in Figure 1.

Section 2 takes into account how the human body model gets the energy to the system. This section considers the inductance, resistance and capacitance of the human's arm and finger and its capacitance relative to ground and the system.

The third section is the inductance and resistance of the arc which is created as section 2 approaches the system (Section 4).

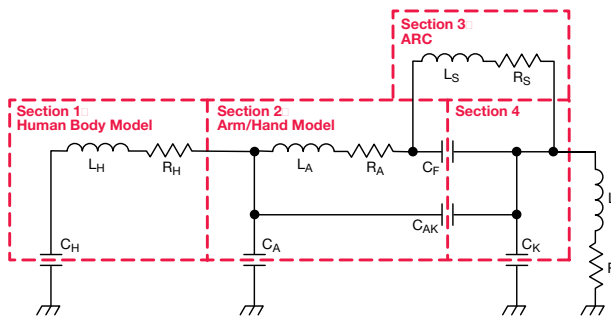
Section four is the system itself.

The combination of the capacitances and inductances in these sections form a complex network of LC tank circuits which will inject a variety of waveforms (transients) into the system. These waveforms will range in frequency from very high (5 GHz) to high (100 MHz) to low (20-50 MHz) plus a variety of under damped and over damped waveforms.

Finally, in addition to current/voltage injection occurring as a result of the discharge, there will be collapsing E and H fields and significant high frequency RF waveforms. Many times these waveforms propagate into shielded equipment and cause system/device failures.

SUMMARY

Designers may be inclined to think that E field variation due to near field electrostatics (as in the person being close to the system but not touching it) can be eliminated by shielding. This is usually not the case because it is difficult to get a tight columbic shield around internal circuitry without incurring significant additional manufacturing costs. Additionally, the shielding will likely have seams, ventilation holes, or I/O ports which represent a significant portion of a wavelength (at 5 GHz). Therefore, E fields and corona generated RF can be a problem. Finally, if the system has I/O connectors, keyboards, antennas, etc., care must be taken to adequately protect them from direct/and indirect transients. The most effective resolution is to place a TransGuard® as close to the device in need of protection as possible. These recommendations and comments are based upon case studies, customer input and Warren Boxleitner's book *Electrostatic Discharge and Electronic Equipment - A Practical Guide for Designing to Prevent ESD Problems*.



- Where: C_H = Lumped capacitance between the human body and earth
 R_H = Lumped resistance of the human body
 L_H = Lumped inductance of the human body
 C_A = Lumped capacitance between the person's arm and earth
 C_{AK} = Lumped capacitance between the person's arm (and near portions of the body) and the keyboard
 R_A = Lumped resistance of the person's arm's discharge path
 L_A = Lumped inductance of the person's arm's discharge path
 C_F = Capacitance between person's finger, hand, and the keyboard
 C_K = Lumped capacitance of the keyboard to earth
 R_K = Lumped resistance of the keyboard earth ground path
 L_K = Lumped inductance of the keyboard earth ground path

Figure 4. Contact Discharge Model

TransGuard®

AVX Multilayer Ceramic Transient Voltage Suppressors

Application Notes: Motor and Relay Application Study



PURPOSE

A significant number of end customers have experienced failures of circuitry in and around low voltage relays and motors. Additionally, EMI problems have been associated with running motors.

This study is aimed at evaluating how TransGuards® can reduce EMI from running motors and clamp transients generated from relays and motors during power off.

DESCRIPTION

Three different motors and two different relays were chosen to represent the wide range of possible devices used by designers. Device choices were as follows:

MOTORS

- Cramer 8001 series Geared Motor
12V, 30rpm (4800 RPM armature speed) 170ma
Start/Run Torque 30oz
- Comair Rotron DC Biscuit Fan - 24V, 480ma
- Comair Rotron DC Biscuit Fan - 12V, 900ma

RELAYS

- Potter and Brumfield 24V Relay
1/3 HP 120V AC, 10A 240 VAC Rating
- Potter and Brumfield 12V Relay
1/3 HP 120V AC, 10A 240 VAC Rating

A Tektronix TDS 784A four channel 1GHz 4G S/s digitizing storage scope was used to capture the -1/2 LI2 transient peak from the relays and motors. A x10 probe was

connected to the scope and one leg of the relay/motor coil; the probe's ground was connected to the other relay coil/motor wire. The scope was triggered on the pulse and waveforms printed.

When suppression was introduced into the circuit, it was placed directly on the relay coils/motor lead wires. The axial TransGuard® and capacitors had a 19mm (3/4") total lead length in each case. Upon careful consideration, it was determined that this was a fairly common lead length for such applications.

SUMMARY

GEARED MOTOR

The Cramer geared motor was tested while running (under load) to determine its "on state" noise as well as under loaded turn off conditions. Both TransGuards® and ceramic capacitors were tested to determine the level of protection they offer.

A 14V axial TransGuard® provided the best protection during running and turn off. The VA100014D300 TransGuard® cut the 60V unprotected turn off voltage spike to 30V. It also cut the on state noise to 4.0V pk-pk due to its internal capacitance. The following is a summary of measured voltages (scope traces are shown in Figures 1, 1A, 2, 2A).

Test Condition	Transient without Protection	Transient with .1µF cap	Transient with .01µF cap	Transient with 14V TransGuard®
Geared motor at turn off	60V	32V	48V	30V
Geared motor during running	12V pk-pk	4.0V pk-pk	4.0V pk-pk	4.0V pk-pk

Fig. 1. Geared Motor Transient at Turnoff without protection 60 V Gear Motor 20 V/Division

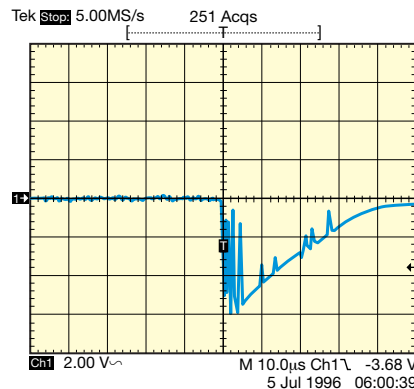


Fig. 2. Geared Motor Running noise without protection 12 V pk-pk 2 V/Division

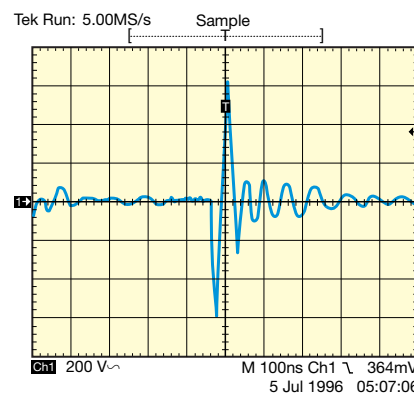


Fig. 1A. Geared Motor Transient at Turnoff with 14 V TransGuard® 30 V 10 V/Division

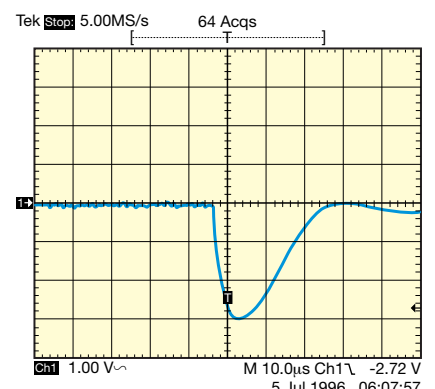
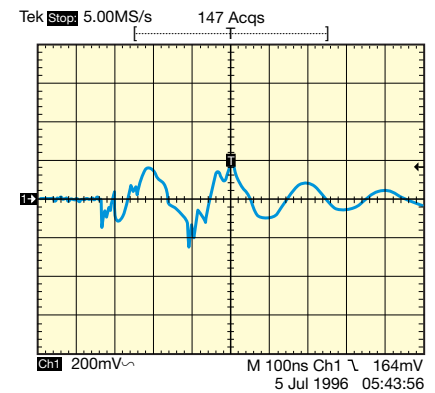


Fig. 2A. Geared Motor Running with 14 V TransGuard® 4 V pk-pk 2 V/Division



TransGuard[®]

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Application Notes: Motor and Relay Application Study



BISCUT FAN

The Comair 24V and 12V biscut fans were tested only for transients at turn off. Results of those tests are shown in the table at the right (as well as slope traces 3, 3A, 4, 4A).

Motor Type	Transient without Protection	Transient with .1 μ F cap	Transient with .01 μ F cap	Transient with TransGuard [®]
24V Fan	165V	120V	140V	65V ⁽¹⁾
12V Fan	60V	52V	64V	30V ⁽²⁾

(1) VA100030D650 TransGuard[®] / (2) VA100014D300 TransGuard[®]

Fig. 3. 24 V Biscut Fan without protection
165 V Biscut 50 V/Division

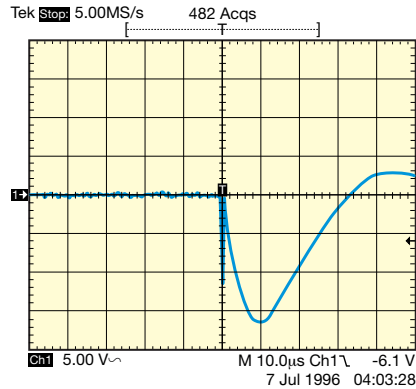


Fig. 3A. 24 V Biscut Fan with 30 V TransGuard[®]
65 V 50 V/Division

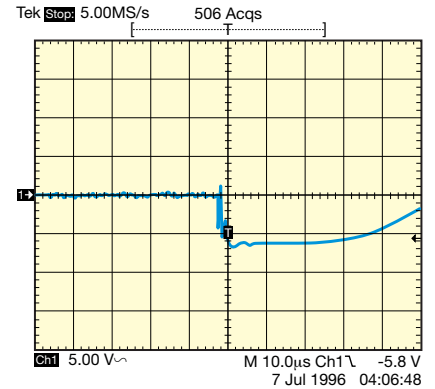


Fig. 4. 12 V Biscut Fan without protection
60 V 20 V/Division

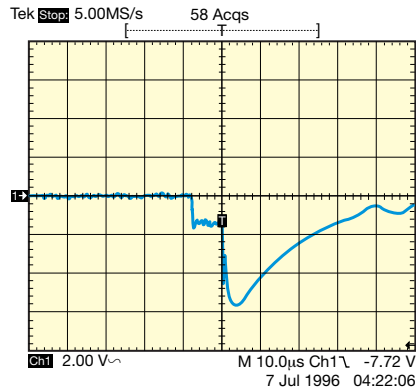
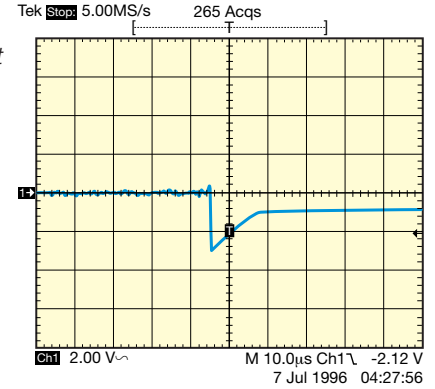


Fig. 4A. 12 V Biscut Fan with 14 V TransGuard[®]
30 V 20 V/Division



TransGuard[®]

AVX Multilayer Ceramic Transient Voltage Suppressors

Application Notes: Motor and Relay Application Study



RELAYS

The 12V and 24V relays were tested only for transients at turn off. The results of those tests are shown in the table at the right (as well as scope traces 5, 5A, 6, 6A).

Relay Type	Transient without Protection	Transient with .1 μ F cap	Transient with .01 μ F cap	Transient with TransGuard [®]
24V	44V	24V	28V	28V ⁽³⁾
12V	105V	63V	100V	30V ⁽⁴⁾

⁽³⁾ VA100026D580 TransGuard[®] / ⁽⁴⁾ VA100014D300 TransGuard[®]

Fig. 5. 24 V Relay Transient without protection
44 V 10 V/Division

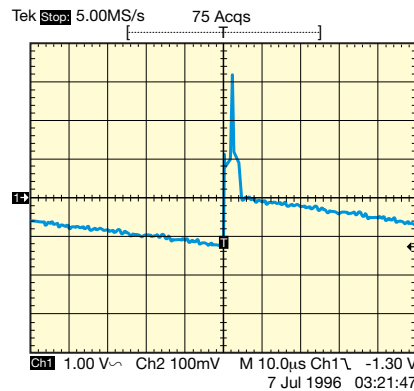


Fig. 5A. 24 V Relay Transient with 26 V TransGuard[®]
10 V/Division

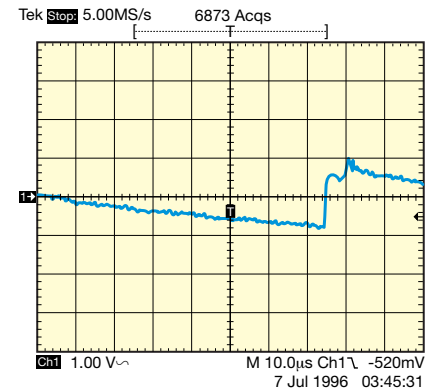


Fig. 6. 12 V Relay Transient without protection
105 V 50 V/Division

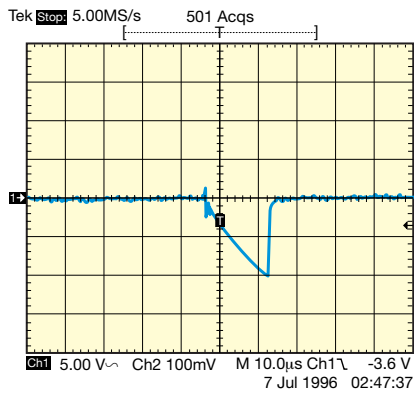
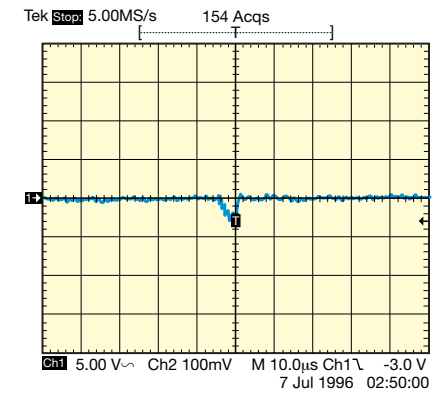


Fig. 6A. 12 V Relay Transient with 14 V TransGuard[®]
30 V 50 V/Division



CONCLUSIONS

TransGuards[®] can clamp the wide range of voltages coming from small/medium motors and relays due to inductive discharge. In addition, TransGuards[®] capacitance can help reduce EMI/RFI. Proper selection of the TransGuards[®] voltage is critical to clamping efficiency and correct circuit operation.

The current trend in automobiles is towards increased performance, comfort and efficiency. To achieve these goals, automobile companies are incorporating an ever increasing array of electronics into cars. As the electronic content within cars increases, auto manufacturers are utilizing multiplex bus designs to network all the sensors to a central point (usually the engine control unit [ECU]). Multiplex lines save wiring harness weight and decrease the harness' complexity, while allowing higher communication speeds. However, the multiplex structure tends to increase the occurrence and severity of Electromagnetic Interference (EMC) and Electrostatic Discharge (ESD).

Multilayer varistors (MLVs) are a single component solution for auto manufacturers to utilize on multiplex nodes to eliminate both ESD and EMC problems. MLVs also offer improved reliability rates (FIT rates <1 failure/billion hours) and smaller designs over traditional diode protection schemes.

TYPICAL MUX NODE APPLICATION

There are a variety of SAE recommended practices for vehicle multiplexing (J-1850, J-1939, J-1708, J-1587, CAN). Given the number of multiplexing specifications, it is easy to understand that bus complexity will vary considerably.

Each node has an interface circuit which typically consists of a terminating resistor (or sometimes a series limiting resistor), back to back Zener diodes (for over voltage protection) and an EMC capacitor. Such a method is compared to that of a multilayer varistor in Figure 1.

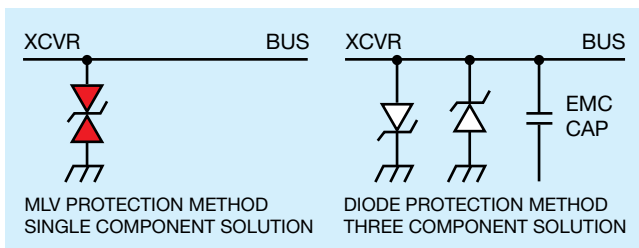


Figure 1. Comparison of past node protection methods to MLV node protection methods.

To more clearly understand the functional structure of a MLV, see the equivalent electrical model shown in Figure 2.

- MULTIPLE ELECTRODES YIELD A CAPACITANCE
- THE CAPACITANCE CAN BE USED IN DECOUPLING
- CAPACITANCE CAN BE SELECTED FROM 30pF TO 4700pF

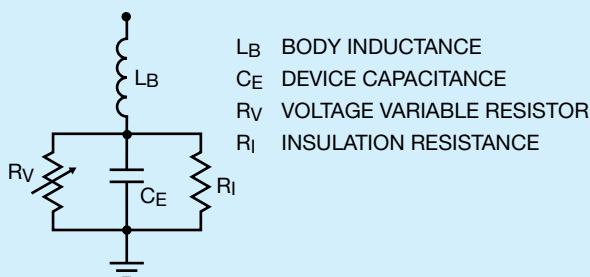


Figure 2. TransGuard® Equivalent Model.

As the schematic in Figure 1 illustrates, the implementation of MLV protection methods greatly simplifies circuit layout, saves PCB space and improves system reliability. The MLV offers many additional electrical improvements over the Zener/passive schemes. Among those advantages are higher multiple strike capability, faster turn on time and larger transient overstrike capability. Further clarification on the types of varistors compared to the performance of Zener diodes follows.

CONSTRUCTION AND PHYSICAL COMPARISON

The construction of Zinc Oxide (ZnO) varistors is a well known, relatively straightforward process in which ZnO grains are doped with cobalt, bismuth, manganese and other oxides. The resulting grains have a Schottky barrier at the grain interface and a typical grain breakdown voltage (V_b) of approximately 3.6V per grain.

Currently, there are two types of varistors. Single layer varistors (SLVs) – an older technology referred to as “pressed pill,” typically are larger, radial leaded components designed to handle significant power. Multilayer varistors (MLVs) are a relatively new technology packaged in true EIA SMT case sizes.

Beyond the ZnO material system and grain breakdown similarity, MLVs and SLVs have little in common. That is, to design a low voltage SLV, the grains must be grown as large as possible to achieve a physically large enough part to be handled in the manufacturing process. Typically it is very difficult to obtain a consistent grain size in a low voltage SLV process.

The electrical performance of SLV is affected by inconsistent grain size in two ways. First, low voltage SLVs often exhibit an inconsistent V_b and leakage current (I_L) from device to device within a particular manufacturing lot of a given rating. This contributes to early high voltage repetitive strike wear out.

Secondly, SLVs with similar voltage and energy ratings as MLVs typically exhibit a lower peak current capability due in part to increased resistance of the long current path of the large grains. This contributes to early repetitive high current wear out.

At higher voltages, the grain size variations within SLVs play a much smaller percentage role in V_b and leakage current values. As a result, SLVs are the most efficient cost effective way to suppress transients in high voltages (e.g., 115 VAC, 220 VAC).

MLV MANUFACTURE

The construction of a MLV was made possible by employing a variety of advanced multilayer chip capacitors (MLCC) manufacturing schemes coupled with a variety of novel and proprietary ZnO manufacturing steps. In the MLCC process, thin dielectrics are commonly employed to obtain very large capacitance values. It is that capability to design and manufacture multilayer structures with dielectric thicknesses of ≤ 1 mil that allows MLVs to be easily made with operating/working voltages (V_{wm}) as low as 3.3V (for use in next generation silicon devices).

Once a particular working voltage has been determined (by altering the ZnO dielectric thickness), the multilayer varistor's transient energy capability is determined by the number of layers of dielectric and electrodes. It is, therefore, generally easy to control the grain size and uniformity within a MLV due to the relative simplicity of this process.

MLVs exhibit capacitance due to their multiple electrode design and the fact that ZnO is a ceramic dielectric. This capacitance can be utilized with the device's series inductance to provide a filter to help limit EMI/RFI. The equivalent model of a MLV is shown in Figure 2.

MLVs are primarily used as transient voltage suppressors. In their "on" state, they act as a back-to-back Zener, diverting to ground any excess, unwanted energy above their clamping voltage. In their "off" state, they act as an EMC capacitor (capacitance can be minimized for high speed applications). A single MLV, therefore, can replace the diode, capacitor and resistor array on multiplex node applications.

Any TVS will see a large number of transient strikes over its lifetime. These transient strikes will result from different events such as well known ESD HBM, IC MM, alternator field decay, load dump models and uncontrolled random events. It is because of the repetitive strikes that all TVS suppressors should be tested for multiple strike capability. Typically, a TVS will fail due to high voltage, high current or over-energy strikes.

High voltage repetitive strikes are best represented by IEC 61000-4-2 8kV waveforms. MLVs demonstrate a greatly superior capability to withstand repetitive ESD high voltage discharge without degradation.

High current repetitive strikes are represented by 8x20 μ s 150A waveforms. A comparison between MLVs, SLVs and SiTVS is shown in Figures 3A, B, C respectively.

SILICON TVS MANUFACTURE

The construction of a silicon TVS departs dramatically from that of either single layer varistor or multilayer varistor construction. Devices are generally produced as Zener diodes with the exception that a larger junction area is designed into the parts and additional testing was likely performed. After the silicon die is processed in accordance to standard semi-conductor manufacturing practice, the TVS die is connected to a heavy metal lead frame and molded into axial and surface mount (SMT) configuration.

MLVs COMPARED TO DIODES

The response time for a silicon diode die is truly sub-nanosecond. The lead frame into which the die is placed and the wire bonds used for die connections introduce a significant amount of inductance. The large inductance of this packaging causes a series impedance that slows the response time of SiTVS devices. A best case response time of 8nS on SOT23 and a 1.5nS to 5nS response time on SMB and SMC products respectively are rather typical. MLVs turn on time is < 7 nS. MLVs turn on time is faster than SiTVS and that fast turn on time diverts more energy and current away from the IC than any other protection device available.

CONCLUSION

The technology to manufacture MLVs exists and allows the manufacture of miniature SMT surge suppressors. MLVs do not have the wear out failure mode of first generation (single layer) varistors. In fact, MLVs exhibit better reliability numbers than that of TVS diodes. MLVs are a viable protection device for auto multiplex bus applications.

Written by Ron Demcko

Originally printed in EDN PRODUCTS EDITION December 1997 by CAHNERS PUBLISHING COMPANY

150 AMP Current Repetitive Strike Comparison

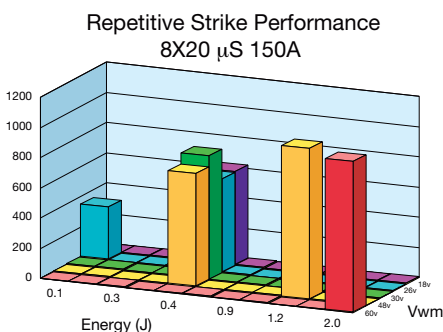


Figure 3A. Multilayer Varistor.

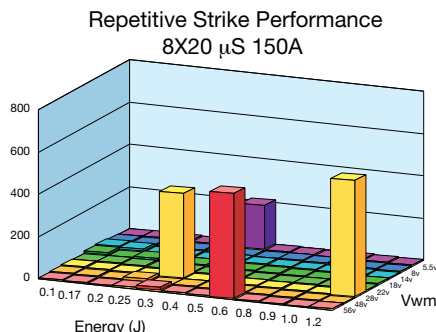


Figure 3B. Single Layer Varistor.

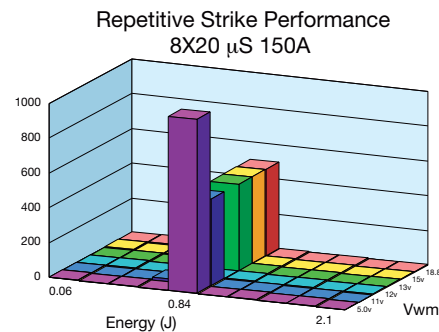


Figure 3C. Silicon TVS.

AVX *TransGuard*[®]

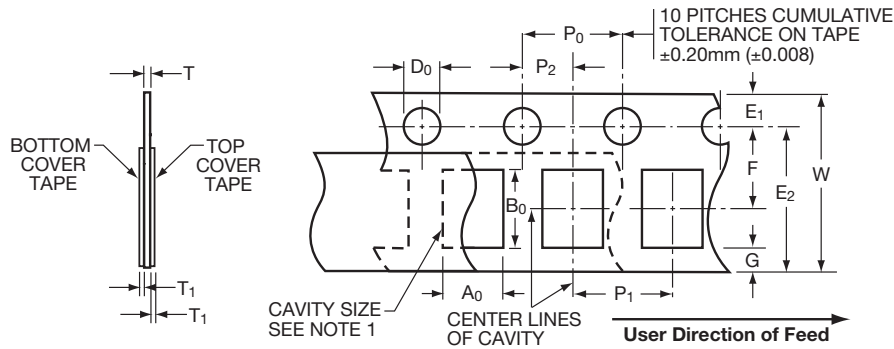
PACKAGING

- Chips
- Axial Leads

Paper Carrier Configuration



8mm Tape Only



8mm Paper Tape Metric Dimensions Will Govern

CONSTANT DIMENSIONS

Tape Size	D_0	E	P_0	P_2	T_1	G. Min.	R Min.
8mm	$1.50^{+0.10}_{-0.00}$ ($0.059^{+0.004}_{-0.004}$)	1.75 ± 0.10 (0.069 ± 0.004)	4.00 ± 0.10 (0.157 ± 0.004)	2.00 ± 0.05 (0.079 ± 0.002)	0.10 (0.004) Max.	0.75 (0.030) Min.	25.0 (0.984) See Note 2 Min.

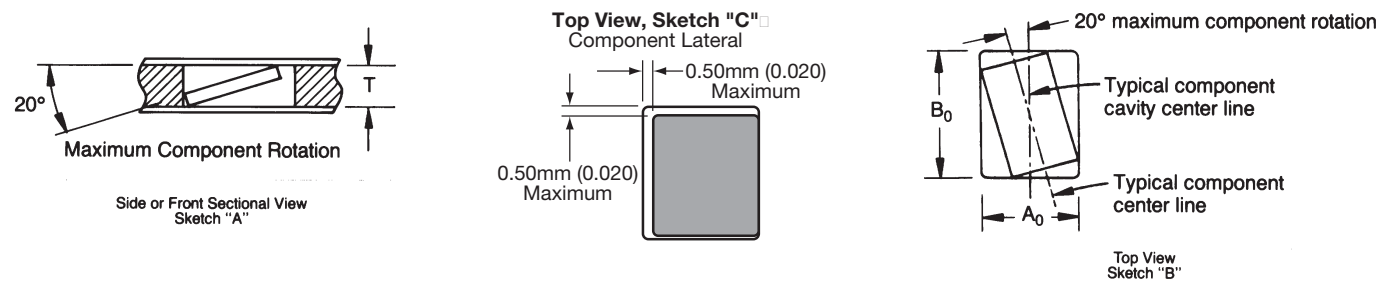
VARIABLE DIMENSIONS

Tape Size	P_1 See Note 4	E_2 Min.	F	W	$A_0 B_0$	T
8mm	4.00 ± 0.10 (0.157 ± 0.004)	6.25 (0.246)	3.50 ± 0.05 (0.138 ± 0.002)	$8.00^{+0.08}_{-0.08}$ ($0.315^{+0.012}_{-0.012}$)	See Note 1	1.10mm (0.043) Max. for Paper Base Tape and 1.60mm (0.063) Max. for Non-Paper Base Compositions

NOTES:

- The cavity defined by A_0 , B_0 , and T shall be configured to provide sufficient clearance surrounding the component so that:
 - the component does not protrude beyond either surface of the carrier tape;
 - the component can be removed from the cavity in a vertical direction without mechanical restriction after the top cover tape has been removed;
 - rotation of the component is limited to 20° maximum (see Sketches A & B);
 - lateral movement of the component is restricted to 0.5mm maximum (see Sketch C).

- Tape with or without components shall pass around radius "R" without damage.
- Bar code labeling (if required) shall be on the side of the reel opposite the sprocket holes. Refer to EIA-556.
- If $P_1 = 2.0$ mm, the tape may not properly index in all tape feeders.



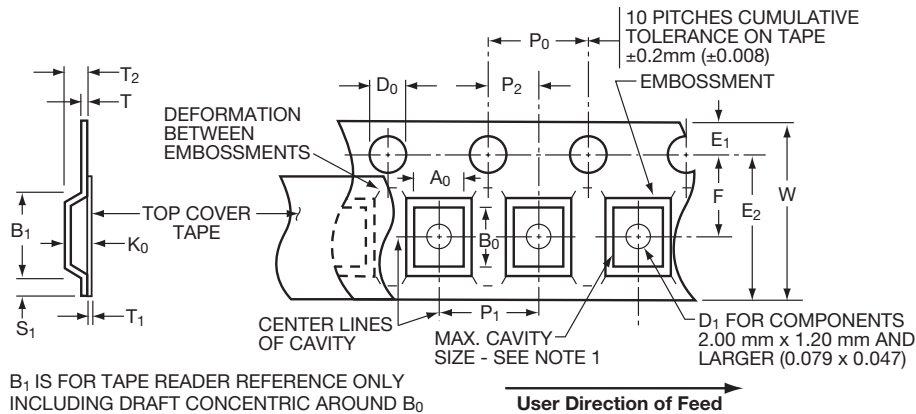
Bar Code Labeling Standard

AVX bar code labeling is available and follows latest version of EIA-556

Embossed Carrier Configuration



8 & 12mm Tape Only



8 & 12mm Embossed Tape Metric Dimensions Will Govern

CONSTANT DIMENSIONS

mm (inches)

Tape Size	D ₀	E	P ₀	P ₂	S ₁ Min.	T Max.	T ₁
8mm and 12mm	1.50 ^{+0.10} _{-0.0} (0.059 ^{+0.004} _{-0.0})	1.75 ± 0.10 (0.069 ± 0.004)	4.0 ± 0.10 (0.157 ± 0.004)	2.0 ± 0.05 (0.079 ± 0.002)	0.60 (0.024)	0.60 (0.024)	0.10 (0.004) Max.

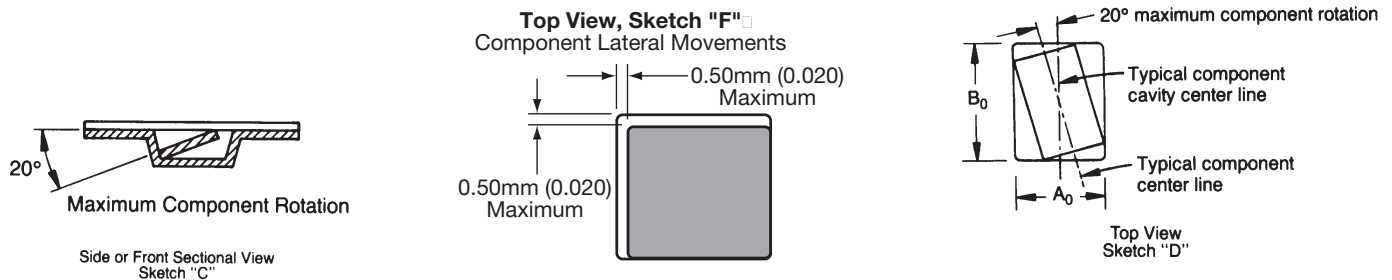
VARIABLE DIMENSIONS

mm (inches)

Tape Size	B ₁ Max.	D ₁ Min.	E ₂ Min.	F	P ₁ See Note 5	R Min. See Note 2	T ₂	W Max.	A ₀ B ₀ K ₀
8mm	4.35 (0.171)	1.00 (0.039)	6.25 (0.246)	3.50 ± 0.05 (0.138 ± 0.002)	4.00 ± 0.10 (0.157 ± 0.004)	25.0 (0.984)	2.50 Max. (0.098)	8.30 (0.327)	See Note 1
12mm	8.20 (0.323)	1.50 (0.059)	10.25 (0.404)	5.50 ± 0.05 (0.217 ± 0.002)	4.00 ± 0.10 (0.157 ± 0.004)	30.0 (1.181)	6.50 Max. (0.256)	12.3 (0.484)	See Note 1

NOTES:

- The cavity defined by A₀, B₀, and K₀ shall be configured to provide the following:
 - the component does not protrude beyond the sealing plane of the cover tape.
 - the component can be removed from the cavity in a vertical direction without mechanical restriction, after the cover tape has been removed.
 - rotation of the component is limited to 20° maximum (see Sketches D & E).
 - lateral movement of the component is restricted to 0.5mm maximum (see Sketch F).
- Tape with or without components shall pass around radius "R" without damage.
- Bar code labeling (if required) shall be on the side of the reel opposite the round sprocket holes. Refer to EIA-556.
- B₁ dimension is a reference dimension for tape feeder clearance only.
- If P₁ = 2.0mm, the tape may not properly index in all tape feeders.

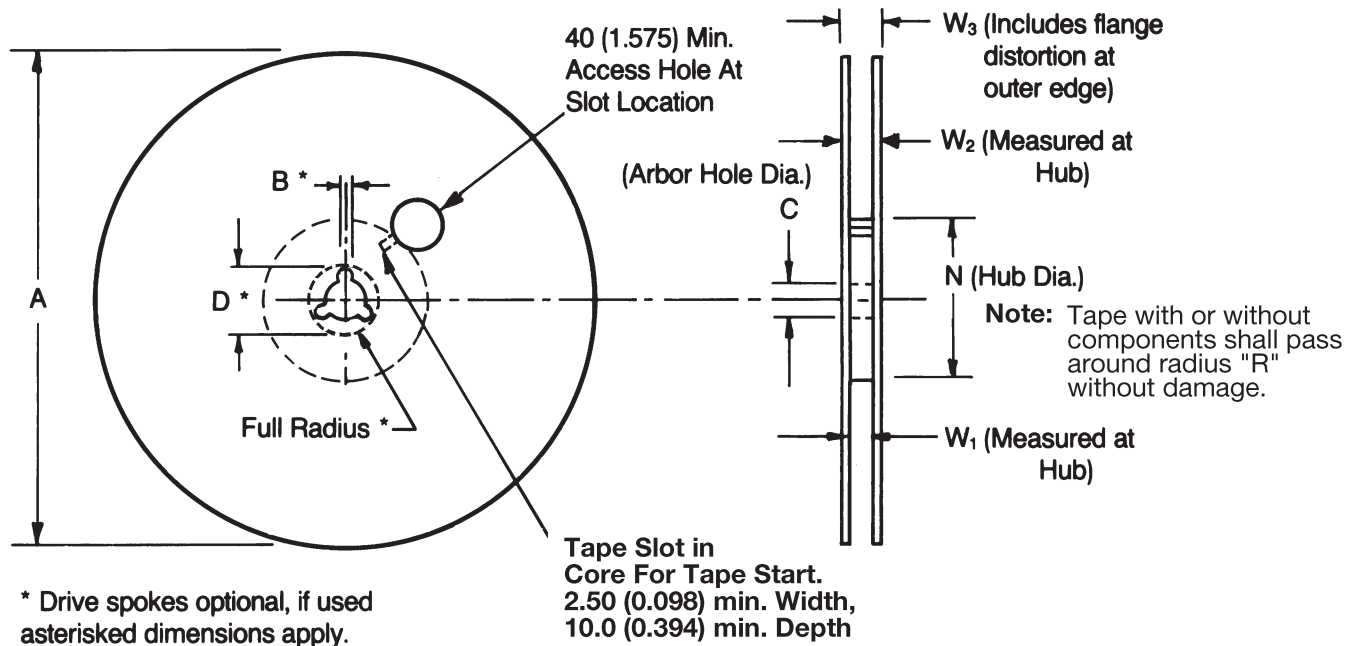


Packaging of Chip Components



Automatic Insertion Packaging

REEL DIMENSIONS



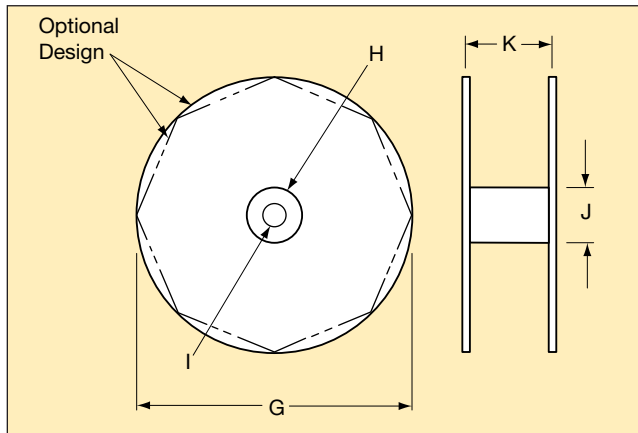
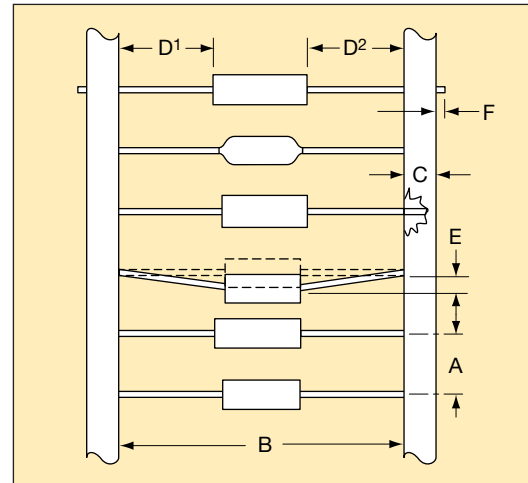
mm (inches)

Tape Size	A Max.	B* Min.	C	D* Min.	N Min.	W ₁	W ₂ Max.	W ₃
8mm	330 (12.992)	1.5 (0.059)	13.0 ^{+0.50} _{-0.20} (0.512 ^{+0.020} _{-0.008})	20.2 (0.795)	50.0 (1.969)	8.40 ^{+1.5} _{-0.0} (0.331 ^{+0.059} _{-0.0})	14.4 (0.567)	7.90 Min. (0.311)
12mm						12.4 ^{+2.0} _{-0.0} (0.488 ^{+0.079} _{-0.0})		11.9 Min. (0.469)
								10.9 Max. (0.429)
								15.4 Max. (0.607)

Metric dimensions will govern.
English measurements rounded and for reference only.

PACKAGING - AXIAL LEADS / TAPE AND REEL

CLASS I / RS-296	
A.	5mm ± 0.5mm (0.200" ± 0.020")
B*	52.4mm ± 1.5mm (2.063" ± 0.059")
C.	6.35mm ± 0.4mm (0.250" ± 0.016")
D ¹ -D ² .	1.4mm (0.055" MAX.)
E.	1.2mm (0.047" MAX.)
F.	1.6mm (0.063" MAX.)
G.	356mm (14.00" MAX.)
H.	76mm (3.000")
I.	25.4mm (1.000")
J.	84mm (3.300")
K.	70mm (2.750")



Leader Tape: 300mm min. (12")

Splicing: Tape Only

Missing Parts: 0.25% of component count max.-
No consecutive missing parts

AMERICAS

AVX Greenville, SC
Tel: 864-967-2150

AVX Northwest, WA
Tel: 360-699-8746

AVX Midwest, IN
Tel: 317-861-9184

AVX Mid/Pacific, CA
Tel: 408-988-4900

AVX Northeast, MA
Tel: 617-479-0345

AVX Southwest, CA
Tel: 949-859-9509

AVX Canada
Tel: 905-238-3151

AVX South America
Tel: +55-11-4688-1960

EUROPE

AVX Limited, England
Tel: +44-1276-697000

AVX S.A.S., France
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AVX GmbH, Germany
Tel: +49-0811-95949-0

AVX SRL, Italy
Tel: +39-02-614-571

AVX Czech Republic
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AVX/ELCO UK
Tel: +44-1638-675000

ELCO Europe GmbH
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KED Taiwan Ltd.
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